

# Fusion Family of Mixed-Signal Flash FPGAs with Optional Soft ARM® Support



#### **Features and Benefits**

# High Performance Reprogrammable Flash Technology

- Advanced 130-nm, 7-Layer Metal, Flash-Based CMOS Process
- Nonvolatile, Retains Program When Powered-Off
- Live at Power-Up (LAPU) Single-Chip Solution
- 350 MHz System Performance

### **Embedded Flash Memory**

- User Flash Memory 2 Mbits to 8 Mbits
  - Configurable 8-, 16-, or 32-Bit Datapath
  - 10 ns Access in Read-Ahead Mode
- 1 kbit of Additional FlashROM

#### Integrated A/D Converter (ADC) and Analog I/O

- Up to 12 bit resolution and Up to 600 ksps
- Internal 2.56 V or External Reference Voltage
- ADC: Up to 30 Scalable Analog Input Channels
- High Voltage Input Tolerance ±12 V
- Current Monitor and Temperature Monitor Blocks
- Up to 10 MOSFET Gate Driver Outputs
  - P- and N-Channel Power MOSFET support
  - Programmable 1, 3, 10, 30 μA and 25 mA Drive Strengths

#### **On-Chip Clocking Support**

- Internal 100 MHz RC Oscillator (accurate to 1%)
- Crystal Oscillator Support (32 kHz to 20 MHz)
- Programmable Real-Time Counter (RTC)
- 6 Clock Conditioning Circuits (CCCs) with 1 or 2 Integrated PLLs
  - Phase Shift, Multiply/Divide, and Delay Capabilities

#### Frequency: Input (1.5–350 MHz), Output (0.75–350 MHz)

#### **Low Power Consumption**

- Single 3.3 V Power Supply with On-Chip 1.5 V Regulator
- Sleep and Standby Low Power Modes

### In-System Programming (ISP) and Security

- Secure ISP with 128-Bit AES Via JTAG
- FlashLock<sup>®</sup> to Secure FPGA Contents

#### Advanced Digital I/O

- 1.5 V, 1.8 V, 2.5 V, and 3.3 V Mixed-Voltage Operation
- Bank-Selectable I/O Voltages Up to 5 Banks per Chip
- Single-Ended I/O Standards: LVTTL, LVCMOS 3.3 V / 2.5 V / 1.8 V / 1.5 V, 3.3 V PCI / 3.3 V PCI-X and LVCMOS 2.5 V / 5.0 V Input
- Differential I/O Standards: LVPECL, LVDS, BLVDS, and M-LVDS
  - Built-In I/O Registers
  - 700 Mbps DDR Operation
- Hot-Swappable I/Os
- Programmable Output Slew Rate, Drive Strength, and Weak Pull-Up/Down Resistor
- Pin-Compatible Packages Across the Fusion Family

#### **SRAMs and FIFOs**

- Variable-Aspect-Ratio 4,608-Bit SRAM Blocks (x1, x2, x4, x9, and x18 organizations available)
- True Dual-Port SRAM (except x18)
- Programmable Embedded FIFO Control Logic

#### Soft ARM7™ Core Support in M7 Fusion Devices

CoreMP7Sd (with debug) and CoreMP7S (without debug)

Table 1	•	Fusion	Family

Fusion Devices		AFS090	AFS250	AFS600	AFS1500
ARM-Enabled Fusion Devices				M7AFS600	M7AFS1500
	System Gates	90,000	250,000	600,000	1,500,000
	Tiles (D-Flip-Flops)	2,304	6,144	13,824	38,400
	Usable Tiles with CoreMP7S <sup>1</sup>			7,500	32,000
General Information	Usable Tiles with CoreMP7Sd <sup>1</sup>			5,237	29,878
illolliation	Secure (AES) ISP	Yes	Yes	Yes	Yes
	PLLs	1	1	2	2
	Globals	18	18	18	18
	Flash Memory Blocks (2 Mbits)	1	1	2	4
	Total Flash Memory Bits	2 M	2 M	4 M	8 M
Memory	FlashROM Bits	1 k	1 k	1 k	1 k
	RAM Blocks (4,608 bits)	6	8	24	60
	RAM kbits	27	36	108	270
	Analog Quads	5	6	10	10
	Analog Input Channels	15	18	30	30
Analog and I/Os	Gate Driver Outputs	5	6	10	10
	I/O Banks (+ JTAG)	4	4	5	5
	Maximum Digital I/Os <sup>2</sup>	75	114	172	252
	Analog I/Os	20	24	40	40

#### Notes:

- 1. Refer to the CoreMP7 datasheet for more information.
- 2. Some debug tools require 10 digital I/Os for external connection.

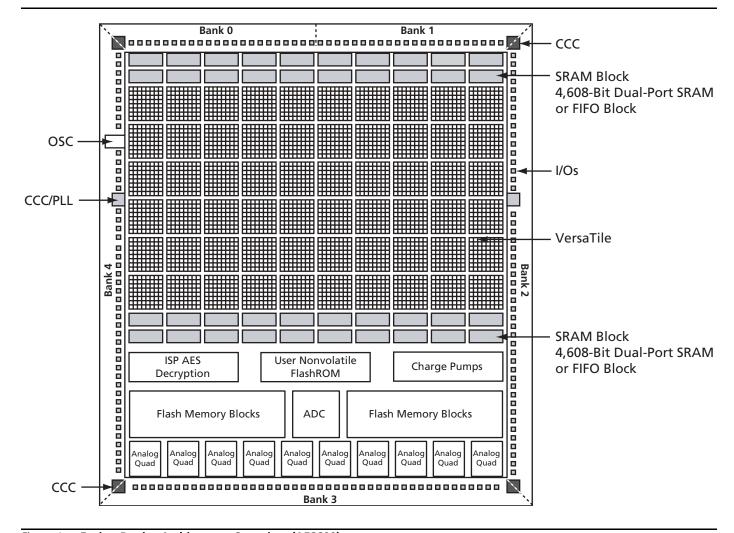


Figure 1 • Fusion Device Architecture Overview (AFS600)

# Package I/Os: Single/Double-Ended (Analog)

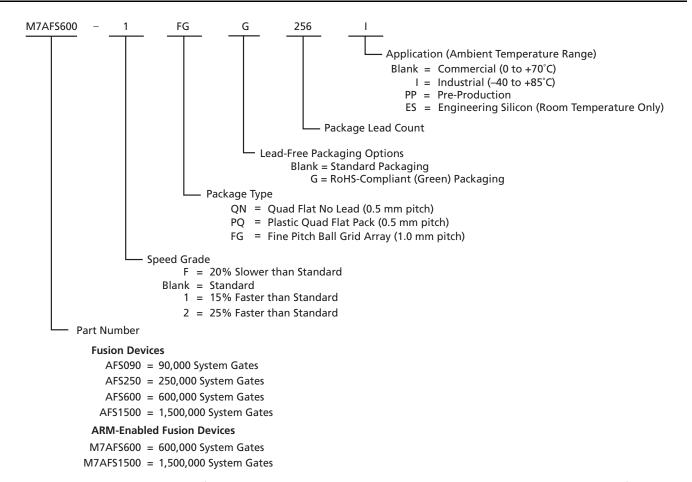
Fusion Devices	AFS090	AFS250	AFS600	AFS1500
ARM-Enabled Devices			M7AFS600	M7AFS1500
QN108	37/9 (16)			
QN180	60/16 (20)	65/15 (24)		
PQ208		93/26 (24)	95/46 (40)	
FG256	75/22 (20)	114/37 (24)	119/58 (40)	119/58 (40)
FG484			172/86 (40)	223/109 (40)
FG676				252/126 (40)

Note: All devices in the same package are pin compatible with the exception of the PQ208 package (AFS250 and AFS600).

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# **Product Ordering Codes**



**Note:** DC and switching characteristics for –F speed grade targets based only on simulation. The characteristics provided for –F speed grade are subject to change after establishing FPGA specifications. Some restrictions might be added and will be reflected in future revisions of this document. The –F speed grade is only supported in commercial temperature range.

# **Temperature Grade Offerings**

Fusion Devices	AFS090	AFS250	AFS600	AFS1500
ARM-Enabled Devices			M7AFS600	M7AFS1500
QN108	С, І	-	-	-
QN180	С, І	С, І	_	-
PQ208	-	С, І	С, І	-
FG256	С, І	С, І	C, I	С, І
FG484	_	_	С, І	С, І
FG676	_	_	-	С, І

#### Notes:

- 1. C = Commercial Temperature Range: 0°C to 70°C Ambient
- 2. I = Industrial Temperature Range: -40°C to 85°C Ambient

# **Speed Grade and Temperature Grade Matrix**

	_F <sup>1</sup>	Std.	-1	-2
C <sup>2</sup>	✓	✓	✓	✓
l <sup>3</sup>	-	✓	✓	✓

#### Notes:

- 1. DC and switching characteristics for –F speed grade targets based only on simulation. The characteristics provided for –F speed grade are subject to change after establishing FPGA specifications. Some restrictions might be added and will be reflected in future revisions of this document. The –F speed grade is only supported in commercial temperature range.
- 2. C = Commercial Temperature Range: 0°C to 70°C Ambient
- 3. I = Industrial Temperature Range: -40°C to 85°C Ambient

Contact your local Actel representative for device availability (http://www.actel.com/contact/offices/index.html).

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# **Introduction and Overview**

### Introduction

The Actel Fusion™ Programmable System Chip (PSC) satisfies the demand from system architects for a device that simplifies design and unleashes their creativity. As the world's first mixed-signal FPGA family, Fusion integrates mixed-signal analog, Flash memory, and FPGA fabric in a monolithic PSC. Actel Fusion devices enable designers to quickly move from concept to completed design, and then deliver feature-rich systems to market. This new technology takes advantage of the unique properties of Actel Flash-based FPGAs, including a highisolation, triple-well process, and the ability to support high-voltage transistors to meet the demanding requirements of mixed-signal system design.

Actel Fusion PSCs bring the benefits of programmable logic to many application areas, including power management, smart battery charging, clock generation and management, and motor control. Until now, these applications have only been implemented with costly and space-consuming discrete analog components or mixed-signal ASIC solutions. Actel Fusion PSCs present new capabilities for system development by allowing designers to integrate a wide range of functionality into a single device, while at the same time offering the flexibility of upgrades late in the manufacturing process or after the device is in the field. Actel Fusion devices provide an excellent alternative to costly and timeconsuming mixed-signal ASIC designs. In addition, when used in conjunction with the Actel 8051-based or ARMbased soft MCU core, the Actel Fusion technology represents the definitive PSC platform.

Flash-based Fusion devices are live at power-up. As soon as system power is applied and within normal operating specifications, Fusion devices are working. Fusion devices have a 128-bit Flash-based lock and industry-leading AES decryption, used to secure programmed intellectual property (IP) and configuration data. Actel Fusion devices are the most comprehensive single-chip analog and digital programmable logic solution available today. To support this new ground-breaking technology, Actel has developed a series of major tool innovations to help maximize designer productivity. Implemented as extensions to the popular Actel Libero® Integrated Design Environment (IDE), these new tools will allow designers to easily instantiate and configure peripherals within a design, establish links between peripherals, create or import building blocks or reference designs, and perform hardware verification. This tools suite will

also add a comprehensive hardware/software debug capability as well as a suite of utilities to simplify development of embedded soft processor-based solutions.

## **General Description**

The Actel Fusion family, based on the highly successful ProASIC®3 and ProASIC3E Flash FPGA architecture, has been designed as a high-performance, programmable, mixed-signal platform. By combining an advanced Flash FPGA core with Flash memory blocks and analog peripherals, Fusion devices dramatically simplify system design, and as a result, dramatically reduce overall system cost and board space.

The state-of-the-art Flash memory technology offers high-density integrated Flash memory blocks, enabling savings in cost, power, and board area relative to external Flash solutions, while providing increased flexibility and performance. The Flash memory blocks and integrated analog peripherals enable true mixed-mode programmable logic designs. Two examples include using an on-chip soft processor to implement a fully functional Flash MCU, or using high-speed FPGA logic to offer system and power supervisory capabilities. Live at power-up and capable of operating from a single 3.3 V supply, the Fusion family is ideally suited for system management and control applications.

The devices in the Fusion family are categorized by FPGA core density. Each family member contains many peripherals, including Flash memory blocks, analog to digital converter (ADC), high-drive outputs, both RC and crystal oscillators, and real-time counter (RTC). This provides the user with a high level of flexibility and integration to support a wide variety of mixed-signal applications. The Flash memory block capacity ranges from 2 Mbits to 8 Mbits. The integrated 12-bit ADC supports up to 30 independently configurable input channels. The on-chip crystal and RC oscillators work in conjunction with the integrated phase-locked loops (PLLs) to provide clocking support to the FPGA array and on-chip resources. In addition to supporting typical RTC uses such as watchdog timer, the Fusion RTC can control the on-chip voltage regulator to power down the device (FPGA fabric, Flash memory block, and ADC), enabling a low power standby mode.

#### **Fusion Family of Mixed-Signal Flash FPGAs**

The Actel Fusion family offers revolutionary features, never before available in an FPGA. The nonvolatile Flash technology gives the Fusion family the advantage of being a secure, low power, single-chip solution that is live at power-up. Fusion is reprogrammable and offers time to market benefits at an ASIC-level unit cost. These features enable designers to create high-density systems using existing ASIC or FPGA design flows and tools.

The family has up to 1.5 M system gates, supported with up to 270 kbits of true dual-port SRAM, up to 8 Mbits of Flash memory, 1 kbit of user FlashROM, and up to 278 user I/Os. With integrated Flash memory, the Fusion family is the ultimate soft processor platform. The AFS600 and AFS1500 devices both support the Actel ARM7 core (CoreMP7). The ARM-enabled versions are identified with the M7 prefix as M7AFS600 and M7AFS1500.

### Flash Advantages

### Reduced Cost of Ownership

Advantages to the designer extend beyond low unit cost, high performance, and ease of use. The Flash-based Fusion devices are live at power-up and do not need to be loaded from an external boot PROM. On-board security mechanisms prevent access to the programming information and enable secure remote updates of the FPGA logic. Designers can perform secure remote insystem reprogramming to support future design iterations and field upgrades with confidence that valuable intellectual property (IP) cannot compromised or copied. Secure ISP can be performed using the industry standard AES algorithm, with MAC data authentication on-board the device. The Fusion family device architecture mitigates the need for ASIC migration at higher user volumes. This makes the Fusion family a cost-effective ASIC replacement solution for applications in the consumer, networking communications, computing, and avionics markets.

### Security

As the nonvolatile, Flash-based Fusion family requires no boot PROM, there is no vulnerable external bitstream. Fusion devices incorporate FlashLock, which provides a unique combination of reprogrammability and design security without external overhead, advantages that only an FPGA with nonvolatile, Flash programming can offer.

Fusion devices utilize a 128-bit Flash-based key lock and a separate AES key used to secure programmed intellectual property (IP) and configuration data. The FlashROM data in the Fusion devices can also be encrypted prior to loading. Additionally, the Flash memory blocks can be programmed during runtime using the industry-leading AES-128 block cipher encryption standard (FIPS Publication 192). The AES

standard was adopted by the National Institute of Standards and Technology (NIST) in 2000 and replaces the DES standard, which was adopted in 1977. Fusion devices have a built-in AES decryption engine and a Flash-based AES key that make Fusion devices the most comprehensive programmable logic device security solution available today. Fusion devices with AES-based security allow for secure remote field updates over public networks, such as the Internet, and ensure that valuable IP remains out of the hands of system overbuilders, system cloners, and IP thieves. As an additional security measure, the FPGA configuration data of a programmed Fusion device cannot be read back, although secure design verification is possible. During design, the user controls and defines both internal and external access to the Flash memory blocks. Security, built into the FPGA fabric, is an inherent

component of the Fusion family. The Flash cells are located beneath seven metal layers and many device design and layout techniques have been used to make invasive attacks extremely difficult. Fusion with FlashLock and AES security is unique in being highly resistant to both invasive and noninvasive attacks. Your valuable IP is protected, making secure remote ISP possible. A Fusion device provides the most impenetrable security for programmable logic designs.

### Single Chip

Flash-based FPGAs store the configuration information in on-chip Flash cells. Once programmed, the configuration data is an inherent part of the FPGA structure and no external configuration data needs to be loaded at system power-up (unlike SRAM-based FPGAs). Therefore, Flash-based Fusion FPGAs do not require system configuration components such as EEPROMs or microcontrollers to load the device configuration data. This reduces bill-of-materials costs and printed circuit board (PCB) area, and increases security and system reliability.

### Live at Power-Up

Flash-based Fusion devices are Level 0 live at power-up (LAPU). LAPU Fusion devices greatly simplify total system design and reduce total system cost by eliminating the need for Complex Programmable Logic Devices (CPLDs). The Fusion LAPU clocking (PLLs) replaces off-chip clocking resources. The Fusion mix of LAPU clocking and analog resources makes these devices an excellent choice for both system supervisor and system management functions. LAPU from a single 3.3 V source enables Fusion devices to initiate, control, and monitor multiple voltage supplies, while also providing system clocks. In addition, glitches and brownouts in system power will not corrupt the Fusion device Flash configuration. Unlike SRAMbased FPGAs, the device will not have to be reloaded when system power is restored. This enables reduction or complete removal of the expensive voltage monitor and

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brownout detection devices from the PCB design. Flash-based Fusion devices simplify total system design and reduce cost and design risk, while increasing system reliability.

#### Firm Errors

Firm errors occur most commonly when high-energy neutrons, generated in the upper atmosphere, strike a configuration cell of an SRAM FPGA. The energy of the collision can change the state of the configuration cell and thus change the logic, routing, or I/O behavior in an unpredictable way. Another source of radiation-induced firm errors comes from alpha particles. For an alpha to cause a soft or firm error, its source must be in very close proximity to the affected circuit. The alpha source must be in the package molding compound or in the die itself. While low alpha molding compounds are being increasingly used, this helps reduce but does not entirely eliminate alpha-induced firm errors.

Firm errors are impossible to prevent in SRAM FPGAs. The consequence of this type of error can be a complete system failure. Firm errors do not occur in Fusion Flashbased FPGAs. Once it is programmed, the Flash cell configuration element of Fusion FPGAs cannot be altered by high-energy neutrons and is therefore immune to errors from them.

Recoverable (or soft) errors occur in the user data SRAMs of all FPGA devices. These can easily be mitigated by using error detection and correction (EDAC) circuitry built into the FPGA fabric.

#### Low Power

Flash-based Fusion devices exhibit power characteristics similar to those of an ASIC, making them an ideal choice for power-sensitive applications. With Fusion devices, there is no power-on current surge and no high current transition, both of which occur on many FPGAs.

Fusion devices also have low dynamic power consumption and support both low power standby mode and very low power sleep mode, offering further power savings.

# **Advanced Flash Technology**

The Fusion family offers many benefits, including nonvolatility and reprogrammability through an advanced Flash-based, 130-nm LVCMOS process with 7 layers of metal. Standard CMOS design techniques are used to implement logic and control functions. The combination of fine granularity, enhanced flexible routing resources, and abundant Flash switches allows very high logic utilization (much higher than competing SRAM technologies) without compromising device routability or performance. Logic functions within the device are interconnected through a four-level routing hierarchy.

### **Advanced Architecture**

The proprietary Fusion architecture provides granularity comparable to standard-cell ASICs. The Fusion device consists of several distinct and programmable architectural features, including the following (Figure 1-1 on page 1-5):

- Embedded memories
  - Flash memory blocks
  - FlashROM
  - SRAM and FIFO
- Clocking resources
  - PLL and CCC
  - RC oscillator
  - Crystal oscillator
  - No Glitch MUX (NGMUX)
- Digital I/Os with advanced I/O standards
- FPGA VersaTiles
- Analog components
  - Analog-to-digital converter (ADC)
  - Analog I/Os supporting voltage, current, and temperature monitoring
  - 1.5 V on-board voltage regulator
  - Real-time counter

The FPGA core consists of a sea of VersaTiles. Each VersaTile can be configured as a three-input logic lookup table (LUT) equivalent or a D-flip-flop or latch (with or without enable) by programming the appropriate Flash switch interconnections. This versatility allows efficient use of the FPGA fabric. The VersaTile capability is unique to the Actel families of Flash-based FPGAs. VersaTiles and larger functions are connected with any of the four levels of routing hierarchy. Flash switches are distributed throughout the device to provide nonvolatile, reconfigurable interconnect programming. Maximum core utilization is possible for virtually any design.

In addition, extensive on-chip programming circuitry allows for rapid (3.3 V) single-voltage programming of the Fusion devices via an IEEE 1532 JTAG interface.

# **Unprecedented Integration**

# **Integrated Analog Blocks and Analog I/Os**

Fusion devices offer a robust and flexible analog mixedsignal capability in addition to the high-performance Flash FPGA fabric and Flash memory block. The many built-in analog peripherals include a configurable 32:1 input analog multiplexer (MUX), up to 10 independent metal-oxide semiconductor field-effect transistor

#### **Fusion Family of Mixed-Signal Flash FPGAs**

(MOSFET) gate driver outputs, and a configurable ADC. The ADC supports 8-, 10-, and 12-bit modes of operation with a cumulative sample rate up to 600 k samples per second (ksps), differential nonlinearity (DNL) < 1.0 LSB, and Total Unadjusted Error (TUE) of ±4 LSB in 10-bit mode. The TUE is used for characterization of the conversion error, and includes errors from all sources, such as offset and linearity. Internal bandgap circuitry offers 1% voltage reference accuracy with the flexibility of utilizing an external reference voltage. The ADC channel sampling sequence and sampling rate are programmable and implemented in the FPGA logic using Designer and Libero IDE software tool support.

Two channels of the 32-channel ADCMUX are dedicated. Channel 0 is connected internally to  $V_{CC}$  and can be used to monitor core power supply. Channel 31 is connected to an internal temperature diode which can be used to monitor device temperature. The 30 remaining channels can be connected to external analog signals. The exact number of I/Os available for external connection signals is device-dependent (refer to Table 1 on page i for details).

With Fusion, Actel also introduces the Analog Quad I/O structure (Figure 1-1 on page 1-5). Each guad consists of three analog inputs and one gate driver. Each quad can be configured in various built-in circuit combinations, such as three pre-scaler circuits, three digital input circuits, a current monitor circuit, or a temperature monitor circuit. Each pre-scaler has multiple scaling factors programmed by FPGA signals to support a large range of analog inputs with positive or negative polarity. The input range for voltage signals is from -12 V to +12 V with full-scale output values from 0.125 V to 16 V. When the current monitor circuit is selected, two adjacent analog inputs measure the voltage drop across a small external sense resistor. Built-in operational amplifiers (op amps) amplify small voltage signals (2 mV sensitivity) for accurate current measurement. One analog input in each quad may be connected to an external temperature monitor diode and achieves detection accuracy of ±2°C with calibration. In addition to the external temperature monitor diode(s), a Fusion device can monitor an internal temperature diode using dedicated channel 31 of the ADCMUX.

Figure 1-1 on page 1-5 illustrates a typical use of the Analog Quad I/O structure. The Analog Quad shown is configured to monitor and control an external power supply. The AV pad is measuring the source of the power supply. The AC pad is measuring the voltage drop across an external sense resistor in order to calculate current. The AG MOSFET gate driver pad turns the external MOSFET on and off. The AT pad is measuring the load side voltage level.

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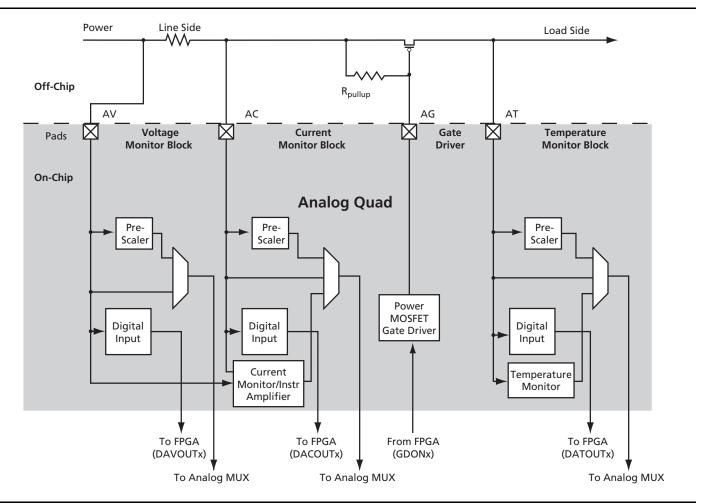


Figure 1-1 • Analog Quad

### **Embedded Memories**

### Flash Memory Blocks

The Flash memory available in each Fusion device is composed of 1 to 4 Flash blocks, each 2 Mbits in density. Each block operates independently with a dedicated Flash controller and interface. Fusion Flash memory blocks combine fast access times (60 ns random access and 10 ns access in Read-Ahead mode) with a configurable 8-, 16-, or 32-bit datapath, enabling high-speed Flash operation without wait states. The memory block is organized in pages and sectors. Each page has 128 bytes, with 33 pages comprising one sector and 64 sectors per block. The Flash block can support multiple partitions. The only constraint on size is that partition boundaries must coincide with page boundaries. The flexibility and granularity enable many use models and allow added granularity in programming updates.

Fusion devices support two methods of external access to the Flash memory blocks. The first method is a serial interface that features a built-in JTAG-compliant port, which allows in-system programmability during user or monitor/test modes. This serial interface supports programming of an AES-encrypted stream. Secure data can be passed through the JTAG interface, decrypted, and then programmed in the Flash block. The second method is a soft parallel interface.

FPGA logic or an on-chip soft microprocessor can access Flash memory through the parallel interface. Since the Flash parallel interface is implemented in the FPGA fabric, it can potentially be customized to meet special user requirements. The Flash memory parallel interface provides configurable byte-wide (x8), word-wide (x16), or dual word-wide (x32) data port options. Through the programmable Flash parallel interface, the on-chip and off-chip memories can be cascaded for wider or deeper configurations.

The Flash memory has built-in security. The user can configure either the entire Flash block or the small blocks to prevent unintentional or intrusive attempts to change or destroy the storage contents. Each on-chip Flash memory block has a dedicated controller, enabling each block to operate independently.

The Flash block logic consists of the following sub-blocks:

- Flash block Contains all stored data. The Flash block contains 64 sectors and each sector contains 33 pages of data.
- Page Buffer Contains the contents of the current page that is being modified. A page contains 8 blocks of data.

- Block Buffer Contains the contents of the last block accessed. A block contains 128 data bits.
- ECC Logic The Flash memory stores error correction information with each block to perform single-bit error correction and double-bit error detection on all data blocks.

### **User Nonvolatile FlashROM**

In addition to the Flash blocks, Actel Fusion devices have 1 kbit of user-accessible, nonvolatile FlashROM on-chip. The FlashROM is organized as 8x128-bit pages. The FlashROM can be used in diverse system applications:

- Internet protocol addressing (wireless or fixed)
- System calibration settings
- Device serialization and/or inventory control
- Subscription-based business models (for example, set-top boxes)
- Secure key storage for secure communications algorithms
- Asset management/tracking
- Date stamping
- Version management

The FlashROM is written using the standard IEEE 1532 JTAG programming interface. Pages can be individually programmed (erased and written). On-chip AES decryption can be used selectively over public networks to securely load data such as security keys stored in the FlashROM for a user design.

The FlashROM can be programmed (erased and written) via the JTAG programming interface, and its contents can be read back either through the JTAG programming interface or via direct FPGA core addressing.

The FlashPoint tool in the Actel Fusion development software solutions, Libero IDE and Designer, has extensive support for Flash memory blocks and FlashROM memory. One such feature is auto-generation of sequential programming files for applications requiring a unique serial number in each part. Another feature allows the inclusion of static data for system version control. Data for the FlashROM can be generated quickly and easily using Actel Libero IDE and Designer software tools. Comprehensive programming file support is also included to allow for easy programming of large numbers of parts with differing FlashROM contents.

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#### SRAM and FIFO

Fusion devices have embedded SRAM blocks along the north and south sides of the device. Each variable-aspectratio SRAM block is 4,608 bits in size. Available memory configurations are 256x18, 512x9, 1kx4, 2kx2, and 4kx1 bits. The individual blocks have independent read and write ports that can be configured with different bit widths on each port. For example, data can be written through a 4-bit port and read as a single bitstream. The SRAM blocks can be initialized from the Flash memory blocks or via the device JTAG port (ROM emulation mode), using the UJTAG macro.

In addition, every SRAM block has an embedded FIFO control unit. The control unit allows the SRAM block to be configured as a synchronous FIFO without using additional core VersaTiles. The FIFO width and depth are programmable. The FIFO also features programmable Almost-Empty (AEMPTY) and Almost-Full (AFULL) flags in addition to the normal EMPTY and FULL flags. The embedded FIFO control unit contains the counters necessary for the generation of the read and write address pointers. The SRAM/FIFO blocks can be cascaded to create larger configurations.

### **Clock Resources**

### PLL and Clock Conditioning Circuitry (CCC)

Fusion devices provide designers with very flexible clock conditioning capabilities. Each member of the Fusion family contains six CCCs. In the two larger family members, two of these CCCs also include a PLL; the smaller devices support one PLL.

The inputs of the CCC blocks are accessible from the FPGA core or from one of several I/O inputs with dedicated CCC block connections.

The CCC block has the following key features:

- Wide input frequency range (f<sub>IN\_CCC</sub>) = 1.5 MHz to 350 MHz
- Output frequency range (f<sub>OUT\_CCC</sub>) = 0.75 MHz to 350 MHz
- Clock phase adjustment via programmable and fixed delays from -6.275 ns to +8.75 ns
- Clock skew minimization (PLL)
- Clock frequency synthesis (PLL)
- On-chip analog clocking resources usable as inputs:
  - 100 MHz on-chip RC oscillator
  - Crystal oscillator

#### Additional CCC specifications:

- Internal phase shift = 0°, 90°, 180°, and 270°
- Output duty cycle = 50% ± 1.5%
- Low output jitter. Samples of peak-to-peak period jitter when a single global network is used:

- 70 ps at 350 MHz
- 90 ps at 100 MHz
- 180 ps at 24 MHz
- Worst case < 2.5% × clock period</li>
- Maximum acquisition time = 150 μs
- Low Power Consumption of 5 mW

### Global Clocking

Fusion devices have extensive support for multiple clocking domains. In addition to the CCC and PLL support described above, there are on-chip oscillators as well as a comprehensive global clock distribution network.

The integrated RC oscillator generates a 100 MHz clock. It is used internally to provide a known clock source to the Flash memory read and write control. It can also be used as a source for the PLLs.

The crystal oscillator supports the following operating modes:

- Crystal (32.768 kHz to 20 MHz)
- Ceramic (500 kHz to 8 MHz)
- RC (32.768 kHz to 4 MHz)

Each VersaTile input and output port has access to nine VersaNets: six main and three quadrant global networks. The VersaNets can be driven by the CCC or directly accessed from the core via MUXes. The VersaNets can be used to distribute low-skew clock signals or for rapid distribution of high-fanout nets.

### Digital I/Os with Advanced I/O Standards

The Fusion family of FPGAs features a flexible digital I/O structure, supporting a range of voltages (1.5 V, 1.8 V, 2.5 V, and 3.3 V). Fusion FPGAs support many different digital I/O standards, both single-ended and differential.

The I/Os are organized into banks, with four or five banks per device. The configuration of these banks determines the I/O standards supported. The banks along the east and west sides of the device support the full range of I/O standards (single-ended and differential). The south bank supports the Analog Quads (analog I/O). In the family's two smaller devices, the north bank supports multiple single-ended digital I/O standards. In the family's larger devices, the north bank is divided into two banks of digital Pro I/Os, supporting a wide variety of single-ended, differential, and voltage-referenced I/O standards.

Each I/O module contains several input, output, and enable registers. These registers allow the implementation of the following applications:

- Single-Data-Rate (SDR) applications
- Double-Data-Rate (DDR) applications—DDR LVDS I/O for chip-to-chip communications
- Fusion banks support LVPECL, LVDS, BLVDS and M-LVDS with 20 multi-drop points.

#### **Fusion Family of Mixed-Signal Flash FPGAs**

#### VersaTiles

The Fusion core consists of VersaTiles, which are also used in the successful Actel ProASIC3 family. The Fusion VersaTile supports the following:

- All three-input logic functions—LUT-3 equivalent
- · Latch with clear or set
- D-flip-flop with clear or set and optional enable

Refer to Figure 1-2 for the VersaTile configuration arrangement.

#### **LUT-3 Equivalent** D-Flip-Flop with Clear or Set **Enable D-Flip-Flop with Clear or Set** X1 Data Data LUT-3 CLK **D-FF D-FFE** X2 CLK X3 CLR Enable CLR

Figure 1-2 • VersaTile Configurations

### **Related Documents**

### **Application Briefs**

Context Save and Reload with Real-Timestamp

http://www.actel.com/documents/ Fusion\_ContextSaving\_AB.pdf

Power Sequencing and Management

http://www.actel.com/documents/

Fusion\_Power\_Sequencing\_AB.pdf

Real-Time Clock in Actel Fusion FPGAs

http://www.actel.com/documents/Fusion\_RTC\_AB.pdf

Lower Power Operation with the Fusion Device

http://www.actel.com/documents/

Fusion\_LowPower\_AB.pdf

Smart Battery Management Applications

http://www.actel.com/documents/

Fusion\_SmartBat\_AB.pdf

## **Application Notes**

Fusion FlashROM

http://www.actel.com/documents/Fusion FROM AN.pdf

Fusion SRAM/FIFO Blocks

http://www.actel.com/documents/

Fusion\_RAM\_FIFO\_AN.pdf

Using DDR in Fusion Devices

http://www.actel.com/documents/Fusion\_DDR\_AN.pdf

**Fusion Security** 

http://www.actel.com/documents/

Fusion Security AN.pdf

Using Fusion RAM as Multipliers

http://www.actel.com/documents/

Fusion\_Multipliers\_AN.pdf

Prototyping with AFS600 for Smaller Devices

http://www.actel.com/documents/

Fusion Prototyp AN.pdf

#### **User's Guides**

Designer User's Guide

http://www.actel.com/documents/designer\_UG.pdf

Fusion Design Flow Tutorial

http://www.actel.com/documents/fusion\_df\_ug.pdf

Fusion and ProASIC3/E Macro Library Guide

http://www.actel.com/documents/pa3\_libguide\_ug.pdf

Peripherals User's Guide

http://www.actel.com/documents/peripheral\_ug.pdf

SmartGen, FlashROM, Flash Memory System Builder, and

Analog System Builder User's Guide

http://www.actel.com/documents/genguide\_ug.pdf

### White Papers

Fusion Technology

http://www.actel.com/documents/Fusion\_Tech\_WP.pdf

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# **Device Architecture**

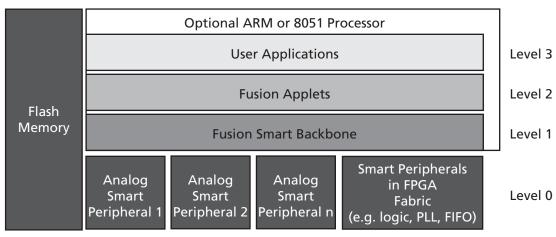
### **Fusion Stack Architecture**

To manage the unprecedented level of integration in Fusion devices, Actel developed the Fusion technology stack (Figure 2-1). This layered model offers a flexible design environment, enabling design at very high and very low levels of abstraction. Fusion peripherals include hard analog IP and hard and soft digital IP. Peripherals will communicate across the FPGA fabric via a layer of soft gates—the Fusion backbone. Much more than a common bus interface, this Fusion backbone integrates a micro-sequencer within the FPGA fabric and will configure the individual peripherals and support lowlevel processing of peripheral data. Fusion applets are application building blocks that can control and respond to peripherals and other system signals. Applets can be rapidly combined to create large applications. The technology is scalable across devices, families, design types, and user expertise, and supports a well-defined interface for external IP and tool integration.

At the lowest level, Level 0, are Fusion peripherals. These are configurable functional blocks that can be hardwired structures such as a PLL or analog input channel, or soft (FPGA-gate) blocks such as a UART or two-wire serial interface. The Fusion peripherals are configurable and support a standard interface to facilitate communication and implementation.

Connecting and controlling access to the peripherals is the Fusion backbone, Level 1. The backbone is a soft-gate structure and is scalable to any number of peripherals. The backbone is a bus and much more; it manages peripheral configuration to ensure proper operation. Leveraging the common peripheral interface and a low-level state machine, the backbone efficiently offloads peripheral management from the system design. The backbone can set and clear flags based upon peripheral behavior and define performance criteria. The flexibility of the stack enables a designer to configure the silicon, directly bypassing the backbone if that level of control is desired.

One step up from the backbone is the Fusion applet, Level 2. The applet is an application building block that implements a specific function in FPGA gates. It can react to stimuli and board-level events coming through the backbone, or from other sources, and responds to these stimuli by accessing and manipulating peripherals via the backbone or initiating some other action. An applet controls or responds to the peripheral(s). Applets can be easily imported or exported from the design environment. The applet structure is open and well-defined, enabling users to import applets from Actel, system developers, third parties, and user groups.



**Note:** Levels 1, 2, and 3 are implemented in FPGA logic gates.

Figure 2-1 • Fusion Architecture Stack

#### **Fusion Family of Mixed-Signal Flash FPGAs**

The system application, Level 3, is the larger user application that utilizes one or more applets. Designing at the highest level of abstraction supported by the Actel Fusion technology stack, the application can be easily created in FPGA gates by importing and configuring multiple applets.

In fact, in some cases an entire FPGA system design can be created without any HDL coding.

An optional MCU enables a combination of software and HDL-based design methodologies. The MCU can be on-chip or off-chip as system requirements dictate. System portioning is very flexible, allowing the MCU to reside above the applets or to absorb applets, or applets and backbone, if desired.

The Actel Fusion technology stack enables a very flexible design environment. Users can engage in design across a continuum of abstraction from very low to very high.

### **Core Architecture**

### VersaTile

Based upon successful Actel ProASIC3/E logic architecture, Fusion devices provide granularity comparable to gate arrays. The Fusion device core consists of a sea-of-VersaTiles architecture.

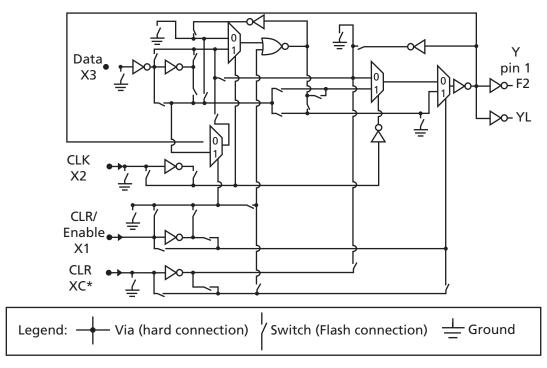
As illustrated in Figure 2-2, there are four inputs in a logic VersaTile cell, and each VersaTile can be configured using the appropriate Flash switch connections:

- Any three-input logic function
- Latch with clear or set
- D-flip-flop with clear or set
- Enable D-flip-flop with clear or set (on a fourth input)

VersaTiles can flexibly map the logic and sequential gates of a design. The inputs of the VersaTile can be inverted (allowing bubble pushing), and the output of the tile can connect to high-speed, very-long-line routing resources. VersaTiles and larger functions are connected with any of the four levels of routing hierarchy.

When the VersaTile is used as an enable D-flip-flop, the SET/CLR signal is supported by a fourth input, which can only be routed to the core cell over the VersaNet (global) network.

The output of the VersaTile is F2 when the connection is to the ultra-fast local lines, or YL when the connection is to the efficient long-line or very-long-line resources (Figure 2-2).



**Note:** \*This input can only be connected to the global clock distribution network.

Figure 2-2 • Fusion Core VersaTile

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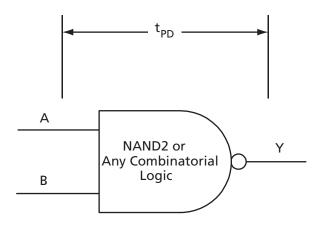


### **VersaTile Characteristics**

### Sample VersaTile Specifications—Combinatorial Module

The Fusion library offers all combinations of LUT-3 combinatorial functions. In this section, timing characteristics are presented for a sample of the library (Figure 2-3). For more details, refer to the Fusion and ProASIC3/E Macro Library Guide.

Figure 2-3 • Sample of Combinatorial Cells



 $t_{PD} = MAX(t_{PD(RR)},\,t_{PD(RF)},\,t_{PD(FF)},\,t_{PD9(FR)})$  where edges are applicable for the particular combinatorial cell

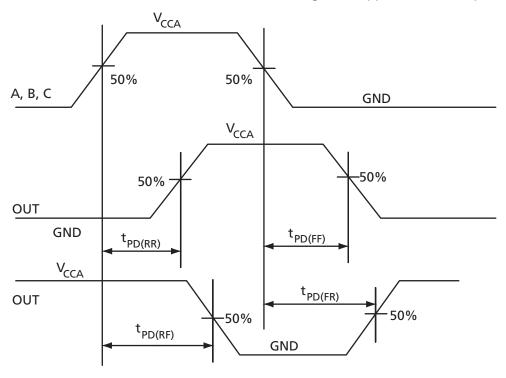


Figure 2-4 • Combinatorial Timing Model and Waveforms

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### **Timing Characteristics**

Table 2-1 • Combinatorial Cell Propagation Delays
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

<b>Combinatorial Cell</b>	Equation	Parameter	-2	-1	Std.	Units
INV	Y = !A	t <sub>PD</sub>	0.40	0.46	0.54	ns
AND2	$Y = A \cdot B$	t <sub>PD</sub>	0.47	0.54	0.63	ns
NAND2	$Y = !(A \cdot B)$	t <sub>PD</sub>	0.47	0.54	0.63	ns
OR2	Y = A + B	t <sub>PD</sub>	0.49	0.55	0.65	ns
NOR2	Y = !(A + B)	t <sub>PD</sub>	0.49	0.55	0.65	ns
XOR2	$Y = A \oplus B$	t <sub>PD</sub>	0.74	0.84	0.99	ns
MAJ3	Y = MAJ (A, B, C)	t <sub>PD</sub>	0.70	0.79	0.93	ns
XOR3	$Y = A \oplus B \oplus C$	t <sub>PD</sub>	0.87	1.00	1.17	ns
MUX2	Y = A !S + B S	t <sub>PD</sub>	0.51	0.58	0.68	ns
AND3	$Y = A \cdot B \cdot C$	t <sub>PD</sub>	0.56	0.64	0.75	ns

Note: For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

### Sample VersaTile Specifications—Sequential Module

The Fusion library offers a wide variety of sequential cells, including flip-flops and latches. Each has a data input and optional enable, clear, or preset. In this section, timing characteristics are presented for a representative sample from the library (Figure 2-5). For more details, refer to the Fusion and ProASIC3/E Macro Library Guide.

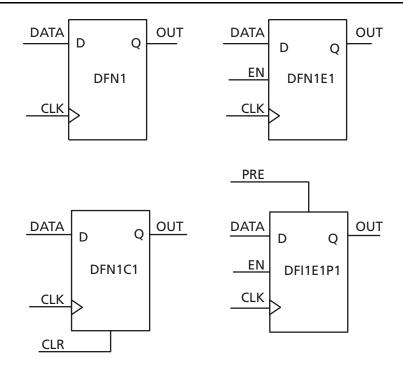


Figure 2-5 • Sample of Sequential Cells

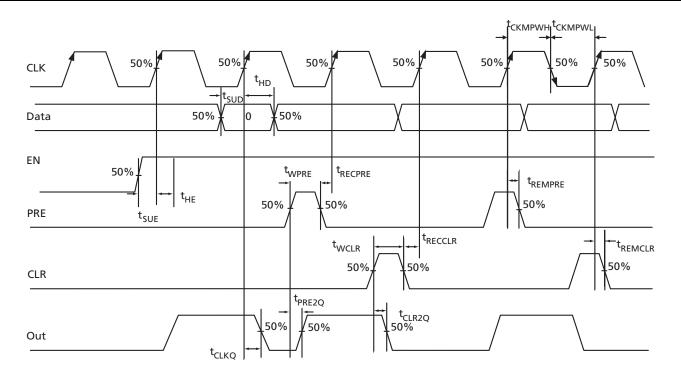


Figure 2-6 • Sequential Timing Model and Waveforms

### **Sequential Timing Characteristics**

Table 2-2 • Register Delays
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>CLKQ</sub>	Clock-to-Q of the Core Register	0.55	0.63	0.74	ns
t <sub>SUD</sub>	Data Setup time for the Core Register	0.43	0.49	0.57	ns
$t_{HD}$	Data Hold time for the Core Register	0.00	0.00	0.00	ns
t <sub>SUE</sub>	Enable Setup time for the Core Register	0.45	0.52	0.61	ns
t <sub>HE</sub>	Enable Hold time for the Core Register	0.00	0.00	0.00	ns
t <sub>CLR2Q</sub>	Asynchronous Clear-to-Q of the Core Register	0.40	0.45	0.53	ns
t <sub>PRE2Q</sub>	Asynchronous Preset-to-Q of the Core Register	0.40	0.45	0.53	ns
t <sub>REMCLR</sub>	Asynchronous Clear Removal time for the Core Register	0.00	0.00	0.00	ns
t <sub>RECCLR</sub>	Asynchronous Clear Recovery time for the Core Register	0.22	0.25	0.30	ns
t <sub>REMPRE</sub>	Asynchronous Preset Removal time for the Core Register	0.00	0.00	0.00	ns
t <sub>RECPRE</sub>	Asynchronous Preset Recovery time for the Core Register	0.22	0.25	0.30	ns
t <sub>WCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Core Register	0.25	0.28	0.33	ns
t <sub>WPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Core Register	0.25	0.28	0.33	ns
t <sub>CKMPWH</sub>	Clock Minimum Pulse Width High for the Core Register	0.36	0.41	0.48	ns
t <sub>CKMPWL</sub>	Clock Minimum Pulse Width Low for the Core Register	0.41	0.46	0.54	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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### **Array Coordinates**

During many place-and-route operations in the Actel Designer software tool, it is possible to set constraints that require array coordinates. Table 2-3 is provided as a reference. The array coordinates are measured from the lower left (0, 0). They can be used in region constraints for specific logic groups/blocks, designated by a wildcard, and can contain core cells, memories, and I/Os.

Table 2-3 provides array coordinates of core cells and memory blocks.

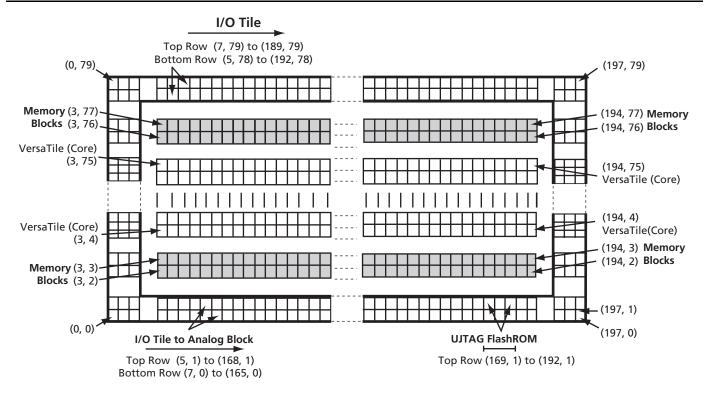
I/O and cell coordinates are used for placement constraints. Two coordinate systems are needed because there is not a one-to-one correspondence between I/O

cells and edge core cells. In addition, the I/O coordinate system changes depending on the die/package combination. It is not listed in Table 2-3. The Designer ChipPlanner tool provides array coordinates of all I/O locations. I/O and cell coordinates are used for placement constraints. However, I/O placement is easier by package pin assignment.

Figure 2-7 illustrates the array coordinates of an AFS600 device. For more information on how to use array coordinates for region/placement constraints, see the *Designer User's Guide* or online help (available in the software) for Fusion software tools.

**Table 2-3** • Array Coordinates

	VersaTiles				Memor	y Rows	All	
	М	in.	M	ах.	Bottom	Тор	Min.	Max.
Device	х	У	х	У	(x, y)	(x, y)	(x, y)	(x, y)
AFS090	3	2	66	25	None	(3, 26)	(0, 0)	(69, 29)
AFS250	3	2	130	49	None	(3, 50)	(0, 0)	(133, 53)
AFS600	3	4	194	75	(3, 2)	(3, 76)	(0, 0)	(197, 79)
AFS1500	3	4	258	99	(3, 2)	(3, 100)	(0, 0)	(261, 103)



**Note:** The vertical I/O tile coordinates are not shown. West side coordinates are {(0, 2) to (2, 2)} to {(0, 77) to (2, 77)}; east side coordinates are {(195, 2) to (197, 2)} to {(197, 77)}.

Figure 2-7 • Array Coordinates for AFS600

### **Routing Architecture**

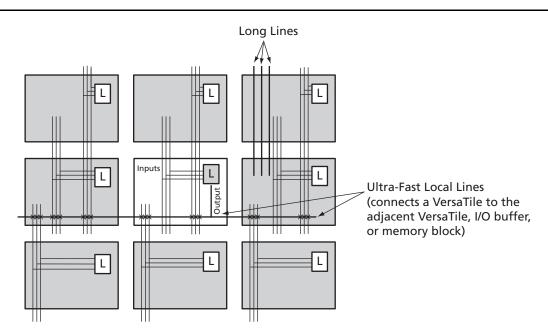
The routing structure of Fusion devices is designed to provide high performance through a flexible four-level hierarchy of routing resources: ultra-fast local resources; efficient long-line resources; high-speed, very-long-line resources; and the high-performance VersaNet networks.

The ultra-fast local resources are dedicated lines that allow the output of each VersaTile to connect directly to every input of the eight surrounding VersaTiles (Figure 2-8). The exception to this is that the SET/CLR input of a VersaTile configured as a D-flip-flop is driven only by the VersaNet global network.

The efficient, long-line resources provide routing for longer distances and higher fanout connections. These resources vary in length (spanning one, two, or four VersaTiles), run both vertically and horizontally, and cover the entire Fusion device (Figure 2-9 on page 2-9). Each VersaTile can drive signals onto the efficient long-line resources, which can access every input of every VersaTile. Active buffers are inserted automatically by routing software to limit the loading effects.

The high-speed, very-long-line resources, which span the entire device with minimal delay, are used to route very long or high-fanout nets: length +/-12 VersaTiles in the vertical direction and length +/-16 in the horizontal direction from a given core VersaTile (Figure 2-10 on page 2-10). Very long lines in Fusion devices, like those in ProASIC3, have been enhanced. This provides a significant performance boost for long-reach signals.

The high-performance VersaNet global networks are low-skew, high-fanout nets that are accessible from external pins or from internal logic (Figure 2-11 on page 2-11). These nets are typically used to distribute clocks, reset signals, and other high-fanout nets requiring minimum skew. The VersaNet networks are implemented as clock trees, and signals can be introduced at any junction. These can be employed hierarchically with signals accessing every input on all VersaTiles.



**Note:** Input to the core cell for the D-flip-flop set and reset is only available via the VersaNet global network connection.

Figure 2-8 • Ultra-Fast Local Lines Connected to the Eight Nearest Neighbors

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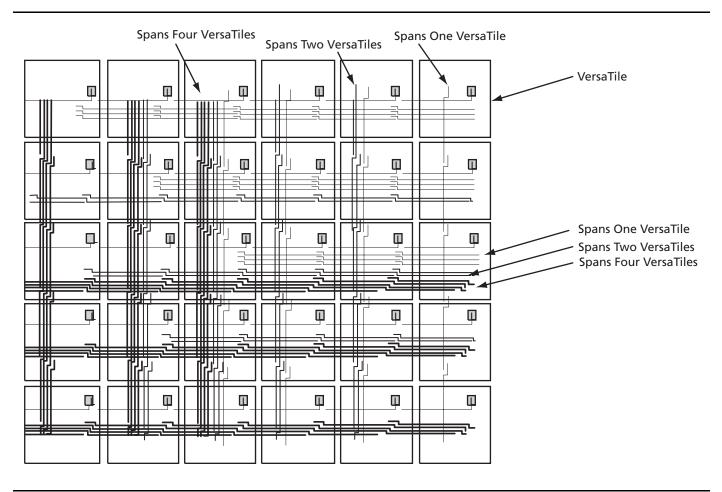


Figure 2-9 • Efficient Long-Line Resources

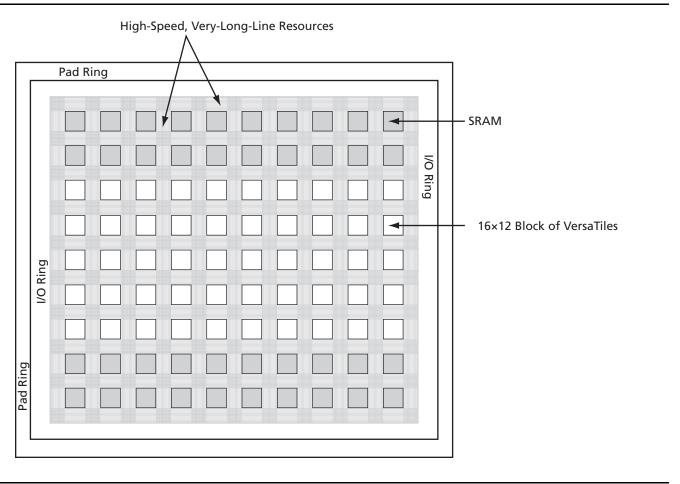


Figure 2-10 • Very-Long-Line Resources

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### **Global Resources (VersaNets)**

Fusion devices offer powerful and flexible control of circuit timing through the use of analog circuitry. Each chip has six clock conditioning circuits (CCCs). The west CCC also contains a phase-locked loop (PLL) core. In the two larger devices (AFS600 and AFS1500), both the west and the east CCC contain a PLL. The PLLs include delay lines, a phase shifter (0°, 90°, 180°, 270°), and clock multipliers/dividers. Each CCC has all the circuitry needed for the selection and interconnection of inputs to the VersaNet global network. The east and west CCCs each have access to three VersaNet global lines on each side of the chip (six lines total). The CCCs at the four corners each have access to three quadrant global lines on each quadrant of the chip.

### Advantages of the VersaNet Approach

One of the architectural benefits of Fusion is the set of powerful and low-delay VersaNet global networks. Fusion offers six chip (main) global networks that are distributed from the center of the FPGA array (Figure 2-11). In

addition, Fusion devices have three regional globals (quadrant globals) in each of the four chip quadrants. Each core VersaTile has access to nine global network resources: three quadrant and six chip (main) global networks. There are a total of 18 global networks on the device. Each of these networks contains spines and ribs that reach all VersaTiles in all quadrants (Figure 2-12 on page 2-12). This flexible VersaNet global network architecture allows users to map up to 180 different internal/external clocks in a Fusion device. Details on the VersaNet networks are given in Table 2-4 on page 2-12. The flexibility of the Fusion VersaNet global network allows the designer to address several design requirements. User applications that are clock-resource-intensive can easily route external or gated internal clocks using VersaNet global routing networks. Designers can also drastically reduce delay penalties and minimize resource usage by mapping critical, high-fanout nets to the VersaNet global network.

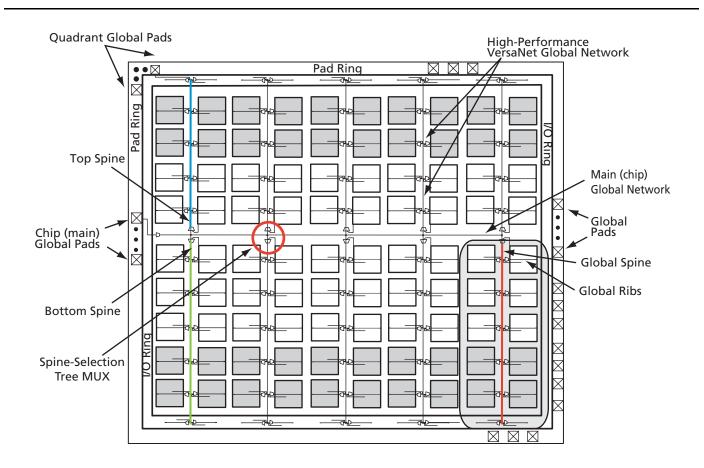


Figure 2-11 • Overview of Fusion VersaNet Global Network

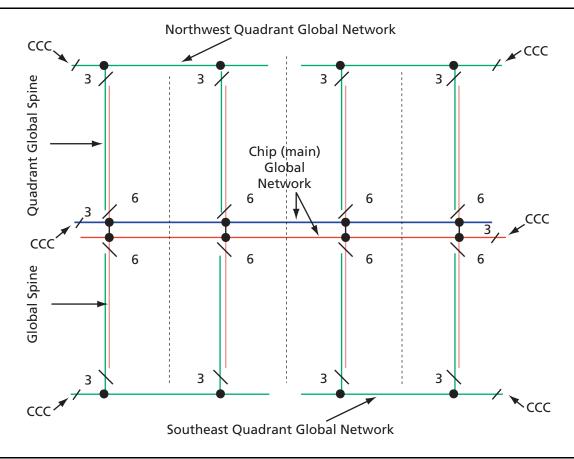


Figure 2-12 • Global Network Architecture

Table 2-4 • Globals/Spines/Rows by Device

	AFS090	AFS250	AFS600	AFS1500
Global VersaNets (Trees)*	9	9	9	9
VersaNet Spines/Tree	4	8	12	20
Total Spines	36	72	108	180
VersaTiles in Each Top or Bottom Spine	384	768	1,152	1,920
Total VersaTiles	2,304	6,144	13,824	38,400

**Note:** \*There are six chip (main) globals and three globals per quadrant.

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### **VersaNet Global Networks and Spine Access**

The Fusion architecture contains a total of 18 segmented global networks that can access the VersaTiles, SRAM memory, and I/O tiles on the Fusion device. There are 6 chip (main) global networks that access the entire device and 12 quadrant networks (3 in each quadrant). Each device has a total of 18 globals. These VersaNet global networks offer fast, low-skew routing resources for high-fanout nets, including clock signals. In addition, these highly segmented global networks offer users the flexibility to create low-skew local networks using spines for up to 180 internal/external clocks (in an AFS1500 device) or other high-fanout nets in Fusion devices. Optimal usage of these low-skew networks can result in significant improvement in design performance on Fusion devices.

The nine spines available in a vertical column reside in global networks with two separate regions of scope: the quadrant global network, which has three spines, and the chip (main) global network, which has six spines. Note that there are three quadrant spines in each quadrant of the device. There are four quadrant global network regions per device (Figure 2-12 on page 2-12).

The spines are the vertical branches of the global network tree, shown in Figure 2-11 on page 2-11. Each spine in a vertical column of a chip (main) global network is further divided into two equal-length spine segments: one in the top and one in the bottom half of the die.

Each spine and its associated ribs cover a certain area of the Fusion device (the "scope" of the spine; see Figure 2-11 on page 2-11). Each spine is accessed by the dedicated global network MUX tree architecture, which defines how a particular spine is driven—either by the signal on the global network from a CCC, for example, or another net defined by the user (Figure 2-13). Quadrant spines can be driven from user I/Os on the north and south sides of the die, via analog I/Os configured as direct digital inputs. The ability to drive spines in the quadrant global networks can have a significant effect on system performance for high-fanout inputs to a design.

Details of the chip (main) global network spine-selection MUX are presented in Figure 2-13. The spine drivers for each spine are located in the middle of the die.

Quadrant spines are driven from a north or south rib. Access to the top and bottom ribs is from the corner CCC or from the I/Os on the north and south sides of the device.

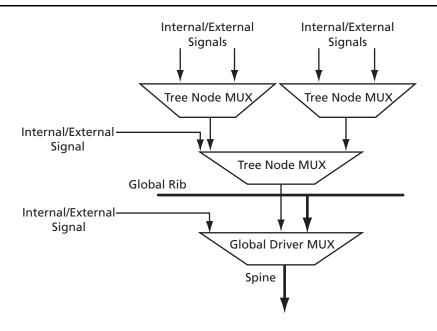


Figure 2-13 • Spine-Selection MUX of Global Tree

#### **Fusion Family of Mixed-Signal Flash FPGAs**

### **Clock Aggregation**

Clock aggregation allows for multi-spine clock domains. A MUX tree provides the necessary flexibility to allow long-lines or I/Os to access domains of one, two, or four global spines. Signal access to the clock aggregation system is achieved through long-line resources in the central rib, and also through local resources in the north and south ribs, allowing I/Os to feed directly into the clock system. As Figure 2-14 indicates, this access system is contiguous.

There is no break in the middle of the chip for the north and south I/O VersaNet access. This is different from the quadrant clocks, located in these ribs, which only reach the middle of the rib.

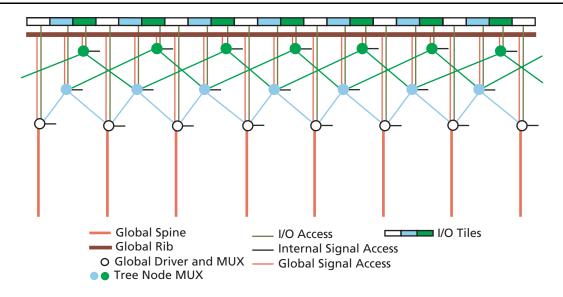


Figure 2-14 • Clock Aggregation Tree Architecture

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# Global Resource Characteristics

## **AFS600 VersaNet Topology**

Clock delays are device-specific. Figure 2-15 is an example of a global tree used for clock routing. The global tree presented in Figure 2-15 is driven by a CCC located on the west side of the AFS600 device. It is used to drive all D-flip-flops in the device.

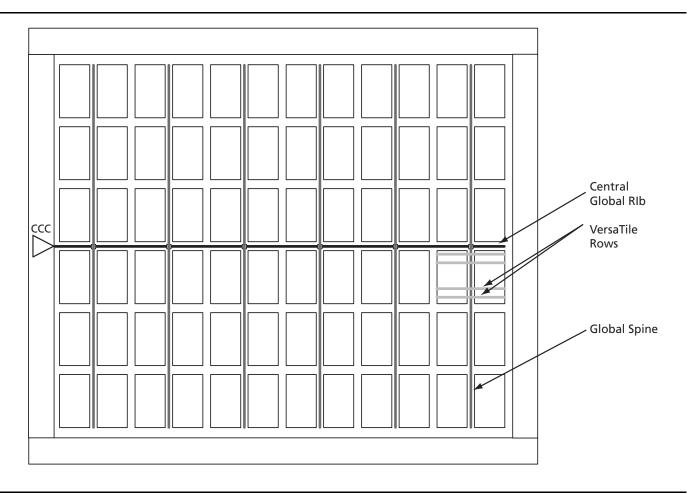


Figure 2-15 • Example of Global Tree Use in an AFS600 Device for Clock Routing

#### **Fusion Family of Mixed-Signal Flash FPGAs**

#### VersaNet Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are dependent upon I/O standard, and the clock may be driven and conditioned internally by the CCC module. Table 2-5, Table 2-6, and Table 2-7 present minimum and maximum global clock delays within the device. Minimum and maximum delays are measured with minimum and maximum loading, respectively.

#### **Timing Characteristics**

Table 2-5 • AFS600 Global Resource Timing
Commercial Case Conditions: T₁ = 70°C, V<sub>CC</sub> = 1.425 V

		-2		-1		Std.		
Parameter	Description	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	1.28	1.51	1.46	1.72	1.71	2.02	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	1.28	1.55	1.45	1.77	1.71	2.08	ns
t <sub>rckmpwh</sub>	Minimum Pulse Width High for Global Clock							ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock							ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.27		0.31		0.37	ns
F <sub>RMAX</sub>	Maximum Frequency for Global Clock							MHz

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

Table 2-6 • AFS250 Global Resource Timing Commercial Case Conditions: T<sub>J</sub> = 70°C, V<sub>CC</sub> = 1.425 V

		-2		-1		Std.		
Parameter	Description	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	1.19	1.42	1.36	1.62	1.59	1.91	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	1.19	1.46	1.35	1.66	1.59	1.96	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock							ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock							ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.27		0.31		0.37	ns
F <sub>RMAX</sub>	Maximum Frequency for Global Clock						·	MHz

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# Table 2-7 ◆ AFS090 Global Resource Timing Commercial Case Conditions: T<sub>J</sub> = 70°C, V<sub>CC</sub> = 1.425 V

		-2		-1		Std.		
Parameter	Description	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Min. <sup>1</sup>	Max. <sup>2</sup>	Units
t <sub>RCKL</sub>	Input Low Delay for Global Clock	1.18	1.41	1.34	1.60	1.58	1.89	ns
t <sub>RCKH</sub>	Input High Delay for Global Clock	1.17	1.44	1.33	1.64	1.57	1.93	ns
t <sub>RCKMPWH</sub>	Minimum Pulse Width High for Global Clock							ns
t <sub>RCKMPWL</sub>	Minimum Pulse Width Low for Global Clock							ns
t <sub>RCKSW</sub>	Maximum Skew for Global Clock		0.27		0.31		0.37	ns
F <sub>RMAX</sub>	Maximum Frequency for Global Clock							MHz

#### Notes:

- 1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element located in a lightly loaded row (single element is connected to the global net).
- 2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element located in a fully loaded row (all available flip-flops are connected to the global net in the row).
- 3. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# **Clocking Resources**

The Fusion family has a robust collection of clocking peripherals, as shown in the block diagram in Figure 2-16. These on-chip resources enable the creation, manipulation, and distribution of many clock signals. The Fusion integrated RC oscillator produces a 100 MHz clock source with no external components. For systems requiring more precise clock signals, the Actel Fusion family supports an on-chip crystal oscillator circuit. The integrated PLLs in each Fusion device can use the RC

oscillator, crystal oscillator, or another on-chip clock signal as a source. These PLLs offer a variety of capabilities to modify the clock source (multiply, divide, synchronize, advance, or delay). Utilizing the CCC found in the popular Actel ProASIC3 family, Fusion incorporates six CCC blocks. The CCCs allow access to Fusion global and local clock distribution nets, as described in the "Global Resources (VersaNets)" section on page 2-11.

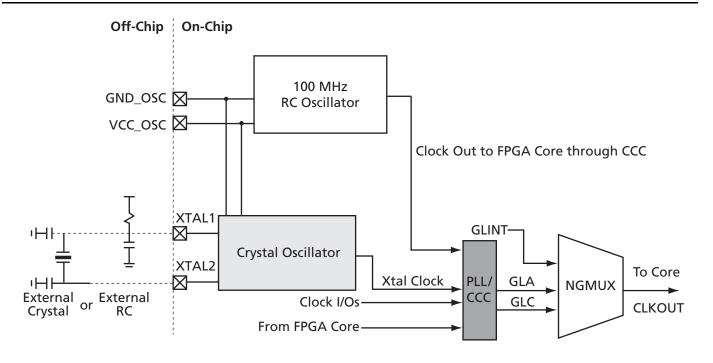


Figure 2-16 • Fusion Clocking Options

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### **RC** Oscillator

The RC oscillator is an on-chip free running clock source generating a 100 MHz clock. It can be used as a source clock for both on-chip and off-chip resources. When used in conjunction with the Fusion PLL and CCC circuits, the RC oscillator clock source can be used to generate clocks of varying frequency and phase.

The Fusion RC oscillator is very accurate at ±1% over commercial and industrial temperature ranges. It is an automated clock, requiring no setup or configuration by the user. It requires only that the power and GND\_OSC pins be connected; no external components are required. The RC oscillator can be used to drive either a PLL or another internal signal.

### **RC Oscillator Characteristics**

Table 2-8 • Electrical Characteristics of RC Oscillator

Parameter	Description	Condition	Min.	Тур.	Max.	Units
F <sub>RC</sub>	Operating Frequency			100		MHz
	Accuracy	Temperature: 0°C to 85°C Voltage: 3.3 V +/- 5%		1		%
		Temperature: -40°C to 125°C Voltage: 3.3 V +/- 5%		3		%
	Output Jitter	Period Jitter (at 5 k cycles)		100		ps
		Cycle–Cycle Jitter (at 5 k cycles)		100		ps
		Period Jitter (at 5 k cycles) with 1 kHz / 300 mV peak-to-peak noise on power supply		150		ps
		Cycle–Cycle Jitter (at 5 k cycles) with 1 kHz/300 mV peak-to-peak noise on power supply		150		ps
	Output Duty Cycle			50		%
I <sub>DYNRC</sub>	Operating Current			1		mA

### **Crystal Oscillator**

The on-chip crystal oscillator circuit works with an offchip crystal to generate a high precision clock. It has an accuracy of 100 ppm (0.01%) and is capable of providing system clocks for Fusion peripherals and other system clock networks, both on-chip and off-chip. When combined with the on-chip CCC/PLL blocks, a wide range of clock frequencies can be created to support various design requirements.

The on-chip circuitry is designed to work with an external crystal, ceramic resonator, or a resistor-capacitor (RC) network. It can only support one of these

configurations at a time. Typical design practices dictate that the desired mode for the crystal oscillator be determined and the board designed for a single configuration. The crystal oscillator supports four modes of operation, defined in Table 2-9.

In Mode 0, the oscillator is configured to work with an external RC network. The RC components are connected to the XTAL1 pin, with XTAL2 left floating. The frequency generated by the circuit in Mode 0 is determined by the RC time constant of the selected components (Figure 2-18).

Table 2-9 • Crystal Oscillator Mode Definition

Mode	RTCMODE/MODE[1:0]	Recommended Capacitor	Frequency Range (MHz)
RC network (Mode 0)	00	N/A	N/A
Low gain (Mode 1)	01	100 pF	0.032 to 0.20
Medium gain (Mode 2)	10	100 pF	0.20 to 2.0
High gain (Mode 3)	11	15 pF	2.0 to 20.0

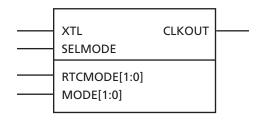


Figure 2-17 • Crystal Oscillator Macro

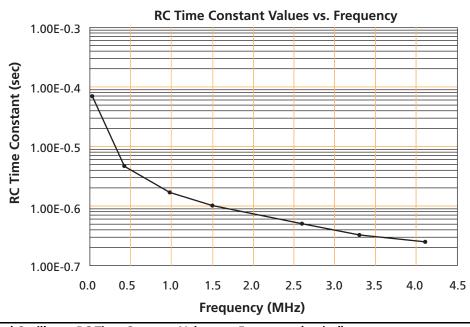


Figure 2-18 • Crystal Oscillator: RC Time Constant Values vs. Frequency (typical)

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In Modes 1 to 3, the crystal oscillator is configured to support an external crystal or ceramic resonator. These modes correspond to low, medium, and high gain. They differ in the frequency of crystal or resonator that is supported. The crystal or resonator is connected to the XTAL1 and XTAL2 pins. Additionally, a capacitor is required on both XTAL1 and XTAL2 pins to ground (Figure 2-16 on page 2-18). Table 2-9 on page 2-20 details each crystal oscillator mode, supported frequency range, and recommended capacitor value.

A use model supported by the Fusion device involves powering down the core while the real-time counter (RTC) continues to run, clocked by the crystal oscillator. When powered down, the core cannot control crystal oscillator mode pins. Also, some designers may wish to avoid the RTC altogether. To support both situations, the crystal oscillator can be controlled by either the RTC or the FGPA core. If the RTC is instantiated in the design, it will by default use RTCMODE[1:0] to set the crystal oscillator control pins (the default). If the RTC is not used in the design, the FPGA core will set the crystal oscillator control pins with MODE[1:0].

### **Crystal Oscillator Characteristics**

Table 2-10 • Electrical Characteristics of the Crystal Oscillator

Parameter	Description	Condition	Min.	Тур.	Max.	Units
F <sub>XTAL</sub>	Operating Frequency	Using External Crystal	0.032		20	MHz
		Using Ceramic Resonator	0.5		8	MHz
		Using RC Network	0.032		4	MHz
	Output Duty Cycle			50		%
	Output Jitter	With 10 MHz Crystal		50		ps RMS
I <sub>DYNXTAL</sub>	Operating Current	RC		0.6		mA
		0.032–0.2 MHz		0.6		mA
		0.2–2.0 MHz		0.6		mA
		2.0–20.0 MHz		0.6		mA
I <sub>STBXTAL</sub>	Sleep Current			10		μΑ
PSRR <sub>XTAL</sub>	Power Supply Noise Tolerance			0.5		Vp-p
V <sub>IHXTAL</sub>	Input Logic Level High		90% of V <sub>CC</sub>			V
V <sub>ILXTAL</sub>	Input Logic Level Low				10% of V <sub>CC</sub>	V

### **Clock Conditioning Circuits**

In Fusion devices, the CCCs are used to implement frequency division, frequency multiplication, phase shifting, and delay operations.

The CCCs are available in six chip locations—each of the four chip corners and in the middle of the east and west chip sides.

Each CCC can implement up to three independent global buffers (with or without programmable delay), or a PLL function (programmable frequency division/multiplication, phase shift, and delays) with up to three global outputs. Unused global outputs of a PLL can be used to implement independent global buffers, up to a maximum of three global outputs for a given CCC.

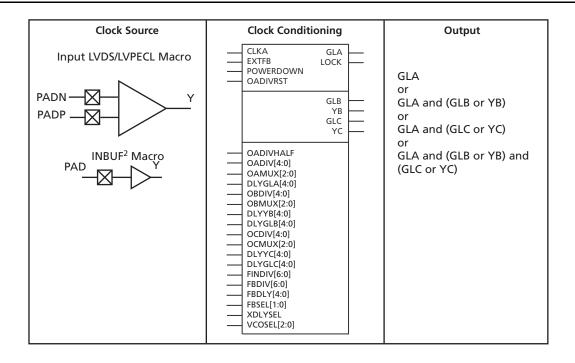
A global buffer can be placed in any of the three global locations (CLKA-GLA, CLKB-GLB, and CLKC-GLC) of a given CCC.

A PLL macro uses the CLKA CCC input to drive its reference clock. It uses the GLA and, optionally, the GLB and GLC global outputs to drive the global networks. A PLL macro can also drive the YB and YC regular core outputs. The GLB (or GLC) global output cannot be reused if the YB (or YC) output is used (Figure 2-19). Refer to the "PLL Macro" section on page 2-27 for more information.

Each global buffer, as well as the PLL reference clock, can be driven from one of the following:

- Three dedicated single-ended I/Os using a hardwired connection
- Two dedicated differential I/Os using a hardwired connection
- The FPGA core

The CCC block is fully configurable, either via Flash configuration bits set in the programming bitstream or through an asynchronous interface. This asynchronous interface is dynamically accessible from inside the Fusion device to permit parameter changes (such as divide ratios) during device operation. To increase the versatility and flexibility of the clock conditioning system, the CCC configuration is determined either by the user during the design process, with configuration data being stored in Flash memory as part of the device programming procedure, or by writing data into a dedicated shift register during normal device operation. This latter mode allows the user to dynamically reconfigure the CCC without the need for core programming. The shift register is accessed through a simple serial interface. Refer to the "CCC and PLL Characteristics" section on page 2-28 for more information.



#### Notes:

- 1. Visit the Actel website for future application notes concerning dynamic PLL reconfiguration. Refer to the "PLL Macro" section on page 2-27 for signal descriptions.
- Many specific INBUF macros support the wide variety of single-ended and differential I/O standards for the Fusion family.

Figure 2-19 • Fusion CCC Options: Global Buffers with the PLL Macro

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Table 2-11 • Available Selections of I/O Standards within CLKBUF and CLKBUF\_LVDS/LVPECL Macros

CLKBUF Macros							
CLKBUF_LVCMOS5							
CLKBUF_LVCMOS33 <sup>1</sup>							
CLKBUF_LVCMOS18							
CLKBUF_LVCMOS15							
CLKBUF_PCI							
CLKBUF_LVDS <sup>2</sup>							
CLKBUF_LVPECL							

#### Notes:

- 1. This is the default macro. For more details refer to the Fusion and ProASIC3/E Macro Library Guide.
- 2. BLVDS and M-LVDS standards are supported with CLKBUF LVDS.

# Global Buffers with No Programmable Delays

The CLKBUF and CLKBUF\_LVPECL/LVDS macros are composite macros that include an I/O macro driving a global buffer, which are hardwired together (Figure 2-20).

The CLKINT macro provides a global buffer function driven by the FPGA core.

The CLKBUF, CLKBUF\_LVPECL/LVDS, and CLKINT macros are pass-through clock sources and do not use the PLL or provide any programmable delay functionality.

Many specific CLKBUF macros support the wide variety of single-ended and differential I/O standards supported by Fusion devices. The available CLKBUF macros are described in the Fusion and ProASIC3/E Macro Library Guide.

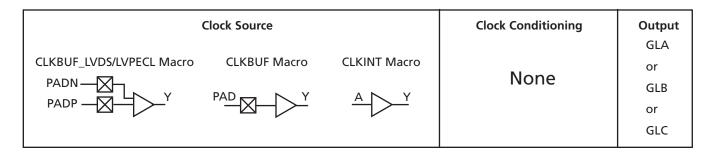


Figure 2-20 • Global Buffers with No Programmable Delay

# Global Buffers with Programmable Delay

The CLKDLY macro is a pass-through clock source that does not use the PLL, but provides the ability to delay the clock input using a programmable delay (Figure 2-21). The CLKDLY macro takes the selected clock input and adds a user-defined delay element. This macro generates an output clock phase shift from the input clock.

The CLKDLY macro can be driven by an INBUF macro to create a composite macro, where the I/O macro drives the global buffer (with programmable delay) using a hardwired connection. In this case, the I/O must be placed in one of the dedicated global I/O locations.

Many specific INBUF macros support the wide variety of single-ended and differential I/O standards supported by the Fusion family. The available INBUF macros are described in the Fusion and ProASIC3/E Macro Library Guide.

The CLKDLY macro can be driven directly from the FPGA core.

The CLKDLY macro can also be driven from an I/O that is routed through the FPGA regular routing fabric. In this case, users must instantiate a special macro, PLLINT, to differentiate from the hardwired I/O connection described earlier.

The visual CLKDLY configuration in the SmartGen part of the Libero IDE and Designer tools allows the user to select the desired amount of delay, and configures the delay elements appropriately. SmartGen also allows the user to select the input clock source. SmartGen will automatically instantiate the special macro, PLLINT, when needed.

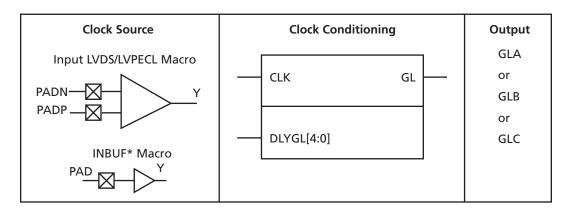


Figure 2-21 • Fusion CCC Options: Global Buffers with Programmable Delay

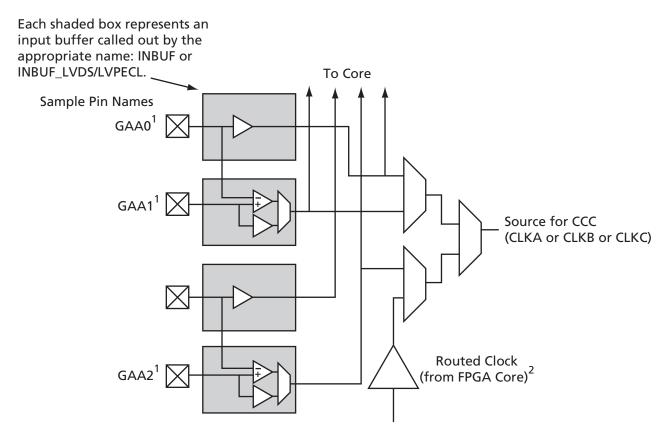
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# **Global Input Selections**

Each global buffer, as well as the PLL reference clock, can be driven from one of the following (Figure 2-22):

- Three dedicated single-ended I/Os using a hardwired connection
- Two dedicated differential I/Os using a hardwired connection
- The FPGA core



GAA[0:2]: GA represents global in the northwest corner of the device. A[0:2]: designates specific A clock source.

## Notes:

- 1. Represents the global input pins. Globals have direct access to the clock conditioning block and are not routed via the FPGA fabric. Refer to the "User I/O Naming Convention" section on page 2-120 for more information.
- Instantiate the routed clock source input as follows:
   a) Connect the output of a logic element to the clock input of the PLL, CLKDLY, or CLKINT macro.
   b) Do not place a clock source I/O (INBUF or INBUF\_LVPECL/LVDS) in a relevant global pin location.
- 3. LVDS-based clock sources are available in the east and west banks on all Fusion devices.

Figure 2-22 • Clock Input Sources Including CLKBUF, CLKBUF\_LVDS/LVPECL, and CLKINT

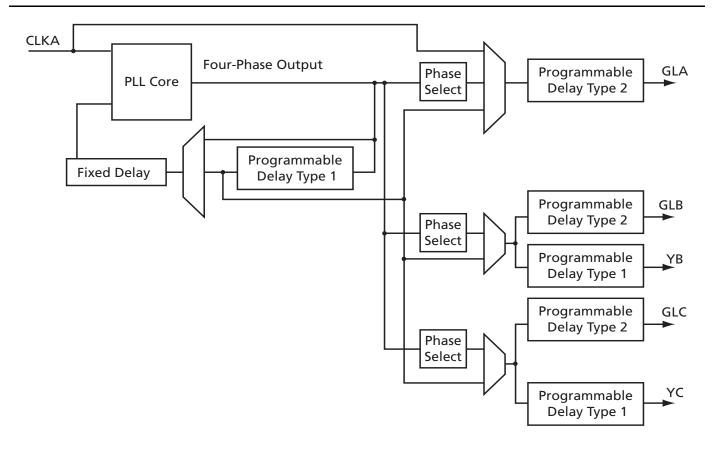
# **CCC Physical Implementation**

The CCC circuit is composed of the following (Figure 2-23):

- PLL core
- Three phase selectors
- Six programmable delays and one fixed delay
- Five programmable frequency dividers that provide frequency multiplication/division (not shown in Figure 2-23 because they are automatically configured based on the user's required frequencies)
- One dynamic shift register that provides CCC dynamic reconfiguration capability (not shown).

## **CCC Programming**

The CCC block is fully configurable. It is configured via static Flash configuration bits in the array, set by the user in the programming bitstream, or configured through an asynchronous dedicated shift register dynamically accessible from inside the Fusion device. The dedicated shift register permits parameter changes such as PLL divide ratios and delays during device operation. This latter mode allows the user to dynamically reconfigure the PLL without the need for core programming. The register file is accessed through a simple serial interface.



**Note:** Clock divider and multiplier blocks are not shown in this figure or in SmartGen. They are automatically configured based on the user's required frequencies.

Figure 2-23 • PLL Block

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## **PLL Macro**

The PLL functionality of the clock conditioning block is supported by the PLL macro. Note that the PLL macro reference clock uses the CLKA input of the CCC block, which is only accessible from the global A[0:2] package pins. Refer to Figure 2-22 on page 2-25 for more information.

The PLL macro provides five derived clocks (three independent) from a single reference clock. The PLL feedback loop can be driven either internally or externally. The PLL macro also provides power-down input and lock output signals. During power-up, POWERDOWN should be asserted low until V<sub>CC</sub> is up. See Figure 2-19 on page 2-22 for more information.

#### Inputs:

- CLKA: selected clock input
- POWERDOWN (active low): disables PLLs. The default state is power-down on (active low).

#### Outputs:

- LOCK (active high): indicates that PLL output has locked on the input reference signal
- GLA, GLB, GLC: outputs to respective global networks
- YB, YC: allows output from the CCC to be routed back to the FPGA core

As previously described, the PLL allows up to five flexible and independently configurable clock outputs. Figure 2-23 on page 2-26 illustrates the various clock output options and delay elements.

As illustrated, the PLL supports three distinct output frequencies from a given input clock. Two of these (GLB and GLC) can be routed to the B and C global networks, respectively, and/or routed to the device core (YB and YC).

There are five delay elements to support phase control on all five outputs (GLA, GLB, GLC, YB, and YC).

There is also a delay element in the feedback loop that can be used to advance the clock relative to the reference clock.

The PLL macro reference clock can be driven by an INBUF macro to create a composite macro, where the I/O macro drives the global buffer (with programmable delay) using a hardwired connection. In this case, the I/O must be placed in one of the dedicated global I/O locations.

The PLL macro reference clock can be driven directly from the FPGA core.

The PLL macro reference clock can also be driven from an I/O that is routed through the FPGA regular routing fabric. In this case, users must instantiate a special macro, PLLINT, to differentiate it from the hardwired I/O connection described earlier.

The visual PLL configuration in SmartGen, available with the Libero IDE and Designer tools, will derive the necessary internal divider ratios based on the input frequency and desired output frequencies selected by the user. SmartGen allows the user to select the various delays and phase shift values necessary to adjust the phases between the reference clock (CLKA) and the derived clocks (GLA, GLB, GLC, YB, and YC). SmartGen also allows the user to select where the input clock is coming from. SmartGen automatically instantiates the special macro, PLLINT, when needed.

# CCC and PLL Characteristics Timing Characteristics

*Table 2-12* • Fusion CCC/PLL Specification

Parameter	Min.	Тур.	Max.	Unit
Clock Conditioning Circuitry Input Frequency f <sub>IN_CCC</sub>	1.5		350	MHz
Clock Conditioning Circuitry Output Frequency f <sub>OUT_CCC</sub>	0.75		350	MHz
Delay Increments in Programmable Delay Blocks <sup>1, 2</sup>		200		ps
Number of Programmable Values in Each Programmable Delay Block			32	
Input Period Jitter			1.5	ns
CCC Output Peak-to-Peak Period Jitter F <sub>CCC_OUT</sub>	Max Pea	ak-to-Peak Pei	riod Jitter	
	1 Global Network Used		3 Global Networks Used	
0.75 MHz to 24 MHz	0.50%		0.70%	
24 MHz to 100 MHz	1.00%		1.20%	
100 MHz to 250 MHz	1.75%		2.00%	
250 MHz to 350 MHz	2.50%		5.60%	
Acquisition Time			150	μs
Output Duty Cycle	48.5		51.5	%
Delay Range in Block: Programmable Delay 1 <sup>1, 2</sup>	0.6		5.56	ns
Delay Range in Block: Programmable Delay 2 <sup>1, 2</sup>	0.025		5.56	ns
Delay Range in Block: Fixed Delay <sup>1, 2</sup>		2.2		ns

## Notes:

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<sup>1.</sup> This delay is a function of voltage and temperature. See Table 3-7 on page 3-7 for deratings.

<sup>2.</sup>  $T_J = 25$ °C,  $V_{CC} = 1.5 V$ 



# **No Glitch MUX (NGMUX)**

Positioned downstream from the PLL/CCC blocks, the NGMUX provides a special switching sequence between two asynchronous clock domains that prevents generating any unwanted narrow clock pulses. The NGMUX is used to switch the source of a global between three different clock sources. Allowable inputs are either two PLL/CCC outputs or a PLL/CCC output and a regular net, as shown

in Figure 2-24. The GLMUXCFG[1:0] configuration bits determine the source of the CLK inputs (i.e., internal signal, GLA, or GLC). These are set by SmartGen during design, but can also be changed by dynamically reconfiguring the PLL. The GLMUXSEL[1:0] bits control which clock source is passed through the NGMUX to the global network (GL). See Table 2-13.

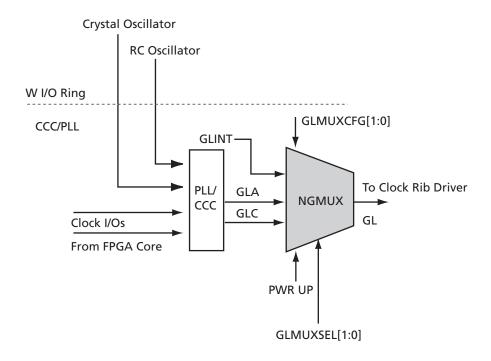


Figure 2-24 • NGMUX

**Table 2-13** • **NGMUX Configuration and Selection Table** 

GLMUXCFG[1:0]	GLMUX	SEL[1:0]	Selected Input Signal	MUX Type
00	Х	0	GLA	2-to-1 GLMUX
	Х	1	GLC	
01	Х	0	GLA	2-to-1 GLMUX
	Χ	1	GLINT	
10	Х	0	GLC	2-to-1 GLMUX
	Х	1	GLINT	
11	0	0	GLA	3-to-1 GLMUX
	0	1	GLC	
	1	0	GLINT	
	1	1	GND	

The NGMUX macro is simplified to show the two clock options that have been selected by the GLMUXCFG[1:0] bits. Figure 2-25 illustrates the NGMUX macro. During design, the two clock sources are connected to CLK0 and CLK1 and are controlled by GLMUXSEL[1:0] to determine which signal is to be passed through the MUX.

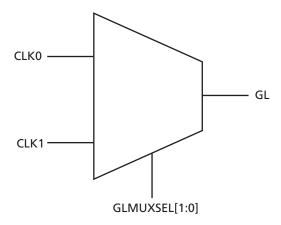


Figure 2-25 • NGMUX Macro

The sequence of switching between two clock sources (from CLK0 to CLK1) is as follows (Figure 2-26):

- GLMUXSEL[1:0] transitions to initiate a switch.
- GL drives one last complete CLK0 positive pulse (i.e., one rising edge followed by one falling edge).
- From that point, GL stays low until the second rising edge of CLK1 occurs.
- At the second CLK1 rising edge, GL will begin to continuously deliver CLK1 signal.
   Minimum t<sub>sw</sub> = 0.05 ns at 25°C (typical conditions).

For examples of NGMUX operation, refer to the Peripherals User's Guide.

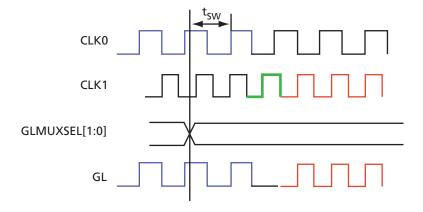


Figure 2-26 • NGMUX Waveform

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# **Real-Time Counter System**

The addition of the RTC system enables Fusion devices to support both standby and sleep modes of operation, greatly reducing power consumption in many applications.

The RTC system comprises six blocks that work together to provide this increased functionality and reduced power consumption. Figure 2-27 shows these blocks and how they are connected.

- RTC (Figure 2-28)
- Crystal oscillator
- V<sub>CC33UP</sub> detector

- Voltage regulator initialization
- Voltage regulator logic
- 1.5 V voltage regulator

The RTC provides a counter as well as a MATCH output signal that may be used in the FPGA and, optionally, to power-up the on-chip 1.5 V voltage regulator and provide a 1.5 V power source (in conjunction with an external pass transistor) to the FPGA fabric portion of the Fusion silicon device. The FPGA fabric can then be used to power-down the 1.5 V voltage regulator.

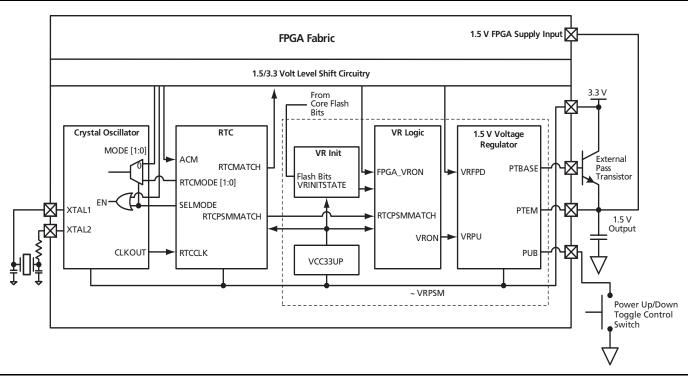


Figure 2-27 • Real-Time Counter System

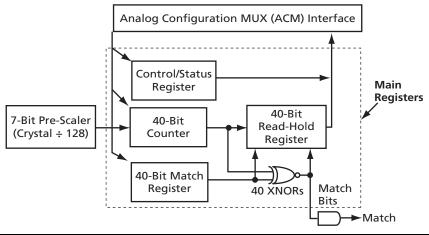


Figure 2-28 • RTC Block Diagram

## **Real-Time Counter**

The RTC can be configured to power up the FPGA fabric at a specific time or periodically. Custom user logic or a soft microcontroller within the FPGA fabric portion of the Fusion device can be programmed to read and modify the registers in the RTC. Based on this information or other internal or external conditions, the FPGA may decide to power down the voltage regulator and thereby shut off the FPGA fabric.

The 3.3 V supply must be valid and the crystal oscillator (nominally 32.768 kHz) enabled for self-time wake-up/restart operation. When operating from the 3.3 V supply and the 1.5 V core voltage is disabled, the ACM interface to the FPGA is disabled.

A 40-bit loadable counter is used as the primary timekeeping element within the RTC. This counter can be configured to reset itself when a count value is reached that matches the value set within a 40-bit match register. Note that the only exception to this self-clearing mechanism occurs when the 40-bit counter is equal to 0 (0x0000000000), since the counter would never increment from zero. When the device is first powered up (i.e., when the 3.3 V supply becomes valid) the 40-bit counter and 40-bit match register are cleared to logic 0, and the MATCH output signal is active (logic 1). At any time when the 40-bit counter value does not match the value in the 40-bit match register, the MATCH output signal will become inactive (logic 0).

Both the counter and match registers are addressable (read/write) from the FPGA and through a JTAG instruction. The RTC is considered part of the analog system and is accessed via ACM. Refer to the "Analog Configuration MUX" section on page 2-89 for detailed instructions on writing to the RTC via the ACM. The counter action can be suspended/resumed by clearing/setting the Cntr\_En bit in the Control/Status Register.

If a 32.768 kHz external crystal is connected to the crystal oscillator pad, the 40-bit counter will have a maximum count of 4,294,967,296 seconds, which equates to just

over 136 years of elapsed timekeeping with a minimum period of 1/256 second, which will be the toggle rate of the LSB bit of the 40-bit counter.

Frequencies other than 32.768 kHz can be used as a clock source, with the appropriate scaling of the LSB time interval. Maximum input clock frequency is 20 MHz (the crystal oscillator limit).

The RTC signals are included in the Analog Block macro. The signal functions and descriptions are listed in Table 2-14.

A Fusion use model includes the RTC controlling the power-up state of the FPGA core via the 1.5 V regulator. To support this model, the crystal oscillator must be running and configured when the FPGA is powered off. Hence, when the RTC is enabled in the system design, it will configure the crystal oscillator via the RTCXTLMODE[1:0] and RTCXTLSEL pins.

A 7-bit pre-scaler block is used to divide the source clock (from the external crystal) by 128. This pre-scaled 50%-duty-cycle clock signal is then used by the counter logic as its reference clock. Given an external crystal frequency of 32.768 kHz, the pre-scaler output clock will toggle at a rate of 32.768 kHz / 128 = 256 Hz.

The RTC is built from and controlled by a set of registers, denoted "Main Registers" in Figure 2-27 on page 2-31. These registers are accessed via the ACM.

The FPGA fabric portion of the Fusion device must be powered up and active at least once to write to the various registers within the RTC to initialize them for the user's application. Users set up the RTC by configuring it from the Actel SmartGen tool implementing custom logic, or programming a soft microcontroller.

The 40-bit counter and match register are each divided into five bytes. Each byte is directly addressable by the ACM. The address map of registers accessed through the ACM and used by the RTC is shown in Table 2-15 on page 2-33.

Table 2-14 • RTC Macro Signal Description

Signal Name	Number of Bits	Direction	Function
RTCMATCH	1	Out	Match between 40-bit counter and match register
RTCPSMMATCH	1	Out	RTCMATCH connected to voltage regulator power supply monitor (VRPSM) (Figure 2-30 on page 2-36)
RTCXTLMODE[1:0]	2	Out	Drives XTLOSC RTCMODE[1:0] pins
RTCXTLSEL	1	Out	Drives XTLOSC SELMODE pin
RTCCLK	1	ln	RTC clock input from XTLOSC CLKOUT pin

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*Table 2-15* • RTC ACM Memory Map

ACM_ADDR[7:0]	Decimal	Register Name	Description	Use
0x40	64	COUNTER0	Counter bits 7:0	Used to preload the counter to a
0x41	65	COUNTER1	Counter bits 15:8	specified start point. Default setting is all zeroes.
0x42	66	COUNTER2	Counter bits 23:16	dii zeroes.
0x43	67	COUNTER3	Counter bits 31:24	
0x44	68	COUNTER4	Counter bits 39:32	
0x48	72	MATCHREG0	Match register bits 7:0	The RTC uses a 40-bit register to
0x49	73	MATCHREG1	Match register bits 15:8	compare against the 40-bit counter value to determine when a match
0x4a	74	MATCHREG2	Match register bits 23:16	occurs. This 40-bit match register, like
0x4b	75	MATCHREG3	Match register bits 31:24	the counter, is broken into 5 bytes
0x4c	76	MATCHREG4	Match register bits 39:32	(MATCHREG0–4).
0x50	80	MATCHBITS0	Individual Match bits 7:0	Each bit of the 40-bit counter is
0x51	81	MATCHBITS1	Individual Match bits 15:8	compared to each bit of the 40-bit match register via XNOR gates. These
0x52	82	MATCHBITS2	Individual Match bits 23:16	40 match bits are partitioned into 5
0x53	83	MATCHBITS3	Individual Match bits 31:24	bytes.
0x54	84	MATCHBITS4	Individual Match bits 39:32	
0x58	88	CTRL_STAT	Control (write) / Status (read) register bits 7:0	Control (write) / Status (read) register bits 7:0
0x59	89	TEST_REG	Test register(s)	Test register(s)

The control/status register (CTRL\_STAT) is an 8-bit register that defines the operation of the RTC. The control register can reset the RTC, enabling operation to begin with all zeroes in the counter. The RTC can be configured to clear upon a match with the Match

register, or it can continue to count while still setting the match signal. To enable the Fusion device to power up at a specific time or at periodic intervals, the RTC can be configured to turn on the 1.5 V voltage regulator. Table 2-16 details the CTRL\_STAT settings.

*Table 2-16* • RTC Control/Status Register

Bit	Name	Description
7	rtc_rst	RTC Reset: Writing a logic 1 to this bit causes an RTC reset. <sup>2</sup> Writing a logic 0 to this bit will allow synchronous deassertion of reset after 2 ACM_CLK cycles if $V_{CC33UP} = 1.3$
6	cntr_en	Counter Enable: A logic 1 in this bit will enable the counter if the RTC is not in reset.
		It takes 64 RTCCLK positive edges (1/2 of the pre-scaler division factor), after reset is removed and $cntr_en = 1$ , before the counter is incremented. <sup>4</sup>
		A logic 0 in this bit resets the pre-scaler and therefore suspends incrementing the counter, but the counter is not reset.
		Before writing to the counter registers, the counter must be disabled.
5	vr_en_mat	Voltage Regulator Enable on Match: Writing a logic 1 to this bit will allow the RTCMATCH output port to go to logic 1 when a match occurs between the 40-bit counter and the 40-bit match register.
		Logic 0 forces RTCMATCH to logic 0, to prevent enabling the voltage regulator from the RTC.
4:3	xt_mode[1:0]	Crystal Oscillator Mode: These bits control the RTCXTLMODE[1:0] output ports that are connected to the RTCMODE[1:0] input pins of the crystal oscillator pad. For 32 kHz crystal operation, this should be set to '01'.
		(See the "Crystal Oscillator" section on page 2-20.)
2	rst_cnt_omat	Reset Counter on Match: A logic 1 written to this bit allows the counter to clear itself when a match occurs. In this situation, the 40-bit counter clears on the next rising edge of the pre-scaled clock, approximately 4 ms after the match occurs (the pre-scaled clock toggles at a rate of 256 Hz, given a 32.768 kHz external crystal).
		A logic 0 written to this bit allows the counter to increment indefinitely, while still allowing match events to occur.
1	rstb_cnt	Counter Reset: A logic 0 resets the 40-bit counter value to 0. A logic 1 allows the counter to count. <sup>4</sup>
0	xtal_en	Crystal Oscillator Enable: This bit controls the RTCXTLSEL output port that is connected to the SELMODE input pin of the crystal oscillator. If a logic 0 is written to this bit, only the FPGA fabric can be used to control the crystal oscillator EN and MODE[1:0] inputs.
		xtal_en = '1': RTC takes control of XTAL oscillator. For example, RTC Mode bits configure the XTAL oscillator (not the FPGA mode bits).
		To enable sleep mode: set xtal_en = '0', so the crystal is controlled from the FPGA EN signal then, when the FPGA is powered down, the from the FPGA will be 0 EN, disabling the crystal oscillator.

#### Notes:

- 1. Default state (set when  $V_{CC33UP} = 0$ ) for bits 0–7 is logic 0.
- 2. Reset of all RTC states (except this Control/Status register) occurs asynchronously if  $V_{CC33UP} = 0$  or CTRL\_STAT bit 7 (rtc\_rst) is set to 1.
- 3. Reset is removed synchronously after 2 rising edges of ACM\_CLK, following both  $V_{CC33UP} = 1$  and  $rtc\_rst = 0$ .
- 4. Counter will first increment on the 64th rising edge of RTCCLK after all of the following are true:
  - a. reset is removed
  - b. rstb\_cnt (CTRL\_STAT bit 1) is set to 1
  - c. cntr\_en (CTRL\_STAT bit 6) is set to 1

and will then increment every 128 RTCCLK cycles.

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# **Crystal Oscillator (Xtal Osc)**

When used as the clock source for the RTC, the crystal oscillator will be configured by the RTC with the RTCXTLMODE[1:0] RTC macro pins. Refer to the "Crystal Oscillator" section on page 2-20 for specific details on crystal oscillator operation.

The crystal oscillator input to the RTC is divided by 128, so bit 0 of the RTC toggles at the frequency of the crystal oscillator divided by 128. The frequencies of the RTC are gated by those of the crystal oscillator; from 32.768 kHz to 20 MHz. When used with a 32.768 kHz crystal, bit 0 of the of RTC has a period of ~7.8 ms, and bit 7 has a period of 1 second.

# **Voltage Regulator Initialization (VR Init)**

The VR Init block determines voltage regulator behavior when the 3.3 V supply is valid. The Fusion devices support different use models. Some of these require the 1.5 V voltage regulator to turn on when the 3.3 V supply is stable. Other use models require additional conditions to be met before the 1.5 V VR turns on. Since the FPGA is not operating when the 3.3 V supply is off, the VR Init lets the user define VR behavior at design time. Two bits can be set within the core, which the VR Init will read as it comes out of reset and either turn on the VR or leave it in an off state.

# **Voltage Regulator (VR) Logic**

The Voltage Regulator Logic block, along with the VR, combines commands from the FPGA, RTC, VR Init block,  $V_{\text{CC33UP}}$  detector, and PUB pad, to determine whether or not the VR is enabled.

The VR can be enabled from several sources: the PUB pin, the RTC\_MATCH signal from the RTC block, or triggered by the VR Init block. Once triggered, the VR will remain on. Only the FPGA fabric can disable the VR, unless the  $V_{\text{CC33A}}$  supply falls below the  $V_{\text{CC33UP}}$  threshold and a reset occurs.

# 1.5 V Voltage Regulator

The VR generates a 1.5 V power supply from the 3.3 V power supply. The 1.5 V output is intended to supply all 1.5 V needs of the Fusion device. This regulator requires an external bipolar pass transistor(Figure 2-29). The VR can drive up to 20 mA of current through the PTBASE pad. The amount of 1.5 V current available is dependent upon the gain of the external pass transistor used. Enable for this block is generated in the VR Logic block or from the PUB pin.

The 1.5 V is not supplied internally to the Fusion device. It must be routed externally to the  $V_{CC}$  pins on the device. Therefore the user is not required to use the VR and can use an off-chip 1.5 V supply if desired.

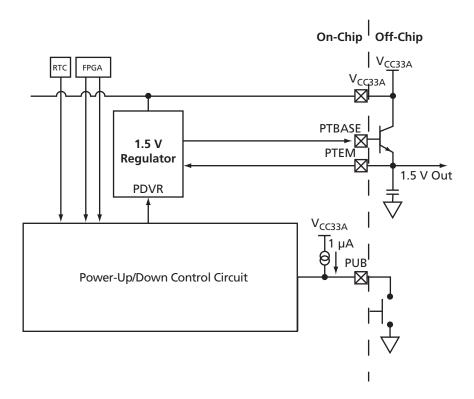


Figure 2-29 • Voltage Regulator

# **Voltage Regulator Power Supply Monitor (VRPSM)**

As the functions of the VR Logic and Power System Monitor work closely together to control the power-up state of the FPGA core, these functions were combined into a single VRPSM macro (Figure 2-30).

The signals for the VRPSM macro are listed in Table 2-17. The PUB input comes from the PUB pin on the device and can be pulled low by a signal external to the Fusion device. This can be used to wake up the device. The inputs VRINITSTATE and RTCPSMMTACH come from the VR Init and RTC blocks, respectively, and either can initiate a VR power-up.

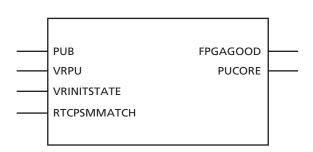


Figure 2-30 • VRPSM Macro

Table 2-17 • Signals for VRPSM Macro

Signal Name	Number of Bits	Direction	Function
PUB	1	Input	Active low signal to power up the FPGA core via the 1.5 V regulator.
			In this reference design, PUB is on the top level connected to an external switch.
VRPU	1	Input	When this pin is at logic '1', the FPGA core will be turned off via the voltage regulator.
VRINITSTATE	1	Input	This feature is not used in this reference design and is not shown in the macro generated by SmartGen. If used, the signal enables you to set your voltage regulator output at power-up (ON or OFF).
RTCPSMMATCH	1	Input	This feature is not used in this reference design. If used, this active high signal is driven by the RTC's match signal to indicate that the RTC counter value matches with the pre-defined Match Register value set in SmartGen.
FPGAGOOD	1	Output	Logic '1' indicates that FPGA is logically functional.
PUCORE	1	Output	Logic '1' indicates that FPGA is logically functional.

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# **Embedded Memories**

Fusion devices include four types of embedded memory: Flash block, FlashROM, SRAM, and FIFO.

# **Flash Memory Block**

Fusion is the first FPGA that offers a Flash memory block (FB). Each FB block stores 2 Mbits of data. The Flash memory block macro is illustrated in Figure 2-31. The port pin name and descriptions are detailed on Table 2-18 on page 2-38. All Flash memory block signals are active high, except for CLK and active low RESET. All Flash memory operations are synchronous to the rising edge of CLK.

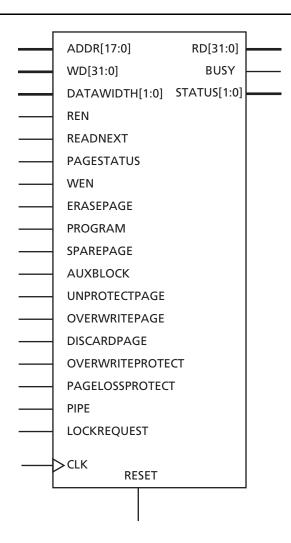


Figure 2-31 • Flash Memory Block

# Flash Memory Block Pin Names

*Table 2-18* • Flash Memory Block Pin Names

Interface Name	Width	Direction	Description
ADDR[17:0]	18	In	Byte offset into the FB. Byte based address.
AUXBLOCK	1	In	When asserted, the page addressed is used to access the auxiliary block within that page.
BUSY	1	Out	When asserted, indicates that the FB is performing an operation.
CLK	1	ln	User interface clock. All operations and status are synchronous to the rising edge of this clock.
DATAWIDTH[1:0]	2	In	Data width  00 = 1 byte in RD/WD[7:0]  01 = 2 bytes in RD/WD[15:0]  1x = 4 bytes in RD/WD[31:0]
DISCARDPAGE	1	In	When asserted, the contents of the Page Buffer are discarded so that a new page write can be started.
ERASEPAGE	1	In	When asserted, the contents of the Page Buffer are discarded so that a new page write can be started.
LOCKREQUEST	1	In	When asserted, indicates to the JTAG controller that the FPGA interface is accessing the FB.
OVERWRITEPAGE	1	In	When asserted, the page addressed is overwritten with the contents of the Page Buffer if the page is writable.
OVERWRITEPROTEC T	1	In	When asserted, all program operations will set the overwrite protect bit of the page being programmed.
PAGESTATUS	1	In	When asserted with REN, initiates a read page status operation.
PAGELOSSPROTECT	1	In	When asserted, a modified Page Buffer must be programmed or discarded before accessing a new page.
PIPE	1	In	Adds a pipeline stage to the output for operation above 50 MHz.
PROGRAM	1	In	When asserted, writes the contents of the Page Buffer into the FB page addressed.
RD[31:0]	32	Out	Read data; data will be valid from the first non-busy cycle (BUSY=0) after REN has been asserted.
READNEXT	1	In	When asserted with REN, initiates a read-next operation.
REN	1	In	When asserted, initiates a read operation.
RESET	1	In	When asserted, resets the state of the FB (active low).
SPAREPAGE	1	In	When asserted, the sector addressed is used to access the spare page within that sector.
STATUS[1:0]	2	Out	Status of the last operation completed:  00: Successful completion  01: Read/Unprotect-Page: single error detected and corrected     Write: operation addressed a write-protected page     Erase-Page: protection violation     Program: Page Buffer is unmodified
UNPROTECTPAGE	1	In	When asserted, the page addressed is copied into the Page Buffer and the Page Buffer is made writable.
WD[31:0]	32	In	Write data
WEN	1	In	When asserted, store WD in the page buffer.

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All Flash memory block input signals are active high, except for RESET.

# Flash Memory Block Diagram

A simplified diagram of the Flash memory block is shown in Figure 2-32.

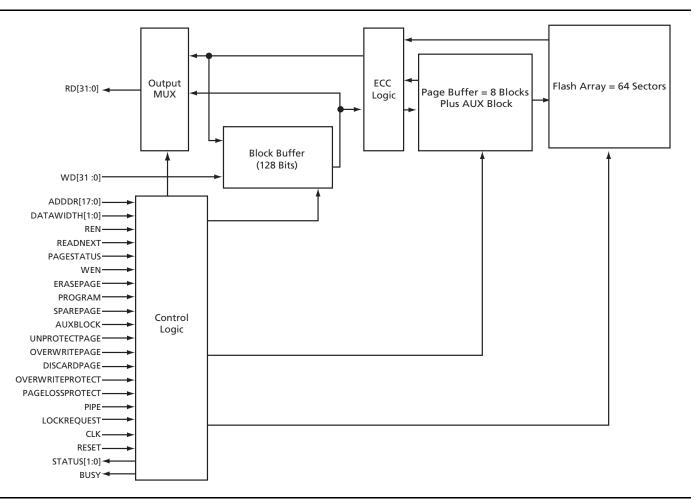


Figure 2-32 • Flash Memory Block Diagram

The logic consists of the following sub-blocks:

- Flash Array
  - Contains all stored data. The Flash array contains 64 sectors, and each sector contains 33 pages of data.
- Page Buffer
  - Is a page-wide volatile register. A page contains 8 blocks of data and an AUX block.
- Block Buffer
  - Contains the contents of the last block accessed. A block contains 128 data bits.
- ECC Logic
  - The FB stores error correction information with each block to perform single-bit error correction and double-bit error detection on all data blocks.

# Flash Memory Block Addressing

Figure 2-33 shows a graphical representation of the Flash memory block.

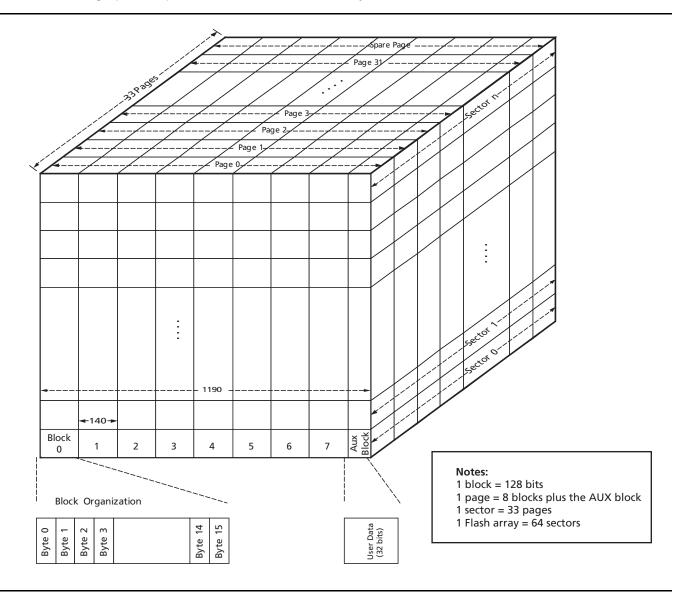


Figure 2-33 • Flash Memory Block Organization

Each FB is partitioned into sectors, pages, blocks, and bytes. There are 64 sectors in an FB, and each sector contains 32 pages and 1 spare page. Each page contains 8 data blocks and 1 auxiliary block. Each data block contains 16 bytes of user data, and the auxiliary block contains 4 bytes of user data.

Addressing for the FB is shown in Table 2-19.

Table 2-19 • FB Address Bit Allocation ADDR[17:0]

17 12	11	7	6	4	3	0
Sector	Pa	ge	Blo	ock	Ву	rte

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When the spare page of a sector is addressed (SPAREPAGE active), ADDR[11:7] are ignored.

When the Auxiliary block is addressed (AUXBLOCK active), ADDR[6:2] are ignored.

Note: The spare page of sector 0 is unavailable for any user data. Writes to this page will return an error, and reads will return all zeroes.

Data operations are performed in widths of 1 to 4 bytes. A write to a location in a page that is not already in the Page Buffer will cause the page to be read from the FB Array and stored in the Page Buffer. The block that was addressed during the write will be put into the Block Buffer and the data written by WD will overwrite the data in the Block Buffer. After the data is written to the Block Buffer, the Block Buffer is then written to the Page Buffer to keep both buffers in sync. Subsequent writes to the same block will overwrite the Block Buffer and the Page Buffer. A write to another block in the page will cause the addressed block to be loaded from the Page Buffer, and the write will be performed as described previously.

The data width can be selected dynamically via the DATAWIDTH input bus. The truth table for the data width settings is detailed in Table 2-20. The minimum resolvable address is one 8-bit byte. For data widths greater than 8 bits, the corresponding address bits are ignored (when DATAWIDTH = 0 (2 bytes), ADDR[0] is ignored and when DATAWIDTH = 10 or 11 (4 bytes), ADDR[1:0] is ignored). Data pins are LSB-oriented and unused WD data pins must be grounded.

Table 2-20 • Data Width Settings

DATAWIDTH[1:0]	Data Width			
00	1 byte [7:0]			
01 2 byte [15:0]				
10, 11	4 bytes [31:0]			

# Flash Memory Block Protection

## **Page Loss Protection**

When the PAGELOSSPROTECT pin is set to logic 1, it prevents writes to any other page except the current page in the Page Buffer, until the page is either discarded or programmed.

A write to another page while the current page is page loss protected will return a STATUS of '11'.

## **Overwrite Protection**

Any page that is overwrite protected will result in the STATUS being set to '01' when an attempt is made to either write, program, or erase it. To set the Overwrite Protection state for a page, set the OVERWRITEPROTECT pin when a program operation is undertaken. To clear the Overwrite Protect state for a given page, an Unprotect Page operation must be performed on the page, and then the page must be programmed with the OVERWRITEPROTECT pin cleared to save the new page.

#### **LOCKREQUEST**

The LOCKREQUEST signal is used to give the user interface control over simultaneous access of the FB from both the User and JTAG interfaces. When LOCKREQUEST is asserted, the JTAG interface will hold off any access attempts until LOCKREQUEST is deasserted.

# Flash Memory Block Operations FB Operation Priority

The FB provides for priority of operations when multiple actions are requested simultaneously. Table 2-21 shows the priority order (priority 0 is the highest).

Table 2-21 • FB Operation Priority

Operation	Priority
System initialization	0
FB reset	1
Read	2
Write	3
Erase page	4
Program	5
Unprotect page	6
Discard page	7

Access to the FB is controlled by the BUSY signal. The BUSY output is synchronous to the CLK signal. FB operations are only accepted in cycles where BUSY is logic 0.

#### **Write Operation**

Write operations are initiated with the assertion of the WEN signal. Figure 2-34 on page 2-42 illustrates the multiple write operations.

When a write operation is initiated to a page that is currently not in the Page Buffer, the FB control logic will issue a BUSY signal to the user interface while the page is loaded from the FB Array into the Page Buffer. (Note: The number of clock cycles that the BUSY output is asserted during the load of the Page Buffer is variable.) After loading the page to the Page Buffer, the addressed data block is loaded from the Page Buffer into the Block Buffer. Subsequent writes to the same block of the page will incur no busy cycles. A write to another block in the page will assert BUSY for four cycles (five cycles when PIPE is asserted), to allow the data to be written to the Page Buffer and have the current block loaded into the Block Buffer.

Write operations are considered successful as long as the STATUS output is '00'. A non-zero STATUS indicates an error was detected during the operation and the write was not performed. Note that the STATUS output is "sticky;" it is unchanged until another operation is started.

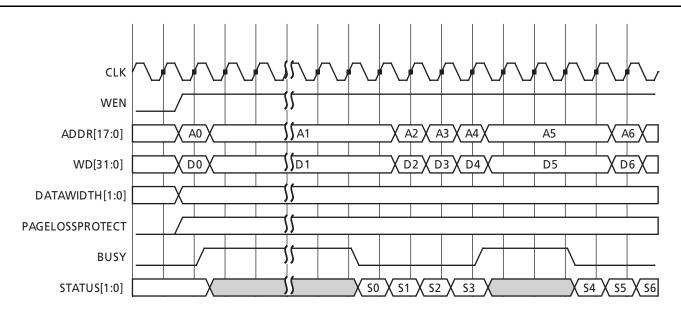


Figure 2-34 • FB Write Waveform

Only one word can be written at a time. Write word width is controlled by the DATAWIDTH bus. Users are responsible for keeping track of the contents of the Page Buffer and when to program it to the array. Just like a regular RAM, writing to random addresses is possible. Users can write into the Page Buffer in any order, but will incur additional BUSY cycles. It is not necessary to modify the entire Page Buffer before saving it to nonvolatile memory.

Write errors include the following:

- 1. Attempting to write a page that is Overwrite Protected (STATUS = 01). The write is not performed.
- 2. Attempting to write to a page that is not in the Page Buffer when Page Loss Protection is enabled (STATUS = 11). The write is not performed.

## **Program Operation**

A program operation is initiated by asserting the PROGRAM signal on the interface. Program operations save the contents of the Page Buffer to the FB Array. Due to the technologies inherent in the FB, a program operation is a time consuming operation (~8 ms). While the FB is writing the data to the array, the BUSY signal will be asserted.

During a Program operation, the sector and page addresses on ADDR are compared with the stored address for the page (and sector) in the Page Buffer. If there is a mismatch between the two addresses, the program operation will be aborted and an error will be reported on the STATUS output.

It is possible to write the Page Buffer to a different page in memory. When asserting the PROGRAM pin, if OVERWRITEPAGE is asserted as well, the FB will write the contents of the Page Buffer to the sector and page designated on the ADDR inputs, if the destination page is not overwrite protected.

A program operation may be utilized to either modify the contents of the page in the Flash memory block or change the protections for the page. Setting the OVERWRITEPROTECT bit on the interface while asserting the PROGRAM pin will put the page addressed into Overwrite Protect Mode. Overwrite Protect Mode safeguards a page from being inadvertently overwritten during subsequent program or erase operations.

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Program operations that result in a STATUS value of '01' do not modify the addressed page. For all other values of STATUS, the addressed page is modified.

Program errors include the following:

- 1. Attempting to program a page that is Overwrite Protected (STATUS = 01)
- 2. Attempting to program to a page that is not in the Page Buffer when the Page Buffer has entered Page Loss Protection mode (STATUS = 01)
- 3. Attempting to perform a program with OVERWRITEPAGE set when the page addressed has been Overwrite Protected (STATUS = 01)

- 4. The Write Count of the page programmed exceeding the Write Threshold defined in the part specification (STATUS = 11)
- 5. The ECC Logic determining that there is an uncorrectable error within the programmed page (STATUS = 10)
- 6. Attempting to program to a page that is **not** in the Page Buffer when OVERWRITEPAGE is not set and the page in the Page Buffer is modified (STATUS = 01)
- 7. Attempting to program the page that is in the Page Buffer when the Page Buffer is **not** modified.

The waveform for a program operation is shown in Figure 2-35.

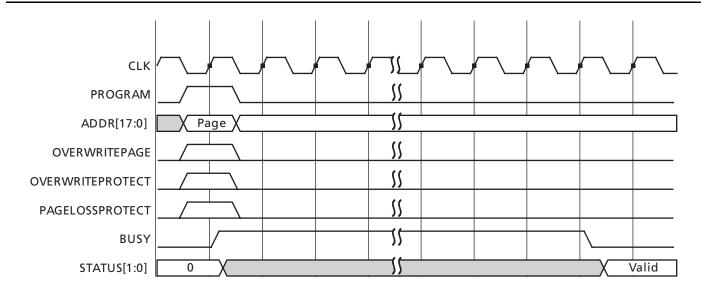


Figure 2-35 • FB Program Waveform

Note: OVERWRITEPAGE is only sampled when the PROGRAM or ERASEPAGE pins are asserted. OVERWRITEPAGE is ignored in all other operations.

## **Erase Page Operation**

The Erase Page operation is initiated when the ERASEPAGE pin is asserted. The Erase Page operation allows the user to erase (set user data to '0') any page within the FB.

The use of the OVERWRITEPAGE and PAGELOSSPROTECT pins is the same for erase as for a Program Page operation.

As with the Program Page operation, a STATUS of '01' indicates that the addressed page is not erased.

A waveform for an Erase Page operation is shown in Figure 2-36.

Erase errors include the following:

- 1. Attempting to erase a page that is Overwrite Protected (STATUS = 01)
- 2. Attempting to erase a page that is not in the Page Buffer when the Page Buffer has entered Page Loss Protection mode (STATUS = 01)
- 3. The Write Count of the erased page exceeding the Write Threshold defined in the part specification (STATUS = 11)
- 4. The ECC Logic determining that there is an uncorrectable error within the erased page (STATUS = 10)

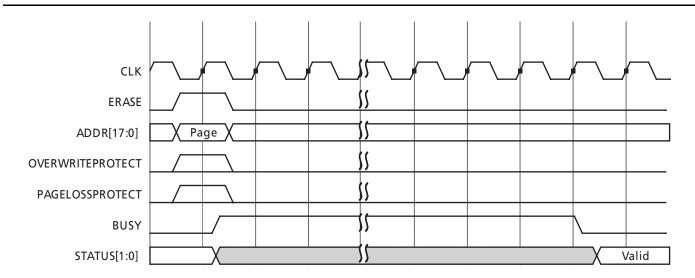


Figure 2-36 • FB Erase Page Waveform

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## **Read Operation**

Read operations are designed to read data from the FB Array, Page Buffer, Block Buffer or status registers. Read operations support a normal read and a read-ahead mode (done by asserting READNEXT). Also, the timing for Read operations is dependent on the setting of PIPE.

The following diagrams illustrate representative timing for Non-Pipe Mode (Figure 2-37) and Pipe Mode (Figure 2-38) reads of the Flash memory block interface.

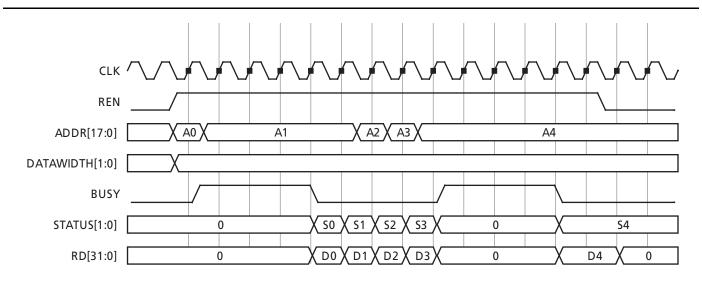


Figure 2-37 • Read Waveform (Non-Pipe Mode, 32-Bit Access)

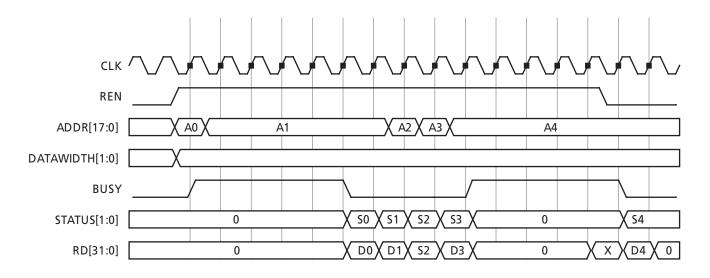


Figure 2-38 • Read Waveform (Pipe Mode, 32-Bit Access)

The following error indications are possible for Read operations:

- 1. STATUS = 01 when a single-bit data error was detected and corrected within the block addressed.
- 2. STATUS = 10 when a double-bit error was detected in the block addressed (note that the error is uncorrected).

In addition to data reads, users can read the status of any page in the FB by asserting PAGESTATUS along with REN. The format of the data returned by a page status read is shown in Table 2-22, and the definition of the page status bits is shown in Table 2-23.

*Table 2-22* • Page Status Read Data Format

31	8	7	4	3	2	1	0
Write	Count	Rese	rved	Over Threshold	Read Protected	Write Protected	Overwrite Protected

Table 2-23 • Page Status Bit Definition

Page Status Bits	Bit Definition				
31–8	The number of times the page addressed has been programmed/erased				
7–4	Reserved; read as 0				
3	Over threshold indicator (see the "Program Operation" section on page 2-42)				
2	Read protected; read protect bit for page which is set via the JTAG interface				
1	Write protected; write protect bit for page which is set via the JTAG interface				
0	Overwrite protected; designates that the user has set the OVERWRITEPROTECT bit on the interface while doing a program operation. The page cannot be written without first performing an Unprotect Page operation.				

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### **Read Next Operation**

The Read Next operation is a feature by which the next block relative to the block in the Block Buffer is read from the FB Array while performing reads from the Block Buffer. The goal is to minimize wait states during consecutive sequential read operations.

The Read Next operation is performed in a predetermined manner because it does look-ahead reads. The general look-ahead function is as follows:

- Within a page, the next block fetched will be the next in the linear address.
- When reading the last data block of a page, it will fetch the first block of the next page.
- When reading spare pages, it will read the first block of the next sector's spare page.

- Reads of the last sector will wrap around to sector 0.
- Reads of Auxiliary blocks will read the next linear page's Auxiliary block.

When an address on the ADDR input does not agree with the predetermined look-ahead address, there is a time penalty for this access. The FB will be busy finishing the current look-ahead read before it can start the next read. The worst case is a total of nine BUSY cycles before data is delivered.

The Non-Pipe Mode and Pipe Mode waveforms for Read Next operations are illustrated in Figure 2-39 and Figure 2-40.

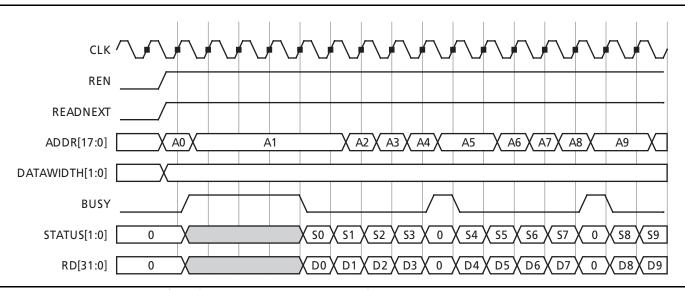


Figure 2-39 • Read Next Waveform (Non-Pipe Mode, 32-Bit Access)

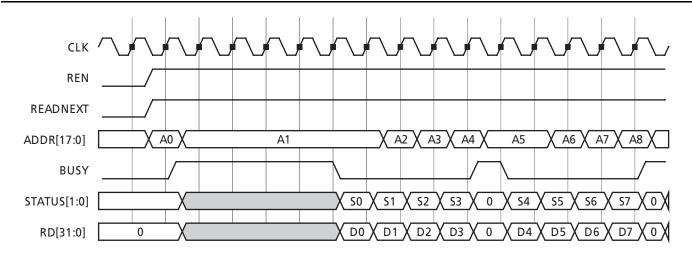


Figure 2-40 • Read Next WaveForm (Pipe Mode, 32-Bit Access)

### **Unprotect Page Operation**

An Unprotect Page operation will clear the protection for a page addressed on the ADDR input. It is initiated by setting the UNPROTECTPAGE signal on the interface along with the page address on ADDR.

If the page is not in the Page Buffer, the Unprotect Page operation will copy the page into the Page Buffer. The copy page operation occurs only if the current page in the Page Buffer is not Page Loss Protected.

The waveform for an Unprotect Page operation is shown in Figure 2-41.

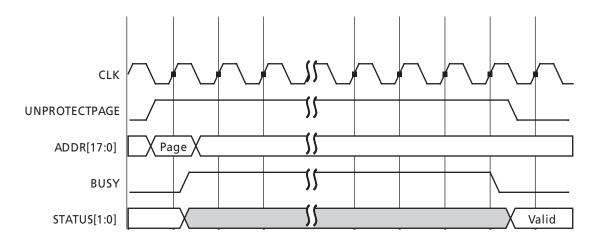


Figure 2-41 • FB Unprotected Page Waveform

The Unprotect Page operation can incur the following error conditions:

- If the copy of the page to the Page Buffer determines that the page has a single-bit correctable error in the data, it will report a STATUS = 01.
- If the address on ADDR does not match the address of the Page Buffer, PAGELOSSPROTECT is asserted, and the Page Buffer has been modified, then the STATUS = 11 and the addressed page is not loaded into the Page Buffer.
- 3. If the copy of the page to the Page Buffer determines that at least one block in the page has a double-bit uncorrectable error, then STATUS = 10 and the Page Buffer will contain the corrupted data.

## **Discard Page Operation**

If the contents of the modified Page Buffer have to be discarded, the DISCARDPAGE signal should be asserted. This command results in the Page Buffer being marked as unmodified.

The timing for the operation is shown in Figure 2-42. The BUSY signal will remain asserted until the operation has completed.

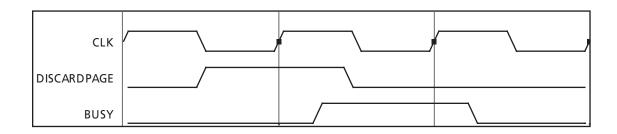


Figure 2-42 • FB Discard Page Waveform

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# **Flash Memory Block Characteristics**

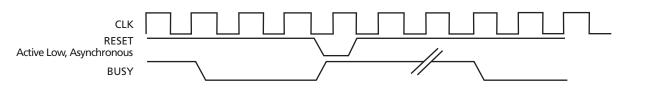


Figure 2-43 • Reset Timing Diagram

Table 2-24 • Flash Memory Block Timing
Commercial-Case Conditions: T<sub>J</sub> = 25°C, Typical Case, V<sub>CC</sub> = 1.5 V

Parameter	Description	Min.	Тур.	Max.	Units
t <sub>CLKQ5CYC</sub>	Clock-to-Q in 5-cycle read mode of the Control Logic		7.5		ns
t <sub>CLKQ6CYC</sub>	Clock-to-Q in 6-cycle read mode of the Control Logic		2.3		ns
t <sub>DSUNVM</sub>	Data Input Setup time for the Control Logic	1.5			ns
t <sub>DHNVM</sub>	Data Input Hold time for the Control Logic	0			ns
t <sub>ASUNVM</sub>	Address Input Setup time for the Control Logic	4.9			ns
t <sub>AHNVM</sub>	Address Input Hold time for the Control Logic	0			ns
t <sub>MPWARNVM</sub>	Asynchronous Reset Minimum Pulse Width for the Control Logic	10			ns
t <sub>MPWCLKNVM</sub>	Clock Minimum Pulse Width for the Control Logic	5			ns

## **FlashROM**

Fusion devices have 1 kbit of on-chip nonvolatile Flash memory that can be read from the FPGA core fabric. The FlashROM is arranged in 8 banks of 128 bits during programming. The 128 bits in each bank are addressable as 16 bytes during the read back of the FlashROM from the FPGA core (Figure 2-44).

The FlashROM can only be programmed via the IEEE 1532 JTAG port. It cannot be programmed directly from the FPGA core. When programming, each of the 8 128-bit banks can be selectively reprogrammed. The FlashROM can only be reprogrammed on a bank boundary. Programming involves an automatic, on-chip bank erase prior to reprogramming the bank. The FlashROM supports a synchronous read and can be read on byte boundaries. The upper 3 bits of the FlashROM address from the FPGA core define the bank that is being accessed. The lower 4 bits of the FlashROM address from the FPGA core define which of the 16 bytes in the bank is being accessed.

The maximum FlashROM access clock is 20 MHz. Figure 2-45 shows the timing behavior of FlashROM access cycle— the address has to be setup on the rising edge of clock for DOUT to be valid on the next clock falling edge.

If the address is unchanged for 2 cycles:

- D0 becomes invalid 10 ns after the second rising edge of clock
- D0 becomes valid again 10 ns after second falling edge

If the address unchanged for 3 cycles:

- D0 becomes invalid 10 ns after the second rising edge of clock
- D0 becomes valid again 10 ns after second falling edge
- D0 becomes invalid 10 ns after the third rising edge of clock
- D0 becomes valid again 10 ns after third falling edge

		Byte Number in Bank 4 LSB of ADDR (READ)															
		15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Bai	7																
Bank Number 3 MSB of ADE	6																
of	5																
nbe AD	4																
×	3																
(READ)	2																
AD	1																
	0																

Figure 2-44 • FlashROM Architecture

#### FlashROM Characteristics

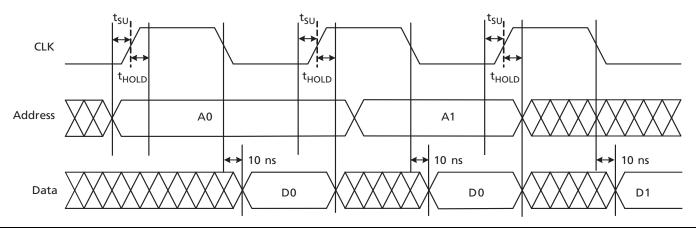


Figure 2-45 • FlashROM Timing Diagram

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## SRAM and FIFO

All Fusion devices have SRAM blocks along the north side of the device. Additionally, AFS600 and AFS1500 devices have an SRAM block on the south side of the device. To meet the needs of high-performance designs, the memory blocks operate strictly in synchronous mode for both read and write operations. The read and write clocks are completely independent, and each may operate at any desired frequency less than or equal to 350 MHz.

- 4k×1, 2k×2, 1k×4, 512×9 (dual-port RAM—two read, two write or one read, one write)
- 512×9, 256×18 (two-port RAM—one read and one write)
- Sync write, sync pipelined/nonpipelined read

The Fusion SRAM memory block includes dedicated FIFO control logic to generate internal addresses and external flag logic (Full, Empty, AFULL, AEMPTY).

During RAM operation, addresses are sourced by the user logic and the FIFO controller is ignored. In FIFO mode, the internal addresses are generated by the FIFO controller and routed to the RAM array by internal MUXes. Refer to Figure 2-46 for more information about the implementation of the embedded FIFO controller.

The Fusion architecture enables the read and write sizes of RAMs to be organized independently, allowing for bus conversion. This is done with the WW (write width) and RW (read width) pins. The different DxW configurations are 256x18, 512x9, 1kx4, 2kx2, and 4kx1. For example, the write size can be set to 256x18 and the read size to 512x9.

Both the write and read widths for the RAM blocks can be specified independently with the WW (write width) and RW (read width) pins. The different DxW configurations are 256×18, 512×9, 1k×4, 2k×2, and 4k×1.

Refer to the allowable RW and WW values supported for each of the RAM macro types in Table 2-25 on page 2-53.

When widths of one, two, or four are selected, the ninth bit is unused. For example, when writing nine-bit values and reading four-bit values, only the first four bits and the second four bits of each nine-bit value are addressable for read operations. The ninth bit is not accessible.

Conversely, when writing four-bit values and reading nine-bit values, the ninth bit of a read operation will be undefined. The RAM blocks employ Little Endian byte order for read and write operations.

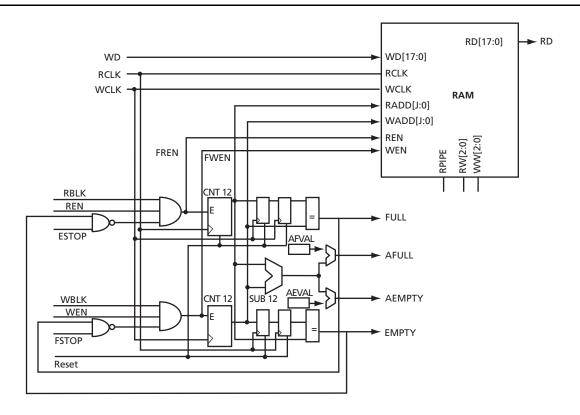


Figure 2-46 • Fusion RAM Block with Embedded FIFO Controller

# **RAM4K9 Description**

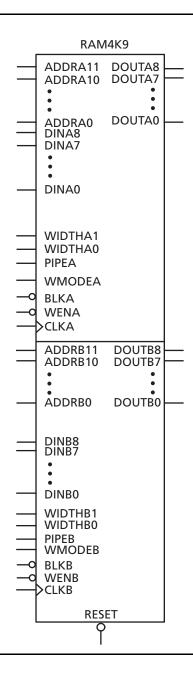


Figure 2-47 • RAM4K9

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The following signals are used to configure the RAM4K9 memory element:

#### WIDTHA and WIDTHB

These signals enable the RAM to be configured in one of four allowable aspect ratios (Table 2-25).

Table 2-25 • Allowable Aspect Ratio Settings for WIDTHA[1:0]

WIDTHA1, WIDTHA0	WIDTHB1, WIDTHB0	D×W
00	00	4k <b>×</b> 1
01	01	2k <b>×</b> 2
10	10	1k <b>×</b> 4
11	11	512 <b>×</b> 9

**Note:** The aspect ratio settings are constant and cannot be changed on the fly.

#### **BLKA and BLKB**

These signals are active low and will enable the respective ports when asserted. When a BLKx signal is deasserted, the corresponding port's outputs hold the previous value.

#### WENA and WENB

These signals switch the RAM between read and write modes for the respective ports. A low on these signals indicates a write operation, and a high indicates a read.

#### **CLKA and CLKB**

These are the clock signals for the synchronous read and write operations. These can be driven independently or with the same driver.

#### PIPEA and PIPEB

These signals are used to specify pipelined read on the output. A low on PIPEA or PIPEB indicates a nonpipelined read and the data appears on the corresponding output in the same clock cycle. A high indicates a pipelined read and data appears on the corresponding output in the next clock cycle.

#### WMODEA and WMODEB

These signals are used to configure the behavior of the output when RAM is in write mode. A low on these signals makes the output retain data from the previous read. A high indicates pass-through behavior, wherein the data being written will appear immediately on the output. This signal is overridden when the RAM is being read.

#### RESET

This active low signal resets the output to zero and disables reads and/or writes from the SRAM block as well as clears the data hold registers when asserted. It does not reset the contents of the memory.

#### **ADDRA and ADDRB**

These are used as read or write addresses, and they are 12 bits wide. When a depth of less than 4 k is specified, the unused high-order bits must be grounded (Table 2-26).

Table 2-26 • Address Pins Unused/Used for Various Supported Bus Widths

	ADDRx			
DxW	Unused	Used		
4k <b>×</b> 1	None	[11:0]		
2k <b>x</b> 2	[11]	[10:0]		
1k <b>×</b> 4	[11:10]	[9:0]		
512 <b>×</b> 9	[11:9]	[8:0]		

**Note:** The "x" in ADDRx implies A or B.

#### **DINA and DINB**

These are the input data signals, and they are nine bits wide. Not all nine bits are valid in all configurations. When a data width less than nine is specified, unused high-order signals must be grounded (Table 2-27).

## **DOUTA and DOUTB**

These are the nine-bit output data signals. Not all nine bits are valid in all configurations. As with DINA and DINB, high-order bits may not be used (Table 2-27). The output data on unused pins is undefined.

Table 2-27 • Unused/Used Input and Output Data Pins for Various Supported Bus Widths

	DINx/DOUTx			
DxW	Unused	Used		
4k <b>×</b> 1	[8:1]	[0]		
2k <b>x</b> 2	[8:2]	[1:0]		
1k <b>x</b> 4	[8:4]	[3:0]		
512 <b>×</b> 9	None	[8:0]		

**Note:** The "x" in DINx and DOUTx implies A or B.

# **RAM512X18 Description**

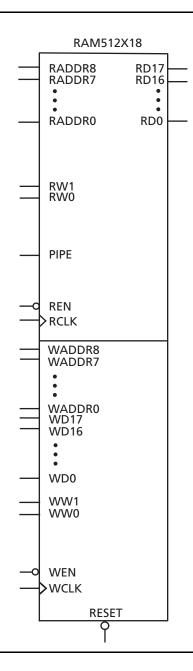


Figure 2-48 • RAM512X18

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RAM512X18 exhibits slightly different behavior from the RAM4K9, as it has dedicated read and write ports.

#### WW and RW

These signals enable the RAM to be configured in one of the two allowable aspect ratios (Table 2-28).

Table 2-28 • Aspect Ratio Settings for WW[1:0]

WW[1:0]	RW[1:0]	D×W			
01	01	512×9			
10	10	256×18			
00, 11	00, 11	Reserved			

#### WD and RD

These are the input and output data signals, and they are 18 bits wide. When a 512×9 aspect ratio is used for write, WD[17:9] are unused and must be grounded. If this aspect ratio is used for read, then RD[17:9] are undefined.

#### **WADDR and RADDR**

These are read and write addresses, and they are nine bits wide. When the 256×18 aspect ratio is used for write or read, WADDR[8] or RADDR[8] are unused and must be grounded.

#### **WCLK and RCLK**

These signals are the write and read clocks, respectively. They are both active high.

#### **WEN and REN**

These signals are the write and read enables, respectively. They are both active low by default. These signals can be configured as active high.

#### RESET

This active low signal resets the output to zero and disables reads and/or writes from the SRAM block as well as clears the data hold registers when asserted. It does not reset the contents of the memory.

#### PIPE

This signal is used to specify pipelined read on the output. A low on PIPE indicates a nonpipelined read and the data appears on the output in the same clock cycle. A high indicates a pipelined read and data appears on the output in the next clock cycle.

## Clocking

The dual-port SRAM blocks are only clocked on the rising edge. SmartGen allows falling-edge triggered clocks by adding inverters to the netlist, hence achieving dual-port SRAM blocks that are clocked on either edge (rising or falling). For dual-port SRAM, each port can be clocked on either edge or by separate clocks, by port.

Fusion devices support inversion (bubble pushing) throughout the FPGA architecture, including the clock input to the SRAM modules. Inversions added to the SRAM clock pin on the design schematic or in the HDL code will be automatically accounted for during design compile without incurring additional delay in the clock path.

The two-port SRAM can be clocked on the rising edge or falling edge of WCLK and RCLK.

If negative-edge RAM and FIFO clocking is selected for memory macros, clock edge inversion management (bubble pushing) is automatically used within the Fusion development tools, without performance penalty.

#### **Modes of Operation**

There are two read modes and one write mode:

- Read Nonpipelined (synchronous—one clock edge): In the standard read mode, new data is driven onto the RD bus in the same clock cycle following RA and REN valid. The read address is registered on the read port clock active edge and data appears at RD after the RAM access time. Setting PIPE to OFF enables this mode.
- Read Pipelined (synchronous—two clock edges):
   The pipelined mode incurs an additional clock delay from the address to the data but enables operation at a much higher frequency. The read address is registered on the read port active clock edge, and the read data is registered and appears at RD after the second read clock edge. Setting PIPE to ON enables this mode.
- Write (synchronous—one clock edge): On the write clock active edge, the write data is written into the SRAM at the write address when WEN is high. The setup times of the write address, write enables, and write data are minimal with respect to the write clock. Write and read transfers are described with timing requirements in the "SRAM Characteristics" section on page 2-56 and "FIFO Characteristics" section on page 2-63.

## **RAM Initialization**

Each SRAM block can be individually initialized on power-up by means of the JTAG port using the UJTAG mechanism (refer to the "JTAG IEEE 1532" section on page 2-172 and the *Fusion SRAM/FIFO Blocks* application note). The shift register for a target block can be selected and loaded with the proper bit configuration to enable serial loading. The 4,608 bits of data can be loaded in a single operation.

# SRAM Characteristics Timing Waveforms

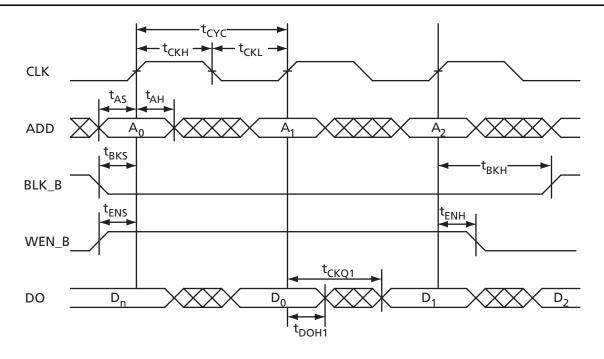


Figure 2-49 • RAM Read for Flow-Through Output

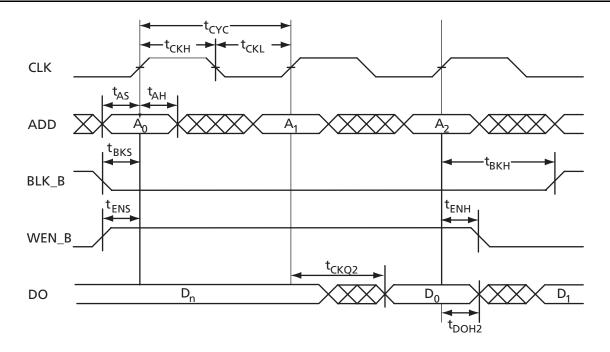


Figure 2-50 • RAM Read for Pipelined Output

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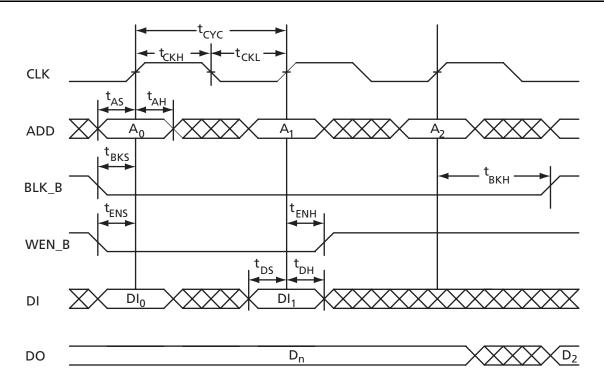


Figure 2-51 • RAM Write, Output Retained (WMODE = 0)

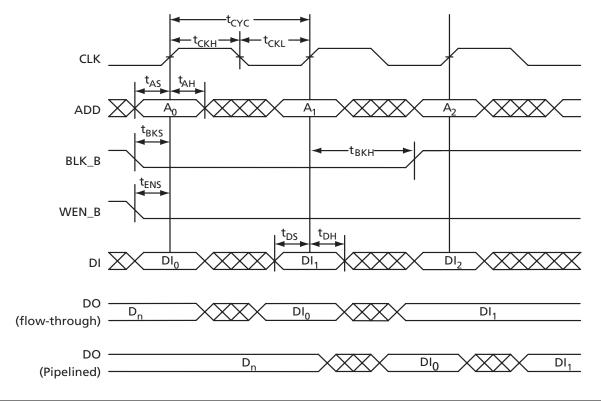


Figure 2-52 • RAM Write, Output as Write Data (WMODE = 1)

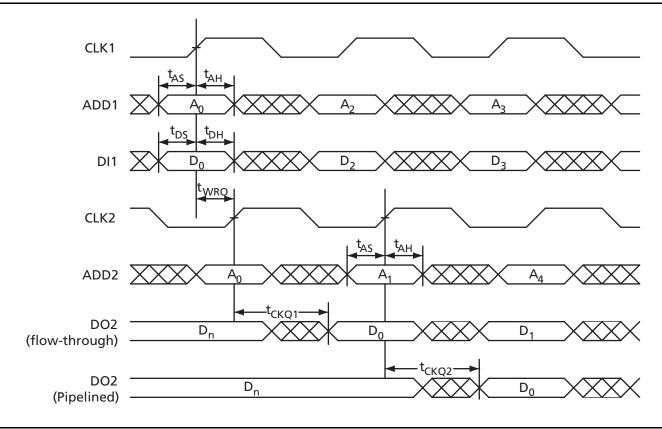


Figure 2-53 • One Port Write/Other Port Read Same

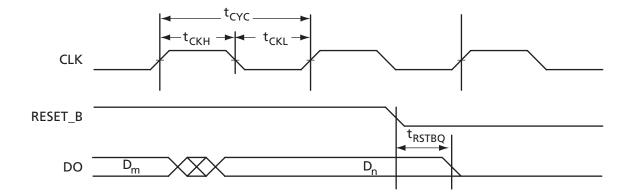


Figure 2-54 • RAM Reset

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## **Timing Characteristics**

Table 2-29 ◆ RAM4K9
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>AS</sub>	Address Setup time	0.25	0.28	0.33	ns
t <sub>AH</sub>	Address Hold time	0.00	0.00	0.00	ns
t <sub>ENS</sub>	REN_B,WEN_B Setup time	0.14	0.16	0.19	ns
t <sub>ENH</sub>	REN_B, WEN_B Hold time	0.10	0.11	0.13	ns
t <sub>BKS</sub>	BLK_B Setup time	0.23	0.27	0.31	ns
t <sub>BKH</sub>	BLK_B Hold time	0.02	0.02	0.02	ns
t <sub>DS</sub>	Input data (DI) Setup time	0.18	0.21	0.25	ns
t <sub>DH</sub>	Input data (DI) Hold time	0.00	0.00	0.00	ns
t <sub>CKQ1</sub>	Clock High to New Data Valid on DO (output retained, WMODE = 0)		2.03	2.39	ns
	Clock High to New Data Valid on DO (flow-through, WMODE = 1)		2.68	3.15	ns
t <sub>CKQ2</sub>	Clock HIGH to New Data Valid on DO (pipelined)	0.89	1.02	1.20	ns
t <sub>RSTBQ</sub>	RESET_B Low to Data Out Low on DO (flow through)	0.92	1.05	1.23	ns
	RESET_B Low to Data Out Low on DO (pipelined)	0.92	1.05	1.23	ns
t <sub>REMRSTB</sub>	RESET_B Removal	0.25	0.28	0.33	ns
t <sub>RECRSTB</sub>	RESET_B Recovery	1.49	1.68	1.98	ns
t <sub>MPWRSTB</sub>	RESET_B Minimum Pulse Width	0.22	0.25	0.29	ns
t <sub>CYC</sub>	Clock Cycle time	1.99	2.26	2.66	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

Table 2-30 • RAM512X18 Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>AS</sub>	Address Setup time	0.25	0.28	0.33	ns
t <sub>AH</sub>	Address Hold time	0.00	0.00	0.00	ns
t <sub>ENS</sub>	REN_B,WEN_B Setup time	0.18	0.20	0.24	ns
t <sub>ENH</sub>	REB_B, WEN_B Hold time	0.06	0.07	0.08	ns
t <sub>DS</sub>	Input data (DI) Setup time	0.18	0.21	0.25	ns
t <sub>DH</sub>	Input data (DI) Hold time		0.00	0.00	ns
t <sub>CKQ1</sub>	Clock High to New Data Valid on DO (output retained, WMODE = 0)		2.46	2.89	ns
t <sub>CKQ2</sub>	Clock High to New Data Valid on DO (pipelined)		1.02	1.20	ns
t <sub>RSTBQ</sub>	RESET_B Low to Data Out Low on DO (flow through)		1.05	1.23	ns
	RESET_B Low to Data Out Low on DO (pipelined)		1.05	1.23	ns
t <sub>REMRSTB</sub>	RESET_B Removal		0.28	0.33	ns
t <sub>RECRSTB</sub>	RESET_B Recovery	1.49	1.68	1.98	ns
t <sub>MPWRSTB</sub>	RESET_B Minimum Pulse Width	0.22	0.25	0.29	ns
t <sub>CYC</sub>	Clock Cycle time	1.99	2.26	2.66	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# FIFO4K18 Description

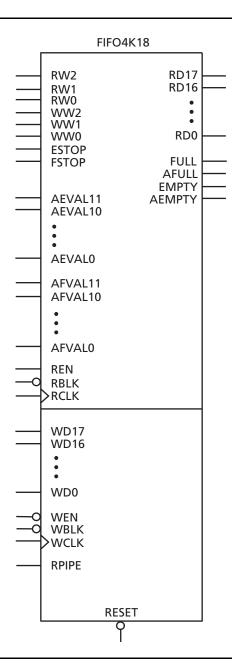


Figure 2-55 • FIFO4KX18

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The following signals are used to configure the FIFO4K18 memory element:

#### WW and RW

These signals enable the FIFO to be configured in one of the five allowable aspect ratios (Table 2-31).

Table 2-31 • Aspect Ratio Settings for WW[2:0]

WW2, WW1, WW0	RW2, RW1, RW0	D×W
000	000	4k <b>×</b> 1
001	001	2k <b>×</b> 2
010	010	1k <b>×</b> 4
011	011	512 <b>×</b> 9
100	100	256×18
101, 110, 111	101, 110, 111	Reserved

#### **WBLK and RBLK**

These signals are active low and will enable the respective ports when low. When the RBLK signal is high, the corresponding port's outputs hold the previous value.

#### **WEN and REN**

Read and write enables. WEN is active low and REN is active high by default. These signals can be configured as active high or low.

## **WCLK and RCLK**

These are the clock signals for the synchronous read and write operations. These can be driven independently or with the same driver.

#### **RPIPE**

This signal is used to specify pipelined read on the output. A low on RPIPE indicates a nonpipelined read and the data appears on the output in the same clock cycle. A high indicates a pipelined read and data appears on the output in the next clock cycle.

#### RESET

This active low signal resets the output to zero when asserted. It resets the FIFO counters. It also sets all the RD pins low, the Full and AFULL pins low, and the Empty and AEMPTY pins high (Table 2-32).

Table 2-32 • Input Data Signal Usage for Different Aspect Ratios

DxW	WD/RD Unused
4k×1	WD[17:1], RD[17:1]
2k <b>x</b> 2	WD[17:2], RD[17:2]
1k×4	WD[17:4], RD[17:4]
512 <b>x</b> 9	WD[17:9], RD[17:9]
256×18	-

#### WD

This is the input data bus and is 18 bits wide. Not all 18 bits are valid in all configurations. When a data width less than 18 is specified, unused higher-order signals must be grounded (Table 2-32).

#### RD

This is the output data bus and is 18 bits wide. Not all 18 bits are valid in all configurations. Like the WD bus, highorder bits become unusable if the data width is less than 18. The output data on unused pins is undefined (Table 2-32).

## **ESTOP, FSTOP**

ESTOP is used to stop the FIFO read counter from further counting once the FIFO is empty (i.e., the Empty flag goes high). A high on this signal inhibits the counting.

FSTOP is used to stop the FIFO write counter from further counting once the FIFO is full (i.e., the Full flag goes high). A high on this signal inhibits the counting.

For more information on these signals, refer to the "ESTOP and FSTOP Usage" section on page 2-62.

## **FULL, EMPTY**

When the FIFO is full and no more data can be written, the Full flag asserts high. The Full flag is synchronous to WCLK to inhibit writing immediately upon detection of a full condition and to prevent overflows. Since the write address is compared to a resynchronized (and thus time-delayed) version of the read address, the Full flag will remain asserted until two WCLK active edges after a read operation eliminates the full condition.

When the FIFO is empty and no more data can be read, the Empty flag asserts high. The Empty flag is synchronous to RCLK to inhibit reading immediately upon detection of an empty condition and to prevent underflows. Since the read address is compared to a resynchronized (and thus time delayed) version of the write address, the Empty flag will remain asserted until two RCLK active edges, after a write operation, removes the empty condition.

For more information on these signals, refer to the "FIFO Flag Usage Considerations" section on page 2-62.

#### **AFULL, AEMPTY**

These are programmable flags and will be asserted on the threshold specified by AFVAL and AEVAL, respectively.

When the number of words stored in the FIFO reaches the amount specified by AEVAL while reading, the AEMPTY output will go high. Likewise, when the number of words stored in the FIFO reaches the amount specified by AFVAL while writing, the AFULL output will go high.

#### **AFVAL, AEVAL**

The AEVAL and AFVAL pins are used to specify the almost-empty and almost-full threshold values, respectively. They are 12-bit signals. For more information on these signals, refer to the "FIFO Flag Usage Considerations" section on page 2-62.

#### **ESTOP and FSTOP Usage**

The ESTOP pin is used to stop the read counter from counting any further once the FIFO is empty (i.e., the EMPTY flag goes high). Likewise, the FSTOP pin is used to stop the write counter from counting any further once the FIFO is full (i.e., the Full flag goes high).

The FIFO counters in the Fusion device start the count at 0, reach the maximum depth for the configuration (e.g., 511 for a 512×9 configuration), and then restart at 0. An example application for the ESTOP, where the read counter keeps counting, would be writing to the FIFO once and reading the same content over and over without doing another write.

## **FIFO Flag Usage Considerations**

The AEVAL and AFVAL pins are used to specify the 12-bit AEMPTY and AFULL threshold values, respectively. The FIFO contains separate 12-bit write address (WADDR) and read address (RADDR) counters. WADDR is incremented every time a write operation is performed, and RADDR is incremented every time a read operation is performed. Whenever the difference between WADDR and RADDR is greater than or equal to AFVAL, the AFULL output is asserted. Likewise, whenever the difference between WADDR and RADDR is less than or equal to AEVAL, the AEMPTY output is asserted. To handle different read and write aspect ratios, AFVAL and AEVAL are expressed in terms of total data bits instead of total data words. When users specify AFVAL and AEVAL in terms of read or write words, the SmartGen tool translates them into bit addresses and configures these signals automatically. SmartGen configures the AFULL flag, AFULL, to assert when the write address exceeds the read address by at least a predefined value. In a 2k×8 FIFO, for example, a value of 1,500 for AFVAL means that the AFULL flag will be asserted after a write when the difference between the write address and the read address reaches 1,500 (there have been at least 1500 more writes than reads). It will stay asserted until the difference between the write and read addresses drops below 1,500.

The AEMPTY flag is asserted when the difference between the write address and the read address is less than a predefined value. In the example above, a value of 200 for AEVAL means that the AEMPTY flag will be asserted when a read causes the difference between the write address and the read address to drop to 200. It will stay asserted until that difference rises above 200. Note that the FIFO can be configured with different read and write widths; in this case the AFVAL setting is based on the number of write data entries and the AEVAL setting is based on the number of read data entries. For aspect ratios of 512×9 and 256×18, only 4,096 bits can be addressed by the 12 bits of AFVAL and AEVAL. The number of words must be multiplied by 8 and 16, instead of 9 and 18. The SmartGen tool automatically uses the proper values. To avoid half-words being written or read. which could happen if different read and write aspect ratios are specified, the FIFO will assert Full or Empty as soon as at least a minimum of one word cannot be written or read. For example, if a two-bit word is written and a four-bit word is being read, FIFO will remain in the Empty state when the first word is written. This occurs even if the FIFO is not completely empty, because in this case a complete word cannot be read. The same is applicable in the Full state. If a four-bit word is written and a two-bit word is read, the FIFO is full and one word is read. The FULL flag will remain asserted because a complete word cannot be written at this point.

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# FIFO Characteristics Timing Waveforms

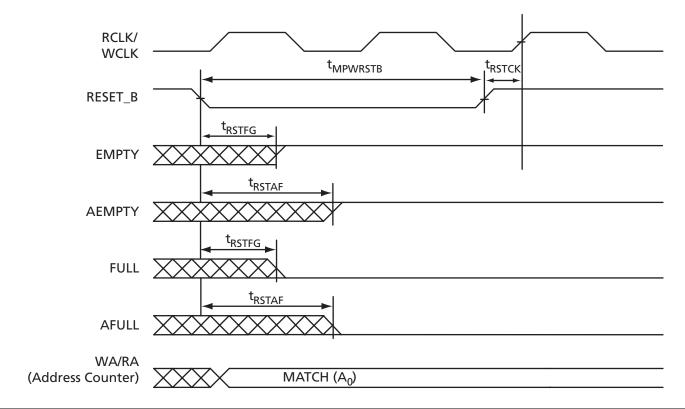


Figure 2-56 • FIFO Reset

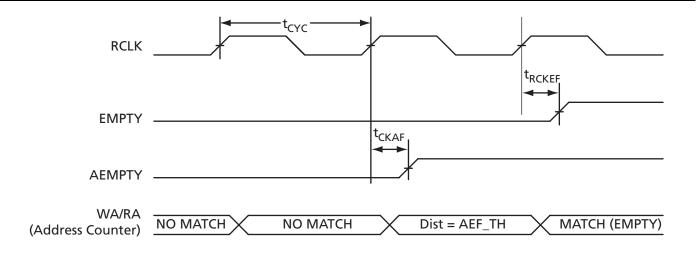


Figure 2-57 • FIFO EMPTY Flag and AEMPTY Flag Assertion

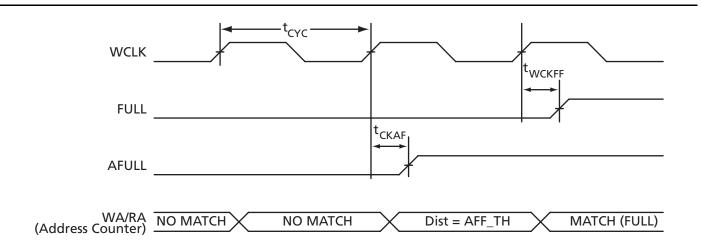


Figure 2-58 • FIFO FULL and AFULL Flag Assertion

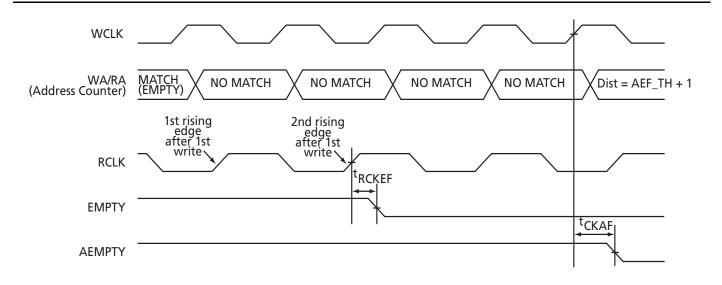


Figure 2-59 • FIFO EMPTY Flag and AEMPTY Flag Deassertion

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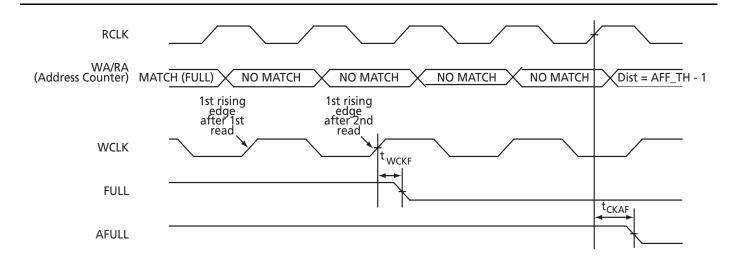


Figure 2-60 • FIFO FULL Flag and AFULL Flag Deassertion

## **Timing Characteristics**

Table 2-33 • FIFO Commercial Case Conditions: T<sub>J</sub> = 70°C, V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>ENS</sub>	REN_B,WEN_B Setup time	0.91	1.04	1.22	ns
t <sub>ENH</sub>	REN_B, WEN_B Hold time	0.00	0.00	0.00	ns
t <sub>BKS</sub>	BLK_B Setup time	0.25	0.29	0.34	ns
t <sub>BKH</sub>	BLK_B Hold time	0.00	0.00	0.00	ns
t <sub>DS</sub>	Input data (DI) Setup time	0.18	0.21	0.25	ns
t <sub>DH</sub>	Input data (DI) Hold time	0.00	0.00	0.00	ns
t <sub>CKQ1</sub>	Clock High to New Data Valid on DO (flow-through)	2.36	2.68	3.15	ns
t <sub>CKQ2</sub>	Clock High to New Data Valid on DO (pipelined)	0.89	1.02	1.20	ns
t <sub>RCKEF</sub>	RCLK High to Empty Flag Valid	1.72	1.96	2.30	ns
t <sub>WCKFF</sub>	WCLK High to Full Flag Valid	1.63	1.86	2.18	ns
t <sub>CKAF</sub>	Clock High to Almost Empty/Full Flag Valid	3.72	4.24	4.99	ns
t <sub>RSTFG</sub>	RESET_B Low to Empty/Full Flag valid	1.69	1.93	2.27	ns
t <sub>RSTAF</sub>	RESET_B Low to Almost-Empty/Full Flag Valid	3.66	4.17	4.90	ns
t <sub>RSTBQ</sub>	RESET_B Low to Data out Low on DO (flow-through)	0.92	1.05	1.23	ns
	RESET_B Low to Data out Low on DO (pipelined)	0.92	1.05	1.23	ns
t <sub>REMRSTB</sub>	RESET_B Removal	0.29	0.33	0.38	ns
t <sub>RECRSTB</sub>	RESET_B Recovery	1.50	1.71	2.01	ns
t <sub>MPWRSTB</sub>	RESET_B Minimum Pulse Width	0.30	0.30	0.30	ns
t <sub>CYC</sub>	Clock Cycle time	2.79	2.79	2.79	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# **Analog Block**

With the Fusion family, Actel has introduced the world's first mixed-mode FPGA solution. Supporting a robust analog peripheral mix, Fusion devices will support a wide variety of applications. It is this Analog Block that separates Fusion from all other FPGA solutions on the market today.

By combining both Flash and high-speed CMOS processes in a single chip, these devices offer the best of both worlds. The high-performance CMOS is used for building RAM resources. These high performance structures support device operation up to 350 MHz. Additionally, the advanced Actel 0.13 µm Flash process incorporates high-voltage transistors and a high-isolation, triple-well process. Both of these are suited for the Flash-based programmable logic and nonvolatile memory structures.

High-voltage transistors support the integration of analog technology in several ways. They aid in noise immunity so that the analog portions of the chip can be better isolated from the digital portions, increasing analog accuracy. Because they support high voltages, Actel Flash FPGAs can be connected directly to high-voltage input signals, eliminating the need for external resistor divider networks, reducing component count, and increasing accuracy. By supporting higher internal voltages, the Actel advanced Flash process enables high-dynamic range on analog circuitry, increasing precision and signal/noise ratio. Actel Flash FPGAs also drive high-voltage outputs, eliminating the need for external level shifters and drivers.

The unique triple-well process enables the integration of high-performance analog features with increased noise immunity and better isolation. By increasing the efficiency of analog design, the triple-well process also enables a smaller overall design size, reducing die size and cost.

The Analog Block consists of the Analog Quad I/O structure, real-time counter (for details refer to the "Real-Time Counter System" section on page 2-31), analog to digital converter (ADC), and analog configuration multiplexer (ACM). All of these elements are combined in the single Analog Block macro, with which the user implements this functionality (Figure 2-61).

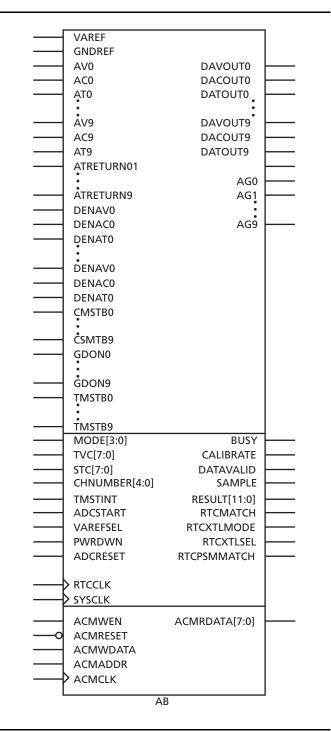


Figure 2-61 • Analog Block Macro

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Table 2-34 describes each pin in the Analog Block. Each function within the Analog Block will be explained in detail in in the following sections.

*Table 2-34* ● Analog Block Pin Description

Signal Name	Number of Bits	Direction	Function	Location of Details
VAREF	1	Input/Output	Voltage reference for ADC; used as either input or output, depending on VREFSEL. Needs to connect a 10 uF capacitor with placement as close as to the VAREF pin.	ADC
GNDREF	1	Input	External ground reference	ADC
MODE[3:0]	4	Input	ADC operating mode	ADC
SYSCLK	1	Input	External system clock	
TVC[7:0]	8	Input	Clock divide control	ADC
STC[7:0]	8	Input	Sample time control	ADC
ADCSTART	1	Input	Start of conversion	ADC
PWRDWN	1	Input	Comparator power-down if 1	ADC
ADCRESET	1	Input	ADC initialize if 1	ADC
BUSY	1	Output	1 – Running conversion	ADC
CALIBRATE	1	Output	1 – Power-up calibration	ADC
DATAVALID	1	Output	1 – Valid conversion result	ADC
RESULT[11:0]	12	Output	Conversion result	ADC
TMSTBINT	1	Input	Internal temp. monitor strobe	ADC
SAMPLE	1	Output	1 – Analog input is sampled	ADC
VAREFSEL	1	Input	0 = Output internal voltage reference (2.56 V) to VAREF	ADC
			1 = Input external voltage reference from VAREF and GNDREF	
CHNUMBER[4:0]	5	Input	Analog input channel select	Input multiplexer
ACMCLK	1	Input	ACM clock	ACM
ACMWEN	1	Input	ACM write enable – active high	ACM
ACMRESET	1	Input	ACM reset – active low	ACM
ACMWDATA[7:0]	8	Input	ACM write data	ACM
ACMRDATA[7:0]	8	Output	ACM read data	ACM
ACMADDR[7:0]	8	Input	ACM address	ACM
CMSTB0 to CMSTB9	10	Input	Current monitor strobe – 1 per quad, active high	Analog Quad
GDON0 to GDON9	10	Input	Control to power MOS – 1 per quad	Analog Quad
TMSTB0 to TMSTB9	10	Input	Temperature monitor strobe – 1 per quad; active high	Analog Quad
DAVOUTO, DACOUTO, DATOUTO to DAVOUT9, DACOUT9, DATOUT9	30	Output	Digital outputs – 3 per quad	Analog Quad
DENAVO, DENACO, DENATO to DENAV9, DENAC9, DENAT9	30	Input	Digital input enables – 3 per quad	Analog Quad
AV0	1	Input	Analog Quad 0	Analog Quad
AC0	1	Input		Analog Quad
AG0	1	Output		Analog Quad

Table 2-34 • Analog Block Pin Description (Continued)

Signal Name	Number of Bits	Direction	Function	Location of Details
AT0	1	Input		Analog Quad
ATRETURN01	1	Input	Temperature monitor return shared by Analog Quads 0 and 1	Analog Quad
AV1	1	Input	Analog Quad 1	Analog Quad
AC1	1	Input		Analog Quad
AG1	1	Output		Analog Quad
AT1	1	Input		Analog Quad
AV2	1	Input	Analog Quad 2	Analog Quad
AC2	1	Input		Analog Quad
AG2	1	Output		Analog Quad
AT2	1	Input		Analog Quad
ATRETURN23	1	Input	Temperature monitor return shared by Analog Quads 2 and 3	Analog Quad
AV3	1	Input	Analog Quad 3	Analog Quad
AC3	1	Input		Analog Quad
AG3	1	Output		Analog Quad
AT3	1	Input		Analog Quad
AV4	1	Input	Analog Quad 4	Analog Quad
AC4	1	Input		Analog Quad
AG4	1	Output		Analog Quad
AT4	1	Input		Analog Quad
ATRETURN45	1	Input	Temperature monitor return shared by Analog Quads 4 and 5	Analog Quad
AV5	1	Input	Analog Quad 5	Analog Quad
AC5	1	Input		Analog Quad
AG5	1	Output		Analog Quad
AT5	1	Input		Analog Quad
AV6	1	Input	Analog Quad 6	Analog Quad
AC6	1	Input		Analog Quad
AG6	1	Output		Analog Quad
AT6	1	Input		Analog Quad
ATRETURN67	1	Input	Temperature monitor return shared by Analog Quads 6 and 7	Analog Quad
AV7	1	Input	Analog Quad 7	Analog Quad
AC7	1	Input		Analog Quad
AG7	1	Output		Analog Quad
AT7	1	Input		Analog Quad
AV8	1	Input	Analog Quad 8	Analog Quad
AC8	1	Input		Analog Quad
AG8	1	Output		Analog Quad
AT8	1	Input		Analog Quad

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Table 2-34 ●	Analog	<b>Block Pin</b>	Description	(Continued)
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Signal Name	Number of Bits	Direction	Function	Location of Details
ATRETURN89	1	Input	Temperature monitor return shared by Analog Quads 8 and 9	Analog Quad
AV9	1	Input	Analog Quad 9	Analog Quad
AC9	1	Input		Analog Quad
AG9	1	Output		Analog Quad
AT9	1	Input		Analog Quad
RTCMATCH	1	Output	MATCH	RTC
RTCPSMMATCH	1	Output	MATCH connected to VRPSM	RTC
RTCXTLMODE[1:0]	2	Output	Drives XTLOSC RTCMODE[1:0] pins	RTC
RTCXTLSEL	1	Output	Drives XTLOSC MODESEL pin	RTC
RTCCLK	1	Input	RTC clock input	RTC

## **Analog Quad**

With the Fusion family, Actel introduces the Analog Quad, shown in Figure 2-62 on page 2-70, as the basic analog I/O structure. The Analog Quad is a four-channel system used to precondition a set of analog signals before sending to the ADC for conversion into a digital signal. In order to maximize the usefulness of the Analog Quad, the analog input signals may also be configured as LVTTL digital input signals. The Analog Quad is divided into four sections.

The first section is called the Voltage Monitor Block and its input pin is named AV. It contains a 2-channel analog multiplexer which allows an incoming analog signal to be routed directly to the ADC or allows the signal to be routed to a pre-scaler circuit before being sent to the ADC. The pre-scaler can be configured to accept analog signals between –12 V and 0, or between 0 and +12 V. The pre-scaler circuit scales the voltage applied to the ADC input pad such that it is compatible with the ADC input voltage range. The AV pin may also be used as a digital input pin.

The second section of the Analog Quad is called the Current Monitor Block. Its input pin is named AC. The Current Monitor Block contains all the same functions as the Voltage Monitor Block with one addition, which is a current monitoring function. A small external current sensing resistor (typically less than 1  $\Omega$ ) is connected between the AV and AC pins and is in series with a power source. The Current Monitor Block contains a current monitor circuit that converts the current through the external resistor to a voltage which can then be read using the ADC.

The third part of the Analog Quad is called the Gate Driver Block and its output pin is named AG. This section is used to drive an external FET. There are two modes available: a high current drive mode and a current source control mode. Both negative and positive voltage polarities are available and in the current source control mode, four different current levels are available.

The fourth section of the Analog Quad is called the Temperature Monitor Block and its input pin name is AT. This block is similar to the Voltage Monitor Block except that it has an additional function: it can be used to monitor the temperature of an external diode connected transistor. It has a modified pre-scaler and is limited to positive voltages only.

The Analog Quad can be configured during design time by Actel Libero IDE; however, the Analog Configuration MUX (ACM) can be used to change the parameters of any of these I/Os during runtime. This type of change is referred to as a context switch. The Analog Quad is a modular structure that is replicated to generate the analog I/O resources. Each Fusion device supports between 5 and 10 Analog Quads.

The analog pads are numbered to clearly identify both the type of pad (voltage, current, gate driver, or temperature pad) and its corresponding Analog Quad (AV0, AC0, AG0, AT0, AV1, ..., AC9, AG9, and AT9). There are three types of input pads (AVx, ACx, and ATx) and one type of analog output pad (AGx). Since there can be up to 10 Analog Quads on a device, there can be a maximum of 30 analog input pads and 10 analog out pads.

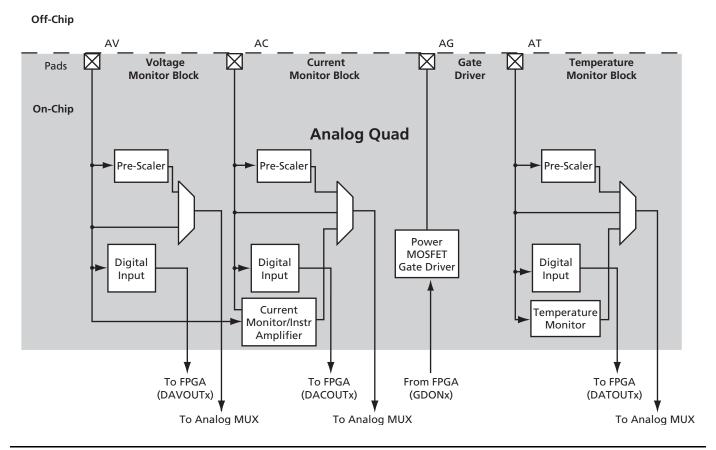


Figure 2-62 • Analog Quad

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## **Voltage Monitor**

The Fusion Analog Quad offers a robust set of voltage monitoring capabilities unique in the FPGA industry. The Analog Quad is comprised of three analog input pads—Analog Voltage (AV), Analog Current (AC), and Analog Temperature (AT)—and a single gate driver output pad, Analog Gate (AG). There are many common characteristics among the analog input pads. Each analog input can be configured to connect directly to the

input MUX of the ADC. When configured in this manner (Figure 2-63), there will be no prescaling of the input signal. Care must be taken in this mode not to drive the ADC into saturation by applying an input voltage greater than the reference voltage. The internal reference voltage of the ADC is 2.56 V. Optionally, an external reference can be supplied by the user. The external reference can be a maximum of 3.3 V DC.

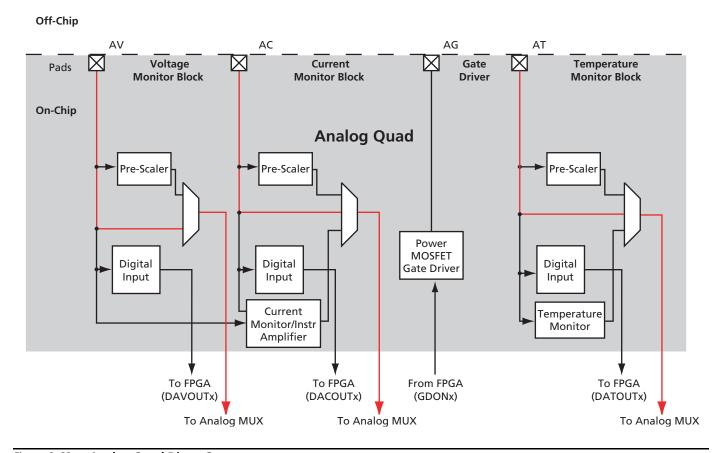


Figure 2-63 • Analog Quad Direct Connect

The Analog Quad inputs are tolerant up to 12 V  $\pm$  10%. The Analog Quad offers a wide variety of prescaling options to enable the ADC to resolve the input signals. Figure 2-64 shows the path through the Analog Quad for a signal that is to be prescaled prior to conversion. The ADC internal reference voltage and the pre-scaler factors were selected to make both prescaling and postscaling of the signals easy, binary calculations (refer to Table 2-45 on page 2-93 for details). When an analog input pad is configured with a pre-scaler, there will be a 1 M $\Omega$  resistor to ground. This occurs even when the device is in power down mode. On low power standby or sleep mode (V<sub>CC</sub> is OFF, V<sub>CC33A</sub> is ON; V<sub>CCI</sub> is ON) or when the resource is not used, Analog inputs are pulled-down to ground through a

1 M $\Omega$  resistor. The gate driver output is floating (or tristated), and there is no extra current on V<sub>CC33A</sub>.

These scaling factors hold true whether the particular pad is configured to accept a positive or negative voltage. Note that while the AV and AC pads support the same prescaling factors, the AT pad supports a reduced set of prescaling factors and support positive voltages only.

Typical scaling factors are given in Table 2-45 on page 2-93, and the gain error (which contributes to the minimum and maximum) is in Table 2-40 on page 2-86.

Each I/O will draw power when connected to power (3 mA at 3 V).

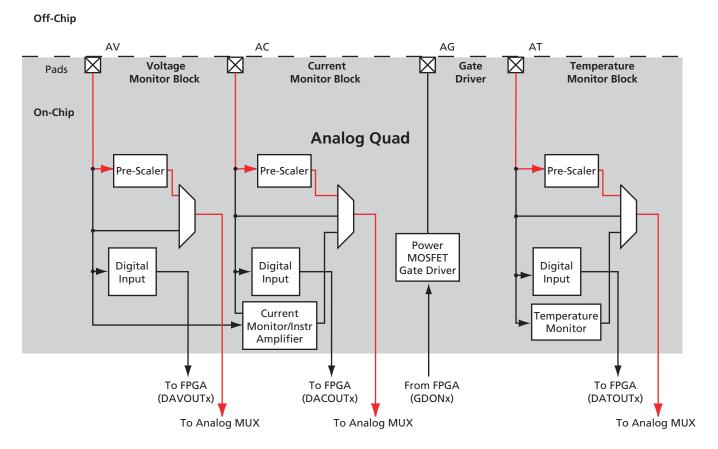


Figure 2-64 • Analog Quad Pre-Scaler Input Configuration

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## **Direct Digital Input**

The AV, AC, and AT pads can also be configured as high voltage digital inputs (Figure 2-65). As these pads are 12 V tolerant, the digital input can also be up to 12 V. However, the frequency at which these pads can operate is limited to 10 MHz.

To enable one of these analog input pads to operate as a digital input, its corresponding Digital Input enable (DENAxy) pin on the Analog Block must be pulled high, where x is either V, C, or T (for AV, AC, or AT pads

respectively) and y is 0 to 9, corresponding to the appropriate Analog Quad.

When the pad is configured as a digital input, this signal will come out of the Analog Block macro on the appropriate DAxOUTy pin, where x represents the pad type (V for AV pad, C for AC pad, or T for AT pad) and y represents the appropriate Analog Quad number. Example: if the AT pad in Analog Quad 5 is configured as a digital input, it will come out on the DATOUT5 pin of the Analog Block macro.

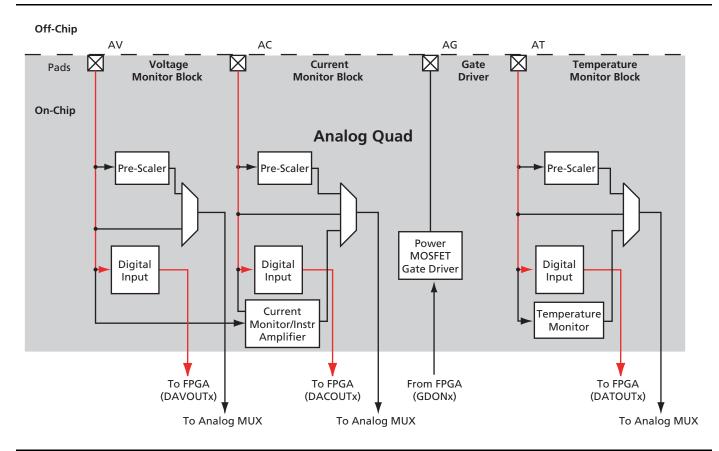


Figure 2-65 • Analog Quad Direct Digital Input Configuration

## **Current Monitor**

The Fusion Analog Quad is an excellent element for voltage and current monitoring applications. In addition to supporting the functionality offered by the AV pad, the AC pad may be configured to monitor current across an external sense resistor (Figure 2-66). To support this current monitor function, the 10x differential amplifier passes the amplified difference between the AV and AC pads to the ADC. The potential on the AV pad MUST be greater than the AC pad in current monitor mode. The amplifier enables the user to use very small resistor

values, thereby limiting any impact on the circuit. This function of the AC pad does not affect the AV pad operation. The current monitor can resolve differences between the AV and AC pads as low as 1 mV.

The current monitor is activated via the Current Monitor Strobe pin (CMST) on the Analog Block macro. There is a CMST pin for each Analog Quad present on the device (CMST0–CMST9).

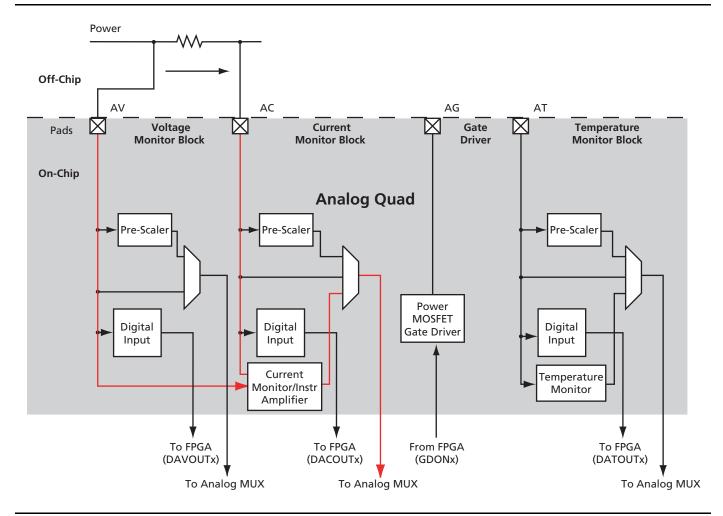


Figure 2-66 • Analog Quad Current Monitor Configuration

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Figure 2-67 illustrates the current monitor operation with an example of the AC pad operating in current monitor mode. In this example, a 10 V supply is passed across a 0.10  $\Omega$  resistor. The difference between the AV and AC pad passes through the 10x amplifier and is then converted by the ADC. In this example, the current drawn from a 10 V supply is measured by the voltage drop it creates across the 0.1  $\Omega$  current sampling resistor. This voltage drop is in turn amplified by ten times by the 10x amplifier and then measured by the ADC. Considering the values shown in Figure 2-67, and making use of Ohm's law, it can be seen that the 1 A current creates a voltage drop across the sampling resistor of 0.1 V, which becomes 1 V after amplification. Thus, the ADC measures a current of 1 A as 1 V, and a current of 0.2 A would therefore be read as 0.2 V by the ADC.

Note that because of the 10x amplification of the voltage difference between these pads, the maximum measurable difference between the AV and AC pads is the ADC reference voltage divided by 10. A larger AV-to-AC voltage drop will result in ADC saturation, i.e., the digital code output by the ADC will stay stuck at the full scale value for the chosen ADC reference voltage. Therefore, the user must select the external sense resistor appropriately. Another important consideration is that the absolute value of the voltage on the AV pin should be greater than or equal to the absolute value of the voltage on the AC pin for the current monitor to function correctly. If voltage available for reading by the ADC the current monitor output voltage available for reading by the ADC will be zero.

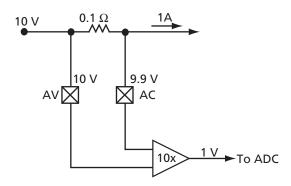


Figure 2-67 • Current Monitor Example

## **Gate Driver**

The Fusion Analog Quad includes a Gate Driver, connected to the quad's AG pin (Figure 2-68). Designed to work with external P-Channel or N-Channel MOSFETs, the Gate driver is a configurable current sink or source and requires an external pull-up or a pull-down resistor. The AG supports 4 selectable gate drive levels: 1  $\mu$ A, 3  $\mu$ A, 10  $\mu$ A, and 30  $\mu$ A (Figure 2-69 on page 2-77). The AG also supports a High Current Drive mode in which it can sink 25 mA. Modeled on an open drain style output, it does not output a voltage level without an appropriate

pull-up or pull-down resistor. If 1 V is forced on the drain, the current sinking/sourcing will exceed the ability of the transistor, and the device could be damaged.

The AG pad is turned on via the corresponding GDONx pin in the Analog Block macro, where x is the number of the corresponding Analog Quad for AG pad to be enabled (GDON0 to GDON9). The maximum AG pad switching frequency is 1.25 MHz.

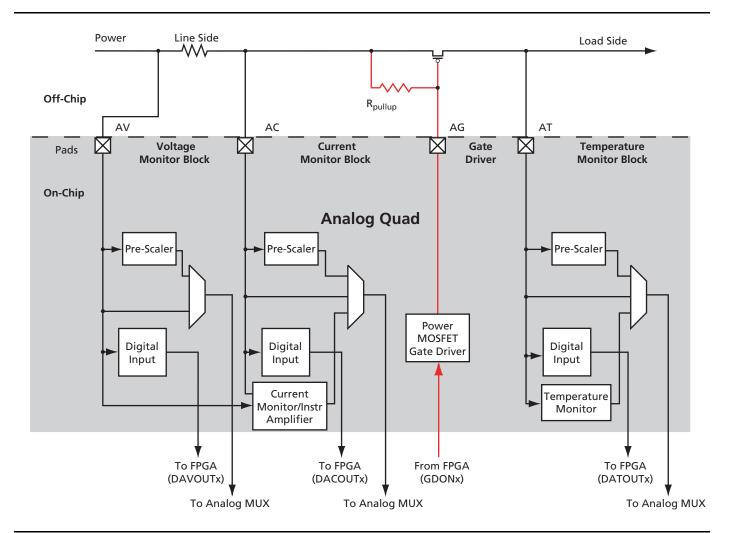


Figure 2-68 • Gate Driver

The gate-to-source voltage (Vgs) of the external MOSFET is limited to the programmable drive current times the external pull-up or pull-down resistor value (EQ 2-1).

$$Vgs \le Ig \times (R_{pullup} \text{ or } R_{pulldown})$$

EQ 2-1

The rate at which the gate voltage of the external MOSFET slews is determined by the current Ig sourced or sunk by the AG pin and the gate to source capacitance CGS of the external MOSFET. As an approximation, the slew rate is given by EQ 2-2.

$$dv/dt = Ig/CGS$$

EQ 2-2

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CGS is not a fixed capacitance but, depending on the circuitry connected to its drain terminal, can vary significantly during the course of a turn-on or turn-off transient. Thus EQ 2-2 on page 2-76 can only be used for a first order estimate of the switching speed of the external MOSFET.

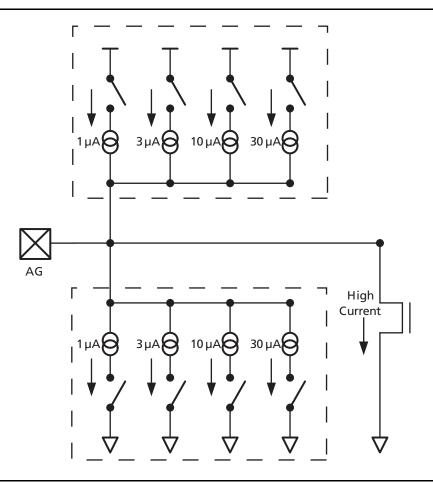


Figure 2-69 • Gate Driver Example

## **Temperature Monitor**

The final pin in the Analog Quad is the Analog Temperature (AT) pin. The AT pin is used to implement an accurate temperature monitor in conjunction with an external diode connected bipolar transistor (Figure 2-70). For improved temperature measurement accuracy, it is important to use the ATRTN pin for the return path of the current sourced by the AT pin. Each ATRTN pin is

shared between two adjacent Analog Quads. Additionally, if not used for temperature monitoring, the AT pin can provide functionality similar to that of the AV pad. However, in this mode only positive voltages may be applied to the AT pin and only two pre-scaler factors are available (16 V and 4 V full scale—refer to Table 2-34 on page 2-67).

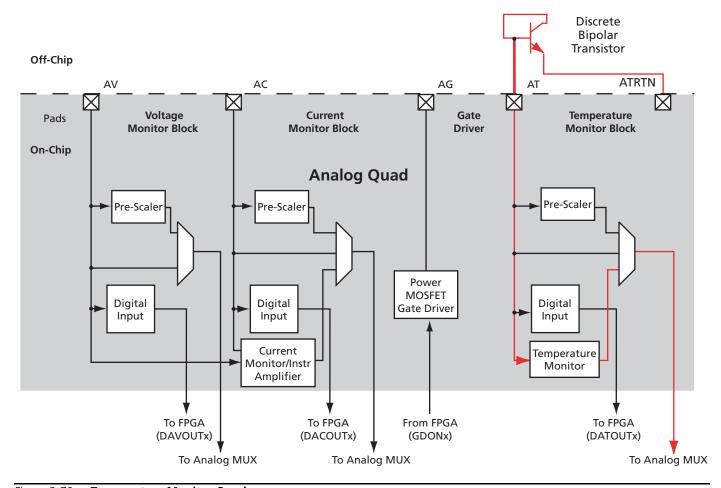


Figure 2-70 • Temperature Monitor Quad

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The well-known temperature dependence of the current versus voltage characteristics of a PN junction form the basis of the temperature measurement scheme implemented in the Fusion devices. Figure 2-71 shows a simplified schematic of this implementation. The diode connected bipolar transistor is used as the temperature sensor. The 12.5x amplifier is a switched-capacitor based design and as such can make pseudo-differential measurements i.e., it multiplies by 12.5 the difference between the voltages that appears across the diode connected bipolar transistor with the 90  $\mu$ A current source switched in (diode current = 100  $\mu$ A) and when it is switched out (diode current = 10  $\mu$ A). The voltage applied to the ADC is then given in EQ 2-3.

$$V_{ADC} = 12.5[(nkT/q) \text{ in } (100 \mu\text{A}/10 \mu\text{A})] = 250 \times 10^{-3} \times T$$

$$EQ 2-3$$

where

n = Ideality factor of the diode connected transistor.
 It is typically 1.008 for the Actel recommended transistor type 2N3904. It does vary from transistor to transistor even of the same type and so for very accurate results calibration is needed.

 $k = 1.3806 \times 10^{-23} \text{ J/K}$  is the Boltzman constant

q = 1.602 x 10<sup>-19</sup> C is the charge of a proton and as such the ADC reads the temperature T in degrees Kelvin

The temperature monitor block is accurate to 5°C. This accuracy is limited by the ideality of the external diode connected bipolar transistor. From the above equation it can be seen that voltage output by the temperature monitor block is about 2.50 mV per degree Kelvin. Thus, it is essential to observe good design practices to reduce noise coupled to the on-board and off-board wiring associated with the diode connected bipolar transistor.

A temperature reading is initiated via the Temperature Monitor Strobe (TMSTB) pin associated with a particular Analog Quad. There are up to 10 TMSTB pins in the device (TMSTB0 – TMSTB9).

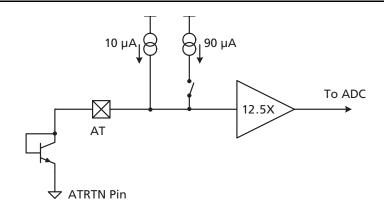


Figure 2-71 • Temperature Monitor Circuit

# **Analog to Digital Converter Block**

At the heart of the Fusion analog system is a programmable Successive Approximation Register (SAR) analog to digital converter (ADC). The ADC can support 8-, 10-, or 12-bit modes of operation. In 12-bit mode, the ADC can resolve 500 ksps. All results are MSB justified in the ADC. The input to the ADC is a large 32:1 analog input multiplexer. A simplified block diagram of the Analog Quads, analog input multiplexer, and ADC is shown in Figure 2-72. The ADC offers multiple self-calibrating modes to ensure consistent high performance at both power-up and during runtime.

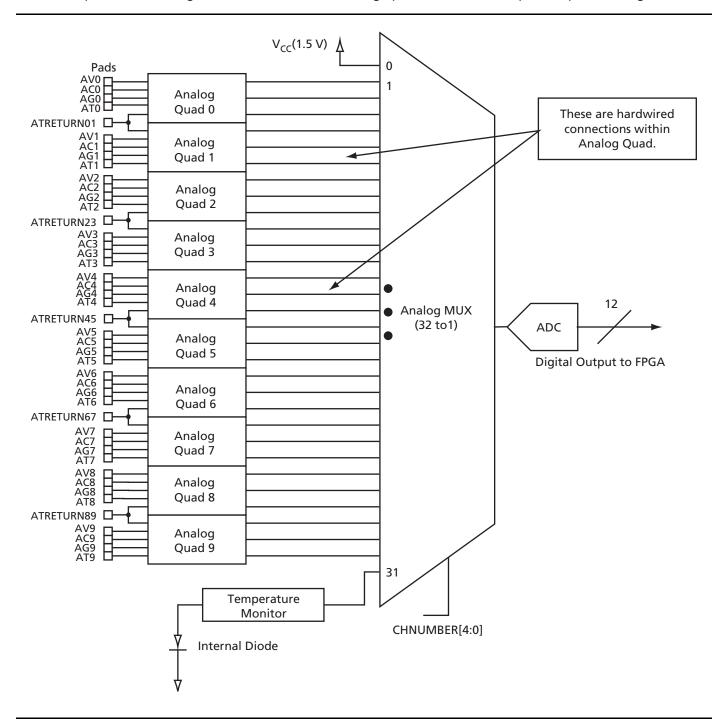


Figure 2-72 • ADC Block Diagram

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## **ADC Input Multiplexer**

At the input to the Fusion ADC is a 32:1 multiplexer. Of the 32 input channels, up to 30 are user definable. Two of these channels are hardwired internally. Channel 31 connects to an internal temperature diode, so that the temperature of the Fusion device itself can be monitored. Channel 0 is wired to the FPGA's 1.5 V V<sub>CC</sub> supply, enabling the Fusion device to monitor its own power supply. Doing this internally makes it unnecessary to use an analog I/O to support these functions. The balance of MUX inputs are connected to Analog Quads (see the "Analog Quad" section on page 2-69). Table 2-35 defines which Analog Quad inputs are associated with which specific analog MUX channel. The number of Analog Quads present is device-dependent; refer to the family list in Table 1 on

page i of this datasheet for the number of quads per device. Regardless of the number of quads populated in a device, the internal connections to both  $V_{CC}$  and internal temperature diode remain on Channels 0 and 31 respectively. In order to sample the internal temperature monitor, it must be strobed (similar to the AT pads). The TMSTBINT pin on the Analog Block macro is the control for strobing the internal temperature measurement diode.

To determine which channel is selected for conversion, there is a 5-pin interface on the Analog Block, CHNUMBER[4:0], defined in Table 2-36 on page 2-82. Table 2-35 shows the correlation between the analog MUX input channels and the analog input pins.

Table 2-35 • Analog MUX Channels

Analog MUX Channel	Signal	Analog Quad Number
0	Vcc_analog	
1	AV0	Analog Quad 0
2	AC0	
3	AT0	
4	AV1	Analog Quad 1
5	AC1	
6	AT1	
7	AV2	Analog Quad 2
8	AC2	
9	AT2	
10	AV3	Analog Quad 3
11	AC3	
12	AT3	
13	AV4	Analog Quad 4
14	AC4	
15	AT4	
16	AV5	Analog Quad 5
17	AC5	
18	AT5	
19	AV6	Analog Quad 6
20	AC6	
21	AT6	
22	AV7	Analog Quad 7
23	AC7	
24	AT7	
25	AV8	Analog Quad 8
26	AC8	

Table 2-35 • Analog MUX Channels (Continued)

Analog MUX Channel	Signal	Analog Quad Number
27	AT8	
28	AV9	Analog Quad 9
29	AC9	
30	AT9	
31	Internal temperature monitor	

## *Table 2-36* • Channel Selection

Channel Number	CHNUMBER[4:0]
0	00000
1	00001
2	00010
3	00011
30	11110
31	11111

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EQ 2-6

## **ADC Description**

The Actel Fusion ADC is a 12-bit SAR ADC. It offers a wide variety of configurations to support many customer use models. It can be programmed to operate in 8-, 10-, or 12-bit modes. This is controlled by MODE[3:0], as defined in Table 2-37.

The conversion time can vary greatly depending on the SYSCLK frequency, ADCCLK frequency (determined by TVC), the STC settings, and the conversion bit-resolution (MODE). See EQ 2-4 through EQ 2-6.

#### where:

t\_sync\_read = Time for latching the input data

t\_sample = Time for sampling the analog signal

t\_distrib = Time for charge distribution

t\_post\_cal = Time for post-calibration

t\_sync\_write = Time for latching the output data

Table 2-37 • MODE[3:0] Truth Table

ADC Mode	Mode[3]	Mode[2]	Mode[1]	Mode[0]
10-bit	0	0	0	0
12-bit	0	0	0	1
8-bit	0	0	1	0
Reserved	0	0	1	1
10-bit without internal power-down after conversion	0	1	0	0
12-bit without internal power-down after conversion	0	1	0	1
8-bit without internal power-down after conversion	0	1	1	0
Reserved	0	1	1	1
10-bit without internal calibration	1	0	0	0
12-bit without internal calibration	1	0	0	1
8-bit without internal calibration	1	0	1	0
Reserved	1	0	1	1
10-bit without internal calibration and without internal power-down after conversion	1	1	0	0
12-bit without internal calibration and without internal power-down after conversion	1	1	0	1
8-bit without internal calibration and without internal power-down after conversion	1	1	1	0
Reserved	1	1	1	1

In addition to the resolution, the ADC offers many different timing configurations. The clock for the ADC is brought into the ADC via the SYSCLK pin on the Analog Block. This base clock can be divided down to suit ADC performance requirements. The clock divider for the ADC clock is TVC[7:0], defined in Table 2-38.

*Table 2-38* • ADC Clock Divider

TVC[7:0]	ADC Clock = SYS	ADC Clock = SYSCLK/(4 × (TVC + 1))			
0	0000000	SYSCLK/4			
1	0000001	SYSCLK/8			
		·			
		·			
		·			
126	01111110	SYSCLK/508			
127	01111111	SYSCLK/5012			
128	1000000	SYSCLK/516			
255	11111111	SYSCLK/1024			

The amount of time allocated for a single sample is also programmable. The clock period defined by 1/ADC clock is the basic unit of measurement for the Sample Time Control (STC). The Sample Time Control table details how the STC can be configured via the STC[7:0] pins on the Analog Block, defined in Table 2-39.

*Table 2-39* • Sample Time Control (STC)

	STC[7:0]	Sample Time = (STC + 2) × ADC_CLK Period
0	00000000	2 ADC clock periods
1	0000001	3 ADC clock periods
254	11111110	256 ADC clock periods
255	11111111	257 ADC clock periods

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The Fusion device has an integrated on-chip 2.56 V reference for the ADC. The value of this reference voltage was chosen to make the pre-scaling and postscaling factors for the pre-scaler blocks change in a binary fashion. However, if desired an external reference voltage of up to 3.3 V can be connected between the VAREF and GNDREF pins. The VAREFSEL control pin is used to select the reference voltage.

- 0 = Output internal voltage reference (2.56 V) to VAREF
- 1 = Input external voltage reference from VAREF and GNDREF

The ADC can be powered down independently of the FPGA core as an additional control or for power saving considerations, via the PWRDWN pin of the Analog Block.

Once the ADC has powered up and been released from reset, ADCRESET, the ADC will initiate a calibration routine designed to provide optimal ADC performance.

The Fusion ADC offers a robust calibration scheme to reduce integrated offset and linearity errors. The offset and linearity errors of the main capacitor array are compensated with an 8-bit calibration capacitor array.

The offset/linearity error calibration is carried out in two ways. First, a power-up calibration is carried out when the ADC comes out of reset. This is initiated by the CALIBRATE output of the Analog Block macro and is a fixed number of ADC\_CLK cycles (3,840 cycles). In this mode, the linearity and offset errors of the capacitors are calibrated. Secondly, to compensate for drift and temperature-dependent effects, every conversion is followed by calibration of either the offset or a bit of the main capacitor array. The calibration procedure takes two additional ADC clock cycles. This ensures that over time and with temperature, the ADC remains consistent.

After both calibration and setting the appropriate configurations as explained above, the ADC is ready for operation. Driving the ADCSTART signal will start a sampling and conversion of a given channel number, which is set using CHNUMBER[4:0]. Status signals SAMPLE and BUSY will show when the ADC is sampling and converting (see Table 2-36 on page 2-82). When the conversion is completed, the DATAVALID pin will go high (BUSY will go low), indicating that the digital result is available on the RESULT[11:0] pins.

# **Analog System Characteristics**

**Table 2-40** • Electrical Specifications

Parameter	Description	Condition	Min.	Тур.	Max.	Units
All Analog	Inputs (Direct Input)	•	•	. <u> </u>		
VINAD	Input Voltage		-0.2		≤ V <sub>REF</sub>	V
CINAD	Input Capacitance	Channel not selected		7		pF
		Channel selected but not sampling		8		pF
		Channel selected and sampling		18		pF
ZINAD	Input Impedance	8-bit mode		4		kΩ
		10-bit mode		4		kΩ
		12-bit mode		4		kΩ
All Analog	Inputs (Using Pre-Scaler)					
VINAP	Input Voltage <sup>1</sup>		-12		12	V
	Accuracy	Positive DC Inputs		1		%
		Negative DC Inputs		2		%
	Offset			2±0.2% of range		mV
	Bandwidth				100	kHz
ZINAP	Impedance (2, 4, 8, and 12-V ranges)		1			МΩ
	Scaling Factor	Pre-Scaler Modes (Table 2-45 on page 2-93)				
	Settling Time	To 0.1% of final value			10	μs
Current Mo	onitor (Potential on the AV	Pad Must be Greater Than the AC	Pad)			
VRSM <sup>2</sup>	Maximum Differential Input				V <sub>REFADC</sub> /10	mV
	Resolution		1			mV
	Common Mode Range		-12		12	V
	Gain			10		
CMRR	Common mode rejection ratio	DC – 1 kHz		60		dB
		1 kHz – 10 kHz		50		dB
		> 10 kHz		30		dB
	Pole			100		kHz
TMPWC	Strobe	Minimum Pulse Width (High and Low)	10			μs
VOFFC	Offset Inaccuracy		-2-(0.05 * (AV- AC))		2 + (0.05 * (AV–AC))	mv

## Notes:

- 1. The input voltage range for the Temperature Monitor Block Pre-Scaler is 0 to 14 V.
- 2. VRSM is the maximum voltage drop across the current sense resistor.
- 3. Analog inputs used as digital inputs can tolerate up to 14V (same as analog inputs). There is no reliability concern on digital inputs as long as VIND does not exceed this maximum input voltage.
- 4. VIND is limited to AVDD+0.2 to allow reaching 10Mhz input frequency.

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**Table 2-40 • Electrical Specifications** 

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Temperatu	re Monitor (Can be Used fo	r Monitoring Positive Voltage Only	<u>()</u>			•
	Resolution			1		°C
	Accuracy			3		°C
TMPWT	Strobe	Minimum Pulse Width (High and Low)	10			μs
Analog Inp	ut as a Digital Input					•
VIND <sup>3, 4</sup>	Input Voltage		-0.2		AVDD + 0.2	V
VHYSDIN	Hysteresis			0.3		V
VIHDIN	Input High			1.2		V
VILDIN	Input Low			0.9		V
VMPWDIN	Minimum Pulse Width		50			ns
VFDIN	Maximum Frequency				10	MHz
ISTBDIN	Sleep Current				20	nA
IDYNDIN	Dynamic Current				20	μΑ
tINDIN	Input Delay			10		ns
Analog Out	tput Pad (G Pad)		•	•	•	•
VG	Voltage Range		-12		12	V
IG	Minimum Output Current Drive	High Current Mode at 1.0 V		25		mA
		Low Current Mode—1 µA		1		μΑ
		Low Current Mode—3 μA		3		μΑ
		Low Current Mode—10 μA		10		μΑ
		Low Current Mode—30 μA		30		μΑ
IOFFG	Maximum Off Current			100		nA

#### Notes:

- 1. The input voltage range for the Temperature Monitor Block Pre-Scaler is 0 to 14 V.
- 2. VRSM is the maximum voltage drop across the current sense resistor.
- 3. Analog inputs used as digital inputs can tolerate up to 14V (same as analog inputs). There is no reliability concern on digital inputs as long as VIND does not exceed this maximum input voltage.
- 4. VIND is limited to AVDD+0.2 to allow reaching 10Mhz input frequency.

**Table 2-41** • ADC Characteristics in Direct Input Mode

Parameter	Description	Condition	Min.	Тур.	Max.	Units
VREFADC	Reference Voltage	Internal Reference		2.56		V
		External Reference	2.527		V <sub>CC33A</sub> + 0.05	V
DC Accuracy	•	•				
TUE	Total Unadjusted Error (external reference)	8-bit mode		0.1186		LSB
		10-bit mode		0.8112		LSB
		12-bit mode		2.4112		LSB
INL	Integral Non-linearity (external reference)	8-bit mode		0.2		LSB
		10-bit mode		0.35		LSB
		12-bit mode		1.75		LSB
DNL	Differential Non-linearity (external reference)	8-bit mode		0.2		LSB
	(No Missing Codes)	10-bit mode		0.6		LSB
		12-bit mode		2.5		LSB
	Offset Error (external reference)	8-bit mode		0.01		LSB
		10-bit mode		0.156		LSB
		12-bit mode		0.125		LSB
	Gain Error (external reference)	8-bit mode		0.5		LSB
		10-bit mode		2.26		LSB
		12-bit mode		3.6		LSB
Conversion Ra	ate		•	•		
	Conversion Time	8-bit mode	1.67			μs
		10-bit mode	1.82			μs
		12-bit mode	2			μs
	Sample Rate <sup>1</sup>	8-bit mode			600	ksps
		10-bit mode			550	ksps
		12-bit mode			500	ksps

## Notes:

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<sup>1.</sup> The Sample Rate is time-shared among active analog inputs.

<sup>2.</sup> Internal voltage reference can handle a load up to 100  $\mu$ A.



# **Analog Configuration MUX**

The Analog Configuration MUX (ACM) is the interface between the FPGA, the Analog Block configurations, and the real-time counter. The Actel Libero IDE Tool will generate IPs that will load and configure the Analog Block via the ACM. However, users are not limited to only using the Libero IDE IP. This section provides a detailed description of the ACM's register map, truth tables for proper configuration of the Analog Block and RTC, as well as timing waveforms so users can access and control the ACM directly from their designs.

The Analog Block contains four 8-bit latches per Analog Quad that are initialized through the ACM. These latches

act as configuration bits for Analog Quads. The ACM block runs from the core voltage supply (1.5 V).

Access to the ACM is achieved via 8-bit address and data buses with enables. The pin list is provided in Table 2-34 on page 2-67. The ACM clock speed is limited to a maximum of 10 MHz operation, more than sufficient to handle the low bandwidth requirements of configuring the Analog Block and the RTC (sub-block of the Analog Block).

Table 2-42 decodes the ACM address space and maps it to the corresponding Analog Quad and configuration byte for that quad.

Table 2-42 • ACM Address Decode Table for Analog Quad

ACMADDR [7:0] in Decimal	Name	Description	Associated Peripheral
0	-	-	Analog Quad
1	AQ0	Byte 0	Analog Quad
2	AQ0	Byte 1	Analog Quad
3	AQ0	Byte 2	Analog Quad
4	AQ0	Byte 3	Analog Quad
5	AQ1	Byte 0	Analog Quad
			Analog Quad
36	AQ8	Byte 3	Analog Quad
37	AQ9	Byte 0	Analog Quad
38	AQ9	Byte 1	Analog Quad
39	AQ9	Byte 2	Analog Quad
40	AQ9	Byte3	Analog Quad
41		Undefined	Analog Quad
		Undefined	Analog Quad
		Undefined	Analog Quad
		Undefined	Analog Quad
63		Undefined	RTC
64	COUNTERO	Counter bits 7:0	RTC
65	COUNTER1	Counter bits 15:8	RTC
66	COUNTER2	Counter bits 23:16	RTC
67	COUNTER3	Counter bits 31:24	RTC
68	COUNTER4	Counter bits 39:32	RTC
72	MATCHREG0	Match register bits 7:0	RTC

Table 2-42 • ACM Address Decode Table for Analog Quad (Continued)

ACMADDR [7:0] in Decimal	Name	Description	Associated Peripheral
73	MATCHREG1	Match register bits 15:8	RTC
74	MATCHREG2	Match register bits 23:16	RTC
75	MATCHREG3	Match register bits 31:24	RTC
76	MATCHREG4	Match register bits 39:32	RTC
80	MATCHBITS0	Individual match bits 7:0	RTC
81	MATCHBITS1	Individual match bits 15:8	RTC
82	MATCHBITS2	Individual match bits 23:16	RTC
83	MATCHBITS3	Individual match bits 31:24	RTC
84	MATCHBITS4	Individual match bits 39:32	RTC
88	CTRL_STAT	Control (write) / status (read) register bits 7:0	RTC
89	TEST_REG	Test register(s)	RTC

Note: ACMADDR bytes 1 to 40 pertain to the Analog Quads, while bytes 64 to 89 pertain to the RTC.

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# **ACM Characteristics**<sup>1</sup>

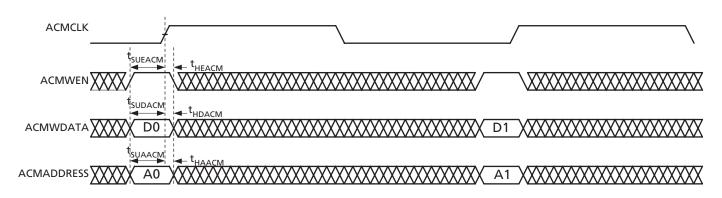


Figure 2-73 • ACM Write Waveform

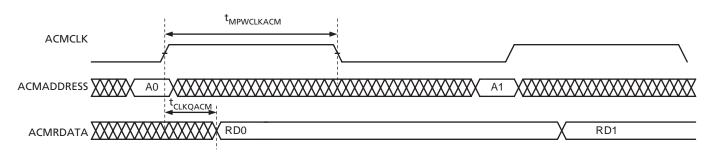


Figure 2-74 • ACM Read Waveform

## **Timing Characteristics**

Table 2-43 • Analog Configuration Multiplexer (ACM) Timing Commercial-Case Conditions: T<sub>J</sub> = 25°C, Typical Case, V<sub>CC</sub> = 1.5 V

Parameter	Description	Min.	Тур.	Max.	Units
t <sub>CLKQACM</sub>	Clock-to-Q of the ACM	10			ns
t <sub>SUDACM</sub>	Data Setup time for the ACM	10			ns
t <sub>HDACM</sub>	Data Hold time for the ACM	0			ns
t <sub>SUAACM</sub>	Address Setup time for the ACM	10			ns
t <sub>HAACM</sub>	Address Hold time for the ACM	0			ns
t <sub>SUEACM</sub>	Enable Setup time for the ACM	10			ns
t <sub>HEACM</sub>	Enable Hold time for the ACM	0			ns
t <sub>MPWARACM</sub>	Asynchronous Reset Minimum Pulse Width for the ACM	10			ns
t <sub>REMARACM</sub>	Asynchronous Reset Removal time for the ACM	10			ns
t <sub>RECARACM</sub>	Asynchronous Reset Recovery time for the ACM	10			ns
t <sub>MPWCLKACM</sub>	Clock Minimum Pulse Width for the ACM	50			ns

<sup>1.</sup> When addressing the RTC addresses (i.e., ACMADDR 64 to 89), there is no timing generator, and the rc\_osc, byte\_en, and aq\_wen signals have no impact.

## **Analog Quad ACM Description**

Table 2-44 maps out the Analog Configuration MUX (ACM) space associated with configuration of the Analog Quads within the Analog Block. Table 2-44 shows the byte assignment within each quad and function of each bit within each byte. Subsequent tables will explain each bit setting and how that corresponds to a particular configuration. After 3.3 V and 1.5 V is applied to Fusion, analog quad configuration registers are loaded with default setting until initialization and configuration state machine changes it to user defined setting.

*Table 2-44* ● Analog Quad ACM Byte Assignment

Byte	Bit	Signal (Bx)	Function	Default Setting
Byte 0	0	B0[0]	Scaling factor control – pre-scaler	Highest voltage Range
(AV)	1	B0[1]		
	2	B0[2]		
	3	B0[3]	Analog MUX select	Pre-Scaler
	4	B0[4]	Current monitor switch	Off
	5	B0[5]	Direct analog input switch	Off
	6	B0[6]	Selects V-pad polarity	Positive
	7	B0[7]	pre-scaler op-amp mode	Power-down
Byte 1	0	B1[0]	Scaling factor control – pre-scaler	Highest voltage range
(AC)	1	B1[1]		
	2	B1[2]		
	3	B1[3]	Analog MUX select	Pre-Scaler
	4	B1[4]		
	5	B1[5]	Direct analog input switch	Off
	6	B1[6]	Selects C-pad polarity	Positive
	7	B1[7]	Pre-scaler op-amp mode	Power-down
Byte 2	0	B2[0]	Chip temperature monitor	Off
(AG)	1	B2[1]	Spare	-
	2	B2[2]	Current drive control	Lowest current
	3	B2[3]		
	4	B2[4]	Spare	-
	5	B2[5]	Spare	-
	6	B2[6]	Selects G-pad polarity	Positive
	7	B2[7]	Selects low/high drive	Low drive
Byte 3	0	B3[0]	Scaling factor control – pre-scaler	Highest voltage range
(AT)	1	B3[1]		
	2	B3[2]		
	3	B3[3]	Analog MUX select	Pre-Scaler
	4	B3[4]		
	5	B3[5]	Direct analog input switch	Off
	6	B3[6]	-	-
	7	B3[7]	Pre-scaler op-amp mode	Power-down

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Table 2-45 details the settings available to control the pre-scaler values of the AV, AC, and AT pins. Note that the AT pin has a reduced number of available pre-scaler values.

Table 2-45 • Pre-Scaler Control Truth Table (AV (x = 0), AC (x = 1), and AT (x = 3))

Control Lines Bx[2:0]	Scaling Factor Pad to ADC Input	LSB for an 8-Bit Conversion (mV)	LSB for a 10-Bit Conversion (mV)	LSB for a 12-Bit Conversion (mV)	Full Scale Voltage	Range Name
000*	0.15625	64	16	4	16.368 V	16 V
001	0.3125	32	8	2	8.184 V	8 V
010*	0.625	16	4	1	4.092 V	4 V
011	1.25	8	2	0.5	2.046 V	2 V
100	2.5	4	1	0.25	1.023 V	1 V
101	5.0	2	0.5	0.125	0.5115 V	0.5 V
110	10.0	1	0.25	0.0625	0.25575 V	0.25 V
111	20.0	0.5	0.125	0.03125	0.127875 V	0.125 V

**Note:** \*These are the only valid ranges for the Temperature Monitor Block Pre-Scaler.

Table 2-46 details the settings available to control the MUX within each of the AV, AC, and AT circuits. This MUX determines whether the signal routed to the ADC is the direct analog input, prescaled signal, or output of either current monitor or temperature monitor blocks.

Table 2-46 • Analog Multiplexer Truth Table (AV (x = 0), AC (x = 1), and AT (x = 3))

Control Lines Bx[4]*	Control Lines Bx[3]	ADC Connected To
0	0	Pre-scaler
0	1	Direct input
1	0	Current amplifier/ Temperature Monitor
1	1	Not valid

**Note:** \*This pin is not available for the Voltage Monitor Block.

Table 2-47 details the settings available to control the Direct Analog Input switch for the AV, AC, and ACT pins.

Table 2-47 • Direct Analog Input Switch Control Truth Table (AV (x = 0), AC (x = 1), and AT (x = 3))

Control Lines Bx[5]	Direct Input Switch
0	Off
1	On

Table 2-48 details the settings available to control the polarity of the signals coming to the AV, AC, and AT pins. Note that the only valid setting for the AT pin is logic 0 to support positive voltages.

Table 2-48 • Voltage Polarity Control Truth Table (AV (x = 0), AC (x = 1), and AT (x = 3)\*)

Control Lines Bx[6]	Input Signal Polarity	
0	Positive	
1	Negative	

**Note:** \*The B3[6] signal for the AT pad should be kept at a logic level 0 to accept only positive voltages.

Table 2-49 details the settings available to either power down or enable the pre-scaler associated with the analog inputs AV, AC, and AT.

Table 2-49 • Pre-Scaler Op-Amp Power-Down Truth Table (AV (x = 0), AC (x = 1), and AT (x = 3))

Control Lines Bx[7]	Pre-Scaler Op-Amp	
0	Power-down	
1	Operational	

Table 2-50 details the settings available to enable the current monitor block associated with the AC pin.

Table 2-50 • Current Monitor Input Switch Control Truth Table (AV (x = 0))

Control Lines B0[4]	Current Monitor Input Switch
0	Off
1	On

Table 2-51 details the settings available to configure the drive strength of the gate drive when not in high drive mode.

Table 2-51 • Low Drive Gate Driver Current Truth Table (AG)

Control Lines B2[3]	Control Lines B2[2]	Current (µA)
0	0	1
0	1	3
1	0	10
1	1	30

Table 2-52 details the settings available to set the polarity of the gate driver (either P-channel or N-Channel type devices).

Table 2-52 • Gate Driver Polarity Truth Table (AG)

Control Lines B2[6]	Gate Driver Polarity	
0	Positive	
1	Negative	

Table 2-53 details the settings available to turn on the Gate Driver and set whether the high drive mode is on or off.

Table 2-53 • Gate Driver Control Truth Table (AG)

Control Lines B2[7]	GDON	Gate Driver
0	0	Off
0	1	Low drive on
1	0	Off
1	1	High drive on

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# User I/Os

#### Introduction

Fusion devices feature a flexible I/O structure, supporting a range of mixed voltages (1.5 V, 1.8 V, 2.5 V, and 3.3 V) through a bank-selectable voltage. Table 2-55, Table 2-56, Table 2-57, and Table 2-58 on page 2-98 show the voltages and the compatible I/O standards. I/Os provide programmable slew rates, drive strengths, weak pull-up, and weak pull-down circuits. 3.3 V PCI and 3.3 V PCI-X are 5 V tolerant. See the "5 V Input Tolerance" section on page 2-107 for possible implementations of 5 V tolerance.

All I/Os are in a known state during power-up and any power-up sequence is allowed without current impact. Refer to the "I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)" section on page 3-4 for more information. On low power standby or sleep mode (V<sub>CC</sub> is OFF, V<sub>CC33A</sub> is ON; V<sub>CCI</sub> is ON) or when the resource is not used, digital inputs are tristated; digital outputs are tristated; digital bibufs (input/output) are tristated.

#### I/O Tile

The Fusion I/O tile provides a flexible, programmable structure for implementing a large number of I/O standards. In addition, the registers available in the I/O tile in selected I/O banks can be used to support high-performance register inputs and outputs, with register enable if desired (Figure 2-75 on page 2-96). The registers can also be used to support the JESD-79C Double Data Rate (DDR) standard within the I/O structure (see the "Double Data Rate (DDR) Support" section on page 2-102 for more information).

As depicted in Figure 2-76 on page 2-101, all I/O registers share one CLR port. The output register and output enable register share one CLK port. Refer to the "I/O Registers" section on page 2-101 for more information.

# I/O Banks and I/O Standards Compatibility

The digital I/Os are grouped into I/O voltage banks. There are three digital I/O banks on the AFS090 and AFS250 devices and four digital I/O banks on the AFS600 and AFS1500 devices. Figure 2-89 on page 2-120 and Figure 2-90 on page 2-121 show the bank configuration by device. The north side of I/O in the AFS600 and AFS1500 devices is comprised of two banks of Actel Pro I/Os. The Actel Pro I/Os support a wide number of voltage referenced I/O standards in addition to the multitude of single-ended and differential I/O standards common throughout all of the Actel digital I/Os. Each I/O voltage bank has dedicated input/output supply and ground voltages (VMV/GNDQ for input buffers and V<sub>CCI</sub>/GND for output buffers). Because of these dedicated supplies, only I/Os with compatible standards can be assigned to the same I/O voltage bank. Table 2-56 and Table 2-57 on page 2-97 show the required voltage compatibility values for each of these voltages.

For more information about I/O and global assignments to I/O banks, refer to the specific pin table of the device in the "Package Pin Assignments" section on page 4-1 and the "User I/O Naming Convention" section on page 2-120.

Each Pro I/O bank is divided into minibanks. Any user I/O in a  $V_{REF}$  minibank (a minibank is the region of scope of a  $V_{REF}$  pin) can be configured as a  $V_{REF}$  pin (Figure 2-75 on page 2-96). Only one  $V_{REF}$  pin is needed to control the entire  $V_{REF}$  minibank. The location and scope of the  $V_{REF}$  minibanks can be determined by the I/O name. For details, see the "User I/O Naming Convention" section on page 2-120.

Table 2-57 on page 2-97 shows the I/O standards supported by the Fusion devices and the corresponding voltage levels.

I/O standards are compatible if:

- Their V<sub>CCI</sub> and VMV values are identical
- If both of the standards need a V<sub>REF</sub>, their V<sub>REF</sub> values must be identical (Pro I/O only)

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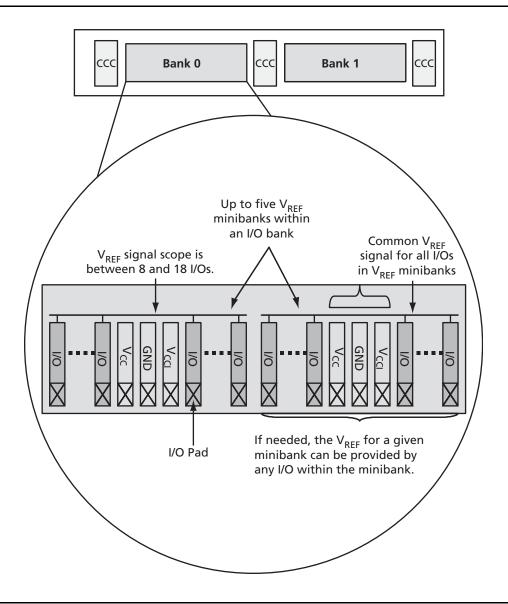


Figure 2-75 • Fusion Pro I/O Bank Detail Showing V<sub>REF</sub> Minibanks (north side of AFS600 and AFS1500)

Table 2-54 • I/O Standard Supported by Bank Type

I/O Bank	Single-Ended I/O Standard	Differential I/O Standard	Voltage-Referenced	Hot-Swap
Hot-Swap	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V/1.8 V/ 1.5 V, LVCMOS2.5/5.0 V	-	-	Yes
LVDS	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V/1.8 V/ 1.5 V, LVCMOS2.5/5.0 V, 3.3 V PCI/3.3 V PCI-X	LVPECL and LVDS	-	-
Pro I/O	LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V/1.8 V/ 1.5 V, LVCMOS2.5/5.0 V, 3.3 V PCI/3.3 V PCI-X		GTL+ 2.5 V / 3.3 V, GTL 2.5 V / 3.3 V, HSTL Class I and II, SSTL2 Class I and II, SSTL3 Class I and II	

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Table 2-55 • I/O Bank Support by Device

I/O Bank	AFS090	AFS250	AFS600	AFS1500
Hot-Swap	N	N	-	-
LVDS, BLVDS, M-LVDS	E, W	E, W	E, W	E, W
Pro I/O	-	-	N	N
Analog Quad	S	S	S	S

**Note:**  $E = East \ side \ of \ the \ device$ 

W = West side of the device N = North side of the deviceS = South side of the device

**Table 2-56** • Fusion V<sub>CCI</sub> Voltages and Compatible Standards

V <sub>CCI</sub> and VMV (typical)	Compatible Standards
3.3 V	LVTTL/LVCMOS 3.3, PCI 3.3, SSTL3 (Class I and II)*, GTL+ 3.3, GTL 3.3*, LVPECL
2.5 V	LVCMOS 2.5, LVCMOS 2.5/5.0, SSTL2 (Class I and II)*, GTL+ 2.5*, GTL 2.5*, LVDS, BLVDS, M-LVDS
1.8 V	LVCMOS 1.8
1.5 V	LVCMOS 1.5, HSTL (Class I)*, HSTL (Class II)*

**Note:** \*I/O standard supported by Pro I/O banks.

**Table 2-57** • Fusion V<sub>REF</sub> Voltages and Compatible Standards\*

V <sub>REF</sub> (typical)	Compatible Standards
1.5 V	SSTL3 (Class I and II)
1.25 V	SSTL2 (Class I and II)
1.0 V	GTL+ 2.5, GTL+ 3.3
0.8 V	GTL 2.5, GTL 3.3
0.75 V	HSTL (Class I), HSTL (Class II)

**Note:** \*I/O standard supported by Pro I/O banks.

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Table 2-58 • Fusion Standard and LVDS I/O Features

I/O Bank Voltage (typical)	Minibank Voltage (typical)	LVTTL/LVCMOS 3.3 V	LVCMOS 2.5 V	LVCMOS 1.8 V	LVCMOS 1.5 V	3.3 V PCI / PCI-X	GTL + (3.3 V)	GTL + (2.5 V)	GTL (3.3 V)	GTL (2.5 V)	HSTL Class I and II (1.5 V)	SSTL2 Class I and II (2.5 V)	SSTL3 Class I and II (3.3 V)	LVDS (2.5 V ± 5%)	LVPECL (3.3 V)
3.3 V	_														
	0.80 V														
	1.00 V														
	1.50 V														
2.5 V	-														
	0.80 V														
	1.00 V														
	1.25 V														
1.8 V	_														
1.5 V	_														
	0.75 V														

**Note:** White box: Allowable I/O standard combinations. Gray box: Illegal I/O standard combinations.

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# Features Supported on Every I/O

Table 2-59 lists all features supported by transmitter/receiver for single-ended and differential I/Os.

*Table 2-59* • Fusion Pro I/O Features

Feature	Description
Single-ended and voltage-referenced transmitter features	Hot insertion in every mode except PCI or 5 V input tolerant (these modes use clamp diodes and do not allow hot insertion)
	Activation of hot insertion (disabling the clamp diode) is selectable by I/Os
	Weak pull-up and pull-down
	Two slew rates
	• Skew between output buffer enable/disable time: 2 ns delay (rising edge) and 0 ns delay (falling edge) (see "Selectable Skew Between Output Buffer Enable/Disable Time" on page 2-112 for more information)
	Five drive strengths
	• 5 V tolerant receiver ("5 V Input Tolerance" section on page 2-107)
	• LVTTL/LVCMOS 3.3 V outputs compatible with 5 V TTL inputs ("5 V Output Tolerance" section on page 2-110)
	High Performance (Table 2-63 on page 2-106)
Single-ended receiver features	Schmitt trigger option
	ESD protection
	• Programmable Delay: 0 ns if bypassed, 0.625 ns with 000 setting, 6.575 ns with 111 setting, 0.85 ns intermediate delay increments (at 25C, 1.5V)
	High performance (Table 2-63 on page 2-106)
	<ul> <li>Separate ground and power planes, GNDQ/VMV, for input buffers only to avoid output-induced noise in the input circuitry</li> </ul>
Voltage-referenced differential receiver features	<ul> <li>Programmable Delay: 0 ns if bypassed, 0.625 ns with 000 setting, 6.575 ns with 111 setting, 0.85 ns intermediate delay increments (at 25°C, 1.5 V)</li> </ul>
	High performance (Table 2-63 on page 2-106)
	<ul> <li>Separate ground and power plane, GNDQ, and VMV pins for input buffers only to avoid output-induced noise in the input circuitry</li> </ul>
CMOS-style LVDS, BLVDS, M-LVDS, or LVPECL transmitter	<ul> <li>Two I/Os and external resistors are used to provide a CMOS style LVDS, BLVDS, M-LVDS, or LVPECL transmitter solution.</li> </ul>
	Activation of hot insertion (disabling the clamp diode) is selectable by I/Os
	Weak pull-up and pull-down
	Fast slew rate
LVDS/LVPECL differential receiver features	ESD protection
	High performance (Table 2-63 on page 2-106)
	<ul> <li>Programmable Delay: 0.625 ns with 000 setting, 6.575 ns with 111 setting, 0.85 ns intermediate delay increments (at 25°C, 1.5 V)</li> </ul>
	Separate input buffer ground and power planes to avoid output-induced noise in the input circuitry

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Table 2-60 • Maximum I/O Frequency for Single-Ended, Voltage-Referenced, and Differential I/Os

Specification	Performance Up To
LVTTL/LVCMOS 3.3 V	200 MHz
LVCMOS 2.5 V	250 MHz
LVCMOS 1.8 V	200 MHz
LVCMOS 1.5 V	130 MHz
PCI	200 MHz
PCI-X	200 MHz
HSTL-I	300 MHz
HSTL-II	300 MHz
SSTL2-I	300 MHz
SSTL2-II	300 MHz
SSTL3-I	300 MHz
SSTL3-II	300 MHz
GTL+ 3.3 V	300 MHz
GTL+ 2.5 V	300 MHz
GTL 3.3 V	300 MHz
GTL 2.5 V	300 MHz
LVDS	350 MHz
BLVDS	200 MHz
M-LVDS	200 MHz
LVPECL	300 MHz

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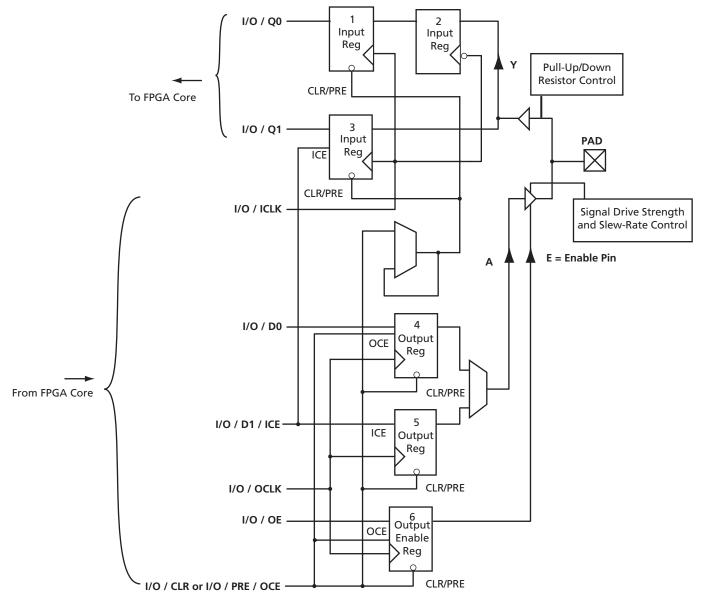


# **I/O Registers**

Each I/O module contains several input, output, and enable registers. Refer to Figure 2-76 for a simplified representation of the I/O block.

The number of input registers is selected by a set of switches (not shown in Figure 2-76) between registers to implement single or differential data transmission to and from the FPGA core. The Designer software sets these switches for the user.

A common CLR/PRE signal is employed by all I/O registers when I/O register combining is used. Input Register 2 does not have a CLR/PRE pin, as this register is used for DDR implementation. The I/O registers combining must satisfy some rules.



**Note:** Fusion I/Os have registers to support DDR functionality (see the "Double Data Rate (DDR) Support" section on page 2-102 for more information).

Figure 2-76 • I/O Block Logical Representation

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# **Double Data Rate (DDR) Support**

Fusion Pro I/Os support 350 MHz DDR inputs and outputs. In DDR mode, new data is present on every transition of the clock signal. Clock and data lines have identical bandwidths and signal integrity requirements, making it very efficient for implementing very high-speed systems.

DDR interfaces can be implemented using HSTL, SSTL, LVDS, and LVPECL I/O standards. In addition, high-speed DDR interfaces can be implemented using LVDS I/O.

## **Input Support for DDR**

The basic structure to support a DDR input is shown in Figure 2-77. Three input registers are used to capture

incoming data, which is presented to the core on each rising edge of the I/O register clock.

Each I/O tile on Fusion devices supports DDR inputs.

# **Output Support for DDR**

The basic DDR output structure is shown in Figure 2-78 on page 2-103. New data is presented to the output every half clock cycle. Note: DDR macros and I/O registers do not require additional routing. The combiner automatically recognizes the DDR macro and pushes its registers to the I/O register area at the edge of the chip. The routing delay from the I/O registers to the I/O buffers is already taken into account in the DDR macro.

Refer to the Actel application note *Using DDR for Fusion Devices* for more information.

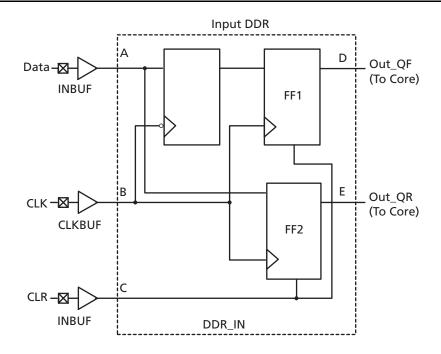


Figure 2-77 • DDR Input Register Support in Fusion Devices

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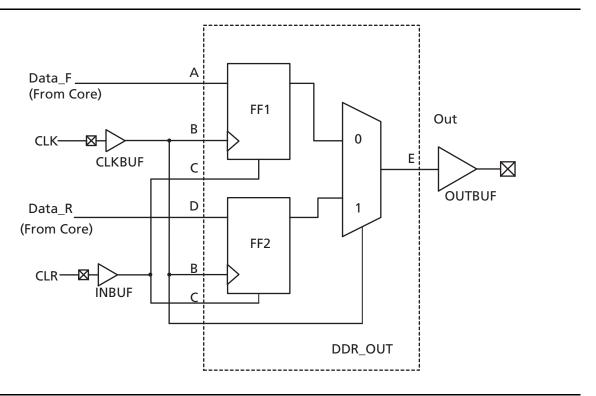


Figure 2-78 • DDR Output Support in Fusion Devices

# **Hot-Swap Support**

Hot-swapping (also called hot plugging) is the operation of hot insertion or hot removal of a card in (or from) a powered-up system. The levels of hot-swap support and examples of related applications are described in Table 2-61. The I/Os also need to be configured in hot insertion mode if hot plugging compliance is required.

Table 2-61 • Levels of Hot-Swap Support

Hot Swapping Level	Description	Power Applied to Device	Bus State	Card Ground Connection	Device Circuitry Connected to Bus Pins	Example of Application with Cards that Contain Fusion Devices	Compliance of Fusion Devices
1	Cold-Swap	No	-	-	_	System and card with Actel FPGA chip are powered down, then the card gets plugged into the system, then the power supplies are turned on for the system but not for the FPGA on the card.	do not have to be set to hot-insertion mode.
2	Hot-Swap while reset	Yes	Held in reset state	Must be made and maintained for 1 msec before, during, and after insertion/ removal	-		
3	Hot-Swap while bus idle	Yes	Held idle (no ongoing I/O processes during insertion/ removal)	Same as Level 2	glitch-free during power- up or power-down	activity on the bus,. It is	with two levels of staging. I/Os have to be set to hot-insertion mode.
4	Hot-Swap on an active bus	Yes	Bus may have active I/O processes ongoing, but device being inserted or removed must be idle	Same as Level 2	Level 3	states set on the bus	with two levels of staging. I/Os have to be set to hot-insertion mode.

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For Fusion devices requiring level 3 and/or level 4 compliance, the board drivers connected to Fusion I/Os need to have 10  $k\Omega$  (or lower) output drive resistance at hot insertion, and 1  $k\Omega$  (or lower) output drive resistance at hot removal. This resistance is the transmitter resistance sending signal towards the Fusion I/O and no additional resistance is needed on the board. If that cannot be assured, three levels of staging can be used to meet level 3 and/or level 4 compliance. Cards with two levels of staging should have the following sequence:

- Grounds
- Powers, I/Os, other pins

# **Cold-Sparing Support**

Cold-sparing means that a subsystem with no power applied (usually a circuit board) is electrically connected to the system that is in operation. This means that all input buffers of the subsystem must present very high input impedance with no power applied so as not to disturb the operating portion of the system.

Fusion devices support cold-sparing for all I/O configurations. Configurations such as PCI standard requiring clamp diodes on the I/Os can also achieve cold-sparing compliance as the clamp diodes get disconnected internally when the supplies are at 0 V.

In designs where Fusion devices are expected to be cold-sparing compliant after supplies are turned off, a discharge resistor, switched resistor, or discharge path needs to be provided from each power supply to ground. If the resistor is chosen, the resistor value must be

calculated based on decoupling capacitance on a given power supply on the board (this decoupling capacitor is in parallel with this resistor). The RC constant should ensure full discharge of supplies before cold-sparing functionality is required. The resistor is necessary to ensure that the power pins get discharged to ground every time there is an interruption of power supply on the device.

# **Electrostatic Discharge (ESD) Protection**

Fusion devices are tested per JEDEC Standard JESD22-A114-B.

Fusion devices contain clamp diodes at every I/O, global, and power pad. Clamp diodes protect all device pads against damage from ESD as well as from excessive voltage transients.

Each I/O has two clamp diodes. One diode has its positive (P) side connected to the pad and its negative (N) side connected to  $V_{CCI}$ . The second diode has its P side connected to GND, and its N side connected to the pad. During operation, these diodes are normally biased in the Off state, except when transient voltage is significantly above  $V_{CCI}$  or below GND levels.

By selecting the appropriate I/O configuration, the diode is turned on or off. Refer to Table 2-62 for more information about the I/O standards and the clamp diode.

The second diode is always connected to the pad, regardless of the I/O configuration selected.

Table 2-62 • Fusion Standard, LVDS, and Standard Plus Hot-Swap I/O Hot-Swap and 5 V Input Tolerance Capabilities

Clamp Diod		Diode	Hot Ins	sertion	5 V Input	Tolerance <sup>1</sup>		
I/O Assignment	Standard Hot- Swap I/O	Standard and LVDS I/O	Standard Hot-Swap I/O	Standard and LVDS I/O	Standard Hot-Swap I/O	Standard and LVDS I/O	Input Buffer	Output Buffer
3.3 V LVTTL/LVCMOS	No	Yes	Yes	No	Yes <sup>1</sup>	Yes <sup>1</sup>	Enabled/	'Disabled
3.3 V PCI, 3.3 V PCI-X	N/A	Yes	N/A	No	N/A	Yes <sup>1</sup>	Enabled/	'Disabled
LVCMOS 2.5 V	No	Yes	Yes	No	Yes <sup>1</sup>	Yes <sup>2</sup>	Enabled/	'Disabled
LVCMOS 2.5 V / 5.0 V	No	Yes	Yes	No	Yes <sup>1</sup>	Yes <sup>2</sup>	Enabled/	'Disabled
LVCMOS 1.8 V	No	Yes	Yes	No	No	No	Enabled/Disabled	
LVCMOS 1.5 V	No	Yes	Yes	No	No	No	Enabled/Disabled	
Differential, LVDS/BLVDS/ M-LVDS/ LVPECL <sup>3</sup>	N/A	Yes	N/A	No	N/A	No	Enabled/Disabled	

#### Notes:

- 1. Can be implemented with an external IDT bus switch, resistor divider, or zener with resistor.
- 2. Can be implemented with an external resistor and an internal clamp diode.
- 3. Bidirectional LVPECL buffers are not supported. I/Os can either be configured as input buffers or output buffers.

Table 2-63 • Fusion Pro I/O Hot-Swap and 5 V Input Tolerance Capabilities

I/O Assignment	Clamp Diode	Hot Insertion	5 V Input Tolerance	Input Buffer Ou	utput Buffer
3.3 V LVTTL/LVCMOS	No	Yes	Yes <sup>1</sup>	Enabled/Disa	abled
3.3 V PCI, 3.3 V PCI-X	Yes	No	Yes <sup>1</sup>	Enabled/Disa	abled
LVCMOS 2.5 V <sup>3</sup>	No	Yes	No	Enabled/Disabled	
LVCMOS 2.5 V / 5.0 V <sup>3</sup>	Yes	No	Yes <sup>2</sup>	Enabled/Disa	abled
LVCMOS 1.8 V	No	Yes	No	Enabled/Disabled	
LVCMOS 1.5 V	No	Yes	No	Enabled/Disabled	
Voltage-Referenced Input Buffer	No	Yes	No	Enabled/Disabled	
Differential, LVDS/BLVDS/M-LVDS/LVPECL <sup>4</sup>	No	Yes	No	Enabled/Disabled	

#### Notes:

- 1. Can be implemented with an external IDT bus switch, resistor divider, or zener with resistor.
- 2. Can be implemented with an external resistor and an internal clamp diode.
- 3. In the SmartGen, FlashROM, Flash Memory System Builder, and Analog System Builder User's Guide, select the LVCMOS5 macro for the LVCMOS 2.5 V / 5.0 V I/O standard or the LVCMOS25 macro for the LVCMOS 2.5 V I/O standard.
- 4. Bidirectional LVPECL buffers are not supported. I/Os can either be configured as input buffers or output buffers.

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# **5 V Input Tolerance**

I/Os can support 5 V input tolerance when LVTTL 3.3 V, LVCMOS 3.3 V, LVCMOS 2.5 V / 5 V, and LVCMOS 2.5 V configurations are used (see Table 2-64 on page 2-110 for more details). There are four recommended solutions (see Figure 2-79 to Figure 2-82 on page 2-110 for details of board and macro setups) to achieve 5 V receiver tolerance. All the solutions meet a common requirement of limiting the voltage at the I/O input to 3.6 V or less. In fact, the I/O absolute maximum voltage rating is 3.6 V, and any voltage above 3.6 V may cause long-term gate oxide failures.

#### **Solution 1**

The board-level design needs to ensure that the reflected waveform at the pad does not exceed the limits provided in Table 3-4 on page 3-3. This is a long-term reliability requirement.

This scheme will also work for a 3.3 V PCI / PCI-X configuration, but the internal diode should not be used for clamping, and the voltage must be limited by the two external resistors as explained below. Relying on the diode clamping would create an excessive pad DC voltage of 3.3 V + 0.7 V = 4 V.

Here are some examples of possible resistor values (based on a simplified simulation model with no line effects, and  $10 \Omega$  transmitter output resistance, where Rtx\_out\_high =  $(V_{CCI} - V_{OH})/I_{OH}$ , Rtx\_out\_low =  $V_{OL}/I_{OL}$ ).

Example 1 (high speed, high current):

Rtx out high = Rtx out low =  $10 \Omega$ 

R1 = 36  $\Omega$  (+/-5%), P(r1)min = 0.069  $\Omega$ 

R2 = 82  $\Omega$  (+/-5%), P(r2)min = 0.158  $\Omega$ 

 $Imax_tx = 5.5 \text{ V} / (82 * 0.95 + 36 * 0.95 + 10) = 45.04 \text{ mA}$ 

 $t_{RISE} = t_{FALL} = 0.85$  ns at C\_pad\_load = 10 pF (includes up to 25% safety margin)

t<sub>RISE</sub> = t<sub>FALL</sub> = 4 ns at C\_pad\_load = 50 pF (includes up to 25% safety margin)

Example 2 (low-medium speed, medium current):

Rtx\_out\_high = Rtx\_out\_low = 10  $\Omega$ 

R1 = 220  $\Omega$  (+/-5%), P(r1)min = 0.018  $\Omega$ 

R2 = 390  $\Omega$  (+/-5%), P(r2)min = 0.032  $\Omega$ 

 $lmax_tx = 5.5 V/(220 * 0.95 + 390 * 0.95 + 10) = 9.17 mA$ 

t<sub>RISE</sub> = t<sub>FALL</sub> = 4 ns at C\_pad\_load = 10 pF (includes up to 25% safety margin)

t<sub>RISE</sub> = t<sub>FALL</sub> = 20 ns at C\_pad\_load = 50 pF (includes up to 25% safety margin)

Other values of resistors are also allowed as long as the resistors are sized appropriately to limit the voltage at the receiving end to 2.5 V < Vin(rx) < 3.6 V\* when the transmitter sends a logic '1'. This range of Vin\_dc(rx) must be assured for any combination of transmitter supply (5 V +/- 0.5 V), transmitter output resistance, and board resistor tolerances.

Temporary overshoots are allowed according to Table 3-4 on page 3-3.

#### Solution 1

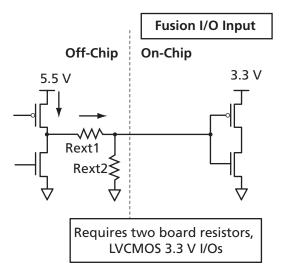


Figure 2-79 • Solution 1

## Solution 2

The board-level design must ensure that the reflected waveform at the pad does not exceed limits provided in Table 3-4 on page 3-3. This is a long-term reliability requirement.

This scheme will also work for a 3.3 V PCI/PCIX configuration, but the internal diode should not be used for clamping, and the voltage must be limited by the external resistors and zener, as shown in Figure 2-80. Relying on the diode clamping would create an excessive pad DC voltage of 3.3 V + 0.7 V = 4 V.

#### Solution 2

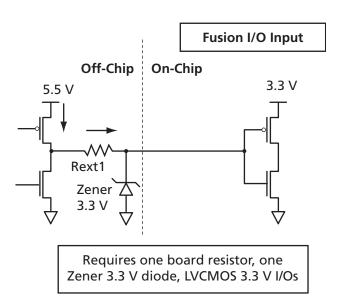


Figure 2-80 • Solution 2

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# **Solution 3**

The board-level design must ensure that the reflected waveform at the pad does not exceed limits provided in Table 3-4 on page 3-3. This is a long-term reliability requirement.

This scheme will also work for a 3.3 V PCI/PCIX configuration, but the internal diode should not be used for clamping, and the voltage must be limited by the bus switch, as shown in Figure 2-81. Relying on the diode clamping would create an excessive pad DC voltage of 3.3 V + 0.7 V = 4 V.

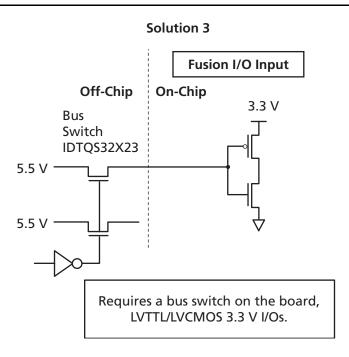


Figure 2-81 • Solution 3

## **Solution 4**

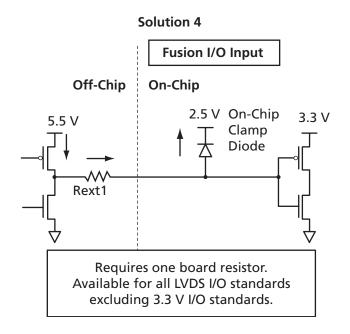


Figure 2-82 • Solution 4

**Table 2-64** • Comparison Table for 5-V-Compliant Receiver Scheme

Scheme	<b>Board Components</b>	Speed	Current Limitations
1	Two resistors	Low to High <sup>1</sup>	Limited by transmitter's drive strength
2	Resistor and Zener 3.3 V	Medium	Limited by transmitter's drive strength
3	Bus switch	High	N/A
4	Minimum resistor value <sup>2</sup> • $R = 47 \Omega$ at $T_J = 70^{\circ}C$ • $R = 150 \Omega$ at $T_J = 85^{\circ}C$ • $R = 420 \Omega$ at $T_J = 100^{\circ}C$	Medium	Maximum diode current at 100% duty cycle, signal constantly at "1" • 52.7 mA at $T_J = 70^{\circ}\text{C}$ / 10-year lifetime • 16.5 mA at $T_J = 85^{\circ}\text{C}$ / 10-year lifetime • 5.9 mA at $T_J = 100^{\circ}\text{C}$ / 10-year lifetime For duty cycles other than 100%, the currents can be increased by a factor = 1/duty cycle Example: 20% duty cycle at 70°C Maximum current = (1/0.2) * 52.7 mA = 5 * 52.7 mA = 263.5 mA

#### Notes:

- 1. Speed and current consumption increase as the board resistance values decrease.
- 2. Resistor values ensure I/O diode long term reliability.

# **5 V Output Tolerance**

Fusion I/Os must be set to 3.3 V LVTTL or 3.3 V LVCMOS mode to reliably drive 5 V TTL receivers. It is also critical that there be NO external I/O pull-up resistor to 5 V, since this resistor would pull the I/O pad voltage beyond the 3.6 V absolute maximum value, and consequently cause damage to the I/O.

When set to 3.3 V LVTTL or 3.3 V LVCMOS mode, Fusion I/Os can directly drive signals into 5 V TTL receivers. In fact,  $V_{OL}$  = 0.4 V and  $V_{OH}$  = 2.4 V in both 3.3 V LVTTL and 3.3 V LVCMOS modes exceed the  $V_{IL}$  = 0.8 V and  $V_{IH}$  = 2 V level requirements of 5 V TTL receivers. Therefore, level '1' and level '0' will be recognized correctly by 5 V TTL receivers.

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# Simultaneous Switching Outputs and Printed Circuit Board Layout

Simultaneously switching outputs (SSO) can produce signal integrity problems on adjacent signals that are not part of SSO bus. Both inductive and capacitive coupling parasitics of bond wires inside packages and of traces on PCB boards will transfer noise from SSO busses onto signals adjacent to those busses. Additionally, SSOs can produce ground bounce noise and  $V_{\rm CCI}$  dip noise. These two noise types are caused by rapidly changing currents through GND and  $V_{\rm CCI}$  package pin inductances during switching activities:

- Ground bounce noise voltage = L (GND) \* di/dt
- V<sub>CCI</sub> dip noise voltage = L (V<sub>CCI</sub>) \* di/dt

Any group of four or more input pins switching on the same clock edge is considered an SSO bus. The shielding should be done both on the board and inside the package unless otherwise described.

In-package shielding can be achieved in several ways; the required shielding will vary depending on whether pins next to SSO bus are LVTTL/LVCMOS inputs, LVTTL/LVCMOS outputs, or GTL/SSTL/HSTL/LVDS/LVPECL inputs and outputs. Board traces in the vicinity of the SSO bus have to be adequately shielded from mutual coupling and inductive noise that can be generated by SSO bus. Also, noise generated by SSO bus needs to be reduced inside the package.

Printed circuit boards (PCB) perform an important function in feeding stable supply voltage to the IC and at the same time maintain signal integrity between devices.

Key issues that need to considered are:

- Power and Ground plane design and decoupling network design
- Transmission Line Reflections and Terminations

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# Selectable Skew Between Output Buffer Enable/Disable Time

The configurable skew block is used to delay the output buffer assertion (enable) without affecting deassertion (disable) time.

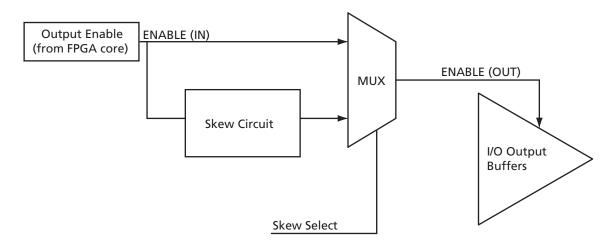


Figure 2-83 • Block Diagram of Output Enable Path

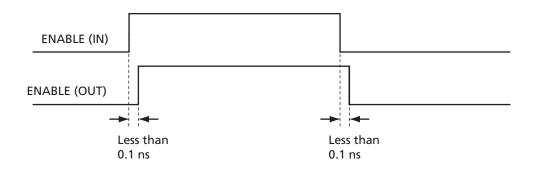


Figure 2-84 • Timing Diagram (Option1: Bypasses Skew Circuit)

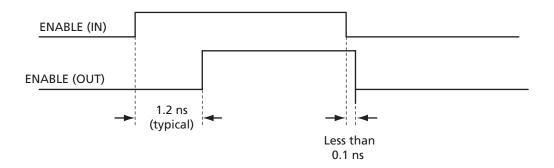


Figure 2-85 • Timing Diagram (Option 2: Enables Skew Circuit)

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At the system level, the skew circuit can be used in applications where transmission activities on bidirectional data lines need to be coordinated. This circuit, when selected, provides a timing margin that can prevent bus contention and subsequent data loss and/or transmitter overstress due to transmitter-to-transmitter current shorts. Figure 2-86 presents an example of the

skew circuit implementation in a bidirectional communication system. Figure 2-87 shows how bus contention is created, and Figure 2-88 on page 2-114 shows how it can be avoided with the skew circuit.

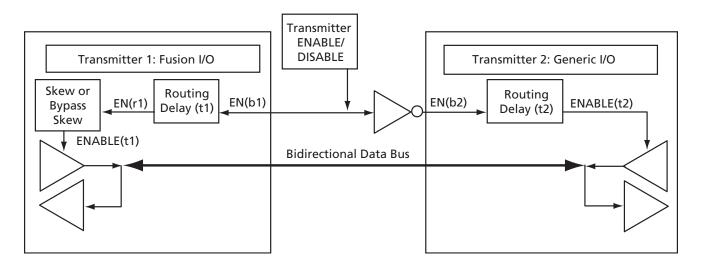


Figure 2-86 • Example of Implementation of Skew Circuits in Bidirectional Transmission Systems Using Fusion Devices

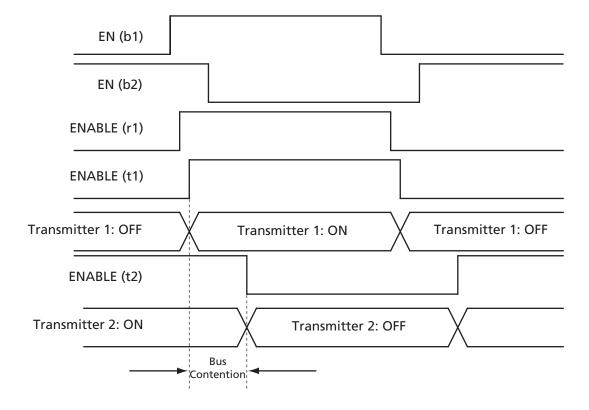


Figure 2-87 • Timing Diagram (Bypasses Skew Circuit)

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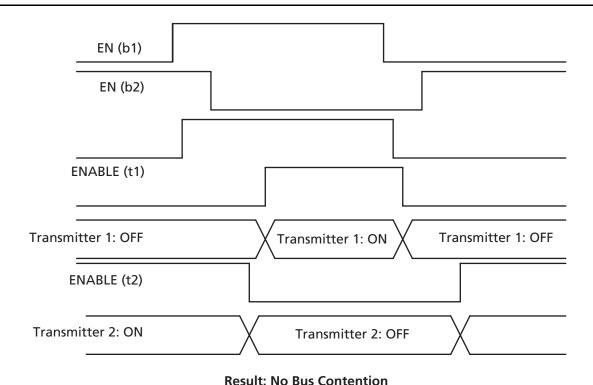


Figure 2-88 • Timing Diagram (with Skew Circuit Selected)

# Weak Pull-Up and Weak Pull-Down Resistors

Fusion devices support optional weak pull-up and pull-down resistors per I/O pin. When the I/O is pulled up, it is connected to the  $V_{CCI}$  of its corresponding I/O bank. When it is pulled-down it is connected to GND. Refer to Table 2-80 on page 2-131 for more information.

# Slew Rate Control and Drive Strength

Fusion devices support output slew rate control: high and low. The Standard hot-swap I/Os do not support slew rate control. The high slew rate option is recommended to minimize the propagation delay. This high-speed option may introduce noise into the system if appropriate signal integrity measures are not adopted. Selecting a low slew rate reduces this kind of noise but adds some delays in the system. Low slew rate is recommended when bus transients are expected. Drive strength should also be selected according to the design requirements and noise immunity of the system.

The output slew rate and multiple drive strength controls are available in LVTTL/LVCMOS 3.3 V, LVCMOS 2.5 V, LVCMOS 2.5 V / 5.0 V input, LVCMOS 1.8 V, and LVCMOS 1.5 V. All other I/O standards have a high output slew rate by default.

For Fusion slew rate and drive strength specifications, refer to the appropriate I/O bank table:

- Fusion hot-swap I/O (Table 2-65 on page 2-115)
- Fusion LVDS I/O (Table 2-66 on page 2-115)
- Fusion Pro I/O (Table 2-67 on page 2-115)

Table 2-69 on page 2-117 lists the default values for the above selectable I/O attributes as well as those that are preset for that I/O standard.

Refer to Table 2-65, Table 2-66, and Table 2-67 on page 2-115 for SLEW and OUT\_DRIVE settings. Table 2-68 on page 2-116 lists the I/O default attributes. Table 2-69 on page 2-117 lists the voltages for the supported I/O standards.

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# Table 2-65 ● Fusion Hot-Swap I/O Standards—OUT\_DRIVE Settings

		OUT_DRIVE (mA)				
I/O Standards	2	4	8			
LVTTL/LVCMOS 3.3 V	✓	✓	✓			
LVCMOS 2.5 V	✓	✓	✓			
LVCMOS 1.8 V	✓	✓	-			
LVCMOS 1.5 V	✓	-	-			

# Table 2-66 • Fusion LVDS I/O Standards—SLEW and OUT\_DRIVE Settings

	OUT_DRIVE (mA)							
I/O Standards	2	4	6	8	12	16	SI	ew
LVTTL/LVCMOS 3.3 V	✓	1	✓	✓	✓	✓	High	Low
LVCMOS 2.5 V	✓	1	✓	1	✓	-	High	Low
LVCMOS 1.8 V	✓	1	✓	✓	-	-	High	Low
LVCMOS 1.5 V	✓	<b>✓</b>	-	-	-	_	High	Low

Table 2-67 • Fusion Pro I/O Standards—SLEW and OUT\_DRIVE Settings

	OUT_DRIVE (mA)								
I/O Standards	2	4	6	8	12	16	24	SI	ew
LVTTL/LVCMOS 3.3 V	✓	✓	✓	1	✓	✓	✓	High	Low
LVCMOS 2.5 V	1	✓	1	✓	✓	✓	✓	High	Low
LVCMOS 2.5 V/5.0 V	1	✓	1	1	✓	✓	✓	High	Low
LVCMOS 1.8 V	1	✓	1	✓	✓	✓	-	High	Low
LVCMOS 1.5 V	<b>√</b>	✓	✓	✓	✓	-	_	High	Low

Table 2-68 • Fusion Pro I/O Default Attributes

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW) (tribuf and bibuf only)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER	IN_DELAY (input only)	IN_DELAY_VAL (input only)	SCHMITT_TRIGGER (input only)	
LVTTL/LVCMOS 3.3 V	Refer to the	Refer to the	Off	None	35pF	_	Off	0	Off	
LVCMOS 2.5 V	following tables for more information:	more information:	Off	None	35 pF	_	Off	0	Off	
LVCMOS 2.5/5.0 V	• Table 2-65 on	<ul> <li>Table 2-65 on page 2-115</li> <li>Table 2-66 on page 2-115</li> </ul>	Off	None	35 pF	ı	Off	0	Off	
LVCMOS 1.8 V	page 2-115		Off	None	35 pF	_	Off	0	Off	
LVCMOS 1.5 V	• Table 2-66 on		Off	None	35 pF	-	Off	0	Off	
PCI (3.3 V)	page 2-115 • Table 2-67 on		Off	None	10 pF	_	Off	0	Off	
PCI-X (3.3 V)	page 2-115	page 2-115	Off	None	10 pF	_	Off	0	Off	
GTL+ (3.3 V)			Off	None	10 pF	_	Off	0	Off	
GTL+ (2.5 V)			Off	None	10 pF	_	Off	0	Off	
GTL (3.3 V)				Off	None	10 pF	_	Off	0	Off
GTL (2.5 V)			Off	None	10 pF	_	Off	0	Off	
HSTL Class I			Off	None	20 pF	-	Off	0	Off	
HSTL Class II			Off	None	20 pF	-	Off	0	Off	
SSTL2 Class I and II			Off	None	30 pF	_	Off	0	Off	
SSTL3 Class I and II			Off	None	30 pF	_	Off	0	Off	
LVDS, BLVDS, M-LVDS			Off	None	0 pF	_	Off	0	Off	
LVPECL			Off	None	0 pF	-	Off	0	Off	

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Table 2-69  $\,\bullet\,$  Fusion Pro I/O Supported Standards and the Corresponding  $V_{REF}$  and  $V_{TT}$  Voltages

I/O Standard	Input/Output Supply Voltage (VMVtyp/V <sub>CCI_TYP</sub> )	Input Reference Voltage (V <sub>REF_TYP</sub> )	Board Termination Voltage (V <sub>TT_TYP</sub> )
LVTTL/LVCMOS 3.3 V	3.30 V	-	-
LVCMOS 2.5 V	2.50 V	_	-
LVCMOS 2.5 V/5.0 V Input	2.50 V	-	-
LVCMOS 1.8 V	1.80 V	-	-
LVCMOS 1.5 V	1.50 V	_	-
PCI 3.3 V	3.30 V	-	-
PCI-X 3.3 V	3.30 V	-	-
GTL+ 3.3 V	3.30 V	1.00 V	1.50 V
GTL+ 2.5 V	2.50 V	1.00 V	1.50 V
GTL 3.3 V	3.30 V	0.80 V	1.20 V
GTL 2.5 V	2.50 V	0.80 V	1.20 V
HSTL Class I	1.50 V	0.75 V	0.75 V
HSTL Class II	1.50 V	0.75 V	0.75 V
SSTL3 Class I	3.30 V	1.50 V	1.50 V
SSTL3 Class II	3.30 V	1.50 V	1.50 V
SSTL2 Class I	2.50 V	1.25 V	1.25 V
SSTL2 Class II	2.50 V	1.25 V	1.25 V
LVDS, BLVDS, M-LVDS	2.50 V	-	-
LVPECL	3.30 V	_	-

# **I/O Software Support**

In the Fusion development software, default settings have been defined for the various I/O standards that are supported. Changes can be made to the default settings via the use of attributes; however, not all I/O attributes are applicable for all I/O standards. Table 2-70 and Table 2-71 list the valid I/O attributes that can be manipulated by the user for each I/O standard.

Single-ended I/O standards in Fusion support up to five different drive strengths.

Table 2-70 • Fusion Standard and LVDS I/O Attributes vs. I/O Standard Applications

	SLEW (output	OUT_DRIVE (output	SKEW (all macros with		OUT_LOAD (output	
I/O Standards	only)	only)	OE)*	RES_PULL	only)	COMBINE_REGISTER
LVTTL/LVCMOS 3.3 V	✓	✓	✓	✓	✓	✓
LVCMOS 2.5 V	✓	✓	✓	✓	✓	✓
LVCMOS 2.5/5.0 V	✓	✓	✓	1	1	✓
LVCMOS 1.8 V	✓	1	✓	1	✓	✓
LVCMOS 1.5 V	✓	1	✓	✓	✓	✓
PCI (3.3 V)			✓		1	✓
PCI-X (3.3 V)	✓		✓		✓	✓
LVDS, BLVDS, M-LVDS			✓			<b>√</b>
LVPECL						✓

**Note:** \*This does not apply to the north I/O bank on AFS090 and AFS250 devices.

Table 2-71 • Fusion Pro I/O Attributes vs. I/O Standard Applications

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW (all macros with OE)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER	IN_DELAY (input only)	IN_DELAY_VAL (input only)	SCHMITT_TRIGGER (input only)	HOT_SWAPPABLE
LVTTL/LVCMOS 3.3 V	<b>√</b>	✓	✓	✓	✓	✓	✓	✓	✓	✓
LVCMOS 2.5 V	✓	✓	✓	✓	✓	✓	✓	✓	✓	1
LVCMOS 2.5/5.0 V	✓	✓	✓	✓	✓	✓	✓	✓	✓	✓
LVCMOS 1.8 V	✓	1	1	1	✓	1	✓	✓	✓	✓
LVCMOS 1.5 V	✓	✓	1	✓	✓	1	✓	✓	✓	✓
PCI (3.3 V)			✓		✓	✓	✓	✓		
PCI-X (3.3 V)	✓		1		✓	1	1	✓		
GTL+ (3.3 V)			1		✓	1	✓	✓		✓
GTL+ (2.5 V)			1		✓	1	✓	✓		✓
GTL (3.3 V)			1		✓	1	✓	✓		✓

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Table 2-71 • Fusion Pro I/O Attributes vs. I/O Standard Applications (Continued)

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW (all macros with OE)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER	IN_DELAY (input only)	IN_DELAY_VAL (input only)	SCHMITT_TRIGGER (input only)	HOT_SWAPPABLE
GTL (2.5 V)			✓		✓	✓	✓	✓		✓
HSTL Class I			✓		✓	✓	✓	✓		✓
HSTL Class II			✓		✓	✓	✓	✓		✓
SSTL2 Class I and II			✓		✓	✓	✓	✓		✓
SSTL3 Class I and II			✓		✓	✓	✓	✓		✓
LVDS, BLVDS, M-LVDS			✓			1	✓	✓		✓
LVPECL	·	·				✓	✓	✓		✓

Table 2-72 lists the default values for the above selectable I/O attributes as well as those that are preset for that I/O standard. See Table 2-65, Table 2-66, and Table 2-67 on page 2-115 for SLEW and OUT\_DRIVE settings.

Table 2-72 • I/O Default Attributes

I/O Standards	SLEW (output only)	OUT_DRIVE (output only)	SKEW) (tribuf and bibuf only)	RES_PULL	OUT_LOAD (output only)	COMBINE_REGISTER
LVTTL/LVCMOS 3.3 V	Refer to the	Refer to the	Off	None	35 pF	-
LVCMOS 2.5 V	following tables for more information:	following tables for more information:	Off	None	35 pF	_
LVCMOS 2.5/5.0 V	• Table 2-65 on		Off	None	35 pF	_
LVCMOS 1.8 V	page 2-115	page 2-115	Off	None	35 pF	-
LVCMOS 1.5 V	• Table 2-66 on	=	Off	None	35 pF	-
PCI (3.3 V)	page 2-115  Table 2-67 on	page 2-115  • Table 2-67 on	Off	None	10 pF	-
PCI-X (3.3 V)	page 2-115	page 2-115	Off	None	10 pF	-
LVDS, BLVDS, M-LVDS			Off	None	-	-
LVPECL			Off	None	_	_

# **User I/O Naming Convention**

Due to the comprehensive and flexible nature of Fusion device user I/Os, a naming scheme is used to show the details of the I/O (Figure 2-89 and Figure 2-90 on page 2-121). The name identifies to which I/O bank it belongs, as well as the pairing and pin polarity for differential I/Os.

I/O Nomenclature = Gmn/IOuxwByVz

Gmn is only used for I/Os that also have CCC access – i.e., global pins.

- G = Global
- m = Global pin location associated with each CCC on the device: A (northwest corner), B (northeast corner), C (east middle), D (southeast corner), E (southwest corner), and F (west middle).
- n = Global input MUX and pin number of the associated Global location m, either A0, A1, A2, B0, B1, B2, C0, C1, or C2. Figure 2-22 on page 2-25 shows the three input pins per each clock source MUX at the CCC location m.
- u = I/O pair number in the bank, starting at 00 from the northwest I/O bank in a clockwise direction.
- x = P (Positive) or N (Negative) for differential pairs, or R (Regular single-ended) for the I/Os that support single-ended and voltage-referenced I/O standards only. U (Positive-LVDS only) or V (Negative-LVDS only) restrict the I/O differential pair from being selected as LVPECL pair.
- w = D (Differential Pair), P (Pair), S (Single-Ended). D (Differential Pair) if both members of the pair are bonded out to adjacent pins or are separated only by one GND or NC pin; P (Pair) if both members of the pair are bonded out but do not meet the adjacency requirement; or S (Single-Ended) if the I/O pair is not bonded out. For Differential (D) pairs, adjacency for ball grid packages means only vertical or horizontal. Diagonal adjacency does not meet the requirements for a true differential pair.
- B = Bank
- y = Bank number [0..3]. The Bank number starts at 0 from the northwest I/O bank and proceeds in a clockwise direction.
- V = Reference voltage
- z = Minibank number

#### CCC CCC Bank 0 "A "B' Bank 3 Bank 1 .VDS I/O Bank LVDS I/O Bank **AFS090** CCC/PLL CCC "F" AFS250 "C" Bank 3 Bank 1

Hot-Swap I/O Bank

**Analog Quads** 

Bank 2 (analog)

CCC

"D"

Figure 2-89 • Naming Conventions of Fusion Devices with Three Digital I/O Banks

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CCC

"E"



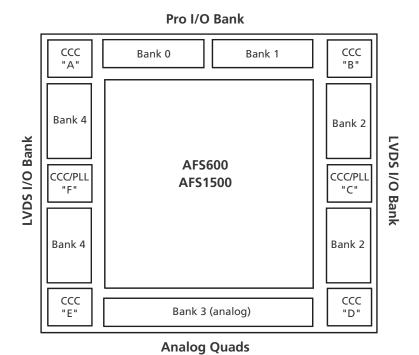


Figure 2-90 • Naming Conventions of Fusion Devices with Four I/O Banks

# **User I/O Characteristics**

# **Timing Model**

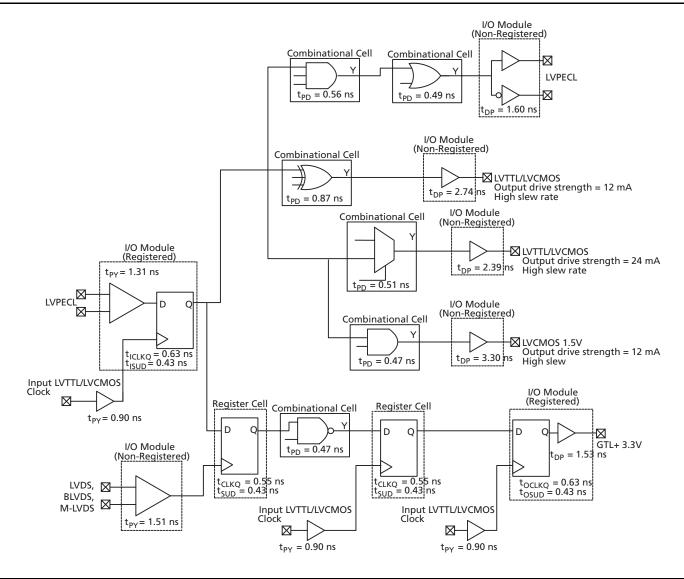
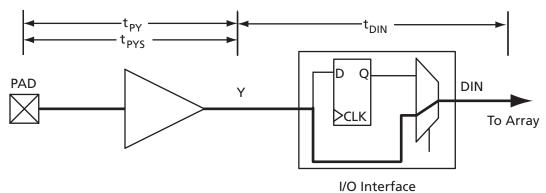


Figure 2-91 • Timing Model
Operating Conditions: –2 Speed, Commercial Temperature Range (T<sub>J</sub> = 70°C), Worst Case V<sub>CC</sub> = 1.425 V

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 $t_{PY} = MAX(t_{PY}(R), t_{PY}(F))$ 

 $t_{PYS} = MAX(t_{PYS}(R), t_{PYS}(F))$ 

 $\mathsf{t}_{\mathsf{DIN}} = \mathsf{MAX}(\mathsf{t}_{\mathsf{DIN}}\left(\mathsf{R}\right),\,\mathsf{t}_{\mathsf{DIN}}(\mathsf{F}))$ 

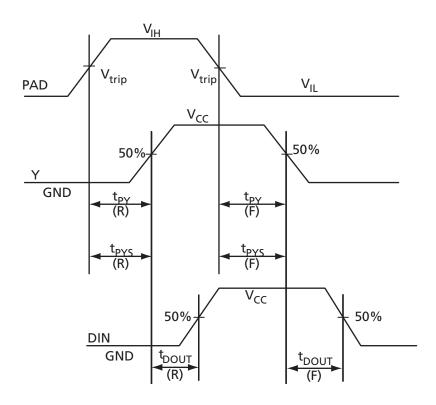


Figure 2-92 • Input Buffer Timing Model and Delays (example)

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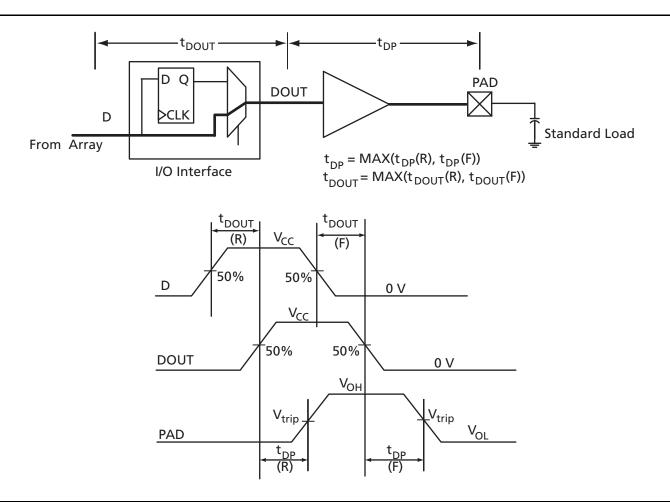


Figure 2-93 • Output Buffer Model and Delays (example)

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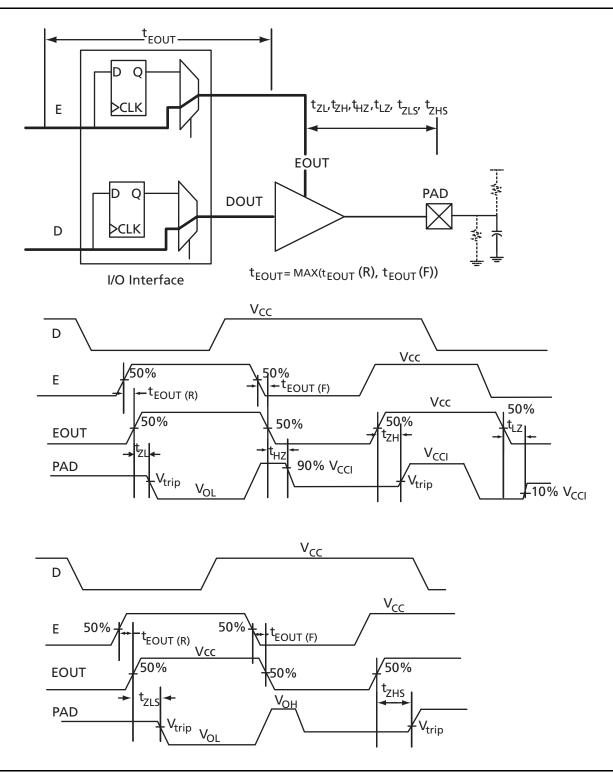


Figure 2-94 • Tristate Output Buffer Timing Model and Delays (example)

# Overview of I/O Performance Summary of I/O DC Input and Output Levels – Default I/O Software Settings

Table 2-73 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions

	Drive	Slew	,	V <sub>IL</sub>	V <sub>IH</sub>		V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>
I/O Standard	Strength	Rate	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA
3.3 V LVTTL / 3.3 V LVCMOS	12 mA	High	-0.3	0.8	2	3.6	0.4	2.4	12	12
2.5 V LVCMOS	12 mA	High	-0.3	0.7	1.7	3.6	0.7	1.7	12	12
1.8 V LVCMOS	12 mA	High	-0.3	0.35 * V <sub>CCI</sub>	0.65 * V <sub>CCI</sub>	3.6	0.45	V <sub>CCI</sub> – 0.45	12	12
1.5 V LVCMOS	12 mA	High	-0.3	0.30V <sub>CCI</sub>	0.7 * V <sub>CCI</sub>	3.6	0.25 * V <sub>CCI</sub>	0.75 * V <sub>CCI</sub>	12	12
3.3 V PCI		Per PCI Specification								
3.3 V PCI-X					Per PCI-X Spe	cification				
3.3 V GTL	25 mA <sup>2</sup>	High	-0.3	V <sub>REF</sub> - 0.05	V <sub>REF</sub> + 0.05	3.6	0.4	_	25	25
2.5 V GTL	25 mA <sup>2</sup>	High	-0.3	V <sub>REF</sub> – 0.05	V <sub>REF</sub> + 0.05	3.6	0.4	_	25	25
3.3 V GTL+	35 mA	High	-0.3	V <sub>REF</sub> – 0.1	V <sub>REF</sub> + 0.1	3.6	0.6	-	51	51
2.5 V GTL+	33 mA	High	-0.3	V <sub>REF</sub> – 0.1	V <sub>REF</sub> + 0.1	3.6	0.6	-	40	40
HSTL (I)	8 mA	High	-0.3	V <sub>REF</sub> - 0.1	V <sub>REF</sub> + 0.1	3.6	0.4	V <sub>CCI</sub> - 0.4	8	8
HSTL (II)	15 mA <sup>2</sup>	High	-0.3	V <sub>REF</sub> – 0.1	V <sub>REF</sub> + 0.1	3.6	0.4	V <sub>CCI</sub> – 0.4	15	15
SSTL2 (I)	15 mA	High	-0.3	V <sub>REF</sub> – 0.2	V <sub>REF</sub> + 0.2	3.6	0.54	V <sub>CCI</sub> – 0.62	15	15
SSTL2 (II)	18 mA	High	-0.3	V <sub>REF</sub> – 0.2	V <sub>REF</sub> + 0.2	3.6	0.35	V <sub>CCI</sub> – 0.43	18	18
SSTL3 (I)	14 mA	High	-0.3	V <sub>REF</sub> – 0.2	V <sub>REF</sub> + 0.2	3.6	0.7	V <sub>CCI</sub> – 1.1	14	14
SSTL3 (II)	21 mA	High	-0.3	V <sub>REF</sub> – 0.2	V <sub>REF</sub> + 0.2	3.6	0.5	V <sub>CCI</sub> – 0.9	21	21

#### Notes:

- 1. Currents are measured at 85°C junction temperature.
- 2. Output drive strength is below JEDEC specification.

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Table 2-74 • Summary of Maximum and Minimum DC Input Levels Applicable to Commercial and Industrial Conditions

	Comm	ercial <sup>1</sup>	Indus	strial <sup>2</sup>
	I <sub>IL</sub>	I <sub>IH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
DC I/O Standards	μΑ	μΑ	μΑ	μΑ
3.3 V LVTTL / 3.3 V LVCMOS	10	10	15	15
2.5 V LVCMOS	10	10	15	15
1.8 V LVCMOS	10	10	15	15
1.5 V LVCMOS	10	10	15	15
3.3 V PCI	10	10	15	15
3.3 V PCI-X	10	10	15	15
3.3 V GTL	10	10	15	15
2.5 V GTL	10	10	15	15
3.3 V GTL+	10	10	15	15
2.5 V GTL+	10	10	15	15
HSTL (I)	10	10	15	15
HSTL (II)	10	10	15	15
SSTL2 (I)	10	10	15	15
SSTL2 (II)	10	10	15	15
SSTL3 (I)	10	10	15	15
SSTL3 (II)	10	10	15	15

#### Notes:

- 1. Commercial range (0°C <  $T_J$  < 70°C)
- 2. Industrial range (-40°C <  $T_J$  < 85°C)

# **Summary of I/O Timing Characteristics – Default I/O Software Settings**

Table 2-75 • Summary of AC Measuring Points

Standard	Input Reference Voltage (V <sub>REF_TYP</sub> )	Board Termination Voltage (V <sub>TT_REF</sub> )	Measuring Trip Point (V <sub>trip</sub> )
3.3 V LVTTL / 3.3 V LVCMOS	-	-	1.4 V
2.5 V LVCMOS	-	_	1.2 V
1.8 V LVCMOS	-	-	0.90 V
1.5 V LVCMOS	-	-	0.75 V
3.3 V PCI	-	-	0.285 * V <sub>CCI</sub> (RR) 0.615 * V <sub>CCI</sub> (FF))
3.3 V PCI-X	-	-	0.285 * V <sub>CCI</sub> (RR) 0.615 * V <sub>CCI</sub> (FF)
3.3 V GTL	0.8 V	1.2 V	V <sub>REF</sub>
2.5 V GTL	0.8 V	1.2 V	V <sub>REF</sub>
3.3 V GTL+	1.0 V	1.5 V	V <sub>REF</sub>
2.5 V GTL+	1.0 V	1.5 V	V <sub>REF</sub>
HSTL (I)	0.75 V	0.75 V	V <sub>REF</sub>
HSTL (II)	0.75 V	0.75 V	V <sub>REF</sub>
SSTL2 (I)	1.25 V	1.25 V	$V_{REF}$
SSTL2 (II)	1.25 V	1.25 V	V <sub>REF</sub>
SSTL3 (I)	1.5 V	1.485 V	$V_{REF}$
SSTL3 (II)	1.5 V	1.485 V	$V_{REF}$
LVDS, BLVDS, M-LVDS	-	-	Cross point
LVPECL	-	-	Cross point

Table 2-76 • I/O AC Parameter Definitions

Parameter	Definition
t <sub>DP</sub>	Data to Pad delay through the Output Buffer
t <sub>PY</sub>	Pad to Data delay through the Input Buffer with Schmitt trigger disabled
t <sub>DOUT</sub>	Data to Output Buffer delay through the I/O interface
t <sub>EOUT</sub>	Enable to Output Buffer Tristate Control delay through the I/O interface
t <sub>DIN</sub>	Input Buffer to Data delay through the I/O interface
t <sub>PYS</sub>	Pad to Data delay through the Input Buffer with Schmitt trigger enabled
t <sub>HZ</sub>	Enable to Pad delay through the Output Buffer—high to Z
t <sub>ZH</sub>	Enable to Pad delay through the Output Buffer—Z to high
t <sub>LZ</sub>	Enable to Pad delay through the Output Buffer—low to Z
t <sub>ZL</sub>	Enable to Pad delay through the Output Buffer—Z to low
$t_{ZHS}$	Enable to Pad delay through the Output Buffer with delayed enable—Z to high
t <sub>ZLS</sub>	Enable to Pad delay through the Output Buffer with delayed enable—Z to low

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Table 2-77 • Summary of I/O Timing Characteristics – Software Default Settings
–2 Speed Grade, Commercial-Case Conditions: T<sub>J</sub>= 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 3.0 V

	z specu dia												-		-	•	
I/O Standard	Drive Strength (mA)	Slew Rate	Capacitive Load (pF)	External Resistor (Ohm)	toour	t <sub>DP</sub>	<sup>‡</sup> DIN	t <sub>р</sub> у	tpys	teour	t <sub>zı</sub>	tzн	t <sub>LZ</sub>	t <sub>нг</sub>	tzıs	<sup>‡</sup> zHs	Units
3.3 V LVTTL / 3.3 V LVCMOS	12 mA	High	35	-	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81	ns
2.5 V LVCMOS	12 mA	High	35	_	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28	ns
1.8 V LVCMOS	12 mA	High	35	-	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98	ns
1.5 V LVCMOS	12 mA	High	35	_	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37	ns
3.3 V PCI	Per PCI spec	High	10	25 <sup>2</sup>	0.49	2.09	0.03	0.78	1.25	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns
3.3 V PCI-X	Per PCI-X spec	High	10	25 <sup>2</sup>	0.49	2.09	0.03	0.78	1.25	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns
3.3 V GTL	25 mA	High	10	25	0.49	1.55	0.03	2.19	-	0.32	1.52	1.55	_	_	3.19	3.22	ns
2.5 V GTL	25 mA	High	10	25	0.49	1.59	0.03	1.83	_	0.32	1.61	1.59	_	_	3.28	3.26	ns
3.3 V GTL+	35 mA	High	10	25	0.49	1.53	0.03	1.19	_	0.32	1.56	1.53	_	_	3.23	3.20	ns
2.5 V GTL+	33 mA	High	10	25	0.49	1.65	0.03	1.13	_	0.32	1.68	1.57	_	_	3.35	3.24	ns
HSTL (I)	8 mA	High	20	50	0.49	2.37	0.03	1.59	_	0.32	2.42	2.35	_	_	4.09	4.02	ns
HSTL (II)	15 mA	High	20	25	0.49	2.26	0.03	1.59	_	0.32	2.30	2.03	_	_	3.97	3.70	ns
SSTL2 (I)	15 mA	High	30	50	0.49	1.59	0.03	1.00	_	0.32	1.62	1.38	_	_	3.29	3.05	ns
SSTL2 (II)	18 mA	High	30	25	0.49	1.62	0.03	1.00	-	0.32	1.65	1.32	_	_	3.32	2.99	ns
SSTL3 (I)	14 mA	High	30	50	0.49	1.72	0.03	0.93	-	0.32	1.75	1.37	_	_	3.42	3.04	ns
SSTL3 (II)	21 mA	High	30	25	0.49	1.54	0.03	0.93	_	0.32	1.57	1.25	_	_	3.24	2.92	ns
lvds, blvds, M-lvds	24 mA	High	-	_	0.49	1.57	0.03	1.51	1	-	_	_	-	-	_	_	ns
LVPECL	24 mA	High	-	_	0.49	1.60	0.03	1.31	_	_	_	_	_	_	_	-	ns

#### Notes:

- 1. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.
- 2. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-99 on page 2-143 for connectivity. This resistor is not required during normal operation.

## **Detailed I/O DC Characteristics**

*Table 2-78* • Input Capacitance

Symbol	Definition	Conditions	Min.	Max.	Units
C <sub>IN</sub>	Input capacitance	$V_{IN} = 0$ , $f = 1.0 \text{ MHz}$		8	pF
C <sub>INCLK</sub>	Input capacitance on the clock pin	$V_{IN} = 0$ , $f = 1.0 \text{ MHz}$		8	pF

Table 2-79 • I/O Output Buffer Maximum Resistances<sup>1</sup>

		R <sub>PULL-DOWN</sub>	R <sub>PULL-UP</sub> (Ohms) <sup>3</sup>		
Standard	Drive Strength	(Ohms) <sup>2</sup>			
3.3 V LVTTL / 3.3 V LVCMOS	4 mA	100	300		
	8 mA	50	150		
	12 mA	25	75		
	16 mA	17	50		
	24 mA	11	33		
2.5 V LVCMOS	4 mA	100	200		
	8 mA	50	100		
	12 mA	25	50		
	16 mA	20	40		
	24 mA	11	22		
1.8 V LVCMOS	2 mA	200	225		
	4 mA	100	112		
	6 mA	50	56		
	8 mA	50	56		
	12 mA	20	22		
	16 mA	20	22		
1.5 V LVCMOS	2 mA	200	224		
	4 mA	100	112		
	6 mA	67	75		
	8 mA	33	37		
	12 mA	33	37		
3.3 V PCI/PCI-X	Per PCI/PCI-X specification	25	75		
3.3 V GTL	25 mA	11	-		
2.5 V GTL	25 mA	14	_		
3.3 V GTL+	35 mA	12	-		
2.5 V GTL+	33 mA	15	-		
HSTL (I)	8 mA	50	50		
HSTL (II)	15 mA	25	25		
SSTL2 (I)	15 mA	27	31		
SSTL2 (II)	18 mA	13	15		
SSTL3 (I)	14 mA	44	69		
SSTL3 (II)	21 mA	18	32		

#### Notes:

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<sup>1.</sup> These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on  $V_{CCI}$ , drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Actel website at http://www.actel.com/techdocs/models/ibis.html.

<sup>2.</sup>  $R_{(PULL\text{-}DOWN\text{-}MAX)} = (V_{OLspec}) / I_{OLspec}$ 3.  $R_{(PULL\text{-}UP\text{-}MAX)} = (V_{CCImax} - V_{OHspec}) / I_{OHspec}$ 



Table 2-80 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

	R( <sub>(WEAK</sub> (Oh	PULL-UP) 1 Ims)	R <sub>(WEAK PULL-DOWN)</sub> <sup>2</sup> (Ohms)				
ν <sub>ccı</sub>	Min.	Max.	Min.	Max.			
3.3 V	10 k	45 k	10 k	45 k			
2.5 V	11 k	55 k	12 k	74 k			
1.8 V	18 k	70 k	17 k	110 k			
1.5 V	19 k	90 k	19 k	140 k			

# Notes:

- 1.  $R_{(WEAK\ PULL-DOWN-MAX)} = (V_{OLspec}) / I_{WEAK\ PULL-DOWN-MIN}$
- 2.  $R_{(WEAK\ PULL-UP-MAX)} = (V_{CCImax} V_{OHspec}) / I_{WEAK\ PULL-UP-MIN}$

Table 2-81 • I/O Short Currents I<sub>OSH</sub>/I<sub>OSL</sub>

	Drive Strength	I <sub>OSH</sub> (mA)*	I <sub>OSL</sub> (mA)*
3.3 V LVTTL / 3.3 V LVCMOS	4 mA	25	27
	8 mA	51	54
	12 mA	103	109
	16 mA	132	127
	24 mA	268	181
2.5 V LVCMOS	4 mA	16	18
	8 mA	32	37
	12 mA	65	74
	16 mA	83	87
	24 mA	169	124
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
	6 mA	35	44
	8 mA	45	51
	12 mA	91	74
	16 mA	91	74
1.5 V LVCMOS	2 mA	13	16
	4 mA	25	33
	6 mA	32	39
	8 mA	66	55
	12 mA	66	55

**Note:** \**T*<sub>J</sub> = 100°C

The length of time an I/O can withstand  $I_{OSH}/I_{OSL}$  events depends on the junction temperature. The reliability data below is based on a 3.3 V, 36 mA I/O setting, which is the worst case for this type of analysis.

For example, at 110°C, the short current condition would have to be sustained for more than three months to cause a reliability concern. The I/O design does not contain any short circuit protection, but such protection would only be needed in extremely prolonged stress conditions.

Table 2-82 • Short Current Event Duration Before Failure

Temperature	Time Before Failure
−40°C	> 20 years
0°C	> 20 years
25°C	> 20 years
70°C	5 years
85°C	2 years
100°C	6 months
110°C	3 months

Table 2-83 • Schmitt Trigger Input Hysteresis
Hysteresis Voltage Value (Typ) for Schmitt Mode Input Buffers

Input Buffer Configuration	Hysteresis Value (Typ)
3.3 V LVTTL/LVCMOS / PCI / PCI-X (Schmitt trigger mode)	240 mV
2.5 V LVCMOS (Schmitt trigger mode)	140 mV
1.8 V LVCMOS (Schmitt trigger mode)	80 mV
1.5 V LVCMOS (Schmitt trigger mode)	60 mV

Table 2-84 • I/O Input Rise Time, Fall Time, and Related I/O Reliability

Input Buffer	Input Rise/Fall Time (Min.)	Input Rise/Fall Time (Max.)	Reliability
LVTTL/LVCMOS (Schmitt trigger disabled)	No requirement	10 ns*	20 years (110°C)
LVTTL/LVCMOS (Schmitt trigger enabled)		No requirement, but input noise voltage cannot exceed Schmitt hysteresis	20 years (110°C)
HSTL/SSTL/GTL	No requirement	10 ns*	10 years (100°C)
LVDS/BLVDS/M-LVDS/LVPECL	No requirement	10 ns*	10 years (100°C)

\*The Maximum Input rise/fall time is related only to the noise induced into the input buffer trace. If the noise is low, then the rise time and fall time of input buffers, when Schmitt trigger is disabled, can be increased beyond the maximum value. The longer the rise/fall times, the more susceptible the input signal is to the board noise. Actel recommends signal integrity evaluation/ characterization of the system to ensure that there is no excessive noise coupling into input signals.

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# Single-Ended I/O Characteristics

# **3.3 V LVTTL / 3.3 V LVCMOS**

Low-Voltage Transistor-Transistor Logic is a general purpose standard (EIA/JESD) for 3.3 V applications. It uses an LVTTL input buffer and push-pull output buffer. The 3.3 V LVCMOS standard is supported as part of the 3.3 V LVTTL support.

Table 2-85 • Minimum and Maximum DC Input and Output Levels

3.3 V LVTTL / 3.3 V LVCMOS	V <sub>IL</sub>		V <sub>IH</sub>		V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
Drive Strength	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup> Max, mA <sup>1</sup>		μA <sup>2</sup>	μA <sup>2</sup>
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10
12 mA	-0.3	0.8	2	3.6	0.4	2.4	12	12	109	103	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	127	132	10	10
24 mA	-0.3	0.8	2	3.6	0.4	2.4	24	24	181	268	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.
- 3. Software default selection highlighted in gray.

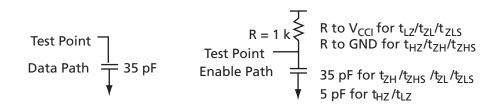


Figure 2-95 • AC Loading

Table 2-86 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
0	3.3	1.4	_	35

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-87 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 3.0 V

Drive Strength (mA)	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	0.66	11.01	0.04	1.20	1.57	0.43	11.21	9.05	2.69	2.44	13.45	11.29	ns
	-1	0.56	9.36	0.04	1.02	1.33	0.36	9.54	7.70	2.29	2.08	11.44	9.60	ns
	-2	0.49	8.22	0.03	0.90	1.17	0.32	8.37	6.76	2.01	1.82	10.04	8.43	ns
8 mA	Std.	0.66	7.86	0.04	1.20	1.57	0.43	8.01	6.44	3.04	3.06	10.24	8.68	ns
	-1	0.56	6.69	0.04	1.02	1.33	0.36	6.81	5.48	2.58	2.61	8.71	7.38	ns
	-2	0.49	5.87	0.03	0.90	1.17	0.32	5.98	4.81	2.27	2.29	7.65	6.48	ns
12 mA	Std.	0.66	6.03	0.04	1.20	1.57	0.43	6.14	5.02	3.28	3.47	8.37	7.26	ns
	-1	0.56	5.13	0.04	1.02	1.33	0.36	5.22	4.27	2.79	2.95	7.12	6.17	ns
	-2	0.49	4.50	0.03	0.90	1.17	0.32	4.58	3.75	2.45	2.59	6.25	5.42	ns
16 mA	Std.	0.66	5.62	0.04	1.20	1.57	0.43	5.72	4.72	3.32	3.58	7.96	6.96	ns
	-1	0.56	4.78	0.04	1.02	1.33	0.36	4.87	4.02	2.83	3.04	6.77	5.92	ns
	-2	0.49	4.20	0.03	0.90	1.17	0.32	4.27	3.53	2.48	2.67	5.94	5.20	ns
24 mA	Std.	0.66	5.24	0.04	1.20	1.57	0.43	5.34	4.69	3.39	3.96	7.58	6.93	ns
	-1	0.56	4.46	0.04	1.02	1.33	0.36	4.54	3.99	2.88	3.37	6.44	5.89	ns
	-2	0.49	3.92	0.03	0.90	1.17	0.32	3.99	3.50	2.53	2.96	5.66	5.17	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

Table 2-88 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 3.0

Drive Strength (mA)	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	0.66	7.88	0.04	1.20	1.57	0.43	8.03	6.70	2.69	2.59	10.26	8.94	ns
	-1	0.56	6.71	0.04	1.02	1.33	0.36	6.83	5.70	2.29	2.20	8.73	7.60	ns
	-2	0.49	5.89	0.03	0.90	1.17	0.32	6.00	5.01	2.01	1.93	7.67	6.67	ns
8 mA	Std.	0.66	5.08	0.04	1.20	1.57	0.43	5.17	4.14	3.05	3.21	7.41	6.38	ns
	-1	0.56	4.32	0.04	1.02	1.33	0.36	4.40	3.52	2.59	2.73	6.30	5.43	ns
	-2	0.49	3.79	0.03	0.90	1.17	0.32	3.86	3.09	2.28	2.40	5.53	4.76	ns
12 mA	Std.	0.66	3.67	0.04	1.20	1.57	0.43	3.74	2.87	3.28	3.61	5.97	5.11	ns
	-1	0.56	3.12	0.04	1.02	1.33	0.36	3.18	2.44	2.79	3.07	5.08	4.34	ns
	-2	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81	ns
16 mA	Std.	0.66	3.46	0.04	1.20	1.57	0.43	3.53	2.61	3.33	3.72	5.76	4.84	ns
	-1	0.56	2.95	0.04	1.02	1.33	0.36	3.00	2.22	2.83	3.17	4.90	4.12	ns
	-2	0.49	2.59	0.03	0.90	1.17	0.32	2.63	1.95	2.49	2.78	4.30	3.62	ns
24 mA	Std.	0.66	3.21	0.04	1.20	1.57	0.43	3.27	2.16	3.39	4.13	5.50	4.39	ns
	-1	0.56	2.73	0.04	1.02	1.33	0.36	2.78	1.83	2.88	3.51	4.68	3.74	ns
	-2	0.49	2.39	0.03	0.90	1.17	0.32	2.44	1.61	2.53	3.08	4.11	3.28	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# 2.5 V LVCMOS

Low-Voltage CMOS for 2.5 V is an extension of the LVCMOS standard (JESD8-5) used for general purpose 2.5 V applications. It uses a 5-V-tolerant input buffer and push-pull output buffer.

Table 2-89 • Minimum and Maximum DC Input and Output Levels

2.5 V LVCMOS	V <sub>IL</sub>		V <sub>IH</sub>		V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
Drive Strength	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
4 mA	-0.3	0.7	1.7	3.6	0.7	1.7	4	4	18	16	10	10
8 mA	-0.3	0.7	1.7	3.6	0.7	1.7	8	8	37	32	10	10
12 mA	-0.3	0.7	1.7	3.6	0.7	1.7	12	12	74	65	10	10
16 mA	-0.3	0.7	1.7	3.6	0.7	1.7	16	16	87	83	10	10
24 mA	-0.3	0.7	1.7	3.6	0.7	1.7	24	24	124	169	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.
- 3. Software default selection highlighted in gray.

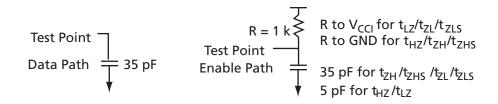


Figure 2-96 • AC Loading

Table 2-90 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
0	2.5	1.2	_	35

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-91 • 2.5 V LVCMOS Low Slew Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 2.3 V

Drive Strength (mA)	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	0.66	12.00	0.04	1.51	1.66	0.43	12.23	11.61	2.72	2.20	14.46	13.85	ns
	-1	0.56	10.21	0.04	1.29	1.41	0.36	10.40	9.88	2.31	1.87	12.30	11.78	ns
	-2	0.49	8.96	0.03	1.13	1.24	0.32	9.13	8.67	2.03	1.64	10.80	10.34	ns
8 mA	Std.	0.66	8.73	0.04	1.51	1.66	0.43	8.89	8.01	3.10	2.93	11.13	10.25	ns
	-1	0.56	7.43	0.04	1.29	1.41	0.36	7.57	6.82	2.64	2.49	9.47	8.72	ns
	-2	0.49	6.52	0.03	1.13	1.24	0.32	6.64	5.98	2.32	2.19	8.31	7.65	ns
12 mA	Std.	0.66	6.77	0.04	1.51	1.66	0.43	6.90	6.11	3.37	3.39	9.14	8.34	ns
	-1	0.56	5.76	0.04	1.29	1.41	0.36	5.87	5.20	2.86	2.89	7.77	7.10	ns
	-2	0.49	5.06	0.03	1.13	1.24	0.32	5.15	4.56	2.51	2.53	6.82	6.23	ns
16 mA	Std.	0.66	6.31	0.04	1.51	1.66	0.43	6.42	5.73	3.42	3.52	8.66	7.96	ns
	-1	0.56	5.37	0.04	1.29	1.41	0.36	5.46	4.87	2.91	3.00	7.37	6.77	ns
	-2	0.49	4.71	0.03	1.13	1.24	0.32	4.80	4.28	2.56	2.63	6.47	5.95	ns
24 mA	Std.	0.66	5.93	0.04	1.51	1.66	0.43	6.04	5.70	3.49	4.00	8.28	7.94	ns
	-1	0.56	5.05	0.04	1.29	1.41	0.36	5.14	4.85	2.97	3.40	7.04	6.75	ns
	-2	0.49	4.43	0.03	1.13	1.24	0.32	4.51	4.26	2.61	2.99	6.18	5.93	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

Table 2-92 ◆ 2.5 V LVCMOS High Slew
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 2.3 V

r			_		T	1								1
Drive Strength (mA)	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
4 mA	Std.	0.66	8.82	0.04	1.51	1.66	0.43	8.13	8.82	2.72	2.29	10.37	11.05	ns
	-1	0.56	7.50	0.04	1.29	1.41	0.36	6.92	7.50	2.31	1.95	8.82	9.40	ns
	-2	0.49	6.58	0.03	1.13	1.24	0.32	6.07	6.58	2.03	1.71	7.74	8.25	ns
8 mA	Std.	0.66	5.27	0.04	1.51	1.66	0.43	5.27	5.27	3.10	3.03	7.50	7.51	ns
	-1	0.56	4.48	0.04	1.29	1.41	0.36	4.48	4.48	2.64	2.58	6.38	6.38	ns
	-2	0.49	3.94	0.03	1.13	1.24	0.32	3.93	3.94	2.32	2.26	5.60	5.61	ns
12 mA	Std.	0.66	3.74	0.04	1.51	1.66	0.43	3.81	3.49	3.37	3.49	6.05	5.73	ns
	-1	0.56	3.18	0.04	1.29	1.41	0.36	3.24	2.97	2.86	2.97	5.15	4.87	ns
	-2	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28	ns
16 mA	Std.	0.66	3.53	0.04	1.51	1.66	0.43	3.59	3.12	3.42	3.62	5.83	5.35	ns
	-1	0.56	3.00	0.04	1.29	1.41	0.36	3.06	2.65	2.91	3.08	4.96	4.55	ns
	-2	0.49	2.63	0.03	1.13	1.24	0.32	2.68	2.33	2.56	2.71	4.35	4.00	ns
24 mA	Std.	0.66	3.26	0.04	1.51	1.66	0.43	3.32	2.48	3.49	4.11	5.56	4.72	ns
	-1	0.56	2.77	0.04	1.29	1.41	0.36	2.83	2.11	2.97	3.49	4.73	4.01	ns
	-2	0.49	2.44	0.03	1.13	1.24	0.32	2.48	1.85	2.61	3.07	4.15	3.52	ns

#### Notes:

- 1. Software default selection highlighted in gray.
- 2. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# 1.8 V LVCMOS

Low-Voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general purpose 1.8 V applications. It uses 1.8 V input buffer and push-pull output buffer.

Table 2-93 • Minimum and Maximum DC Input and Output Levels

1.8 V LVCMOS	V <sub>IL</sub>		V <sub>IH</sub>		V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
Drive Strength	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
2 mA	-0.3	0.35 * V <sub>CCI</sub>	0.65 * V <sub>CCI</sub>	3.6	0.45	V <sub>CCI</sub> – 0.45	2	2	11	9	10	10
4 mA	-0.3	0.35 * V <sub>CCI</sub>	0.65 * V <sub>CCI</sub>	3.6	0.45	V <sub>CCI</sub> – 0.45	4	4	22	17	10	10
6 mA	-0.3	0.35 * V <sub>CCI</sub>	0.65 * V <sub>CCI</sub>	3.6	0.45	V <sub>CCI</sub> – 0.45	6	6	44	35	10	10
8 mA	-0.3	0.35 * V <sub>CCI</sub>	0.65 * V <sub>CCI</sub>	3.6	0.45	V <sub>CCI</sub> – 0.45	8	8	51	45	10	10
12 mA	-0.3	0.35 * V <sub>CCI</sub>	0.65 * V <sub>CCI</sub>	3.6	0.45	V <sub>CCI</sub> – 0.45	12	12	74	91	10	10
16 mA	-0.3	0.35 * V <sub>CCI</sub>	0.65 * V <sub>CCI</sub>	3.6	0.45	V <sub>CCI</sub> – 0.45	16	16	74	91	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.
- 3. Software default selection highlighted in gray.

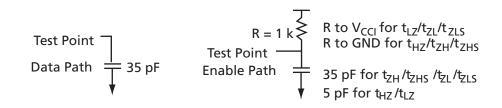


Figure 2-97 • AC Loading

Table 2-94 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
0	1.8	0.9	_	35

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-95 • 1.8 V LVCMOS Low Slew Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 1.7 V

Drive Strength (mA)	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	15.84	0.04	1.45	1.91	0.43	15.65	15.84	2.78	1.58	17.89	18.07	ns
	-1	0.56	13.47	0.04	1.23	1.62	0.36	13.31	13.47	2.37	1.35	15.22	15.37	ns
	-2	0.49	11.83	0.03	1.08	1.42	0.32	11.69	11.83	2.08	1.18	13.36	13.50	ns
4 mA	Std.	0.66	11.39	0.04	1.45	1.91	0.43	11.60	10.76	3.26	2.77	13.84	12.99	ns
	-1	0.56	9.69	0.04	1.23	1.62	0.36	9.87	9.15	2.77	2.36	11.77	11.05	ns
	-2	0.49	8.51	0.03	1.08	1.42	0.32	8.66	8.03	2.43	2.07	10.33	9.70	ns
6 mA	Std.	0.66	8.97	0.04	1.45	1.91	0.43	9.14	8.10	3.57	3.36	11.37	10.33	ns
	-1	0.56	7.63	0.04	1.23	1.62	0.36	7.77	6.89	3.04	2.86	9.67	8.79	ns
	-2	0.49	6.70	0.03	1.08	1.42	0.32	6.82	6.05	2.66	2.51	8.49	7.72	ns
8 mA	Std.	0.66	8.35	0.04	1.45	1.91	0.43	8.50	7.59	3.64	3.52	10.74	9.82	ns
	-1	0.56	7.10	0.04	1.23	1.62	0.36	7.23	6.45	3.10	3.00	9.14	8.35	ns
	-2	0.49	6.24	0.03	1.08	1.42	0.32	6.35	5.66	2.72	2.63	8.02	7.33	ns
12 mA	Std.	0.66	7.94	0.04	1.45	1.91	0.43	8.09	7.56	3.74	4.11	10.32	9.80	ns
	-1	0.56	6.75	0.04	1.23	1.62	0.36	6.88	6.43	3.18	3.49	8.78	8.33	ns
	-2	0.49	5.93	0.03	1.08	1.42	0.32	6.04	5.65	2.79	3.07	7.71	7.32	ns
16 mA	Std.	0.66	7.94	0.04	1.45	1.91	0.43	8.09	7.56	3.74	4.11	10.32	9.80	ns
	-1	0.56	6.75	0.04	1.23	1.62	0.36	6.88	6.43	3.18	3.49	8.78	8.33	ns
	-2	0.49	5.93	0.03	1.08	1.42	0.32	6.04	5.65	2.79	3.07	7.71	7.32	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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Table 2-96 • 1.8 V LVCMOS High Slew Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 1.7 V

<b>Drive Strength</b>	Speed													
(mA)	Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	12.10	0.04	1.45	1.91	0.43	9.59	12.10	2.78	1.64	11.83	14.34	ns
	-1	0.56	10.30	0.04	1.23	1.62	0.36	8.16	10.30	2.37	1.39	10.06	12.20	ns
	-2	0.49	9.04	0.03	1.08	1.42	0.32	7.16	9.04	2.08	1.22	8.83	10.71	ns
4 mA	Std.	0.66	7.05	0.04	1.45	1.91	0.43	6.20	7.05	3.25	2.86	8.44	9.29	ns
	-1	0.56	6.00	0.04	1.23	1.62	0.36	5.28	6.00	2.76	2.44	7.18	7.90	ns
	-2	0.49	5.27	0.03	1.08	1.42	0.32	4.63	5.27	2.43	2.14	6.30	6.94	ns
6 mA	Std.	0.66	4.52	0.04	1.45	1.91	0.43	4.47	4.52	3.57	3.47	6.70	6.76	ns
	-1	0.56	3.85	0.04	1.23	1.62	0.36	3.80	3.85	3.04	2.95	5.70	5.75	ns
	-2	0.49	3.38	0.03	1.08	1.42	0.32	3.33	3.38	2.66	2.59	5.00	5.05	ns
8 mA	Std.	0.66	4.12	0.04	1.45	1.91	0.43	4.20	3.99	3.63	3.62	6.43	6.23	ns
	-1	0.56	3.51	0.04	1.23	1.62	0.36	3.57	3.40	3.09	3.08	5.47	5.30	ns
	-2	0.49	3.08	0.03	1.08	1.42	0.32	3.14	2.98	2.71	2.71	4.81	4.65	ns
12 mA	Std.	0.66	3.80	0.04	1.45	1.91	0.43	3.87	3.09	3.73	4.24	6.10	5.32	ns
	-1	0.56	3.23	0.04	1.23	1.62	0.36	3.29	2.63	3.18	3.60	5.19	4.53	ns
	-2	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98	ns
16 mA	Std.	0.66	3.80	0.04	1.45	1.91	0.43	3.87	3.09	3.73	4.24	6.10	5.32	ns
	-1	0.56	3.23	0.04	1.23	1.62	0.36	3.29	2.63	3.18	3.60	5.19	4.53	ns
	-2	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98	ns

## Notes:

- 1. Software default selection highlighted in gray.
- 2. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# 1.5 V LVCMOS (JESD8-11)

Low-voltage CMOS for 1.5 V is an extension of the LVCMOS standard (JESD8-5) used for general purpose 1.5 V applications. It uses a 1.5 V input buffer and push-pull output buffer.

Table 2-97 • Minimum and Maximum DC Input and Output Levels

1.5 V LVCMOS	V <sub>IL</sub>		V <sub>IH</sub>		V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
Drive Strength	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
2 mA	-0.3	0.30 * V <sub>CCI</sub>	0.7 * V <sub>CCI</sub>	3.6	0.25 * V <sub>CCI</sub>	0.75 * V <sub>CCI</sub>	2	2	16	13	10	10
4 mA	-0.3	0.30 * V <sub>CCI</sub>	0.7 * V <sub>CCI</sub>	3.6	0.25 * V <sub>CCI</sub>	0.75 * V <sub>CCI</sub>	4	4	33	25	10	10
6 mA	-0.3	0.30 * V <sub>CCI</sub>	0.7 * V <sub>CCI</sub>	3.6	0.25 * V <sub>CCI</sub>	0.75 * V <sub>CCI</sub>	6	6	39	32	10	10
8 mA	-0.3	0.30 * V <sub>CCI</sub>	0.7 * V <sub>CCI</sub>	3.6	0.25 * V <sub>CCI</sub>	0.75 * V <sub>CCI</sub>	8	8	55	66	10	10
12 mA	-0.3	0.30 * V <sub>CCI</sub>	0.7 * V <sub>CCI</sub>	3.6	0.25 * V <sub>CCI</sub>	0.75 * V <sub>CCI</sub>	12	12	55	66	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.
- 3. Software default selection highlighted in gray.

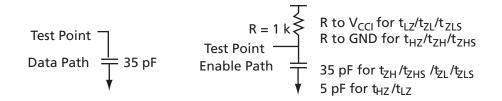


Figure 2-98 • AC Loading

Table 2-98 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
0	1.5	0.75	-	35

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

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# **Timing Characteristics**

Table 2-99 • 1.5 V LVCMOS Low Slew
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 1.4 V

Drive Strength	Speed													
(mA)	Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	14.11	0.04	1.70	2.14	0.43	14.37	13.14	3.40	2.68	16.61	15.37	ns
	-1	0.56	12.00	0.04	1.44	1.82	0.36	12.22	11.17	2.90	2.28	14.13	13.08	ns
	-2	0.49	10.54	0.03	1.27	1.60	0.32	10.73	9.81	2.54	2.00	12.40	11.48	ns
4 mA	Std.	0.66	11.23	0.04	1.70	2.14	0.43	11.44	9.87	3.77	3.36	13.68	12.10	ns
	-1	0.56	9.55	0.04	1.44	1.82	0.36	9.73	8.39	3.21	2.86	11.63	10.29	ns
	-2	0.49	8.39	0.03	1.27	1.60	0.32	8.54	7.37	2.81	2.51	10.21	9.04	ns
6 mA	Std.	0.66	10.45	0.04	1.70	2.14	0.43	10.65	9.24	3.84	3.55	12.88	11.48	ns
	-1	0.56	8.89	0.04	1.44	1.82	0.36	9.06	7.86	3.27	3.02	10.96	9.76	ns
	-2	0.49	7.81	0.03	1.27	1.60	0.32	7.95	6.90	2.87	2.65	9.62	8.57	ns
8 mA	Std.	0.66	10.02	0.04	1.70	2.14	0.43	10.20	9.23	3.97	4.22	12.44	11.47	ns
	-1	0.56	8.52	0.04	1.44	1.82	0.36	8.68	7.85	3.38	3.59	10.58	9.75	ns
	-2	0.49	7.48	0.03	1.27	1.60	0.32	7.62	6.89	2.97	3.15	9.29	8.56	ns
12 mA	Std.	0.66	10.02	0.04	1.70	2.14	0.43	10.20	9.23	3.97	4.22	12.44	11.47	ns
	-1	0.56	8.52	0.04	1.44	1.82	0.36	8.68	7.85	3.38	3.59	10.58	9.75	ns
	-2	0.49	7.48	0.03	1.27	1.60	0.32	7.62	6.89	2.97	3.15	9.29	8.56	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

Table 2-100 • 1.5 V LVCMOS High Slew Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V, Worst Case V<sub>CCI</sub> = 1.4 V

Drive Strength (mA)	Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
2 mA	Std.	0.66	8.53	0.04	1.70	2.14	0.43	7.26	8.53	3.39	2.79	9.50	10.77	ns
	-1	0.56	7.26	0.04	1.44	1.82	0.36	6.18	7.26	2.89	2.37	8.08	9.16	ns
	-2	0.49	6.37	0.03	1.27	1.60	0.32	5.42	6.37	2.53	2.08	7.09	8.04	ns
4 mA	Std.	0.66	5.41	0.04	1.70	2.14	0.43	5.22	5.41	3.75	3.48	7.45	7.65	ns
	-1	0.56	4.60	0.04	1.44	1.82	0.36	4.44	4.60	3.19	2.96	6.34	6.50	ns
	-2	0.49	4.04	0.03	1.27	1.60	0.32	3.89	4.04	2.80	2.60	5.56	5.71	ns
6 mA	Std.	0.66	4.80	0.04	1.70	2.14	0.43	4.89	4.75	3.83	3.67	7.13	6.98	ns
	-1	0.56	4.09	0.04	1.44	1.82	0.36	4.16	4.04	3.26	3.12	6.06	5.94	ns
	-2	0.49	3.59	0.03	1.27	1.60	0.32	3.65	3.54	2.86	2.74	5.32	5.21	ns
8 mA	Std.	0.66	4.42	0.04	1.70	2.14	0.43	4.50	3.62	3.96	4.37	6.74	5.86	ns
	-1	0.56	3.76	0.04	1.44	1.82	0.36	3.83	3.08	3.37	3.72	5.73	4.98	ns
	-2	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37	ns
12 mA	Std.	0.66	4.42	0.04	1.70	2.14	0.43	4.50	3.62	3.96	4.37	6.74	5.86	ns
	-1	0.56	3.76	0.04	1.44	1.82	0.36	3.83	3.08	3.37	3.72	5.73	4.98	ns
	-2	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37	ns

# Notes:

- 1. Software default selection highlighted in gray.
- 2. For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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#### 3.3 V PCI, 3.3 V PCI-X

Peripheral Component Interface for 3.3 V standard specifies support for 33 MHz and 66 MHz PCI Bus applications.

Table 2-101 • Minimum and Maximum DC Input and Output Levels

3.3 V PCI/PCI-X	٧	İL	٧	IН	V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
Drive Strength	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μ <b>Α</b> <sup>2</sup>	μ <b>Α</b> <sup>2</sup>
Per PCI specification					Per PC	CI curves					10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

AC loadings are defined per the PCI/PCI-X specifications for the data path; Actel loadings for enable path characterization are described in Figure 2-99.

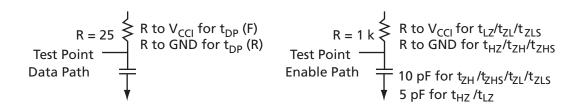


Figure 2-99 • AC Loading

AC loading are defined per PCI/PCI-X specifications for the data path; Actel loading for tristate is described in Table 2-102.

Table 2-102 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
0	3.3	0.285 * $V_{CCI}$ for $t_{DP(R)}$	_	10
		0.615 * $V_{CCI}$ for $t_{DP(F)}$		

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

## **Timing Characteristics**

Table 2-103 • 3.3 V PCI/PCI-X

Commercial Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCJ} = 3.0$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>PYS</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.81	0.04	1.05	1.67	0.43	2.86	2.00	3.28	3.61	5.09	4.23	ns
<b>-1</b>	0.56	2.39	0.04	0.89	1.42	0.36	2.43	1.70	2.79	3.07	4.33	3.60	ns
-2	0.49	2.09	0.03	0.78	1.25	0.32	2.13	1.49	2.45	2.70	3.80	3.16	ns

Note: For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# **Voltage Referenced I/O Characteristics**

#### 3.3 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open drain output buffer. The V<sub>CCI</sub> pin should be connected to 3.3 V.

Table 2-104 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL	,	V <sub>IL</sub>	VII	4	V <sub>OL</sub>	V <sub>OH</sub>	l <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
Drive Strength	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
25 mA <sup>3</sup>	-0.3	V <sub>REF</sub> – 0.05	V <sub>REF</sub> + 0.05	3.6	0.4	_	25	25	181	268	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.
- 3. Output drive strength is below JEDEC specification.

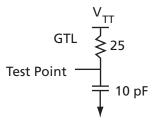


Figure 2-100 • AC Loading

Table 2-105 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> - 0.05	V <sub>REF</sub> + 0.05	0.8	0.8	1.2	10

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-106 • 3.3 V GTL

# Commercial Case Conditions: $T_J = 70^{\circ}$ C, Worst Case $V_{CC} = 1.425$ V, Worst Case $V_{CCI} = 3.0$ V $V_{REF} = 0.8$ V

			-									
Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.08	0.04	2.93	0.43	2.04	2.08			4.27	4.31	ns
-1	0.56	1.77	0.04	2.50	0.36	1.73	1.77			3.63	3.67	ns
-2	0.49	1.55	0.03	2.19	0.32	1.52	1.55			3.19	3.22	ns

Note: For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# 2.5 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open drain output buffer. The V<sub>CCI</sub> pin should be connected to 2.5 V.

Table 2-107 • Minimum and Maximum DC Input and Output Levels

2.5 GTL	•	/ <sub>IL</sub>	V <sub>IH</sub>	l	$V_{OL}$	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	崖	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
25 mA <sup>3</sup>	-0.3	V <sub>REF</sub> – 0.05	V <sub>REF</sub> + 0.05	3.6	0.4	-	25	25	124	169	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.
- 3. Output drive strength is below JEDEC specification.

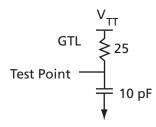


Figure 2-101 • AC Loading

Table 2-108 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> - 0.05	V <sub>REF</sub> + 0.05	0.8	0.8	1.2	10

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

#### **Timing Characteristics**

Table 2-109 • 2.5 V GTL

Commercial Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 3.0$  V  $V_{REF} = 0.8$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>zH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.13	0.04	2.46	0.43	2.16	2.13			4.40	4.36	ns
<b>-1</b>	0.56	1.81	0.04	2.09	0.36	1.84	1.81			3.74	3.71	ns
-2	0.49	1.59	0.03	1.83	0.32	1.61	1.59			3.28	3.26	ns

Note: For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

#### 3.3 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open drain output buffer. The V<sub>CCI</sub> pin should be connected to 3.3 V.

Table 2-110 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL+	•	/ <sub>IL</sub>	VIH	ı	V <sub>OL</sub>	V <sub>OH</sub>	l <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	≓	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
35 mA	-0.3	V <sub>REF</sub> – 0.1	V <sub>REF</sub> + 0.1	3.6	0.6	-	35	35	181	268	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

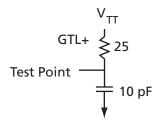


Figure 2-102 • AC Loading

Table 2-111 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> - 0.1	V <sub>REF</sub> + 0.1	1.0	1.0	1.5	10

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

## **Timing Characteristics**

Table 2-112 • 3.3 V GTL+

Commercial Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 3.0$  V,  $V_{REF} = 1.0$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.06	0.04	1.59	0.43	2.09	2.06			4.33	4.29	ns
-1	0.56	1.75	0.04	1.35	0.36	1.78	1.75			3.68	3.65	ns
-2	0.49	1.53	0.03	1.19	0.32	1.56	1.53			3.23	3.20	ns

Note: For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# 2.5 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open drain output buffer. The  $V_{CCI}$  pin should be connected to 2.5 V.

Table 2-113 • Minimum and Maximum DC Input and Output Levels

2.5 V GTL+	•	/ <sub>IL</sub>	VII	ı	V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
33 mA	-0.3	V <sub>REF</sub> - 0.1	V <sub>REF</sub> + 0.1	3.6	0.6	_	33	33	124	169	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

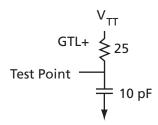


Figure 2-103 • AC Loading

Table 2-114 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> - 0.1	V <sub>REF</sub> + 0.1	1.0	1.0	1.5	10

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-115 • 2.5 V GTL+

Commercial Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 2.3$  V,  $V_{REF} = 1.0$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.21	0.04	1.59	0.43	2.25	2.10			4.48	4.34	ns
-1	0.56	1.88	0.04	1.35	0.36	1.91	1.79			3.81	3.69	ns
-2	0.49	1.65	0.03	1.19	0.32	1.68	1.57			3.35	3.24	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

#### **HSTL Class I**

High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). Fusion devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-116 • Minimum and Maximum DC Input and Output Levels

HSTL Class I	•	/ <sub>IL</sub>	VII	н	$V_{OL}$	V <sub>OH</sub>	l <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	ш	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
8 mA	-0.3	V <sub>REF</sub> - 0.1	$V_{REF} + 0.1$	3.6	0.4	V <sub>CCI</sub> – 0.4	8	8	39	32	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

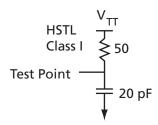


Figure 2-104 • AC Loading

Table 2-117 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> – 0.1	V <sub>REF</sub> + 0.1	0.75	0.75	0.75	20

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

## **Timing Characteristics**

Table 2-118 • HSTL Class I

Commercial Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 1.4$  V,  $V_{REF} = 0.75$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	3.18	0.04	2.12	0.43	3.24	3.14			5.47	5.38	ns
<b>-1</b>	0.56	2.70	0.04	1.81	0.36	2.75	2.67			4.66	4.58	ns
-2	0.49	2.37	0.03	1.59	0.32	2.42	2.35			4.09	4.02	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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#### **HSTL Class II**

High-Speed Transceiver Logic is a general-purpose high-speed 1.5 V bus standard (EIA/JESD8-6). Fusion devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-119 • Minimum and Maximum DC Input and Output Levels

HSTL Class II	\	/ <sub>IL</sub>	VIH	ı	V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
15 mA <sup>3</sup>	-0.3	V <sub>REF</sub> - 0.1	V <sub>REF</sub> + 0.1	3.6	0.4	V <sub>CCI</sub> – 0.4	15	15	55	66	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.
- 3. Output drive strength is below JEDEC specification.

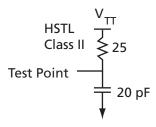


Figure 2-105 • AC Loading

Table 2-120 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> – 0.1	V <sub>REF</sub> + 0.1	0.75	0.75	0.75	20

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

#### **Timing Characteristics**

Table 2-121 • HSTL Class II

Commercial-Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 1.4$  V,  $V_{REF} = 0.75$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	3.02	0.04	2.12	0.43	3.08	2.71			5.32	4.95	ns
-1	0.56	2.57	0.04	1.81	0.36	2.62	2.31			4.52	4.21	ns
-2	0.49	2.26	0.03	1.59	0.32	2.30	2.03			3.97	3.70	ns

Note: For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

#### SSTL2 Class I

Stub-Speed Terminated Logic for 2.5 V memory bus standard (JESD8-9). Fusion devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-122 • Minimum and Maximum DC Input and Output Levels

SSTL2 Class I	'	V <sub>IL</sub>	V	н	V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
Drive Strength	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
15 mA	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	0.54	V <sub>CCI</sub> – 0.62	15	15	87	83	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

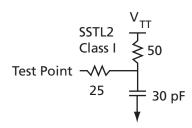


Figure 2-106 • AC Loading

Table 2-123 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> – 0.2	V <sub>REF</sub> + 0.2	1.25	1.25	1.25	30

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-124 • SSTL 2 Class I

Commercial-Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 2.3$  V,  $V_{REF} = 1.25$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.13	0.04	1.33	0.43	2.17	1.85			4.40	4.08	ns
-1	0.56	1.81	0.04	1.14	0.36	1.84	1.57			3.74	3.47	ns
-2	0.49	1.59	0.03	1.00	0.32	1.62	1.38			3.29	3.05	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# SSTL2 Class II

Stub-Speed Terminated Logic for 2.5 V memory bus standard (JESD8-9). Fusion devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-125 • Minimum and Maximum DC Input and Output Levels

SSTL2 Class II	,	V <sub>IL</sub>	VII	I	V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	Ι <sub>Ι</sub>	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
18 mA	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	0.35	V <sub>CCI</sub> – 0.43	18	18	124	169	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

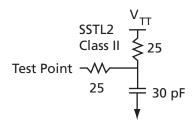


Figure 2-107 • AC Loading

Table 2-126 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> - 0.2	V <sub>REF</sub> + 0.2	1.25	1.25	1.25	30

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-127 • SSTL 2 Class II

Commercial Case Conditions:  $T_J = 70$ °C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 2.3$  V,  $V_{REF} = 1.25$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.17	0.04	1.33	0.43	2.21	1.77			4.44	4.01	ns
-1	0.56	1.84	0.04	1.14	0.36	1.88	1.51			3.78	3.41	ns
-2	0.49	1.62	0.03	1.00	0.32	1.65	1.32			3.32	2.99	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

#### SSTL3 Class I

Stub-Speed Terminated Logic for 3.3 V memory bus standard (JESD8-8). Fusion devices support Class I. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-128 • Minimum and Maximum DC Input and Output Levels

SSTL3 Class I	\	/ <sub>IL</sub>	VI	н	V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	∄	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
14 mA	-0.3	$V_{REF} - 0.2$	$V_{REF} + 0.2$	3.6	0.7	V <sub>CCI</sub> – 1.1	14	14	54	51	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

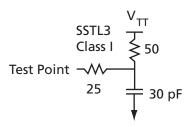


Figure 2-108 • AC Loading

Table 2-129 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> - 0.2	V <sub>REF</sub> + 0.2	1.5	1.5	1.485	30

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# **Timing Characteristics**

Table 2-130 • SSTL3 Class I

Commercial Case Conditions:  $T_J = 70$ °C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 3.0$  V,  $V_{REF} = 1.5$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.31	0.04	1.25	0.43	2.35	1.84			4.59	4.07	ns
<b>-</b> 1	0.56	1.96	0.04	1.06	0.36	2.00	1.56			3.90	3.46	ns
-2	0.49	1.72	0.03	0.93	0.32	1.75	1.37			3.42	3.04	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# SSTL3 Class II

Stub-Speed Terminated Logic for 3.3 V memory bus standard (JESD8-8). Fusion devices support Class II. This provides a differential amplifier input buffer and a push-pull output buffer.

Table 2-131 • Minimum and Maximum DC Input and Output Levels

SSTL3 Class II	\	/ <sub>IL</sub>	VII	н	V <sub>OL</sub>	V <sub>OH</sub>	I <sub>OL</sub>	I <sub>OH</sub>	I <sub>OSL</sub>	I <sub>OSH</sub>	I <sub>IL</sub>	I <sub>IH</sub>
<b>Drive Strength</b>	Min, V	Max, V	Min, V	Max, V	Max, V	Min, V	mA	mA	Max, mA <sup>1</sup>	Max, mA <sup>1</sup>	μA <sup>2</sup>	μA <sup>2</sup>
21 mA	-0.3	V <sub>REF</sub> – 0.2	V <sub>REF</sub> + 0.2	3.6	0.5	V <sub>CCI</sub> – 0.9	21	21	109	103	10	10

#### Notes:

- 1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
- 2. Currents are measured at 85°C junction temperature.

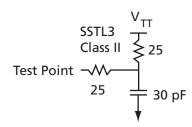


Figure 2-109 • AC Loading

Table 2-132 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)	V <sub>TT</sub> (Typ) (V)	C <sub>LOAD</sub> (pF)
V <sub>REF</sub> – 0.2	V <sub>REF</sub> + 0.2	1.5	1.5	1.485	30

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

#### **Timing Characteristics**

Table 2-133 • SSTL3- Class II

Commercial-Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 3.0$  V,  $V_{REF} = 1.5$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	t <sub>EOUT</sub>	t <sub>ZL</sub>	t <sub>ZH</sub>	t <sub>LZ</sub>	t <sub>HZ</sub>	t <sub>ZLS</sub>	t <sub>ZHS</sub>	Units
Std.	0.66	2.07	0.04	1.25	0.43	2.10	1.67			4.34	3.91	ns
<b>-</b> 1	0.56	1.76	0.04	1.06	0.36	1.79	1.42			3.69	3.32	ns
-2	0.49	1.54	0.03	0.93	0.32	1.57	1.25			3.24	2.92	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# Differential I/O Characteristics

Configuration of the I/O modules as a differential pair is handled by the Actel Designer software when the user instantiates a differential I/O macro in the design.

Differential I/Os can also be used in conjunction with the embedded Input Register (InReg), Output Register (OutReg), Enable Register (EnReg), and Double Data Rate (DDR). However, there is no support for bidirectional I/Os or tristates with these standards.

#### LVDS

Low-Voltage Differential Signal (ANSI/TIA/EIA-644) is a high-speed, differential I/O standard. It requires that one

data bit is carried through two signal lines; so two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-110. The building blocks of the LVDS transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVPECL implementation, because the output standard specifications are different.

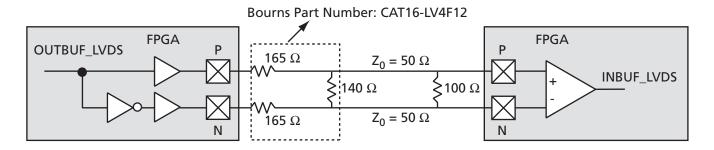


Figure 2-110 • LVDS Circuit Diagram and Board-Level Implementation

Table 2-134 • Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Тур.	Max.	Units
V <sub>CCI</sub>	Supply Voltage	2.375	2.5	2.625	V
V <sub>OL</sub>	Output Low Voltage	0.9	1.075	1.25	V
V <sub>OH</sub>	Output High Voltage	1.25	1.425	1.6	V
V <sub>I</sub>	Input Voltage	0		2.925	V
V <sub>ODIFF</sub>	Differential Output Voltage	250	350	450	mV
V <sub>OCM</sub>	Output Common Mode Voltage	1.125	1.25	1.375	V
V <sub>ICM</sub>	Input Common Mode Voltage	0.05	1.25	2.35	V
V <sub>IDIFF</sub>	Input Differential Voltage	100	350		mV

#### Notes:

- 1. +/- 5%
- 2. Differential input voltage = +/-350 mV

Table 2-135 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)
1.075	1.325	Cross point	_

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

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# **Timing Characteristics**

Table 2-136 • LVDS

Commercial Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 2.3$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	0.66	2.10	0.04	2.02	ns
-1	0.56	1.79	0.04	1.72	ns
-2	0.49	1.57	0.03	1.51	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

#### **BLVDS/M-LVDS**

Bus LVDS (BLVDS) and Multi-Point LVDS (M-LVDS) specifications extend the existing LVDS standard to high-performance multi-point bus applications. Multidrop and multi-point bus configurations may contain any combination of drivers, receivers and transceivers. Actel LVDS drivers provide the higher drive current required by BLVDS and M-LVDS to accommodate the loading. The driver requires series terminations for better signal quality and to control voltage swing. Termination is also required at both ends of the bus since the driver can be located anywhere on the bus. These configurations can

be implemented using TRIBUF\_LVDS and BIBUF\_LVDS macros along with appropriate terminations. Multi-point designs using Actel LVDS macros can achieve up to 200 MHz with a maximum of 20 loads. A sample application is given in Figure 2-111. The input and output buffer delays are available in the LVDS section in Table 2-136.

Example: For a bus consisting of 20 equidistant loads, the following terminations provide the required differential voltage, in worst case Industrial operating conditions, at the farthest receiver:  $R_S=60~\Omega$  and  $R_T=70~\Omega$ , given  $Z_0=50~\Omega$  (2") and a  $Z_{stub}=50~\Omega$  (~1.5").

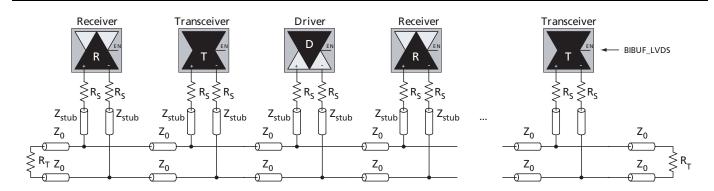


Figure 2-111 • BLVDS/M-LVDS Multi-Point Application Using LVDS I/O Buffers

#### **LVPECL**

Low-Voltage Positive Emitter-Coupled Logic (LVPECL) is another differential I/O standard. It requires that one data bit is carried through two signal lines. Like LVDS, two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-112. The

building blocks of the LVPECL transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVDS implementation, because the output standard specifications are different.

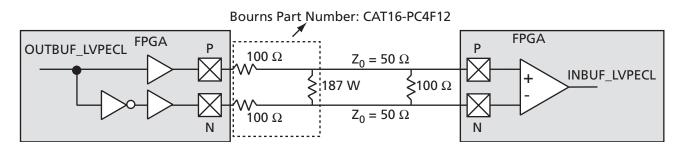


Figure 2-112 • LVPECL Circuit Diagram and Board-Level Implementation

Table 2-137 • Minimum and Maximum DC Input and Output Levels

DC Parameter	Description	Min.	Мах.	Min.	Мах.	Min.	Мах.	Units
V <sub>CCI</sub>	Supply Voltage	3	.0	3	.3	3	.6	V
V <sub>OL</sub>	Output Low Voltage	0.96	1.27	1.06	1.43	1.30	1.57	V
V <sub>OH</sub>	Output High Voltage	1.8	2.11	1.92	2.28	2.13	2.41	V
$V_{IL}$ , $V_{IH}$	Input Low, Input High voltages	0	3.3	0	3.6	0	3.9	V
V <sub>ODIFF</sub>	Differential Output Voltage	0.625	0.97	0.625	0.97	0.625	0.97	V
V <sub>OCM</sub>	Output Common Mode Voltage	1.762	1.98	1.762	1.98	1.762	1.98	V
V <sub>ICM</sub>	Input Common Mode Voltage	1.01	2.57	1.01	2.57	1.01	2.57	V
V <sub>IDIFF</sub>	Input Differential Voltage	300		300		300		mV

*Table 2-138* • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	V <sub>REF</sub> (Typ) (V)
1.64	1.94	Cross point	_

**Note:** \*Measuring point =  $V_{trip}$ . See Table 2-75 on page 2-128 for a complete table of trip points.

# Timing Characteristics

Table 2-139 • LVPECL

Commercial Case Conditions:  $T_J = 70^{\circ}$ C, Worst Case  $V_{CC} = 1.425$  V, Worst Case  $V_{CCI} = 3.0$  V

Speed Grade	t <sub>DOUT</sub>	t <sub>DP</sub>	t <sub>DIN</sub>	t <sub>PY</sub>	Units
Std.	0.66	2.14	0.04	1.75	ns
-1	0.56	1.82	0.04	1.49	ns
-2	0.49	1.60	0.03	1.31	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# I/O Register Specifications Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

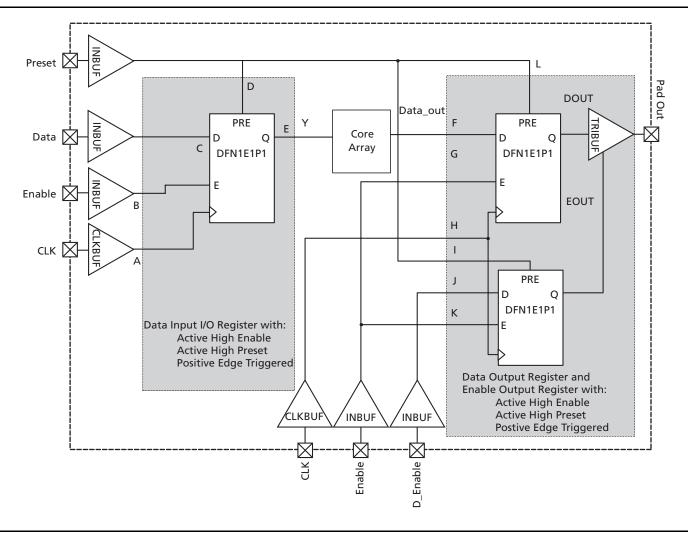


Figure 2-113 • Timing Model of Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

Table 2-140 • Parameter Definition and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (From, To)*
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	H, DOUT
t <sub>OSUD</sub>	Data Setup time for the Output Data Register	F, H
t <sub>OHD</sub>	Data Hold time for the Output Data Register	F, H
t <sub>OSUE</sub>	Enable Setup time for the Output Data Register	G, H
t <sub>OHE</sub>	Enable Hold time for the Output Data Register	G, H
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	L,DOUT
t <sub>OREMPRE</sub>	Asynchronous Preset removal time for the Output Data Register	L, H
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery time for the Output Data Register	L, H
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	H, EOUT
t <sub>OESUD</sub>	Data Setup time for the Output Enable Register	J, H
t <sub>OEHD</sub>	Data Hold time for the Output Enable Register	J, H
t <sub>OESUE</sub>	Enable Setup time for the Output Enable Register	К, Н
t <sub>OEHE</sub>	Enable Hold time for the Output Enable Register	К, Н
t <sub>OEPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Enable Register	I, EOUT
t <sub>OEREMPRE</sub>	Asynchronous Preset Removal time for the Output Enable Register	I, H
t <sub>OERECPRE</sub>	Asynchronous Preset Recovery time for the Output Enable Register	I, H
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	A, E
t <sub>ISUD</sub>	Data Setup time for the Input Data Register	C, A
t <sub>IHD</sub>	Data Hold time for the Input Data Register	C, A
t <sub>ISUE</sub>	Enable Setup time for the Input Data Register	B, A
t <sub>IHE</sub>	Enable Hold time for the Input Data Register	B, A
t <sub>IPRE2Q</sub>	Asynchronous Preset-to-Q of the Input Data Register	D, E
t <sub>IREMPRE</sub>	Asynchronous Preset Removal time for the Input Data Register	D, A
t <sub>IRECPRE</sub>	Asynchronous Preset Recovery time for the Input Data Register	D, A

**Note:** \*See Figure 2-113 on page 2-157 for more information.

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# Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Clear

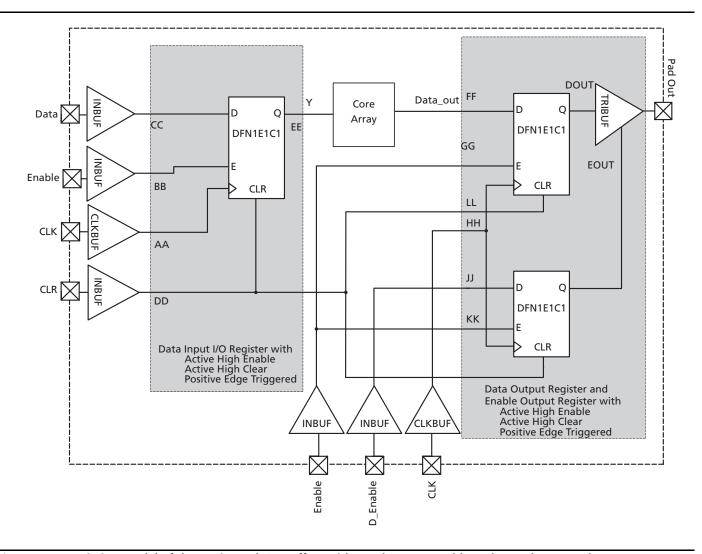


Figure 2-114 • Timing Model of the Registered I/O Buffers with Synchronous Enable and Asynchronous Clear

Table 2-141 • Parameter Definition and Measuring Nodes

Parameter Name	Parameter Definition	Measuring Nodes (From, To)*
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	HH, DOUT
t <sub>OSUD</sub>	Data Setup time for the Output Data Register	FF, HH
t <sub>OHD</sub>	Data Hold time for the Output Data Register	FF, HH
t <sub>OSUE</sub>	Enable Setup time for the Output Data Register	GG, HH
t <sub>OHE</sub>	Enable Hold time for the Output Data Register	GG, HH
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	LL, DOUT
t <sub>OREMCLR</sub>	Asynchronous Clear Removal time for the Output Data Register	LL, HH
t <sub>ORECCLR</sub>	Asynchronous Clear Recovery time for the Output Data Register	LL, HH
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	HH, EOUT
t <sub>OESUD</sub>	Data Setup time for the Output Enable Register	JJ, HH
t <sub>OEHD</sub>	Data Hold time for the Output Enable Register	JJ, HH
t <sub>OESUE</sub>	Enable Setup time for the Output Enable Register	KK, HH
t <sub>OEHE</sub>	Enable Hold time for the Output Enable Register	KK, HH
t <sub>OECLR2Q</sub>	Asynchronous Clear-to-Q of the Output Enable Register	II, EOUT
t <sub>OEREMCLR</sub>	Asynchronous Clear Removal time for the Output Enable Register	II, HH
t <sub>OERECCLR</sub>	Asynchronous Clear Recovery time for the Output Enable Register	II, HH
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	AA, EE
t <sub>ISUD</sub>	Data Setup time for the Input Data Register	CC, AA
t <sub>IHD</sub>	Data Hold time for the Input Data Register	CC, AA
t <sub>ISUE</sub>	Enable Setup time for the Input Data Register	BB, AA
t <sub>IHE</sub>	Enable Hold time for the Input Data Register	BB, AA
t <sub>ICLR2Q</sub>	Asynchronous Clear-to-Q of the Input Data Register	DD, EE
t <sub>IREMCLR</sub>	Asynchronous Clear Removal time for the Input Data Register	DD, AA
t <sub>IRECCLR</sub>	Asynchronous Clear Recovery time for the Input Data Register	DD, AA

**Note:** \*See Figure 2-114 on page 2-159 for more information.

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# **Input Register**

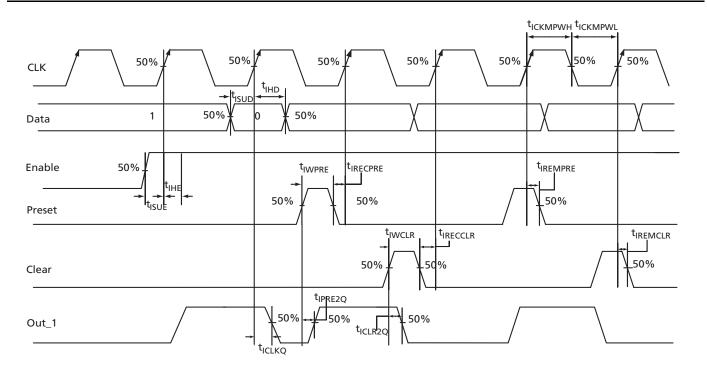


Figure 2-115 • Input Register Timing Diagram

# **Timing Characteristics**

Table 2-142 • Input Data Register Propagation Delays
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>ICLKQ</sub>	Clock-to-Q of the Input Data Register	0.63	0.71	0.84	ns
t <sub>ISUD</sub>	Data Setup time for the Input Data Register	0.43	0.49	0.57	ns
t <sub>IHD</sub>	Data Hold time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>ISUE</sub>	Enable Setup time for the Input Data Register	0.43	0.49	0.57	ns
t <sub>IHE</sub>	Enable Hold time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>ICLR2Q</sub>	Asynchronous Clear-to-Q of the Input Data Register	0.63	0.71	0.84	ns
t <sub>IPRE2Q</sub>	Asynchronous Preset-to-Q of the Input Data Register	0.45	0.51	0.60	ns
t <sub>IREMCLR</sub>	Asynchronous Clear Removal time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>IRECCLR</sub>	Asynchronous Clear Recovery time for the Input Data Register	0.22	0.25	0.30	ns
t <sub>IREMPRE</sub>	Asynchronous Preset Removal time for the Input Data Register	0.00	0.00	0.00	ns
t <sub>IRECPRE</sub>	Asynchronous Preset Recovery time for the Input Data Register	0.22	0.25	0.30	ns
t <sub>IWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.25	0.28	0.33	ns
t <sub>IWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.25	0.28	0.33	ns
t <sub>ICKMPWH</sub>	Clock Minimum Pulse Width High for the Input Data Register	0.36	0.41	0.48	ns
t <sub>ICKMPWL</sub>	Clock Minimum Pulse Width Low for the Input Data Register	0.41	0.46	0.54	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# **Output Register**

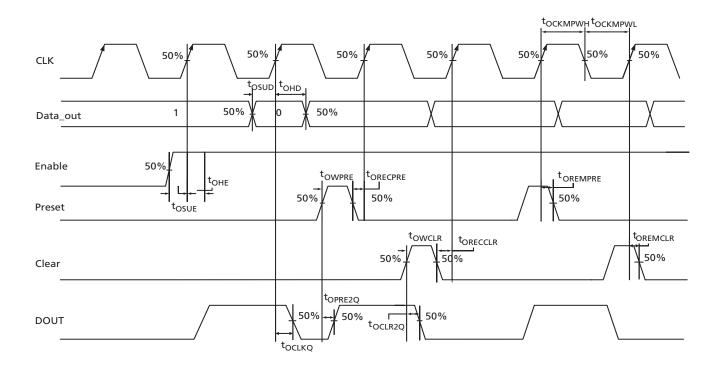


Figure 2-116 • Output Register Timing Diagram

# **Timing Characteristics**

Table 2-143 • Output Data Register Propagation Delays
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>OCLKQ</sub>	Clock-to-Q of the Output Data Register	0.63	0.71	0.84	ns
t <sub>OSUD</sub>	Data Setup time for the Output Data Register	0.43	0.49	0.57	ns
t <sub>OHD</sub>	Data Hold time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>OSUE</sub>	Enable Setup time for the Output Data Register	0.43	0.49	0.57	ns
t <sub>OHE</sub>	Enable Hold time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>OCLR2Q</sub>	Asynchronous Clear-to-Q of the Output Data Register	0.63	0.71	0.84	ns
t <sub>OPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Data Register	0.45	0.51	0.60	ns
t <sub>OREMCLR</sub>	Asynchronous Clear Removal time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>ORECCLR</sub>	Asynchronous Clear Recovery time for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OREMPRE</sub>	Asynchronous Preset Removal time for the Output Data Register	0.00	0.00	0.00	ns
t <sub>ORECPRE</sub>	Asynchronous Preset Recovery time for the Output Data Register	0.22	0.25	0.30	ns
t <sub>OWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.25	0.28	0.33	ns
t <sub>OWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.25	0.28	0.33	ns
t <sub>OCKMPWH</sub>	Clock Minimum Pulse Width High for the Output Data Register	0.36	0.41	0.48	ns
t <sub>OCKMPWL</sub>	Clock Minimum Pulse Width Low for the Output Data Register	0.41	0.46	0.54	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# **Output Enable Register**

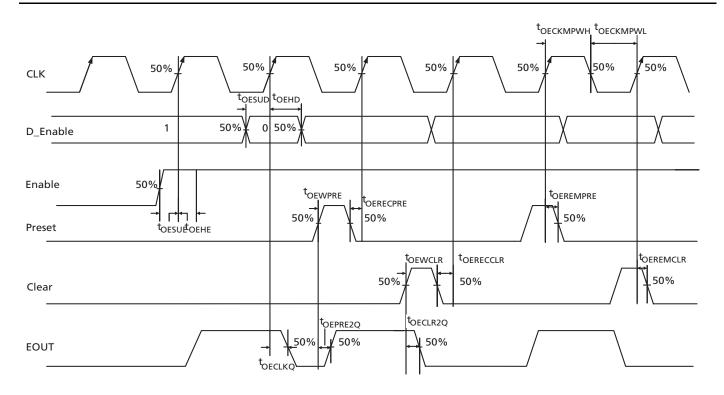


Figure 2-117 • Output Enable Register Timing Diagram

# **Timing Characteristics**

Table 2-144 • Output Enable Register Propagation Delays
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>OECLKQ</sub>	Clock-to-Q of the Output Enable Register	0.63	0.71	0.84	ns
t <sub>OESUD</sub>	Data Setup time for the Output Enable Register	0.43	0.49	0.57	ns
t <sub>OEHD</sub>	Data Hold time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OESUE</sub>	Enable Setup time for the Output Enable Register	0.43	0.49	0.57	ns
t <sub>OEHE</sub>	Enable Hold time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OECLR2Q</sub>	Asynchronous Clear-to-Q of the Output Enable Register	0.63	0.71	0.84	ns
t <sub>OEPRE2Q</sub>	Asynchronous Preset-to-Q of the Output Enable Register	0.45	0.51	0.60	ns
t <sub>OEREMCLR</sub>	Asynchronous Clear Removal time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OERECCLR</sub>	Asynchronous Clear Recovery time for the Output Enable Register	0.22	0.25	0.30	ns
t <sub>OEREMPRE</sub>	Asynchronous Preset Removal time for the Output Enable Register	0.00	0.00	0.00	ns
t <sub>OERECPRE</sub>	Asynchronous Preset Recovery time for the Output Enable Register	0.22	0.25	0.30	ns
t <sub>OEWCLR</sub>	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.25	0.28	0.33	ns
t <sub>OEWPRE</sub>	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.25	0.28	0.33	ns
t <sub>OECKMPWH</sub>	Clock Minimum Pulse Width High for the Output Enable Register	0.36	0.41	0.48	ns
t <sub>OECKMPWL</sub>	Clock Minimum Pulse Width Low for the Output Enable Register	0.41	0.46	0.54	ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# DDR Module Specifications Input DDR Module

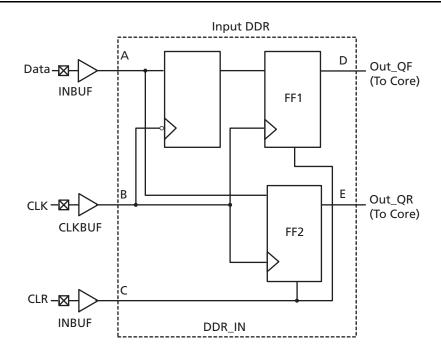


Figure 2-118 • Input DDR Timing Model

*Table 2-145* • Parameter Definitions

Parameter Name	Parameter Definition	Measuring Nodes (From, To)
t <sub>DDRICLKQ1</sub>	Clock-to-Out Out_QR	B, D
t <sub>DDRICLKQ2</sub>	Clock-to-Out Out_QF	B, E
t <sub>DDRISUD</sub>	Data Setup time of DDR input	А, В
t <sub>DDRIHD</sub>	Data Hold time of DDR input	А, В
t <sub>DDRICLR2Q1</sub>	Clear-to-Out Out_QR	C, D
t <sub>DDRICLR2Q2</sub>	Clear-to-Out Out_QF	C, E
t <sub>DDRIREMCLR</sub>	Clear Removal	С, В
† <sub>DDRIRECCLR</sub>	Clear Recovery	С, В

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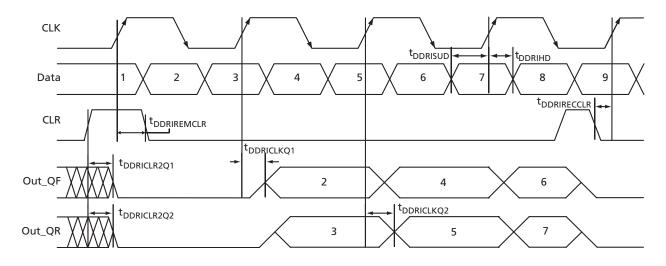


Figure 2-119 • Input DDR Timing Diagram

# **Timing Characteristics**

Table 2-146 • Input DDR Propagation Delays
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>DDRICLKQ1</sub>	Clock-to-Out Out_QR for Input DDR	0.63	0.71	0.84	ns
t <sub>DDRICLKQ2</sub>	Clock-to-Out Out_QF for Input DDR	0.57	0.65	0.76	ns
t <sub>DDRISUD</sub>	Data Setup for Input DDR	0.53	0.61	0.71	ns
t <sub>DDRIHD</sub>	Data Hold for Input DDR	0.00	0.00	0.00	ns
t <sub>DDRICLR2Q1</sub>	Asynchronous Clear to Out Out_QR for Input DDR	0.57	0.65	0.76	ns
t <sub>DDRICLR2Q2</sub>	Asynchronous Clear-to-Out Out_QF for Input DDR	0.57	0.65	0.76	ns
t <sub>DDRIREMCLR</sub>	Asynchronous Clear Removal time for Input DDR	0.00	0.00	0.00	ns
t <sub>DDRIRECCLR</sub>	Asynchronous Clear Recovery time for Input DDR	0.22	0.25	0.30	ns
t <sub>DDRIWCLR</sub>	Asynchronous Clear Minimum Pulse Width for Input DDR				ns
t <sub>DDRICKMPWH</sub>	Clock Minimum Pulse Width High for Input DDR				ns
t <sub>DDRICKMPWL</sub>	Clock Minimum Pulse Width Low for Input DDR				ns
F <sub>DDRIMAX</sub>	Maximum Frequency for Input DDR				MHz

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# **Output DDR**

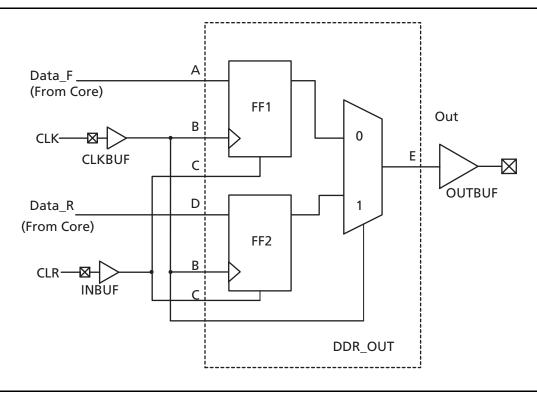


Figure 2-120 • Output DDR Timing Model

**Table 2-147 • Parameter Definitions** 

Parameter Name	Parameter Definition	Measuring Nodes (From, To)
t <sub>DDROCLKQ</sub>	Clock-to-Out	B, E
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out	C, E
t <sub>DDROREMCLR</sub>	Clear Removal	С, В
t <sub>DDRORECCLR</sub>	Clear Recovery	С, В
t <sub>DDROSUD1</sub>	Data Setup Data_F	А, В
t <sub>DDROSUD2</sub>	Data Setup Data_R	D, B
t <sub>DDROHD1</sub>	Data Hold Data_F	А, В
t <sub>DDROHD2</sub>	Data Hold Data_R	D, B

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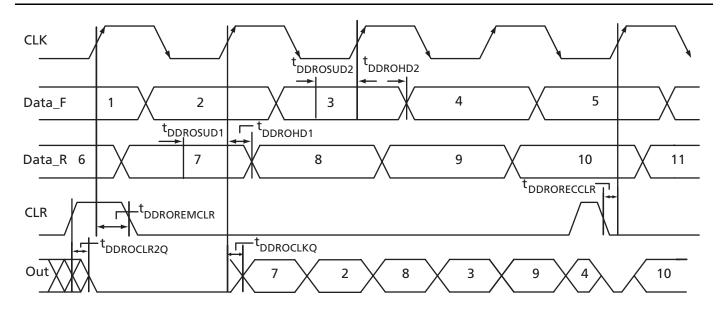


Figure 2-121 • Output DDR Timing Diagram

### **Timing Characteristics**

Table 2-148 • Output DDR Propagation Delays
Commercial Case Conditions: T<sub>J</sub> = 70°C, Worst Case V<sub>CC</sub> = 1.425 V

Parameter	Description	-2	-1	Std.	Units
t <sub>DDROCLKQ</sub>	Clock-to-Out of DDR for Output DDR	0.63	0.71	0.84	ns
t <sub>DDROSUD1</sub>	Data_F Data Setup for Output DDR	0.43	0.49	0.57	ns
t <sub>DDROSUD2</sub>	Data_R Data Setup for Output DDR	0.43	0.49	0.57	ns
t <sub>DDROHD1</sub>	Data_F Data Hold for Output DDR	0.00	0.00	0.00	ns
t <sub>DDROHD2</sub>	Data_R Data Hold for Output DDR	0.00	0.00	0.00	ns
t <sub>DDROCLR2Q</sub>	Asynchronous Clear-to-Out for Output DDR		0.65	0.76	ns
t <sub>DDROREMCLR</sub>	Asynchronous Clear Removal time for Output DDR		0.00	0.00	ns
t <sub>DDRORECCLR</sub>	Asynchronous Clear Recovery time for Output DDR	0.22	0.25	0.30	ns
t <sub>DDROWCLR1</sub>	Asynchronous Clear Minimum Pulse Width for Output DDR				ns
t <sub>DDROCKMPWH</sub>	Clock Minimum Pulse Width High for the Output DDR				ns
t <sub>DDROCKMPWL</sub>	Clock Minimum Pulse Width Low for the Output DDR				ns
F <sub>DDOMAX</sub>	Maximum Frequency for the Output DDR				MHz

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

# **Pin Descriptions**

### **Supply Pins**

#### GND Ground

Ground supply voltage to the core, I/O outputs, and I/O logic.

#### GNDQ Ground (quiet)

Quiet ground supply voltage to input buffers of I/O banks. Within the package, the GNDQ plane is decoupled from the simultaneous switching noise originated from the output buffer ground domain. This minimizes the noise transfer within the package, and improves input signal integrity. GNDQ needs to always be connected on the board to GND.

#### ADCGNDREF Analog Reference Ground

Analog ground reference used by the ADC. This pad should be connected to a quiet analog ground.

#### GNDA Ground (analog)

Quiet ground supply voltage to the Analog Block of the Fusion devices. The use of a separate analog ground helps isolate the analog functionality of the Fusion device from any digital switching noise.

#### GNDAQ Ground (analog quiet)

Quiet ground supply voltage to the analog I/O of the Fusion devices. The use of a separate analog ground helps isolate the analog functionality of the Fusion device from any digital switching noise.

#### GNDNVM Flash Memory Ground

Ground supply used by the Fusion device's Flash memory block module(s).

#### GNDOSC Oscillator Ground

Ground supply for both integrated RC oscillator and crystal oscillator circuit.

#### V<sub>CC15A</sub> Analog Power Supply (1.5 V)

1.5 V clean analog power supply input for use by the 1.5 V portion of the analog circuitry.

### V<sub>CC33A</sub> Analog Power Supply (3.3 V)

3.3 V clean analog power supply input for use by the 3.3 V portion of the analog circuitry.

#### V<sub>CC33N</sub> Negative 3.3 V output

VOLTAGE CONVERTER OUTPUT is the -3.3 V output from the voltage converter. A 2.2  $\mu$ F capacitor must be connected from this pin to ground.

#### V<sub>CC33PMP</sub> Analog Power Supply (3.3 V)

3.3 V clean analog power supply input for use by the analog charge pump. To avoid high current draw,  $V_{\text{CC33PMP}}$  should be powered up before or simultaneously with  $V_{\text{CC33A}}$ .

# V<sub>CCNVM</sub> Flash Memory Block Power Supply (1.5 V)

1.5 V power supply used by the Fusion device's Flash memory block module(s). To avoid high current draw  $V_{CC}$  should be powered up before or simultaneously with  $V_{CCNVM}$ .

#### V<sub>CCOSC</sub> Oscillator Power Supply (3.3 V)

Power supply for both integrated RC oscillator and crystal oscillator circuit.

#### V<sub>CC</sub> Core Supply Voltage

Supply voltage to the FPGA core, nominal 1.5 V.  $V_{CC}$  is also required for powering the JTAG state machine in addition to  $V_{JTAG}$ . Even when a Fusion device is in bypass mode in a JTAG chain of interconnected devices, both  $V_{CC}$  and  $V_{JTAG}$  must remain powered to allow JTAG signals to pass through the Fusion device.

#### V<sub>CCI</sub>Bx I/O Supply Voltage

Supply voltage to the bank's I/O output buffers and I/O logic. Bx is the I/O bank number. There are either 4 (AFS090 and AFS250) or 5 (AFS600 and AFS1500) I/O banks on the Fusion devices plus a dedicated  $V_{JTAG}$  bank. Each bank can have a separate  $V_{CCI}$  connection. All I/Os in a bank will run off the same  $V_{CCI}$ Bx supply.  $V_{CCI}$  can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V nominal voltage. Unused I/O banks should have their corresponding  $V_{CCI}$  pins tied to GND.

#### VMVx I/O Supply Voltage (quiet)

Quiet supply voltage to the input buffers of each I/O bank. X is the bank number. Within the package, the VMV plane is decoupled from the simultaneous switching noise originated from the output buffer V<sub>CCI</sub> domain. This minimizes the noise transfer within the package, and improves input signal integrity. Each bank must have at least one VMV connection. All I/Os in a bank run off the same VMVx supply. VMV is used to provide a quiet supply voltage to the input buffers of each I/O bank. VMVx can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V nominal voltage. Unused I/O banks should have their corresponding VMV and V<sub>CCI</sub> pins tied to GND. VMV and V<sub>CCI</sub> must be connected to the same power supply and V<sub>CCI</sub> pins within a given I/O bank. Used VMV pins must be connected to the corresponding V<sub>CCI</sub> pins of the same bank (i.e., VMV0 to  $V_{CCI}B0$ , VMV1 to  $V_{CCI}B1$ , etc.).

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#### V<sub>CCPLA/B</sub> PLL Supply Voltage

Supply voltage to analog PLL, nominal 1.5 V, where A and B refer to the PLL. The AFS090 and AFS250 each have a single PLL. The AFS600 and AFS1500 devices each have two PLLs. If unused,  $V_{\text{CCPLA/B}}$  should be tied to GND.

### V<sub>COMPLF</sub> PLL Ground8

Ground to analog PLL, where A and B refer to the PLL. The AFS090 and AFS250 each have a single PLL. The AFS600 and AFS1500 devices each have two PLLs. Unused  $V_{COMPLF}$  pin should be connected to GND.

#### V<sub>JTAG</sub> JTAG Supply Voltage

Fusion devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). Isolating the JTAG power supply in a separate I/O bank gives greater flexibility with supply selection and simplifies power supply and printed circuit board design. If the JTAG interface is not used nor planned to be used, the V<sub>JTAG</sub> pin together with the TRST pin could be tied to GND. It should be noted that V<sub>CC</sub> is required to be powered for JTAG operation; V<sub>JTAG</sub> alone is insufficient. If a Fusion device is in a JTAG chain of interconnected boards, and it is desired to power down the board containing the Fusion device, this may be done provided both V<sub>JTAG</sub> and V<sub>CC</sub> to the Fusion part remain powered; otherwise, JTAG signals will not be able to transition the Fusion device, even in bypass mode.

#### V<sub>PUMP</sub> Programming Supply Voltage

Fusion devices support single-voltage ISP programming of the configuration Flash and FlashROM. For programming, V<sub>PUMP</sub> should be 3.3 V nominal. During normal device operation, V<sub>PUMP</sub> can be left floating or can be tied (pulled up) to any voltage between 0 V and 3.6 V.

# **User-Defined Supply Pins**

#### V<sub>REF</sub> I/O Voltage Reference

Reference voltage for I/O minibanks. Both the AFS600 (north bank only) and AFS1500 (all digital I/O banks) support Actel Pro I/O. These I/O banks support voltage reference standard I/O. The V<sub>REF</sub> pins are configured by the user from regular I/Os, and any I/O in a bank, except JTAG I/Os, which can be designated as the voltage reference I/O. Only certain I/O standards require a voltage reference – HSTL (I) and (II), SSTL2 (I) and (II), SSTL3 (I) and (II), and GTL/GTL+. One V<sub>REF</sub> pin can support the number of I/Os available in its minibank.

#### VAREF Analog Reference Voltage

Analog reference voltage to be used by analog to digital converter. The Fusion device provides a 2.56 V internal reference voltage that can be used by the ADC. Optionally this voltage can be configured to be brought

out on this pin for use by the system. The pin in this can would either open or 2.56 V output.

If a different reference voltage is required, it can be supplied on this pin and used by the ADC. The valid range of values that can be supplied to the ADC is between 1.0 V and 3.3 V.

#### **User Pins**

#### I/O User Input/Output

The I/O pin functions as an input, output, tristate, or bidirectional buffer. Input and output signal levels are compatible with the I/O standard selected. Unused I/O pins are configured as inputs with pull-up resistors.

During programming, I/Os become tristated and weakly pulled up to  $V_{CCI}$ . With  $V_{CCI}$ , VMV and  $V_{CC}$  supplies continuously powered-up, and the device transitions from programming to operating mode, the I/Os get instantly configured to the desired user configuration.

### Axy Analog Input/Output

Analog I/O pin where x is the analog pad type (C = current pad, G = Gate driver pad, T = Temperature pad, V = Voltage pad) and y is the Analog Quad number <math>(0 to 9).

#### ATRTNx Temperature Monitor Return

**AT RETURN** are the returns for the temperature sensors. The cathode terminal of the external diodes should be connected to these pins. There is 1 analog return pin for every two analog quads. The x in the ATRTNx designator indicates the quad pairing (x = 0 for AQ1 and AQ2, x = 1 for AQ2 and AQ3..., x = 4 for AQ8 and AQ9). These signals that drive these pins are called out as ATRETUNxy in the software (where x and y refer to the quads that share the return signal).

#### GL Globals

GL I/Os have access to certain clock conditioning circuitry (and the PLL) and/or have direct access to the global network (spines). Additionally, the global I/Os can be used as Pro I/Os, since they have identical capabilities. Unused GL pins are configured as inputs with pull-up resistors. See more detailed descriptions of global I/O connectivity in the "Clock Conditioning Circuits" section on page 2-22.

Refer to the "User I/O Naming Convention" section on page 2-120 for a description of naming of global pins.

#### **JTAG Pins**

Fusion devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal).  $V_{CC}$  must also be powered in order for the JTAG state machine to operate even if the

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device is in bypass mode;  $V_{JTAG}$  alone is insufficient. Both  $V_{JTAG}$  and  $V_{CC}$  to the Fusion part must be supplied to allow JTAG signals to transition the Fusion device. Isolating the JTAG power supply.

in a separate I/O bank gives greater flexibility with supply selection and simplifies power supply and printed circuit board design. If the JTAG interface is not used nor planned to be used, the V<sub>JTAG</sub> pin together with the TRST pin could be tied to GND.

#### TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/down resistor. If JTAG is not used, Actel recommends tying off TCK to GND or V<sub>JTAG</sub> through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all V<sub>JTAG</sub> voltages, 500  $\Omega$  to 1 k $\Omega$  will satisfy the requirements. Refer to Table 2-149 for more information.

Table 2-149 • Recommended Tie-Off Values for the TCK and TRST Pins

V <sub>JTAG</sub>	Tie Off Resistance <sup>2, 3</sup>
V <sub>JTAG</sub> at 3.3 V	200 $\Omega$ to 1 k $\Omega$
V <sub>JTAG</sub> at 2.5 V	200 $\Omega$ to 1 k $\Omega$
V <sub>JTAG</sub> at 1.8 V	500 $\Omega$ to 1 k $\Omega$
V <sub>JTAG</sub> at 1.5 V	500 Ω to 1 kΩ

#### Notes:

- Equivalent parallel resistance if more than one device is on JTAG chain.
- 2. The TCK pin can be pulled-up/down.
- 3. The TRST pin can only be pulled-down.

Note that to operate at all  $V_{JTAG}$  voltages, 500  $\Omega$  to 1  $k\Omega$  will satisfy the requirements.

#### TDI Test Data Input

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

#### TDO Test Data Output

Serial output for JTAG boundary scan, ISP, and UJTAG usage.

#### TMS Test Mode Select

The TMS pin controls the use of the IEEE1532 boundary scan pins (TCK,TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

#### TRST Boundary Scan Reset Pin

The TRST pin functions as an active low input to asynchronously initialize (or reset) the boundary scan

circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the TAP is held in reset mode. The resistor values must be chosen from Table 2-149 and must satisfy the parallel resistance value requirement. The values in Table 2-149 correspond to the resistor recommended when a single device is used and to the equivalent parallel resistor when multiple devices are connected via a JTAG chain.

In critical applications, an upset in the JTAG circuit could allow entering an undesired JTAG state. In such cases, Actel recommends tying off TRST to GND through a resistor placed close to the FPGA pin.

Note that to operate at all V<sub>JTAG</sub> voltages, 500  $\Omega$  to 1  $k\Omega$  will satisfy the requirements.

### **Special Function Pins**

#### NC No Connect

This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.

#### DC Don't Connect

This pin should not be connected to any signals on the printed circuit board (PCB). These pins should be left unconnected.

#### NCAP Negative Capacitor

NEGATIVE CAPACITOR is where the negative terminal of the charge pump capacitor is connected.

#### PCAP Positive Capacitor

**POSITIVE CAPACITOR** is where the positive terminal of the charge pump capacitor is connected.

#### PUB Power Up Bar

**PUSH BUTTON** is the connection for the external momentary switch which is used to turn on the 1.5 V voltage regulator and can be floating if not used.

#### PTBASE Pass Transistor Base

**PASS TRANSISTOR BASE** is the control signal of the voltage regulator. This pin should be connected to the base of the external pass transistor used with the 1.5 V internal voltage regulator and can be floating if not used.

### PTEM Pass Transistor Emitter

**PASS TRANSISTOR EMITTER** is the feedback input of the voltage regulator.

This pin should be connected to the Emitter of the external pass transistor used with the 1.5 V internal voltage regulator and can be floating if not used.

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#### V<sub>CC33ACAP</sub> Analog Power Filter

Analog power pin for the analog power supply low pass filter. An external 1  $\mu F$  capacitor should be connected between this pin and ground.

#### XTAL1 Crystal Oscillator Circuit Input

Input to crystal oscillator circuit. Pin for connecting external crystal, ceramic resonator, RC network, or external clock input. When using an external crystal or ceramic oscillator external capacitors are also recommended (< 2 MHz 100 pF, > 2 MHz – 15 pF).

If using external RC network or clock input, XTAL1 should be used and XTAL2 left unconnected.

#### XTAL2 Crystal Oscillator Circuit Input

Input to crystal oscillator circuit. Pin for connecting external crystal, ceramic resonator, RC network, or external clock input. When using an external crystal or ceramic oscillator external capacitors are also recommended (<2 MHz 100 pF, >2 MHz – 15 pF).

If using external RC network or clock input, XTAL1 should be used and XTAL2 left unconnected.

# **Software Tools and Programming**

#### **Overview of Tools Flow**

The Fusion family of FPGAs is fully supported by both Actel Libero IDE and Designer FPGA Development software. Actel Libero IDE is an integrated design manager that seamlessly integrates design tools while guiding the user through the design flow, managing all design and log files, and passing necessary design data among tools. Additionally, Libero IDE allows users to integrate both schematic and HDL synthesis into a single flow and verify the entire design in a single environment (see the Libero IDE flow diagram located on the Actel website). Libero IDE includes Synplify® AE from Synplicity<sup>®</sup>, ViewDraw<sup>®</sup> AE from Mentor Graphics<sup>®</sup>, ModelSim<sup>®</sup> HDL Simulator from Mentor Graphics, WaveFormer Lite™ AE from SynaptiCAD®, PALACE™ AE Physical Synthesis from Magma Design Automation™, and Designer software from Actel.

Actel Designer software is a place-and-route tool and provides a comprehensive suite of back-end support tools for FPGA development. The Designer software includes the following:

- SmartTime a world-class integrated static timing analyzer and constraints editor that supports timing-driven place-and-route
- NetlistViewer a design netlist schematic viewer
- ChipPlanner a graphical floorplanning viewer and editor

- SmartPower a sophisticated power analysis environment that gives designers the ability to quickly determine the power consumption of an FPGA or its components
- PinEditor a graphical application for editing pin assignments and I/O attributes
- I/O Attribute Editor displays all assigned and unassigned I/O macros and their attributes in a spreadsheet format

With the Designer software, a user can lock the design pins before layout while minimally impacting the results of place-and-route. Additionally, the Actel back-annotation flow is compatible with all the major simulators. Included in the Designer software is SmartGen core generator, which easily creates commonly used logic functions for implementation into your Fusion-based schematic or HDL design.

Actel Designer software is compatible with the most popular FPGA design entry and verification tools from EDA vendors, such as Cadence<sup>®</sup>, Magma<sup>®</sup>, Mentor Graphics, Synopsys, and Synplicity. The Designer software is available for both the Windows<sup>®</sup> and UNIX operating systems.

### **CoreMP7 Software Tools**

CoreConsole is the Intellectual Property Deployment Platform (IDP) that assists the developer in programming the soft ARM (CoreMP7) core onto M7 Fusion devices. CoreConsole provides the seamless environment to work with Libero IDE and Designer FPGA development software tools concurrently.

### Security

Fusion devices have a built-in 128-bit AES decryption core. The decryption core facilitates secure, in-system programming of the FPGA core array fabric and the FlashROM. The FlashROM and the FPGA core fabric can be programmed independently from each other, allowing the FlashROM to be updated without the need for change to the FPGA core fabric. The AES master key is stored in on-chip nonvolatile memory (Flash). The AES master key can be preloaded into parts in a secure programming environment (such as the Actel in-house programming center) and then "blank" parts can be shipped to an untrusted programming or manufacturing center for final personalization with an AES encrypted bitstream. Late stage product changes or personalization can be implemented easily and securely by simply sending a STAPL file with AES encrypted data. Secure remote field updates over public networks (such as the Internet) are possible by sending and programming a STAPL file with AES encrypted data. For more information, refer to the *Fusion Security* application note.

### 128-Bit AES Decryption

The 128-bit AES standard (FIPS-192) block cipher is the National Institute of Standards and Technology (NIST) replacement for the DES (Data Encryption Standard FIPS46-2). AES has been designed to protect sensitive government information well into the 21st century. It replaces the aging DES, which NIST adopted in 1977 as a Federal Information Processing Standard used by federal agencies to protect sensitive, unclassified information. The 128-bit AES standard has 3.4x10<sup>38</sup> possible 128-bit key variants, and it has been estimated that it would take 1,000 trillion years to crack 128-bit AES cipher text using exhaustive techniques. Keys are stored (securely) in Fusion devices in nonvolatile Flash memory. All programming files sent to the device can be authenticated by the part prior to programming to ensure that bad programming data is not loaded into the part that may possibly damage it. All programming verification is performed on-chip, ensuring that the contents of Fusion devices remain secure.

AES decryption can also be used on the 1,024-bit FlashROM to allow for secure remote updates of the FlashROM contents. This allows for easy, secure support for subscription model products.

### **AES for Flash Memory**

AES decryption can also be used on the Flash memory blocks. This allows for the secure update of the Flash memory blocks. During runtime, the encrypted data can be clocked in via the JTAG interface. The data can be passed through the internal AES decryption engine, the decrypted data can then be stored in the Flash memory block.

### **Programming**

Programming can be performed using various programming tools, such as Silicon Sculptor II (BP Micro Systems) or FlashPro3 (Actel).

The user can generate \*.stp programming files from the Designer software and can use these files to program a device.

Fusion devices can be programmed in system.

#### **ISP**

Fusion devices support IEEE 1532 ISP via JTAG and require a single V<sub>PUMP</sub> voltage of 3.3 V during programming. In addition, programming via a Microcontroller (MCU) in a target system can be achieved.

#### JTAG IEEE 1532

#### **Programming with IEEE 1532**

Fusion devices support the JTAG-based IEEE1532 standard for ISP. As part of this support, when a Fusion device is in an

unprogrammed state, all user I/O pins are disabled. This is achieved by keeping the global IO\_EN signal deactivated, which also has the effect of disabling the input buffers. Consequently, the SAMPLE instruction will have no effect while the Fusion device is in this unprogrammed state—different behavior from that of the ProASICPLUS® device family. This is done because SAMPLE is defined in the IEEE1532 specification as a noninvasive instruction. If the input buffers were to be enabled by SAMPLE temporarily turning on the I/Os, then it would not truly be a noninvasive instruction.

### **Boundary Scan**

Fusion devices are compatible with IEEE Standard 1149.1, which defines a hardware architecture and the set of mechanisms for boundary scan testing. The basic Fusion boundary scan logic circuit is composed of the test access port (TAP) controller, test data registers, and instruction register (Figure 2-122 on page 2-173). This circuit supports all mandatory IEEE 1149.1 instructions (EXTEST, SAMPLE/PRELOAD, and BYPASS) and the optional IDCODE instruction (Table 2-151 on page 2-173).

Each test section is accessed through the TAP, which has five associated pins: TCK (test clock input), TDI, TDO (test data input and output), TMS (test mode selector), and TRST (test reset input). TMS, TDI, and TRST are equipped with pull-up resistors to ensure proper operation when no input data is supplied to them. These pins are dedicated for boundary scan test usage. Refer to the "JTAG Pins" section on page 2-169 for pull-up/down recommendations for TDO and TCK pins. The TAP controller is a 4-bit state machine (16 states) that operates as shown in Figure 2-122 on page 2-173. The 1s and 0s represent the values that must be present at TMS at a rising edge of TCK for the given state transition to occur. IR and DR indicate that the instruction register or the data register is operating in that state.

**Table 2-150** • TRST and TCK Pull-Down Recommendations

V <sub>JTAG</sub>	Tie-off Resistance*
V <sub>JTAG</sub> at 3.3 V	200 $\Omega$ to 1 k $\Omega$
V <sub>JTAG</sub> at 2.5 V	200 $\Omega$ to 1 k $\Omega$
V <sub>JTAG</sub> at 1.8 V	500 $\Omega$ to 1 k $\Omega$
V <sub>JTAG</sub> at 1.5 V	500 Ω to 1 kΩ

**Note:** \*Equivalent parallel resistance if more than one device is on JTAG chain.

The TAP controller receives two control inputs (TMS and TCK) and generates control and clock signals for the rest of the test logic architecture. On power-up, the TAP controller enters the Test-Logic-Reset state. To guarantee a reset of the controller from any of the possible states, TMS must remain high for five TCK cycles. The TRST pin may also be used to asynchronously place the TAP controller in the Test-Logic-Reset state.

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Fusion devices support three types of test data registers: bypass, device identification, and boundary scan. The bypass register is selected when no other register needs to be accessed in a device. This speeds up test data transfer to other devices in a test data path. The 32-bit device identification register is a shift register with four fields (LSB, ID number, part number, and version). The boundary scan register observes and controls the state of each I/O pin. Each I/O cell has three boundary scan register cells, each with a serial-in, serial-out, parallel-in, and parallel-out pin.

The serial pins are used to serially connect all the boundary scan register cells in a device into a boundary scan register chain, which starts at the TDI pin and ends at the TDO pin. The parallel ports are connected to the internal core logic I/O tile and the input, output, and control ports of an I/O buffer to capture and load data into the register to control or observe the logic state of each I/O.

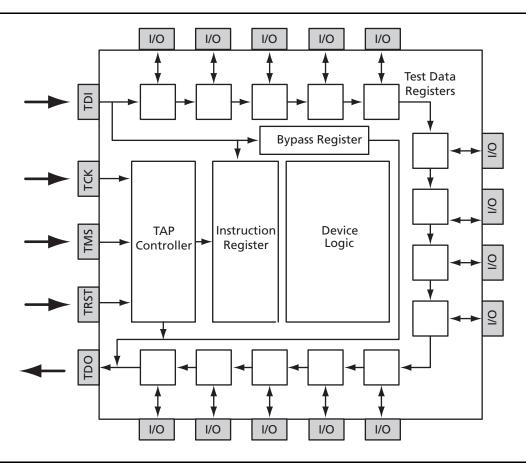


Figure 2-122 • Boundary Scan Chain in Fusion

Table 2-151 • Boundary Scan Opcodes

	Hex Opcode
EXTEST	00
HIGHZ	07
USERCODE	OE
SAMPLE/PRELOAD	01
IDCODE	OF
CLAMP	05
BYPASS	FF

#### **IEEE 1532 Characteristics**

JTAG timing delays do not include JTAG I/Os. To obtain complete JTAG timing, add I/O buffer delays to the corresponding standard selected, refer to the I/O Timing characteristics for more details.

Table 2-152 • JTAG 1532 Commercial Case Conditions:  $T_J = 70^{\circ}\text{C}$ ,  $V_{CC} = 1.425 \text{ V}$ 

Parameter	Description	-2	-1	Std.	Units
t <sub>DISU</sub>	Test Data Input Setup Time				ns
t <sub>DIHD</sub>	Test Data Input Hold Time				ns
t <sub>TMSSU</sub>	Test Mode Select Setup Time				ns
t <sub>TMDHD</sub>	Test Mode Select Hold Time				ns
t <sub>TCK2Q</sub>	Clock to Q (Data Out)				ns
t <sub>RSTB2Q</sub>	Reset to Q (Data Out)				ns
F <sub>TCKMAX</sub>	TCK maximum frequency	20	20	20	MHz
t <sub>TRSTREM</sub>	ResetB Removal time				ns
t <sub>TRSTREC</sub>	ResetB Recovery time				ns
t <sub>TRSTMPW</sub>	ResetB minimum pulse				ns

**Note:** For the derating values at specific junction-temperature and voltage-supply levels, refer to Table 3-7 on page 3-7.

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# **DC and Power Characteristics**

# **General Specifications**

DC and switching characteristics for -F speed grade targets are based only on simulation.

The characteristics provided for –F speed grade are subject to change after establishing FPGA specifications. Some restrictions might be added and will be reflected in future revisions of this document. The –F speed grade is only supported in the commercial temperature range.

# **Operating Conditions**

Stresses beyond those listed in the Table 3-1 may cause permanent damage to the device.

Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Devices should not be operated outside the recommended operating ranges specified in Table 3-2 on page 3-2.

Table 3-1 ● Absolute Maximum Ratings

Symbol	Parameter	Limits	Units		
V <sub>CC</sub>	DC core supply voltage	-0.3 to 1.65			
$V_{JTAG}$	JTAG DC voltage	–0.3 to 3.75	V		
$V_{PUMP}$	Programming voltage	–0.3 to 3.75	V		
$V_{CCPLL}$	Analog power supply (PLL)	–0.3 to 1.65	V		
$V_{CCI}$	DC I/O output buffer supply voltage	–0.3 to 3.75	V		
VMV	DC I/O input buffer supply voltage	–0.3 to 3.75	V		
VI	I/O input voltage	-0.3 V to 3.6 V (when I/O hot insertion mode is enabled)	V		
		-0.3 V to (V <sub>CCI</sub> + 1 V) or 3.6 V, whichever voltage is lower (when I/O hot-insertion mode is disabled)			
V <sub>CC33A</sub>	(+3.3 V) power supply	–0.3 to 3.75	V		
VAREF	Voltage reference for ADC	1.0 to 3.75	V		
V <sub>CC15A</sub>	Digital Power supply for the analog system	–0.3 to 1.65	V		
$V_{CCNVM}$	Embedded Flash power supply	–0.3 to 1.65	V		
$V_{CCOSC}$	Oscillator power supply	–0.3 to 3.75	V		

#### Notes:

- 1. Device performance is not guaranteed if storage temperature exceeds 110°C.
- 2. The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in Table 3-4 on page 3-3.

Table 3-2 • Recommended Operating Conditions

Symbol	Parameter		Commercial	Industrial	Units
T <sub>A</sub> , T <sub>J</sub>	Ambient and Junction temperature		0 to +70	–40 to +85	°C
$V_{CC}$	1.5 V DC core supply voltage		1.425 to 1.575	1.425 to 1.575	V
$V_{JTAG}$	JTAG DC voltage		1.4 to 3.6	1.4 to 3.6	V
V <sub>PUMP</sub>	Programming voltage Pro	gramming mode	3.0 to 3.6	3.0 to 3.6	V
	Ор	eration <sup>3</sup>	0 to 3.6	0 to 3.6	V
$V_{CCPLL}$	Analog power supply (PLL)		1.4 to 1.6	1.4 to 1.6	V
V <sub>CCI</sub> and VMV	1.5 V DC supply voltage		1.425 to 1.575	1.425 to 1.575	V
	1.8 V DC supply voltage		1.7 to 1.9	1.7 to 1.9	V
	2.5 V DC supply voltage		2.3 to 2.7	2.3 to 2.7	V
	3.3 V DC supply voltage		3.0 to 3.6	3.0 to 3.6	V
	LVDS differential I/O		2.375 to 2.625	2.375 to 2.625	V
	LVPECL differential I/O		3.0 to 3.6	3.0 to 3.6	V
V <sub>CC33A</sub>	(+3.3 V) power supply		2.97 to 3.63	2.97 to 3.63	V
VAREF	Voltage reference for ADC		2.527 to 2.593	2.527 to 2.593	V
V <sub>CC15A</sub>	Digital Power supply for the analog system		1.425 to 1.575	1.425 to 1.575	V
$V_{CCNVM}$	Embedded Flash power supply		1.425 to 1.575	1.425 to 1.575	V
V <sub>CCOSC</sub>	Oscillator power supply		2.97 to 3.63	2.97 to 3.63	V

#### Notes:

- 1. The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-73 on page 2-126. VMV and  $V_{CCI}$  must be connected to the same power supply and  $V_{CCI}$  pins within a given I/O bank.
- 2. All parameters representing voltages are measured with respect to GND unless otherwise specified.
- 3. V<sub>PLIMP</sub> can be left floating during normal operation (not programming mode).

Table 3-3 • Required Conditions to Avoid Stress on Analog Input Pads

Pads	Pad Configuration	Polarity	Prescaler Range	Input Resistance to Ground
AV, AC	Direct input*	Positive	16 V, 8 V, 4 V, 2 V	1 MΩ (typ)
			1 V, 0.5 V, 0.25 V, 0.125 V	> 10 MΩ
	Postive Prescaler	Positive	16 V, 8 V, 4 V, 2 V	1 MΩ (typ)
			1 V, 0.5 V, 0.25 V, 0.125 V	> 10 MΩ
	Negative Prescaler	Negative	16 V, 8 V, 4 V, 2 V	1 MΩ (typ)
			1 V, 0.5 V, 0.25 V, 0.125 V	> 10 MΩ
	Digital input	Positive	16 V, 8 V, 4 V, 2 V	1 MΩ (typ)
	Positive Current Monitor	Positive	16 V, 8 V, 4 V, 2 V	1 MΩ (typ)
	Negative Current Monitor	Negative	16 V, 8 V, 4 V, 2 V	1 MΩ (typ)
AT	Direct input	Positive	16 V, 4 V	1 MΩ (typ)
	Postive Prescaler	Positive	16 V, 4 V	1 MΩ (typ)
	Digital input	Positive	16 V, 4 V	1 MΩ (typ)
	Temprature Monitor	Positive	16 V, 4 V	> 10 MΩ

**Note:** \*AFS600 should always use high prescaler ranges in Direct input mode.

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Table 3-4 • Overshoot and Undershoot Limits (as measured on quiet I/Os)<sup>1</sup>

V <sub>CCI</sub> and VMV	Average V <sub>CCI</sub> -GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle <sup>2</sup>	Maximum Overshoot/ Undershoot) <sup>2</sup>
2.7 V or less	10%	1.4 V
	5%	1.49 V
3.0 V	10%	1.1 V
	5%	1.19 V
3.3 V	10%	0.79 V
	5%	0.88 V
3.6 V	10%	0.45 V
	5%	0.54 V

#### Notes:

- 1. Based on reliability requirements at 85°C.
- 2. The duration is allowed at one cycle out of six clock cycles (estimated SSO density over cycles). If the overshoot/undershoot occurs at 1 out of 2 cycles, then the maximum overshoot/undershoot has to be reduced by 0.15 V.

*Table 3-5* ● **FPGA Programming, Storage, and Operating Limits** 

	Grade Programming	Program	Storage Te	Maximum Operating Junction	
Products	Cycles	Retention	Min.	Max.	Temperature T <sub>J</sub> (°C)
Commercial	500	20 years	0	110	110
	1 k	20 years	0	110	110
	15 k	5 years	0	110	110
Industrial	500	20 years	-40	110	110
	1 k	20 years	-40	110	110
	15 k	5 years	-40	110	110

**Note:** This is a stress rating only. Functional operation at any other condition other than those indicated is not implied.

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# I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every Fusion device. These circuits ensure easy transition from the powered-off state to the powered-up state of the device. The many different supplies can power-up in any sequence with minimized current spikes or surges. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in Figure 3-1.

There are five regions to consider during power-up.

Fusion I/Os are activated only if ALL of the following three conditions are met:

- 1. V<sub>CC</sub> and V<sub>CCI</sub> are above the minimum specified trip points (Figure 3-1).
- 2.  $V_{CCI} > V_{CC} 0.75 \text{ V (Typical)}.$
- 3. Chip is in the operating mode.

#### **V<sub>CCI</sub> Trip Point:**

Ramping up: 0.6 V < trip\_point\_up < 1.2 V

Ramping down: 0.5 V < trip\_point\_down < 1.1 V

#### **V<sub>CC</sub>** Trip Point:

Ramping up: 0.6 V < trip\_point\_up < 1.1 V Ramping down: 0.5 V < trip\_point\_down < 1 V

V<sub>CC</sub> and V<sub>CCI</sub> ramp-up trip points are about 100 mV higher than ramp-down trip points. This specifically built-in hysteresis prevents undesirable power-up oscillations and current surges. Note the following:

- During programming, I/Os become tristated and weakly pulled up to V<sub>CCI</sub>.
- JTAG supply, PLL power supplies, and charge pump V<sub>PUMP</sub> supply have no influence on I/O behavior.

### **Internal Power-Up Activation Sequence**

- 1. Core
- 2. Input buffers
- 3. Output buffers, after 200 ns delay from input buffer activation.

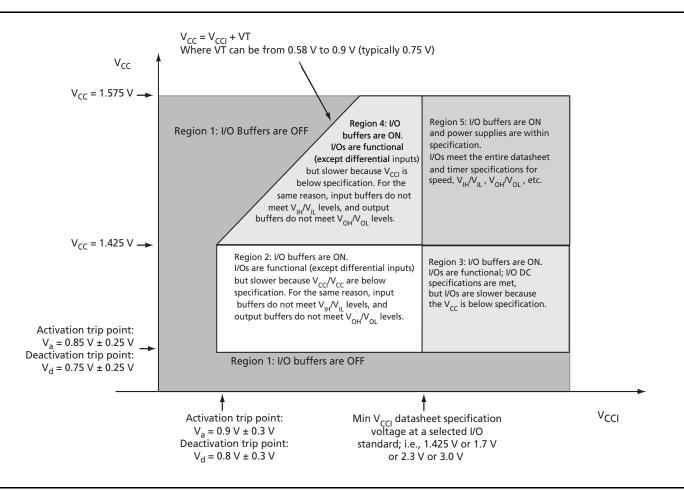


Figure 3-1 • I/O State as a Function of V<sub>CCI</sub> and V<sub>CC</sub> Voltage Levels

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### Thermal Characteristics

#### Introduction

*Table 3-6* •

The temperature variable in the Actel Designer software refers to the junction temperature, not the ambient, case, or board temperatures. This is an important distinction because dynamic and static power consumption will cause the chip's junction temperature to be higher than the ambient, case, or board temperatures. EQ 3-1 and EQ 3-3 give the relationship between thermal resistance, temperature gradient, and power.

$$\theta_{JA} = \frac{T_J - \theta_A}{P}$$

EQ 3-1

$$\theta_{JB} = \frac{T_J - T_B}{P}$$

EQ 3-2

$$\theta_{JC} = \frac{T_J - T_C}{P}$$

**Package Thermal Resistance** 

EQ 3-3

#### where:

 $\theta_{IA}$  = Junction-to-air thermal resistance

 $\theta_{IR}$  = Junction-to-board thermal resistance

 $\theta_{\text{IC}}$  = Junction-to-case thermal resistance

 $T_1$  = Junction temperature

 $T_A$  = Ambient temperature

 $T_B$  = Board temperature (measured 1.0 mm away

from the package edge)

T<sub>C</sub> = Case temperature

P = Total power dissipated by the device

	$AL^{\theta}$					
Product	Still Air	1.0 m/s	2.5 m/s	$\theta$ JC	$\theta_{JB}$	Units
AFS090-QN108	TBD	TBD	TBD	TBD	TBD	°C/W
AFS090-QN180	TBD	TBD	TBD	TBD	TBD	°C/W
AFS250-QN180	TBD	TBD	TBD	TBD	TBD	°C/W
AFS250-PQ208	TBD	TBD	TBD	TBD	TBD	°C/W
AFS600-PQ208	TBD	TBD	TBD	TBD	TBD	°C/W
AFS090-FG256	TBD	TBD	TBD	TBD	TBD	°C/W
AFS250-FG256	TBD	TBD	TBD	TBD	TBD	°C/W
AFS600-FG256	36.86	25.11	22.62	5.80	16.40	°C/W
AFS1500-FG256	TBD	TBD	TBD	TBD	TBD	°C/W
AFS600-FG484	30.67	19.00	17.00	8.28	10.87	°C/W
AFS1500-FG484	TBD	TBD	TBD	TBD	TBD	°C/W
AFS1500-FG676	TBD	TBD	TBD	TBD	TBD	°C/W

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#### Theta-JA

Junction-to-ambient thermal resistance  $(\theta_{JA})$  is determined under standard conditions specified by JEDEC (JESD-51), but it has little relevance in actual performance of the product. It should be used with caution but is useful for comparing the thermal performance of one package to another.

A sample calculation showing the maximum power dissipation allowed for the AFS600-FG484 package under forced convection of 1.0 m/s and 75°C ambient temperature is as follows:

Maximum Power Allowed = 
$$\frac{T_{J(MAX)} - T_{A(MAX)}}{\theta_{JA}}$$

EQ 3-4

where:

 $\theta_{JA}$  = 19.00°C/W (taken from Table 3-6 on page 3-5).

 $T_A = 75.00^{\circ}C$ 

Maximum Power Allowed = 
$$\frac{110.00^{\circ}\text{C} - 75.00^{\circ}\text{C}}{19.00^{\circ}\text{C/W}} = 1.84 \text{ W}$$

The power consumption of a device can be calculated using the Actel power calculator. The device's power consumption must be lower than the calculated maximum power dissipation by the package. If the power consumption is higher than the device's maximum allowable power dissipation, then a heat sink can be attached on top of the case or the airflow inside the system must be increased.

#### Theta-JB

Junction-to-board thermal resistance ( $\theta_{JB}$ ) measures the ability of the package to dissipate heat from the surface of the chip to the printed circuit board. As defined by the JEDEC (JESD-51) standard, the thermal resistance from junction to board uses an isothermal ring cold plate zone concept. The ring cold plate is simply a means to generate an isothermal boundary condition at the perimeter. The cold plate is mounted on a JEDEC standard board with a minimum distance of 5.0 mm away from the package edge.

#### Theta-JC

Junction-to-case thermal resistance ( $\theta_{JC}$ ) measures the ability of a device to dissipate heat from the surface of the chip to the top or bottom surface of the package. It is applicable for packages used with external heat sinks. Constant temperature is applied to the surface in consideration and acts as a boundary condition. This only applies to situations where all or nearly all of the heat is dissipated through the surface in consideration.

#### **Calculation for Heat Sink**

For example, in a design implemented in an AFS600-FG484 package with 2.5 m/s airflow, the power consumption value using the power calculator is 3.00 W. The user-dependent  $T_a$  and  $T_i$  are given as follows:

 $T_J = 110.00$ °C  $T_A = 70.00$ °C

From the datasheet:

 $\theta_{JA}$  = 17.00°C/W  $\theta_{JC}$  = 8.28°C/W

$$P = \frac{T_J - T_A}{\theta_{JA}} = \frac{110^{\circ}C - 70^{\circ}C}{17.00 \text{ W}} = 2.35 \text{ W}$$

EQ 3-5

The 2.35 W power is less than the required 3.00 W. The design therefore requires a heat sink, or the airflow where the device is mounted should be increased. The design's total junction-to-air thermal resistance requirement can be estimated by EQ 3-6:

$$\theta_{ja(total)} = \frac{T_J - T_A}{P} = \frac{110^{\circ}C - 70^{\circ}C}{3.00 \text{ W}} = 13.33^{\circ}C/W$$

EQ 3-6

Determining the heat sink's thermal performance:

$$\theta_{\text{JA(TOTAL)}} = \theta_{\text{JC}} + \theta_{\text{CS}} + \theta_{\text{SA}}$$

EQ 3-7

where:

 $\theta_{JA} = 0.37 \text{ °C/W}$ 

Thermal resistance of the interface material between the case and the heat sink, usually provided by the thermal interface manufacturer

 $\theta_{SA}$  = Thermal resistance of the heat sink in °C/W

$$\theta_{SA} = \theta_{JA(TOTAL)} - \theta_{JC} - \theta_{CS}$$

EQ 3-8

$$\theta_{SA} = 13.33$$
°C/W  $- 8.28$ °C/W  $- 0.37$ °C/W  $= 5.01$ °C/W

A heat sink with a thermal resistance of 5.01°C/W or better should be used. Thermal resistance of heat sinks is a function of airflow. The heat sink performance can be significantly improved with increased airflow.

Carefully estimating thermal resistance is important in the long-term reliability of an Actel FPGA. Design engineers should always correlate the power consumption of the device with the maximum allowable power dissipation of the package selected for that device.

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Note: The junction-to-air and junction-to-board thermal resistances are based on JEDEC standard (JESD-51) and assumptions made in building the model. It may not be realized in actual application and therefore should be used with a degree of caution. Junction-to-case thermal resistance assumes that all power is dissipated through the case.

### **Temperature and Voltage Derating Factors**

Table 3-7 • Temperature and Voltage Derating Factors for Timing Delays (Normalized to T₁ = 70°C, V<sub>CC</sub> = 1.425 V)

Array Voltage		Junction Temperature (°C)						
V <sub>CC</sub> (V)	–40°C	0°C	25°C	70°C	85°C	100°C		
1.425	0.88	0.93	0.95	1.00	1.02	1.05		
1.500	0.83	0.88	0.90	0.95	0.96	0.99		
1.575	0.80	0.85	0.86	0.91	0.93	0.96		

# **Calculating Power Dissipation**

### **Quiescent Supply Current**

Table 3-8 • Quiescent Supply Current Characteristics (I<sub>DDO</sub>)¹

Parameter	Conditions and Modes	AFS600	AFS250	AFS090
	Maximum in operating mode (85°C) <sup>2</sup>	45 mA	30 mA	15 mA
	Maximum in operating mode (70°C) <sup>2</sup>	30 mA	20 mA	10 mA
I <sub>DC1</sub>	Typical in operating mode (25°C) <sup>2</sup>	5 mA	3 mA	2 mA
I <sub>DC2</sub>	Typical in standby mode (25°C) <sup>3</sup>	200 μΑ	200 μΑ	200 μΑ
I <sub>DC3</sub>	Typical in sleep mode (25°C) <sup>4</sup>	10 μΑ	10 μΑ	10 μΑ

#### Notes:

- -F speed grade devices may experience higher Quiescent Supply current of up to five times the standard I<sub>DD</sub> and higher I/O leakage.
- 2.  $I_{DC1}$  includes  $V_{CG}$ ,  $V_{PUMP}$ ,  $V_{CCI}$ , and VMV currents. Values do not include I/O static contribution, which is shown in Table 3-9 on page 3-8 and Table 3-10 on page 3-9.
- 3.  $I_{DC2}$  represents the current from the  $V_{CC33A}$  supply when the RTC (and the crystal oscillator) is ON, the FPGA is OFF, and voltage regulator is OFF.
- I<sub>DC3</sub> represents the current from the V<sub>CC33A</sub> supply when the RTC (and the crystal oscillator), the FPGA, and the voltage regulator are OFF.

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### **Power Per I/O Pin**

Table 3-9 • Summary of I/O Input Buffer Power (Per Pin) – Default I/O Software Settings<sup>1, 2</sup>

	VMV (V)	Static Power P <sub>DC7</sub> (mW) <sup>3</sup>	Dynamic Power P <sub>AC9</sub> (μW/MHz) <sup>4</sup>
Single-Ended	<u> </u>		
3.3 V LVTTL/LVCMOS	3.3	_	17.39
3.3 V LVTTL/LVCMOS – Schmitt trigger	3.3	_	25.51
2.5 V LVCMOS	2.5	_	5.76
2.5 V LVCMOS – Schmitt trigger	2.5	_	7.16
1.8 V LVCMOS	1.8	_	2.72
1.8 V LVCMOS – Schmitt trigger	1.8	_	2.80
1.5 V LVCMOS (JESD8-11)	1.5	-	2.08
1.5 V LVCMOS (JESD8-11) – Schmitt trigger	1.5	_	2.00
3.3 V PCI	3.3	_	18.82
3.3 V PCI – Schmitt trigger	3.3	_	20.12
3.3 V PCI-X	3.3	-	18.82
3.3 V PCI-X – Schmitt trigger	3.3	_	20.12
Voltage-Referenced			
3.3 V GTL	3.3	2.90	8.23
2.5 V GTL	2.5	2.13	4.78
3.3 V GTL +	3.3	2.81	4.14
2.5 V GTL +	2.5	2.57	3.71
HSTL (I)	1.5	0.17	2.03
HSTL (II)	1.5	0.17	2.03
SSTL2 (I)	2.5	1.38	4.48
SSTL2 (II)	2.5	1.38	4.48
SSTL3 (I)	3.3	3.21	9.26
SSTL3 (II)	3.3	3.21	9.26
Differential			•
LVDS, BLVDS, M-LVDS	2.5	2.26	1.50
LVPECL	3.3	5.71	2.17

#### Notes:

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<sup>1.</sup> Input buffer power values provided in this table correspond to Pro I/Os. Pins assigned to east and west peripheries may have slightly lower power characteristics.

<sup>2.</sup> For a different pin location, Actel recommends using the Actel power calculator or SmartPower in Actel Libero IDE software.

<sup>3.</sup> P<sub>DC7</sub> is the static power (where applicable) measured on VMV.

<sup>4.</sup>  $P_{AC9}$  is the total dynamic power measured on  $V_{CC}$  and VMV.



Table 3-10 • Summary of I/O Output Buffer Power (Per Pin)—Default I/O Software Settings<sup>1, 2, 3</sup>

	C <sub>LOAD</sub> (pF)	V <sub>CCI</sub> (V)	Static Power P <sub>DC8</sub> (mW) <sup>4</sup>	Dynamic Power P <sub>AC10</sub> (μW/MHz) <sup>5</sup>
Single-Ended			•	
3.3 V LVTTL/LVCMOS	35	3.3	-	474.70
2.5 V LVCMOS	35	2.5	-	270.73
1.8 V LVCMOS	35	1.8	-	151.78
1.5 V LVCMOS (JESD8-11)	35	1.5	-	104.55
3.3 V PCI	10	3.3	-	204.61
3.3 V PCI-X	10	3.3	-	204.61
Voltage-Referenced			•	-
3.3 V GTL	10	3.3	-	24.08
2.5 V GTL	10	2.5	-	13.52
3.3 V GTL+	10	3.3	-	24.10
2.5 V GTL+	10	2.5	-	13.54
HSTL (I)	20	1.5	7.08	26.22
HSTL (II)	20	1.5	13.88	27.22
SSTL2 (I)	30	2.5	16.69	105.56
SSTL2 (II)	30	2.5	25.91	116.60
SSTL3 (I)	30	3.3	26.02	114.87
SSTL3 (II)	30	3.3	42.21	131.76
Differential			•	•
LVDS, BLVDS, M-LVDS	-	2.5	7.70	89.62
LVPECL	-	3.3	19.42	168.02

#### Notes:

- 1. Dynamic power consumption is given for standard load and software default drive strength and output slew.
- 2. Output buffer power values provided in this table correspond to Pro I/Os. Output buffers assigned to east and west peripheries may have slightly lower power characteristics.
- 3. For a different pin location, output load, drive strength, or slew rate, Actel recommends using the Actel power calculator or SmartPower in Actel Libero IDE software.
- 4.  $P_{DC8}$  is the static power (where applicable) measured on  $V_{CCI}$ .
- 5.  $P_{AC10}$  is the total dynamic power measured on  $V_{CC}$  and  $V_{CCI}$ .

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## **Dynamic Power Consumption of Various Internal Resources**

 Table 3-11
 Different Components Contributing to the Dynamic Power Consumption in Fusion Devices

		Power	Supply		Device-Specific Dynamic Contributions			
Parameter	Definition	Name	Setting	AFS600	AFS250	AFS090	Units	
P <sub>AC1</sub>	Clock contribution of a Global Rib	V <sub>CC</sub>	1.5 V	12.8	12.8	12.8	μW/MHz	
P <sub>AC2</sub>	Clock contribution of a Global Spine	V <sub>CC</sub>	1.5 V	1.9	1.9	1.9	μW/MHz	
P <sub>AC3</sub>	Clock contribution of a VersaTile row	V <sub>CC</sub>	1.5 V	0.81	0.81	0.81	μW/MHz	
P <sub>AC4</sub>	Clock contribution of a VersaTile used as a sequential module	V <sub>CC</sub>	1.5 V	0.11	0.11	0.11	μW/MHz	
P <sub>AC5</sub>	First contribution of a VersaTile used as a sequential module	V <sub>CC</sub>	1.5 V	0.07	0.07	0.07	μW/MHz	
P <sub>AC6</sub>	Second contribution of a VersaTile used as a sequential module	V <sub>CC</sub>	1.5 V	0.29	0.29	0.29	μW/MHz	
P <sub>AC7</sub>	Contribution of a VersaTile used as a combinatorial module	V <sub>CC</sub>	1.5 V	0.29	0.29	0.29	μW/MHz	
P <sub>AC8</sub>	Average contribution of a routing net	V <sub>CC</sub>	1.5 V	0.70	0.70	0.70	μW/MHz	
P <sub>AC9</sub>	Contribution of an I/O input pin (standard dependent)	VMV/ V <sub>CC</sub>						
P <sub>AC10</sub>	Contribution of an I/O output pin (standard dependent)	V <sub>CCI</sub> /V <sub>CC</sub>	See Table 3-10 on page 3-9					
P <sub>AC11</sub>	Average contribution of a RAM block during a read operation	V <sub>CC</sub>	1.5 V	25.00	25.00	25.00	μW/MHz	
P <sub>AC12</sub>	Average contribution of a RAM block during a write operation	V <sub>CC</sub>	1.5 V	30.00	30.00	30.00	μW/MHz	
P <sub>AC13</sub>	First contribution of a PLL	V <sub>CC</sub>	1.5 V	4.00	4.00	4.00	μW/MHz	
P <sub>AC14</sub>	Second contribution of a PLL	V <sub>CC</sub>	1.5 V	2.00	2.00	2.00	μW/MHz	
P <sub>AC15</sub>	Contribution of NVM block during a read operation $(F < 33MHz)$	V <sub>CC</sub>	1.5 V	358.00	358.00	358.00	μW/MHz	
P <sub>AC16</sub>	1st contribution of NVM block during a read operation (F > 33MHz)	V <sub>CC</sub>	1.5 V	12.88	12.88	12.88	mW	
P <sub>AC17</sub>	2nd contribution of NVM block during a read operation (F > 33MHz)	V <sub>CC</sub>	1.5 V	4.80	4.80	4.80	μW/MHz	
P <sub>AC18</sub>	Crystal Oscillator contribution	V <sub>CC33A</sub>	3.3 V	0.63	0.63	0.63	mW	
P <sub>AC19</sub>	RC Oscillator contribution	V <sub>CC33A</sub>	3.3 V	3.30	3.30	3.30	mW	
P <sub>AC20</sub>	Analog Block dynamic power contribution of ADC	V <sub>CC</sub>	1.5 V	3.00	3.00	3.00	mW	

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# **Static Power Consumption of Various Internal Resources**

Table 3-12 • Different Components Contributing to the Static Power Consumption in Fusion Devices

		Powe	er Supply		ice-Specific S Contribution		
Parameter	Definition	Name	Setting	AFS600	AFS250	AFS090	Units
P <sub>DC1</sub>	Core static power contribution in operating mode	V <sub>CC</sub>	1.5 V	7.50	4.50	3.00	mW
P <sub>DC2</sub>	Device static power contribution in standby mode	V <sub>CC33A</sub>	3.3 V	0.03	0.03	0.03	mW
P <sub>DC3</sub>	Device static power contribution in sleep mode	V <sub>CC33A</sub>	3.3 V	0.03	0.03	0.03	mW
$P_{DC4}$	NVM static power contribution	$V_{CC}$	1.5 V	1.19	1.19	1.19	mW
P <sub>DC5</sub>	Analog Block static power contribution of ADC	V <sub>CC33A</sub>	3.3 V	8.25	8.25	8.25	mW
P <sub>DC6</sub>	Analog Block static power contribution per Quad	V <sub>CC33A</sub>	3.3 V	3.30	3.30	3.30	mW
P <sub>DC7</sub>	Static contribution per input pin – standard dependent contribution	VMV/ V <sub>CC</sub>					
P <sub>DC8</sub>	Static contribution per input pin – standard dependent contribution	VMV/ V <sub>CC</sub>	1.13.11				

### **Power Calculation Methodology**

The section below describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in the Libero IDE software.

The power calculation methodology described below uses the following variables:

- The number of PLLs as well as the number and the frequency of each output clock generated
- The number of combinatorial and sequential cells used in the design
- The internal clock frequencies
- The number and the standard of I/O pins used in the design
- The number of RAM blocks used in the design
- The number of NVM blocks used in the design
- The number of Analog quads used in the design
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in Table 3-13 on page 3-16
- Enable rates of output buffers—guidelines are provided for typical applications in Table 3-14 on page 3-16
- Read rate and write rate to the RAM—quidelines are provided for typical applications in Table 3-14 on page 3-16.
- Read rate to the NVM blocks

The calculation should be repeated for each clock domain defined in the design.

### Methodology

### Total Power Consumption—P<sub>TOTAL</sub>

#### Operating Mode, Standby Mode, and Sleep Mode

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

P<sub>STAT</sub> is the total static power consumption.

P<sub>DYN</sub> is the total dynamic power consumption.

### **Total Static Power Consumption—PSTAT**

#### **Operating Mode**

$$P_{STAT} = P_{DC1} + (N_{NVM-BLOCKS} * P_{DC4}) + P_{DC5} + (N_{OUADS} * P_{DC6}) + (N_{INPUTS} * P_{DC7}) + (N_{OUTPUTS} * P_{DC8})$$

N<sub>NVM-RLOCKS</sub> is the number of NVM blocks available in the device.

N<sub>OUADS</sub> is the number of Analog Quads used in the design.

N<sub>INPUTS</sub> is the number of I/O input buffers used in the design.

N<sub>OUTPUTS</sub> is the number of I/O output buffers used in the design.

#### **Standby Mode**

$$P_{STAT} = P_{DC2}$$

### **Sleep Mode**

$$P_{STAT} = P_{DC3}$$

### Total Dynamic Power Consumption—P<sub>DYN</sub>

#### **Operating Mode**

### **Standby Mode**

$$P_{DYN} = P_{XTL-OSC}$$

#### Sleep Mode

$$P_{DYN} = 0 W$$

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#### Global Clock Dynamic Contribution—PCLOCK

#### **Operating Mode**

$$P_{CLOCK} = (P_{AC1} + N_{SPINE} * P_{AC2} + N_{ROW} * PAC3 + N_{S-CELL} * P_{AC4}) * F_{CLK}$$

N<sub>SPINE</sub> is the number of global spines used in the user design—guidelines are provided in Table 3-13 on page 3-16.

N<sub>ROW</sub> is the number of VersaTile rows used in the design—guidelines are provided in Table 3-13 on page 3-16.

F<sub>CLK</sub> is the global clock signal frequency.

N<sub>S-CELL</sub> is the number of VersaTiles used as sequential modules in the design.

#### Standby Mode and Sleep Mode

 $P_{CLOCK} = 0 W$ 

### Sequential Cells Dynamic Contribution—P<sub>S-CELL</sub>

#### **Operating Mode**

$$P_{S-CELL} = N_{S-CELL} * (P_{AC5} + (\alpha_1 / 2) * P_{AC6}) * F_{CLK}$$

N<sub>S-CELL</sub> is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 3-13 on page 3-16.

F<sub>CLK</sub> is the global clock signal frequency.

#### **Standby Mode and Sleep Mode**

 $P_{S-CELL} = 0 W$ 

### Combinational Cells Dynamic Contribution—P<sub>C-CELL</sub>

#### **Operating Mode**

$$P_{C-CELL} = N_{C-CELL} * (\alpha_1 / 2) * P_{AC7} * F_{CLK}$$

N<sub>C-CELL</sub> is the number of VersaTiles used as combinatorial modules in the design.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 3-13 on page 3-16.

F<sub>CLK</sub> is the global clock signal frequency.

### **Standby Mode and Sleep Mode**

 $P_{C-CELL} = 0 W$ 

#### Routing Net Dynamic Contribution—P<sub>NET</sub>

#### **Operating Mode**

$$P_{NET} = (N_{S-CELL} + N_{C-CELL}) * (\alpha_1 / 2) * P_{AC8} * F_{CLK}$$

N<sub>S-CELL</sub> is the number VersaTiles used as sequential modules in the design.

 $N_{\text{C-CELL}}$  is the number of VersaTiles used as combinatorial modules in the design.

 $\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 3-13 on page 3-16.

F<sub>CLK</sub> is the global clock signal frequency.

#### Standby Mode and Sleep Mode

$$P_{NET} = 0 W$$

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### I/O Input Buffer Dynamic Contribution-PINPUTS

### **Operating Mode**

$$P_{INPUTS} = N_{INPUTS} * (\alpha_2 / 2) * P_{AC9} * F_{CLK}$$

N<sub>INPLITS</sub> is the number of I/O input buffers used in the design.

 $\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 3-13 on page 3-16.

F<sub>CLK</sub> is the global clock signal frequency.

#### **Standby Mode and Sleep Mode**

 $P_{INPLITS} = 0 W$ 

### I/O Output Buffer Dynamic Contribution—POUTPUTS

### **Operating Mode**

$$P_{OUTPUTS} = N_{OUTPUTS} * (\alpha_2 / 2) * \beta_1 * P_{AC10} * F_{CLK}$$

N<sub>OUTPUTS</sub> is the number of I/O output buffers used in the design.

 $\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 3-13 on page 3-16.

 $\beta_1$  is the I/O buffer enable rate—guidelines are provided in Table 3-14 on page 3-16.

F<sub>CLK</sub> is the global clock signal frequency.

### **Standby Mode and Sleep Mode**

 $P_{OUTPUTS} = 0 W$ 

### **RAM Dynamic Contribution—P<sub>MEMORY</sub>**

#### **Operating Mode**

$$P_{MEMORY} = (NBLOCKS * P_{AC11} * \beta_2 * F_{READ-CLOCK}) + (NBLOCK * P_{AC12} * \beta_3 * F_{WRITE-CLOCK})$$

NBLOCKS is the number of RAM blocks used in the design.

F<sub>READ-CLOCK</sub> is the memory read clock frequency.

 $\beta_2$  is the RAM enable rate for read operations—guidelines are provided in Table 3-14 on page 3-16.

 $eta_3$  the RAM enable rate for write operations—guidelines are provided in Table 3-14 on page 3-16.

F<sub>WRITE-CLOCK</sub> is the memory write clock frequency.

#### Standby Mode and Sleep Mode

 $P_{MEMORY} = 0 W$ 

#### PLL/CCC Dynamic Contribution—PPLL

#### **Operating Mode**

$$P_{PLL} = P_{AC13} * F_{CLKIN} + \Sigma (P_{AC14} * F_{CLKOLIT})$$

F<sub>CLKIN</sub> is the input clock frequency.

F<sub>CLKOUT</sub> is the output clock frequency.<sup>1</sup>

#### Standby Mode and Sleep Mode

 $P_{PLL} = 0 W$ 

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<sup>1.</sup> The PLL dynamic contribution depends on the input clock frequency, the number of output clock signals generated by the PLL, and the frequency of each output clock. If a PLL is used to generate more than one output clock, include each output clock in the formula output clock by adding its corresponding contribution ( $P_{AC14} * F_{CLKOUT}$  product) to the total PLL contribution.



### Nonvolatile Memory Dynamic Contribution—P<sub>NVM</sub>

#### **Operating Mode**

The NVM dynamic power consumption is a piece-wise linear function of frequency.

$$P_{NVM} = N_{NVM-BLOCKS} * \beta_4 * P_{AC15} * F_{READ-NVM}$$
 when  $F_{READ-NVM} \le 33$  MHz,

$$P_{NVM} = N_{NVM-BLOCKS} * \beta_4 * (P_{AC16} + P_{AC17} * F_{READ-NVM}) when F_{READ-NVM} > 33 \text{ MHz}$$

N<sub>NVM-BLOCKS</sub> is the number of NVM blocks used in the design (2 in AFS600)

 $\beta_{\text{4}}$  is the NVM enable rate for read operations. Default is 0 (NVM mainly in idle state)

F<sub>READ-NVM</sub> is the NVM read-clock frequency

#### Standby Mode and Sleep Mode

 $P_{NVM} = 0 W$ 

### Crystal Oscillator Dynamic Contribution—PXTL-OSC

#### **Operating Mode**

 $P_{XTL-OSC} = P_{AC18}$ 

### **Standby Mode**

 $P_{XTL-OSC} = P_{AC18}$ 

### Sleep Mode

 $P_{XTL-OSC} = 0 W$ 

### RC Oscillator Dynamic Contribution—P<sub>RC-OSC</sub>

### **Operating Mode**

 $P_{RC-OSC} = P_{AC19}$ 

#### Standby Mode and Sleep Mode

 $P_{RC-OSC} = 0 W$ 

### Analog System Dynamic Contribution—PAB

### **Operating Mode**

 $P_{AB} = P_{AC20}$ 

#### **Standby Mode and Sleep Mode**

 $P_{AB} = 0 W$ 

### **Guidelines**

#### **Toggle Rate Definition**

A toggle rate defines the frequency of a net or logic element relative to a clock. It is a percentage. If the toggle rate of a net is 100%, this means that this net switches at half the clock frequency. Below are some examples:

- The average toggle rate of a shift register is 100% as all flip-flop outputs toggle at half of the clock frequency.
- The average toggle rate of an 8-bit counter is 25%:
  - Bit 0 (LSB) = 100%
  - Bit 1 = 50%
  - Bit 2 = 25%
  - ...
  - Bit 7 (MSB) = 0.78125%
  - The average toggle rate is = (100% + 50% + 25% + 12.5% + ... 0.78125%) / 8.

#### **Enable Rate Definition**

Output enable rate is the average percentage of time during which tristate outputs are enabled. When nontristate output buffers are used, the enable rate should be 100%.

Table 3-13 • Toggle Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline
$\alpha_1$	Toggle rate of VersaTile outputs	10%
$\alpha_2$	I/O buffer toggle rate	10%

*Table 3-14* • Enable Rate Guidelines Recommended for Power Calculation

Component	Definition	Guideline
$\beta_1$	I/O output buffer enable rate	100%
$\beta_2$	RAM enable rate for read operations	12.5%
$\beta_3$	RAM enable rate for write operations	12.5%
$\beta_4$	NVM enable rate for read operations	0%

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### **Example of Power Calculation**

This example considers a shift register with 5,000 storage tiles including a counter and memory that stores analog information. The shift register is clocked at 50 MHz and stores and reads information from a RAM.

The device used is a commercial AFS600 device operating in typical conditions.

The calculation below uses the power calculation methodology previously presented and shows how to determine the dynamic and static power consumption of resources used in the application.

Also included in the example is the calculation of power consumption in operating, standby, and sleep modes to illustrate the benefit of power-saving modes.

### Global Clock Contribution—P<sub>CLOCK</sub>

 $F_{CLK} = 50 \text{ MHz}$ 

Number of Sequential VersaTiles: N<sub>S-CELL</sub> = 5,000

Estimated number of Spines:  $N_{SPINES} = 5$ Estimated number of Rows:  $N_{ROW} = 313$ 

#### **Operating Mode**

$$P_{CLOCK} = (P_{AC1} + N_{SPINE} * P_{AC2} + N_{ROW} * PAC3 + N_{S-CELL} * P_{AC4}) * F_{CLK}$$
  
 $P_{CLOCK} = (0.0128 + 5*0.0019 + 313*0.00081 + 5,000*0.00011)*50$   
 $P_{CLOCK} = 41.28 \text{ mW}$ 

#### **Standby Mode and Sleep Mode**

 $P_{CLOCK} = 0 W$ 

### Logic – Sequential Cells, Combinational Cells, and Routing Net Contributions—P<sub>S-CELL</sub>, P<sub>C-CELL</sub>, and P<sub>NET</sub>

 $F_{CLK} = 50 \text{ MHz}$ 

Number of Sequential VersaTiles:  $N_{S-CELL} = 5,000$ Number of Combinational VersaTiles:  $N_{C-CELL} = 6,000$ Estimated Toggle rate of VersaTile outputs:  $\alpha_1 = 0.1$  (10%)

#### **Operating Mode**

$$\begin{split} &P_{S\text{-CELL}} = N_{S\text{-CELL}} * (P_{AC5} + (\alpha_1 \, / \, 2) * P_{AC6}) * F_{CLK} \\ &P_{S\text{-CELL}} = 5,000*(0.00007 + (0.1/2)*0.00029) * 50 \\ &P_{S\text{-CELL}} = 21.13 \text{ mW} \\ &P_{C\text{-CELL}} = 21.13 \text{ mW} \\ &P_{C\text{-CELL}} = N_{C\text{-CELL}} * (\alpha_1 \, / \, 2) * P_{AC7} * F_{CLK} \\ &P_{C\text{-CELL}} = 6,000 * (0.1/2) * 0.00029 * 50 \\ &P_{C\text{-CELL}} = 4.35 \text{ mW} \\ &P_{NET} = (N_{S\text{-CELL}} + N_{C\text{-CELL}}) * (\alpha_1 \, / \, 2) * P_{AC8} * F_{CLK} \\ &P_{NET} = (5,000 + 6,000) * (0.1/2) * 0.0007 * 50 \\ &P_{NET} = 19.25 \text{ mW} \\ &P_{LOGIC} = P_{S\text{-CELL}} + P_{C\text{-CELL}} + P_{NET} \\ &P_{LOGIC} = 21.13 \text{ mW} + 4.35 \text{mW} + 19.25 \text{ mW} \\ &P_{LOGIC} = 44.73 \text{ mW} \end{split}$$

#### Standby Mode and Sleep Mode

 $P_{S-CELL} = 0 W$  $P_{C-CELL} = 0 W$ 

 $P_{NET} = 0 W$ 

PLOGIC = 0 W

### I/O Input and Output Buffer Contribution—P<sub>I/O</sub>

This example uses LVTTL 3.3 V I/O cells. The output buffers are 12 mA capable configured with high output slew and are driving a 35 pF output load.

 $F_{CLK} = 50 \text{ MHz}$ 

Number of input pin used:  $N_{INPUTS} = 30$ Number of output pins used:  $N_{OUTPUTS} = 40$ Estimated I/O buffer toggle rate:  $\alpha_2$  = 0.1 (10%) Estimated IO buffer enable rate:  $\beta_1 = 1$  (100%)

#### **Operating Mode**

 $P_{INPUTS} = N_{INPUTS} * (\alpha_2 / 2) * P_{AC9} * F_{CLK}$ 

 $P_{INPLITS} = 30 * (0.1/2) * 0.01739 * 50$ 

 $P_{INPLITS} = 1.30 \text{ mW}$ 

 $P_{OUTPUTS} = N_{OUTPUTS} * (\alpha_2/2) * \beta_1 * P_{AC10} * F_{CLK}$ 

 $P_{OLITPLITS} = 40 * (0.1/2) * 1 * 0.4747 * 50$ 

 $P_{OUTPUTS} = 47.47 \text{ mW}$ 

 $PIO = P_{INPUTS} + P_{OUTPUTS}$ 

PIO = 1.30 mW + 47.47 mW

PIO = 48.77 mW

#### Standby Mode and Sleep Mode

 $P_{INPLITS} = 0 W$ 

 $P_{OUTPUTS} = 0 W$ 

 $P_{I/O} = 0 W$ 

### RAM Contribution—P<sub>MEMORY</sub>

Frequency of Read-Clock:  $F_{READ-CLOCK} = 10 \text{ MHz}$ Frequency of Write-Clock: F<sub>WRITE-CLOCK</sub> = 10 MHz

Number of Ram Blocks: NBLOCKS = 20

Estimated RAM Read Enable Rate:  $\beta_2 = 0.125$  (12.5%) Estimated RAM Write Enable Rate:  $\beta_3 = 0.125$  (12.5%)

### **Operating Mode**

 $P_{MEMORY} = (NBLOCKS * P_{AC11} * \beta_2 * F_{READ-CLOCK}) + (NBLOCK * P_{AC12} * \beta_3 * F_{WRITE-CLOCK})$ 

P<sub>MEMORY</sub> =( 20 \* 0.025 \* 0.125 \* 10) + (20 \* 0.030 \* 0.125 \* 10)

 $P_{MEMORY} = 1.38 \text{ mW}$ 

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#### Standby Mode and Sleep Mode

 $P_{MEMORY} = 0 W$ 

#### PLL/CCC Contribution—P<sub>PLL</sub>

PLL is not used in this application.

$$P_{PII} = 0 W$$

#### Nonvolatile Memory—P<sub>NVM</sub>

Nonvolatile memory is not used in this application.

$$P_{NVM} = 0 W$$

### Crystal Oscillator—P<sub>XTL-OSC</sub>

The application utilizes standby mode. The crystal oscillator is assumed to be active.

#### **Operating Mode**

 $P_{XTL-OSC} = P_{AC18}$ 

 $P_{XTL-OSC} = 0.63 \text{ mW}$ 

#### **Standby Mode**

 $P_{XTL-OSC} = P_{AC18}$ 

 $P_{XTL-OSC} = 0.63 \text{ mW}$ 

### Sleep Mode

 $P_{XTL-OSC} = 0 W$ 

### RC Oscillator—P<sub>RC-OSC</sub>

#### **Operating Mode**

 $P_{RC-OSC} = P_{AC19}$ 

 $P_{RC-OSC} = 3.30 \text{ mW}$ 

#### **Standby Mode and Sleep Mode**

 $P_{RC-OSC} = 0 W$ 

### Analog System—PAB

Number of Quads used:  $N_{OUADS} = 4$ 

#### **Operating Mode**

 $P_{AB} = P_{AC20}$ 

 $P_{AB} = 3.00 \text{ mW}$ 

#### **Standby Mode and Sleep Mode**

 $P_{AB} = 0 W$ 

### **Total Dynamic Power Consumption—PDYN**

#### **Operating Mode**

 $P_{\mathsf{DYN}} = \mathsf{PCLOCK} + \mathsf{P}_{\mathsf{S-CELL}} + \mathsf{P}_{\mathsf{C-CELL}} + \mathsf{P}_{\mathsf{NET}} + \mathsf{P}_{\mathsf{INPUTS}} + \mathsf{P}_{\mathsf{OUTPUTS}} + \mathsf{P}_{\mathsf{MEMORY}} + \mathsf{P}_{\mathsf{PLL}} + \mathsf{P}_{\mathsf{NVM}} + \mathsf{P}_{\mathsf{XTL-OSC}} + \mathsf{P}_{\mathsf{RC-OSC}} + \mathsf{P}_{\mathsf{AB}}$ 

 $P_{DYN} = 41.28 \text{ mW} + 21.1 \text{ mW} + 4.35 \text{ mW} + 19.25 \text{ mW} + 1.30 \text{ mW} + 47.47 \text{ mW} + 1.38 \text{ mW} + 0 + 0 + 0.63 \text{ mW} + 3.30 \text{ mW} + 3.00 \text{ mW}$ 

 $P_{DYN} = 143.06 \text{ mW}$ 

### **Standby Mode**

 $P_{DYN} = P_{XTL-OSC}$ 

 $P_{DYN} = 0.63 \text{ mW}$ 

#### **Sleep Mode**

 $P_{DYN} = 0 W$ 

### **Total Static Power Consumption—PSTAT**

Number of Quads used:  $N_{QUADS} = 4$ 

Number of NVM blocks available AFS600: N<sub>NVM-BLOCKS</sub> = 2

Number of Input pins used:  $N_{INPUTS} = 30$ Number of Output pins used:  $N_{OUTPUTS} = 40$ 

#### **Operating Mode**

$$P_{STAT} = P_{DC1} + (N_{NVM-BLOCKS} * P_{DC4}) + P_{DC5} + (N_{QUADS} * P_{DC6}) + (N_{INPUTS} * P_{DC7}) + (N_{OUTPUTS} * P_{DC8})$$

$$P_{STAT} = 7.50 \text{ mW} + (2 * 1.19 \text{ mW}) + 8.25 \text{ mW} + (4 * 3.30 \text{ mW}) + (30 * 0.00) + (40 * 0.00)$$

 $P_{STAT} = 31.33 \text{ mW}$ 

### **Standby Mode**

 $P_{STAT} = P_{DC2}$ 

 $P_{STAT} = 0.03 \text{ mW}$ 

#### Sleep Mode

 $P_{STAT} = P_{DC3}$ 

 $P_{STAT} = 0.03 \text{ mW}$ 

### **Total Power Consumption—PTOTAL**

In operating mode, the total power consumption of the device is 174.39 mW:

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$$P_{TOTAL} = 143.06 \text{ mW} + 31.33 \text{ mW}$$

$$P_{TOTAL} = 174.39 \text{ mW}$$

In standby mode, the total power consumption of the device is limited to 0.66 mW:

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$$P_{TOTAL} = 0.03 \text{ mW} + 0.63 \text{ mW}$$

$$P_{TOTAL} = 0.66 \text{ mW}$$

In sleep mode, the total power consumption of the device drops as low as 0.03 mW:

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$$P_{TOTAL} = 0.03 \text{ mW}$$

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# **Power Consumption**

*Table 3-15* • **Power Consumption** 

Parameter	Description	Condition	Min.	Тур.	Max.	Units
Crystal Oscillate	or	<u>, , , , , , , , , , , , , , , , , , , </u>				1
I <sub>STBXTAL</sub>	Standby Current of Crystal Oscillator			10		μΑ
I <sub>DYNXTAL</sub>	Operating Current	RC		0.6		mA
		0.032-0.2		0.6		mA
		0.2–2.0		0.6		mA
		2.0–20.0		0.6		mA
RC Oscillator	<u> </u>	<u>'</u>				
I <sub>DYNRC</sub>	Operating Current			1		mA
ACM	•					
	Operating Current (Fixed Clock)			200		µA/MHz
	Operating Current (User Clock)			30		μΑ
NVM System	•	•				
	NVM Array Operating Power					
		Idle		795		μΑ
		Read operation		See Table 3-12 on page 3-11.		See Table 3-12 on page 3-11.
		Erase		900		μΑ
		Write		900		μΑ
P <sub>NVMCTRL</sub>	NVM Controller Operating Power			20		uW/MHz



# **Package Pin Assignments**

# 108-Pin QFN

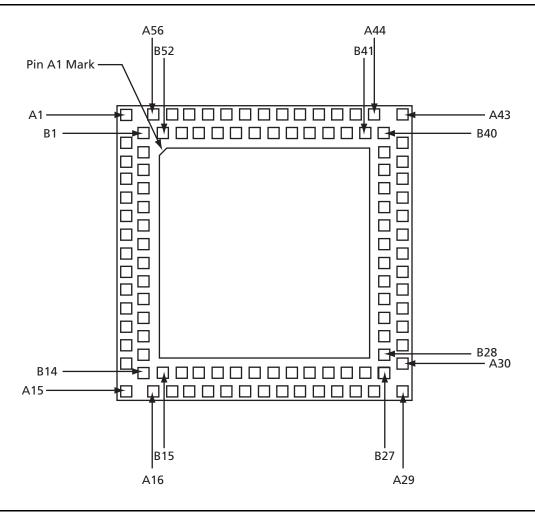


Figure 4-1 • 108-Pin QFN (Top View)

#### **Note**

For Package Manufacturing and Environmental information, visit Resource center at http://www.actel.com/products/rescenter/package/index.html.

108-Pin QFN			
Pin Number	AFS090 Function		
A1	NC		
A2	GNDQ		
A3	GAA2/IO52PDB3V0		
A4	GND		
A5	GFA1/IO47PDB3V0		
A6	GEB1/IO45PDB3V0		
A7	$V_{CCOSC}$		
A8	XTAL2		
A9	GEA1/IO44PPB3V0		
A10	GEA0/IO44NPB3V0		
A11	GEB2/IO42PDB3V0		
A12	V <sub>CCNVM</sub>		
A13	V <sub>CC15A</sub>		
A14	PCAP		
A15	NC		
A16	GNDA		
A17	AV0		
A18	AG0		
A19	ATRTN0		
A20	AT1		
A21	AC1		
A22	AV2		
A23	AG2		
A24	AT2		
A25	AT3		
A26	AC3		
A27	GNDAQ		
A28	ADCGNDREF		
A29	NC		
A30	GNDA		
A31	PTEM		
A32	GNDNVM		
A33	V <sub>PUMP</sub>		
A34	TCK		
A35	TMS		
A36	TRST		
A37	GDB1/IO39PSB1V0		
A38	GDC1/IO38PDB1V0		

108-Pin QFN				
Pin Number	AFS090 Function			
A39	GND			
A40	GCB1/IO35PDB1V0			
A41	GCB2/IO33PDB1V0			
A42	GBA2/IO31PDB1V0			
A43	NC			
A44	GBA1/IO30RSB0V0			
A45	GBB1/IO28RSB0V0			
A46	GND			
A47	V <sub>CC</sub>			
A48	GBC1/IO26RSB0V0			
A49	IO21RSB0V0			
A50	IO19RSB0V0			
A51	IO09RSB0V0			
A52	GAC0/IO04RSB0V0			
A53	V <sub>CCI</sub> B0			
A54	GND			
A55	GAB0/IO02RSB0V0			
A56	GAA0/IO00RSB0V0			
B1	V <sub>COMPLA</sub>			
B2	VMV3			
В3	GAB2/IO52NDB3V0			
В4	V <sub>CCI</sub> B3			
B5	GFA0/IO47NDB3V0			
В6	GEB0/IO45NDB3V0			
В7	XTAL1			
В8	GNDOSC			
В9	GEC2/IO43PSB3V0			
B10	GEA2/IO42NDB3V0			
B11	V <sub>CC</sub>			
B11	V <sub>CC</sub>			
B12	GNDNVM			
B13	NCAP			
B14	V <sub>CC33PMP</sub>			
B15	V <sub>CC33N</sub>			
B16	GNDAQ			
B17	AC0			
B18	AT0			
B19	AG1			

B20         AV1           B21         AC2           B22         ATRTN1           B23         AG3           B24         AV3           B25         V <sub>CC33ACAP</sub> B26         VAREF           B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0	108-Pin QFN			
B21         AC2           B22         ATRTN1           B23         AG3           B24         AV3           B25         V <sub>CC33ACAP</sub> B26         VAREF           B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0	Pin Number	AFS090 Function		
B22         ATRTN1           B23         AG3           B24         AV3           B25         V <sub>CC33ACAP</sub> B26         VAREF           B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBAO/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBBO/IO25RSB0V0           B45         GBCO/IO25RSB0V0           B46         IO20RSB0V0	B20	AV1		
B23         AG3           B24         AV3           B25         V <sub>CC33ACAP</sub> B26         VAREF           B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0	B21	AC2		
B24         AV3           B25         V <sub>CC33ACAP</sub> B26         VAREF           B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBAO/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBBO/IO27RSB0V0           B45         GBCO/IO25RSB0V0           B46         IO20RSB0V0	B22	ATRTN1		
B25         V <sub>CC33ACAP</sub> B26         VAREF           B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0	B23	AG3		
B26         VAREF           B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBAO/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBBO/IO27RSB0V0           B45         GBCO/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B24	AV3		
B27         PUB           B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B25	V <sub>CC33ACAP</sub>		
B28         V <sub>CC33A</sub> B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBAO/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBBO/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B26	VAREF		
B29         PTBASE           B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B27	PUB		
B30         V <sub>CCNVM</sub> B31         V <sub>CC</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B28	V <sub>CC33A</sub>		
B31         V <sub>CC</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B29	PTBASE		
B31         V <sub>CC</sub> B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B30	V <sub>CCNVM</sub>		
B31         V <sub>CC</sub> B32         TDI           B33         TDO           B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B31			
B33         TDO           B34         V <sub>JTAG</sub> B35         GDCO/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B31			
B34         V <sub>JTAG</sub> B35         GDC0/IO38NDB1V0           B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B32	TDI		
B35 GDC0/IO38NDB1V0 B36 V <sub>CCI</sub> B1 B37 GCB0/IO35NDB1V0 B38 GCC2/IO33NDB1V0 B39 GBB2/IO31NDB1V0 B40 VMV1 B41 GNDQ B42 GBA0/IO29RSB0V0 B43 V <sub>CCI</sub> B0 B44 GBB0/IO27RSB0V0 B45 GBC0/IO25RSB0V0 B46 IO20RSB0V0	B33	TDO		
B36         V <sub>CCI</sub> B1           B37         GCB0/IO35NDB1V0           B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B34	$V_{JTAG}$		
B37 GCB0/IO35NDB1V0 B38 GCC2/IO33NDB1V0 B39 GBB2/IO31NDB1V0 B40 VMV1 B41 GNDQ B42 GBA0/IO29RSB0V0 B43 V <sub>CCI</sub> B0 B44 GBB0/IO27RSB0V0 B45 GBC0/IO25RSB0V0 B46 IO20RSB0V0 B47 IO10RSB0V0	B35	GDC0/IO38NDB1V0		
B38         GCC2/IO33NDB1V0           B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B36	V <sub>CCI</sub> B1		
B39         GBB2/IO31NDB1V0           B40         VMV1           B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B37	GCB0/IO35NDB1V0		
B40     VMV1       B41     GNDQ       B42     GBA0/IO29RSB0V0       B43     V <sub>CCI</sub> B0       B44     GBB0/IO27RSB0V0       B45     GBC0/IO25RSB0V0       B46     IO20RSB0V0       B47     IO10RSB0V0	B38	GCC2/IO33NDB1V0		
B41         GNDQ           B42         GBA0/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B39	GBB2/IO31NDB1V0		
B42         GBAO/IO29RSB0V0           B43         V <sub>CCI</sub> B0           B44         GBBO/IO27RSB0V0           B45         GBCO/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B40	VMV1		
B43         V <sub>CCI</sub> B0           B44         GBB0/IO27RSB0V0           B45         GBC0/IO25RSB0V0           B46         IO20RSB0V0           B47         IO10RSB0V0	B41	GNDQ		
B44 GBB0/IO27RSB0V0 B45 GBC0/IO25RSB0V0 B46 IO20RSB0V0 B47 IO10RSB0V0	B42	GBA0/IO29RSB0V0		
B45 GBC0/IO25RSB0V0 B46 IO20RSB0V0 B47 IO10RSB0V0	B43	V <sub>CCI</sub> B0		
B46 IO20RSB0V0 B47 IO10RSB0V0	B44	GBB0/IO27RSB0V0		
B47 IO10RSB0V0	B45	GBC0/IO25RSB0V0		
	B46	IO20RSB0V0		
B48 GAC1/IO05RSB0V0	B47	IO10RSB0V0		
	B48	GAC1/IO05RSB0V0		
B49 GAB1/IO03RSB0V0	B49	GAB1/IO03RSB0V0		
B50 V <sub>CC</sub>	B50	V <sub>CC</sub>		
B51 GAA1/IO01RSB0V0	B51			
B52 V <sub>CCPLA</sub>	B52	$V_{CCPLA}$		

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# 180-Pin QFN

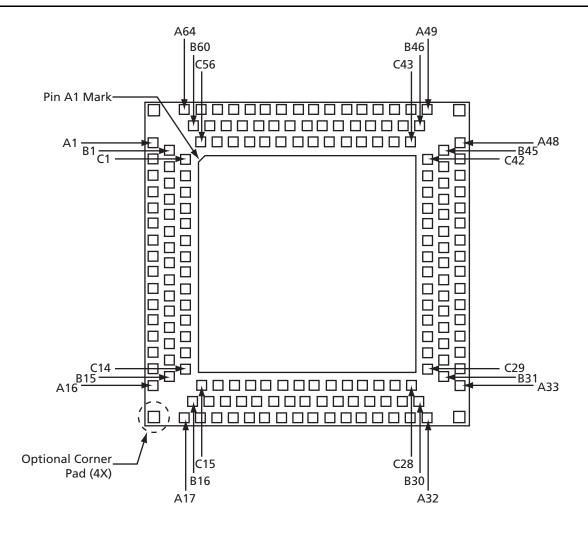


Figure 4-2 • 180-Pin QFN (Top View)

#### **Note**

For Package Manufacturing and Environmental information, visit Resource center at http://www.actel.com/products/rescenter/package/index.html.

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180-Pin QFN	
Pin Number	AFS090 Function
A1	GNDQ
A2	VMV3
А3	GAB2/IO52NDB3V0
A4	GFA2/IO51NDB3V0
A5	GFC2/IO50NDB3V0
A6	V <sub>CCI</sub> B3
A7	GFA1/IO47PPB3V0
A8	GEB0/IO45NDB3V0
A9	XTAL1
A10	GNDOSC
A11	GEC2/IO43PPB3V0
A12	IO43NPB3V0
A13	NC
A14	GNDNVM
A15	PCAP
A16	V <sub>CC33PMP</sub>
A17	NC
A18	AV0
A19	AG0
A20	ATRTN0
A21	AG1
A22	AC1
A23	AV2
A24	AT2
A25	AT3
A26	AC3
A27	AV4
A28	AC4
A29	AT4
A30	NC
A31	NC
A32	ADCGNDREF
A33	V <sub>CC33A</sub>
A34	GNDA
A35	PTBASE
A36	V <sub>CCNVM</sub>
A37	$V_{PUMP}$
	•

180	180-Pin QFN	
Pin Number	AFS090 Function	
A38	TDI	
A39	TDO	
A40	V <sub>JTAG</sub>	
A41	GDB1/IO39PPB1V0	
A42	GDC1/IO38PDB1V0	
A43	V <sub>CC</sub>	
A44	GCB0/IO35NPB1V0	
A45	GCC1/IO34PDB1V0	
A46	V <sub>CCI</sub> B1	
A47	GBC2/IO32PPB1V0	
A48	VMV1	
A49	NC	
A50	GBA0/IO29RSB0V0	
A51	V <sub>CCI</sub> B0	
A51 A52	GBB0/IO27RSB0V0	
A52 A53	GBC1/IO26RSB0V0	
A54	IO24RSB0V0	
A55	IO21RSB0V0	
A56		
A50	V <sub>CCI</sub> B0 IO15RSB0V0	
A57	IO10RSB0V0	
A58 A59	IO07RSB0V0	
A59 A60	GAC0/IO04RSB0V0	
A61	GAB1/IO03RSB0V0	
A62	V <sub>CC</sub>	
A63	GAA1/IO01RSB0V0	
A64	NC V	
B1	V <sub>COMPLA</sub>	
B2	GAA2/IO52PDB3V0	
B3	GAC2/IO51PDB3V0	
B4	GFB2/IO50PDB3V0	
B5	V <sub>CC</sub>	
B6	GFC0/IO49NDB3V0	
B7	GEB1/IO45PDB3V0	
B8	V <sub>CCOSC</sub>	
B9	XTAL2	
B10	GEA0/IO44NDB3V0	

180-Pin QFN	
Pin Number	AFS090 Function
B11	GEB2/IO42PDB3V0
B12	V <sub>CC</sub>
B12	V <sub>CC</sub>
B13	V <sub>CCNVM</sub>
B14	V <sub>CC15A</sub>
B15	NCAP
B16	V <sub>CC33N</sub>
B17	GNDAQ
B18	AC0
B19	AT0
B20	AT1
B21	AV1
B22	AC2
B23	ATRTN1
B24	AG3
B25	AV3
B26	AG4
B27	ATRTN2
B28	NC
B29	V <sub>CC33ACAP</sub>
B30	VAREF
B31	PUB
B32	PTEM
B33	GNDNVM
B34	V <sub>CC</sub>
B34	V <sub>CC</sub>
B35	TCK
B36	TMS
B37	TRST
B38	GDB2/IO41PSB1V0
B39	GDC0/IO38NDB1V0
B40	V <sub>CCI</sub> B1
B41	GCA1/IO36PDB1V0
B42	GCC0/IO34NDB1V0
B43	GCB2/IO33PSB1V0
B44	V <sub>CC</sub>
B45	GBA2/IO31PDB1V0

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180	-Pin QFN
Pin Number	AFS090 Function
B46	GNDQ
B47	GBA1/IO30RSB0V0
B48	GBB1/IO28RSB0V0
B49	V <sub>CC</sub>
B50	GBC0/IO25RSB0V0
B51	IO23RSB0V0
B52	IO20RSB0V0
B53	V <sub>CC</sub>
B54	IO11RSB0V0
B55	IO08RSB0V0
B56	GAC1/IO05RSB0V0
B57	V <sub>CCI</sub> B0
B58	GAB0/IO02RSB0V0
B59	GAA0/IO00RSB0V0
B60	$V_{CCPLA}$
C1	NC
C2	NC
C3	GND
C4	NC
C5	GFC1/IO49PDB3V0
C6	GFA0/IO47NPB3V0
C7	V <sub>CCI</sub> B3
C8	GND
С9	GEA1/IO44PDB3V0
C10	GEA2/IO42NDB3V0
C11	NC
C12	NC
C13	GND
C14	NC
C15	NC
C16	GNDA
C17	NC
C18	NC
C19	NC
C20	NC
C21	AG2
C22	NC

180-Pin QFN	
Pin Number	AFS090 Function
C23	NC
C24	NC
C25	NC
C26	GNDAQ
C27	NC
C28	NC
C29	NC
C30	NC
C31	GND
C32	NC
C33	NC
C34	NC
C35	GND
C36	GDB0/IO39NPB1V0
C37	GDA1/IO37NSB1V0
C38	GCA0/IO36NDB1V0
C39	GCB1/IO35PPB1V0
C40	GND
C41	GCA2/IO32NPB1V0
C42	GBB2/IO31NDB1V0
C43	NC
C44	NC
C45	NC
C46	GND
C47	NC
C48	IO22RSB0V0
C49	GND
C50	IO13RSB0V0
C51	IO09RSB0V0
C52	IO06RSB0V0
C53	GND
C54	NC
C55	NC
C56	NC

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180-Pin QFN	
Pin Number	AFS250 Function
A1	GNDQ
A2	VMV3
A3	IO74NDB3V0
A4	IO71NDB3V0
A5	IO69NPB3V0
A6	V <sub>CCI</sub> B3
A7	GFB1/IO67PPB3V0
A8	NC
A9	XTAL1
A10	GNDOSC
A11	GEA1/IO61PPB3V0
A12	GEA0/IO61NPB3V0
A13	V <sub>CCI</sub> B3
A14	GNDNVM
A15	PCAP
A16	V <sub>CC33PMP</sub>
A17	NC
A18	AV0
A19	AG0
A20	ATRTN0
A21	AG1
A22	AC1
A23	AV2
A24	AT2
A25	AT3
A26	AC3
A27	AV4
A28	AC4
A29	AT4
A30	AG5
A31	AV5
A32	ADCGNDREF
A33	V <sub>CC33A</sub>
A34	GNDA
A35	PTBASE
A36	V <sub>CCNVM</sub>
A37	V <sub>PUMP</sub>
A38	TDI

180-Pin QFN	
Pin Number	AFS250 Function
A39	TDO
A40	$V_{\rm JTAG}$
A41	GDA1/IO54PPB1V0
A42	GDB1/IO53PDB1V0
A43	V <sub>CC</sub>
A44	GCB0/IO48NPB1V0
A45	GCC1/IO47PDB1V0
A46	V <sub>CCI</sub> B1
A47	GBB2/IO41PPB1V0
A48	VMV1
A49	NC
A50	GBB1/IO37RSB0V0
A51	V <sub>CCI</sub> B0
A52	GBC0/IO34RSB0V0
A53	IO33RSB0V0
A54	IO29RSB0V0
A55	IO26RSB0V0
A56	V <sub>CCI</sub> B0
A57	IO21RSB0V0
A58	IO13RSB0V0
A59	IO10RSB0V0
A60	IO06RSB0V0
A61	GAC1/IO05RSB0V0
A62	V <sub>CC</sub>
A63	GAB0/IO02RSB0V0
A64	NC
B1	V <sub>COMPLA</sub>
B2	GAC2/IO74PDB3V0
В3	GFA2/IO71PDB3V0
В4	GFB2/IO70PSB3V0
B5	V <sub>CC</sub>
В6	GFC0/IO68NDB3V0
В7	NC
B8	V <sub>CCOSC</sub>
В9	XTAL2
B10	GFA0/IO66NDB3V0
B11	IO60NDB3V0
B12	V <sub>CC</sub>

Pin Number AFS250 Function  B12 V <sub>CC</sub> B13 V <sub>CCNVM</sub>	1
B13 V <sub>CCNVM</sub>	
B14 V <sub>CC15A</sub>	
B15 NCAP	
B16 V <sub>CC33N</sub>	
B17 GNDAQ	
B18 AC0	
B19 AT0	
B20 AT1	
B21 AV1	
B22 AC2	
B23 ATRTN1	
B24 AG3	
B25 AV3	
B26 AG4	
B27 ATRTN2	
B28 AC5	
B29 V <sub>CC33ACAP</sub>	
B30 VAREF	
B31 PUB	
B32 PTEM	
B33 GNDNVM	
B34 V <sub>CC</sub>	
B34 V <sub>CC</sub>	
B35 TCK	
B36 TMS	
B37 TRST	
B38 GDA2/IO55PSB1V0	)
B39 GDB0/IO53NDB1V0	)
B40 V <sub>CCI</sub> B1	
B41 GCA1/IO49PDB1V0	)
B42 GCC0/IO47NDB1V	)
B43 GBC2/IO42PSB1V0	)
B44 V <sub>CC</sub>	
B45 GBA2/IO40PDB1V0	)
B46 GNDQ	
B47 GBA0/IO38RSB0V0	)
B48 GBC1/IO35RSB0VC	)

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180-Pin QFN	
Pin Number	AFS250 Function
B49	V <sub>CC</sub>
B50	IO31RSB0V0
B51	IO28RSB0V0
B52	IO25RSB0V0
B53	V <sub>CC</sub>
B54	IO14RSB0V0
B55	IO11RSB0V0
B56	IO08RSB0V0
B57	V <sub>CCI</sub> B0
B58	GAC0/IO04RSB0V0
B59	GAA1/IO01RSB0V0
B60	V <sub>CCPLA</sub>
C1	NC NC
C2	V <sub>CCI</sub> B3
C3	GND
C4	GFC2/IO69PPB3V0
C5	GFC1/IO68PDB3V0
C6	GFB0/IO67NPB3V0
C7	NC
C8	GND
C9	GFA1/IO66PDB3V0
C10	GEC2/IO60PDB3V0
C11	GEA2/IO58PSB3V0
C12	NC
C13	GND
C14	NC
C15	NC
C16	GNDA
C17	NC
C18	NC
C19	NC
C20	NC
C21	AG2
C22	NC
C23	NC
C24	NC
C25	AT5
C26	GNDAQ

180-Pin QFN	
Pin Number	AFS250 Function
C27	NC
C28	NC
C29	NC
C30	NC
C31	GND
C32	NC
C33	NC
C34	NC
C35	GND
C36	GDA0/IO54NPB1V0
C37	GDC0/IO52NSB1V0
C38	GCA0/IO49NDB1V0
C39	GCB1/IO48PPB1V0
C40	GND
C41	IO41NPB1V0
C42	IO40NDB1V0
C43	NC
C44	GBA1/IO39RSB0V0
C45	GBB0/IO36RSB0V0
C46	GND
C47	IO30RSB0V0
C48	IO27RSB0V0
C49	GND
C50	IO16RSB0V0
C51	IO12RSB0V0
C52	IO09RSB0V0
C53	GND
C54	GAB1/IO03RSB0V0
C55	GAA0/IO00RSB0V0
C56	NC

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# 208-Pin PQFP

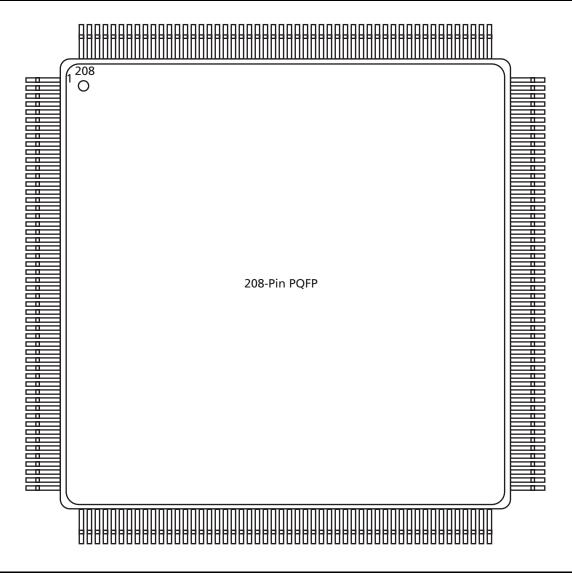


Figure 4-3 • 208-Pin PQFP (Top View)

#### Note

For Package Manufacturing and Environmental information, visit Resource center at http://www.actel.com/products/rescenter/package/index.html.

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208-Pin PQFP	
Pin Number	AFS250 Function
1	$V_{CCPLA}$
2	V <sub>COMPLA</sub>
3	GNDQ
4	VMV3
5	GAA2/IO76PDB3V0
6	IO76NDB3V0
7	GAB2/IO75PDB3V0
8	IO75NDB3V0
9	NC
10	NC
11	VCC
12	GND
13	V <sub>CCI</sub> B3
14	IO72PDB3V0
15	IO72NDB3V0
16	GFA2/IO71PDB3V0
17	IO71NDB3V0
18	GFB2/IO70PDB3V0
19	IO70NDB3V0
20	GFC2/IO69PDB3V0
21	IO69NDB3V0
22	V <sub>CC</sub>
23	GND
24	V <sub>CCI</sub> B3
25	GFC1/IO68PDB3V0
26	GFC0/IO68NDB3V0
27	GFB1/IO67PDB3V0
28	GFB0/IO67NDB3V0
29	$V_{ccosc}$
30	XTAL1
31	XTAL2
32	GNDOSC
33	GEB1/IO62PDB3V0
34	GEB0/IO62NDB3V0
35	GEA1/IO61PDB3V0
36	GEA0/IO61NDB3V0

208-Pin PQFP	
Pin Number	AFS250 Function
37	GEC2/IO60PDB3V0
38	IO60NDB3V0
39	GND
40	V <sub>CCI</sub> B3
41	GEB2/IO59PDB3V0
42	IO59NDB3V0
43	GEA2/IO58PDB3V0
44	IO58NDB3V0
45	V <sub>CC</sub>
46	V <sub>CCNVM</sub>
47	GNDNVM
48	GND
49	V <sub>CC15A</sub>
50	PCAP
51	NCAP
52	V <sub>CC33PMP</sub>
53	V <sub>CC33N</sub>
54	GNDA
55	GNDAQ
56	NC
57	NC
58	NC
59	NC
60	NC
61	NC
62	NC
63	NC
64	NC
65	AV0
66	AC0
67	AG0
68	AT0
69	ATRTN0
70	AT1
71	AG1
72	AC1

Pin Number         AFS250 Function           73         AV1           74         AV2           75         AC2           76         AG2           77         AT2           78         ATRTN1           79         AT3           80         AG3           81         AC3           82         AV3           83         AV4           84         AC4           85         AG4           86         AT4           87         ATRTN2           88         AT5           89         AG5           90         AC5           91         AV5           92         NC           93         NC           94         NC           95         NC           96         NC           97         NC           98         NC           99         NC           100         NC           101         GNDAQ           102         V <sub>CC33ACAP</sub> 103         ADCGNDREF           104         V <sub>AREF</sub> 1	208-Pin PQFP	
74         AV2           75         AC2           76         AG2           77         AT2           78         ATRTN1           79         AT3           80         AG3           81         AC3           82         AV3           83         AV4           84         AC4           85         AG4           86         AT4           87         ATRTN2           88         AT5           89         AG5           90         AC5           91         AV5           92         NC           93         NC           94         NC           95         NC           96         NC           97         NC           98         NC           99         NC           100         NC           101         GNDAQ           102         V <sub>CC33ACAP</sub> 103         ADCGNDREF           104         V <sub>AREF</sub> 105         PUB           106         V <sub>CC33A</sub> 107	Pin Number	AFS250 Function
75         AC2           76         AG2           77         AT2           78         ATRTN1           79         AT3           80         AG3           81         AC3           82         AV3           83         AV4           84         AC4           85         AG4           86         AT4           87         ATRTN2           88         AT5           89         AG5           90         AC5           91         AV5           92         NC           93         NC           94         NC           95         NC           96         NC           97         NC           98         NC           99         NC           100         NC           101         GNDAQ           102         V <sub>CC33ACAP</sub> 103         ADCGNDREF           104         V <sub>AREF</sub> 105         PUB           106         V <sub>CC33A</sub> 107         GNDA	73	AV1
76         AG2           77         AT2           78         ATRTN1           79         AT3           80         AG3           81         AC3           82         AV3           83         AV4           84         AC4           85         AG4           86         AT4           87         ATRTN2           88         AT5           89         AG5           90         AC5           91         AV5           92         NC           93         NC           94         NC           95         NC           96         NC           97         NC           98         NC           99         NC           100         NC           101         GNDAQ           102         V <sub>CC33ACAP</sub> 103         ADCGNDREF           104         V <sub>AREF</sub> 105         PUB           106         V <sub>CC33A</sub> 107         GNDA	74	AV2
77         AT2           78         ATRTN1           79         AT3           80         AG3           81         AC3           82         AV3           83         AV4           84         AC4           85         AG4           86         AT4           87         ATRTN2           88         AT5           89         AG5           90         AC5           91         AV5           92         NC           93         NC           94         NC           95         NC           96         NC           97         NC           98         NC           99         NC           100         NC           101         GNDAQ           102         V <sub>CC33ACAP</sub> 103         ADCGNDREF           104         V <sub>AREF</sub> 105         PUB           106         V <sub>CC33A</sub> 107         GNDA	75	AC2
78         ATRTN1           79         AT3           80         AG3           81         AC3           82         AV3           83         AV4           84         AC4           85         AG4           86         AT4           87         ATRTN2           88         AT5           89         AG5           90         AC5           91         AV5           92         NC           93         NC           94         NC           95         NC           96         NC           97         NC           98         NC           99         NC           100         NC           101         GNDAQ           102         V <sub>CC33ACAP</sub> 103         ADCGNDREF           104         V <sub>AREF</sub> 105         PUB           106         V <sub>CC33A</sub> 107         GNDA	76	AG2
79       AT3         80       AG3         81       AC3         82       AV3         83       AV4         84       AC4         85       AG4         86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	77	AT2
80       AG3         81       AC3         82       AV3         83       AV4         84       AC4         85       AG4         86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	78	ATRTN1
81       AC3         82       AV3         83       AV4         84       AC4         85       AG4         86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	79	AT3
82       AV3         83       AV4         84       AC4         85       AG4         86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	80	AG3
83       AV4         84       AC4         85       AG4         86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	81	AC3
84       AC4         85       AG4         86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	82	AV3
85       AG4         86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	83	AV4
86       AT4         87       ATRTN2         88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	84	AC4
87     ATRTN2       88     AT5       89     AG5       90     AC5       91     AV5       92     NC       93     NC       94     NC       95     NC       96     NC       97     NC       98     NC       99     NC       100     NC       101     GNDAQ       102     V <sub>CC33ACAP</sub> 103     ADCGNDREF       104     V <sub>AREF</sub> 105     PUB       106     V <sub>CC33A</sub> 107     GNDA	85	AG4
88       AT5         89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	86	AT4
89       AG5         90       AC5         91       AV5         92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	87	ATRTN2
90 AC5 91 AV5 92 NC 93 NC 94 NC 95 NC 96 NC 97 NC 98 NC 99 NC 100 NC 101 GNDAQ 102 V <sub>CC33ACAP</sub> 103 ADCGNDREF 104 V <sub>AREF</sub> 105 PUB 106 V <sub>CC33A</sub> 107 GNDA	88	AT5
91 AV5 92 NC 93 NC 94 NC 95 NC 96 NC 97 NC 98 NC 99 NC 100 NC 101 GNDAQ 102 V <sub>CC33ACAP</sub> 103 ADCGNDREF 104 V <sub>AREF</sub> 105 PUB 106 V <sub>CC33A</sub> 107 GNDA	89	AG5
92       NC         93       NC         94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	90	AC5
93 NC 94 NC 95 NC 96 NC 97 NC 98 NC 99 NC 100 NC 101 GNDAQ 102 V <sub>CC33ACAP</sub> 103 ADCGNDREF 104 V <sub>AREF</sub> 105 PUB 106 V <sub>CC33A</sub> 107 GNDA	91	AV5
94       NC         95       NC         96       NC         97       NC         98       NC         99       NC         100       NC         101       GNDAQ         102       V <sub>CC33ACAP</sub> 103       ADCGNDREF         104       V <sub>AREF</sub> 105       PUB         106       V <sub>CC33A</sub> 107       GNDA	92	NC
95 NC 96 NC 97 NC 98 NC 99 NC 100 NC 101 GNDAQ 102 V <sub>CC33ACAP</sub> 103 ADCGNDREF 104 V <sub>AREF</sub> 105 PUB 106 V <sub>CC33A</sub> 107 GNDA	93	NC
96 NC 97 NC 98 NC 99 NC 100 NC 101 GNDAQ 102 V <sub>CC33ACAP</sub> 103 ADCGNDREF 104 V <sub>AREF</sub> 105 PUB 106 V <sub>CC33A</sub> 107 GNDA	94	NC
97 NC  98 NC  99 NC  100 NC  101 GNDAQ  102 V <sub>CC33ACAP</sub> 103 ADCGNDREF  104 V <sub>AREF</sub> 105 PUB  106 V <sub>CC33A</sub> 107 GNDA	95	NC
98 NC 99 NC 100 NC 101 GNDAQ 102 V <sub>CC33ACAP</sub> 103 ADCGNDREF 104 V <sub>AREF</sub> 105 PUB 106 V <sub>CC33A</sub> 107 GNDA	96	NC
99 NC  100 NC  101 GNDAQ  102 V <sub>CC33ACAP</sub> 103 ADCGNDREF  104 V <sub>AREF</sub> 105 PUB  106 V <sub>CC33A</sub> 107 GNDA	97	NC
100     NC       101     GNDAQ       102     V <sub>CC33ACAP</sub> 103     ADCGNDREF       104     V <sub>AREF</sub> 105     PUB       106     V <sub>CC33A</sub> 107     GNDA	98	NC
101     GNDAQ       102     V <sub>CC33ACAP</sub> 103     ADCGNDREF       104     V <sub>AREF</sub> 105     PUB       106     V <sub>CC33A</sub> 107     GNDA	99	NC
102     V <sub>CC33ACAP</sub> 103     ADCGNDREF       104     V <sub>AREF</sub> 105     PUB       106     V <sub>CC33A</sub> 107     GNDA	100	NC
103 ADCGNDREF  104 V <sub>AREF</sub> 105 PUB  106 V <sub>CC33A</sub> 107 GNDA	101	GNDAQ
104 V <sub>AREF</sub> 105 PUB 106 V <sub>CC33A</sub> 107 GNDA	102	V <sub>ССЗЗАСАР</sub>
105 PUB  106 V <sub>CC33A</sub> 107 GNDA	103	ADCGNDREF
106 V <sub>CC33A</sub> 107 GNDA	104	$V_{AREF}$
107 GNDA	105	PUB
107 GNDA	106	V <sub>CC33A</sub>
108 PTEM	107	
	108	PTEM

208-Pin PQFP	
Pin Number	AFS250 Function
109	PTBASE
110	GNDNVM
111	$V_{CCNVM}$
112	V <sub>CC</sub>
113	V <sub>PUMP</sub>
114	GNDQ
115	VMV1
116	TCK
117	TDI
118	TMS
119	TDO
120	TRST
121	$V_{JTAG}$
122	IO57NDB1V0
123	GDC2/IO57PDB1V0
124	IO56NDB1V0
125	GDB2/IO56PDB1V0
126	V <sub>CCI</sub> B1
127	GND
128	IO55NDB1V0
129	GDA2/IO55PDB1V0
130	GDA0/IO54NDB1V0
131	GDA1/IO54PDB1V0
132	GDB0/IO53NDB1V0
133	GDB1/IO53PDB1V0
134	GDC0/IO52NDB1V0
135	GDC1/IO52PDB1V0
136	IO51NSB1V0
137	V <sub>CCI</sub> B1
138	GND
139	V <sub>CC</sub>
140	IO50NDB1V0
141	IO50PDB1V0
142	GCA0/IO49NDB1V0
143	GCA1/IO49PDB1V0
144	GCB0/IO48NDB1V0

208-Pin PQFP	
Pin Number	AFS250 Function
145	GCB1/IO48PDB1V0
146	GCC0/IO47NDB1V0
147	GCC1/IO47PDB1V0
148	IO42NDB1V0
149	GBC2/IO42PDB1V0
150	V <sub>CCI</sub> B1
151	GND
152	V <sub>CC</sub>
153	IO41NDB1V0
154	GBB2/IO41PDB1V0
155	IO40NDB1V0
156	GBA2/IO40PDB1V0
157	GBA1/IO39RSB0V0
158	GBA0/IO38RSB0V0
159	GBB1/IO37RSB0V0
160	GBB0/IO36RSB0V0
161	GBC 1/IO35RSB0V0
162	V <sub>CCI</sub> B0
163	GND
164	V <sub>CC</sub>
165	GBC0/IO34RSB0V0
166	IO33RSB0V0
167	IO32RSB0V0
168	IO31RSB0V0
169	IO30RSB0V0
170	IO29RSB0V0
171	IO28RSB0V0
172	IO27RSB0V0
173	IO26RSB0V0
174	IO25RSB0V0
175	V <sub>CCI</sub> B0
176	GND
177	V <sub>CC</sub>
178	IO24RSB0V0
179	IO23RSB0V0
180	IO22RSB0V0

208-Pin PQFP	
Pin Number AFS250 Function	
181	IO21RSB0V0
182	IO20RSB0V0
183	IO19RSB0V0
184	IO18RSB0V0
185	IO17RSB0V0
186	IO16RSB0V0
187	IO15RSB0V0
188	V <sub>CCI</sub> B0
189	GND
190	V <sub>CC</sub>
191	IO14RSB0V0
192	IO13RSB0V0
193	IO12RSB0V0
194	IO11RSB0V0
195	IO10RSB0V0
196	IO09RSB0V0
197	IO08RSB0V0
198	IO07RSB0V0
199	IO06RSB0V0
200	GAC1/IO05RSB0V0
201	V <sub>CCI</sub> B0
202	GND
203	V <sub>CC</sub>
204	GAC0/IO04RSB0V0
205	GAB1/IO03RSB0V0
206	GAB0/IO02RSB0V0
207	GAA1/IO01RSB0V0
208	GAA0/IO00RSB0V0

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208-Pin PQFP	
Pin Number	AFS600 Function
1	$V_{CCPLA}$
2	$V_{COMPLA}$
3	GAA2/IO85PDB4V0
4	IO85NDB4V0
5	GAB2/IO84PDB4V0
6	IO84NDB4V0
7	GAC2/IO83PDB4V0
8	IO83NDB4V0
9	IO77PDB4V0
10	IO77NDB4V0
11	IO76PDB4V0
12	IO76NDB4V0
13	V <sub>CC</sub>
14	GND
15	V <sub>CCI</sub> B4
16	GFA2/IO75PDB4V0
17	IO75NDB4V0
18	GFC2/IO73PDB4V0
19	IO73NDB4V0
20	$V_{CCOSC}$
21	XTAL1
22	XTAL2
23	GNDOSC
24	GFC1/IO72PDB4V0
25	GFC0/IO72NDB4V0
26	GFB1/IO71PDB4V0
27	GFB0/IO71NDB4V0
28	GFA1/IO70PDB4V0
29	GFA0/IO70NDB4V0
30	IO69PDB4V0
31	IO69NDB4V0
32	V <sub>CC</sub>
33	GND
34	V <sub>CCI</sub> B4
35	GEC1/IO63PDB4V0
36	GEC0/IO63NDB4V0

208-Pin PQFP	
Pin Number	AFS600 Function
37	GEB1/IO62PDB4V0
38	GEB0/IO62NDB4V0
39	GEA1/IO61PDB4V0
40	GEA0/IO61NDB4V0
41	GEC2/IO60PDB4V0
42	IO60NDB4V0
43	VMV4
44	GNDQ
45	V <sub>CC</sub>
46	$V_{CCNVM}$
47	GNDNVM
48	GND
49	V <sub>CC15A</sub>
50	PCAP
51	NCAP
52	V <sub>CC33PMP</sub>
53	V <sub>CC33N</sub>
54	GNDA
55	GNDAQ
56	AV0
57	AC0
58	AG0
59	AT0
60	ATRTN0
61	AT1
62	AG1
63	AC1
64	AV1
65	AV2
66	AC2
67	AG2
68	AT2
69	ATRTN1
70	AT3
71	AG3
72	AC3

208-Pin PQFP	
Pin Number	AFS600 Function
73	AV3
74	AV4
75	AC4
76	AG4
77	AT4
78	ATRTN2
79	AT5
80	AG5
81	AC5
82	AV5
83	AV6
84	AC6
85	AG6
86	AT6
87	ATRTN3
88	AT7
89	AG7
90	AC7
91	AV7
92	AV8
93	AC8
94	AG8
95	AT8
96	ATRTN4
97	AT9
98	AG9
99	AC9
100	AV9
101	GNDAQ
102	V <sub>ССЗЗАСАР</sub>
103	ADCGNDREF
104	VAREF
105	PUB
106	V <sub>CC33A</sub>
107	GNDA
108	PTEM

208-Pin PQFP	
Pin Number	AFS600 Function
109	PTBASE
110	GNDNVM
111	$V_{CCNVM}$
112	V <sub>CC</sub>
113	V <sub>PUMP</sub>
114	NC
115	TCK
116	TDI
117	TMS
118	TDO
119	TRST
120	$V_{JTAG}$
121	IO57NDB2V0
122	GDC2/IO57PDB2V0
123	IO56NDB2V0
124	GDB2/IO56PDB2V0
125	IO55NDB2V0
126	GDA2/IO55PDB2V0
127	GDA0/IO54NDB2V0
128	GDA1/IO54PDB2V0
129	V <sub>CCI</sub> B2
130	GND
131	V <sub>CC</sub>
132	GCA0/IO45NDB2V0
133	GCA1/IO45PDB2V0
134	GCB0/IO44NDB2V0
135	GCB1/IO44PDB2V0
136	GCC0/IO43NDB2V0
137	GCC1/IO43PDB2V0
138	IO42NDB2V0
139	IO42PDB2V0
140	IO41NDB2V0
141	GCC2/IO41PDB2V0
142	V <sub>CCI</sub> B2
143	GND
144	V <sub>CC</sub>

208-Pin PQFP	
Pin Number	AFS600 Function
145	IO40NDB2V0
146	GCB2/IO40PDB2V0
147	IO39NDB2V0
148	GCA2/IO39PDB2V0
149	IO31NDB2V0
150	GBB2/IO31PDB2V0
151	IO30NDB2V0
152	GBA2/IO30PDB2V0
153	VMV2
154	GNDQ
155	$V_{COMPLB}$
156	$V_{CCPLB}$
157	VMV1
158	GNDQ
159	GBB1/IO27PPB1V1
160	GBA1/IO28PPB1V1
161	GBB0/IO27NPB1V1
162	GBA0/IO28NPB1V1
163	V <sub>CCI</sub> B1
164	GND
165	V <sub>CC</sub>
166	GBC1/IO26PDB1V1
167	GBC0/IO26NDB1V1
168	IO24PPB1V1
169	IO23PPB1V1
170	IO24NPB1V1
171	IO23NPB1V1
172	IO22PPB1V0
173	IO21PPB1V0
174	IO22NPB1V0
175	IO21NPB1V0
176	IO20PSB1V0
177	IO19PSB1V0
178	IO14NSB0V1
179	IO12PDB0V1
180	IO12NDB0V1

208-Pin PQFP		
Pin Number	AFS600 Function	
181	V <sub>CCI</sub> B0	
182	GND	
183	V <sub>CC</sub>	
184	IO10PPB0V1	
185	IO09PPB0V1	
186	IO10NPB0V1	
187	IO09NPB0V1	
188	IO08PPB0V1	
189	IO07PPB0V1	
190	IO08NPB0V1	
191	IO07NPB0V1	
192	IO06PPB0V0	
193	IO05PPB0V0	
194	IO06NPB0V0	
195	IO04PPB0V0	
196	IO05NPB0V0	
197	IO04NPB0V0	
198	GAC1/IO03PDB0V0	
199	GAC0/IO03NDB0V0	
200	V <sub>CCI</sub> B0	
201	GND	
202	V <sub>CC</sub>	
203	GAB1/IO02PDB0V0	
204	GAB0/IO02NDB0V0	
205	GAA1/IO01PDB0V0	
206	GAA0/IO01NDB0V0	
207	GNDQ	
208	VMV0	

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## 256-Pin FBGA

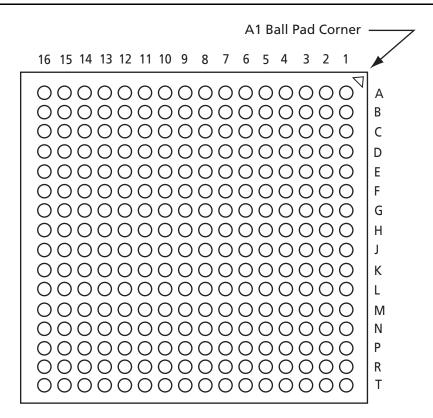


Figure 4-4 • 256-Pin FBGA (Bottom View)

#### Note

For Package Manufacturing and Environmental information, visit Resource center at http://www.actel.com/products/rescenter/package/index.html.

256-Pin FBGA	
Pin Number	AFS090 Function
A1	GND
A2	V <sub>CCI</sub> B0
А3	GAB0/IO02RSB0V0
A4	GAB1/IO03RSB0V0
A5	GND
A6	IO07RSB0V0
A7	IO10RSB0V0
A8	IO11RSB0V0
A9	IO16RSB0V0
A10	IO17RSB0V0
A11	IO18RSB0V0
A12	GND
A13	GBC0/IO25RSB0V0
A14	GBA0/IO29RSB0V0
A15	V <sub>CCI</sub> B0
A16	GND
В1	V <sub>COMPLA</sub>
B2	$V_{CCPLA}$
В3	GAA0/IO00RSB0V0
В4	GAA1/IO01RSB0V0
B5	NC
В6	IO06RSB0V0
В7	V <sub>CCI</sub> B0
В8	IO12RSB0V0
В9	IO13RSB0V0
B10	V <sub>CCI</sub> B0
B11	IO19RSB0V0
B12	GBB0/IO27RSB0V0
B13	GBC1/IO26RSB0V0
B14	GBA1/IO30RSB0V0
B15	NC
B16	NC
C1	V <sub>CCI</sub> B3
C2	GND
C3	VMV3
C4	NC

256-P	256-Pin FBGA	
Pin Number	AFS090 Function	
C5	V <sub>CCI</sub> B0	
C6	GAC1/IO05RSB0V0	
C7	IO09RSB0V0	
C8	IO14RSB0V0	
C9	IO15RSB0V0	
C10	NC	
C11	IO20RSB0V0	
C12	V <sub>CCI</sub> B0	
C13	GBB1/IO28RSB0V0	
C14	VMV1	
C15	GND	
C16	V <sub>CCI</sub> B1	
D1	GFA2/IO51NDB3V0	
D2	GAC2/IO51PDB3V0	
D3	GAB2/IO52NDB3V0	
D4	GAA2/IO52PDB3V0	
D5	NC	
D6	GAC0/IO04RSB0V0	
D7	IO08RSB0V0	
D8	NC	
D9	NC	
D10	IO21RSB0V0	
D11	IO23RSB0V0	
D12	NC	
D13	GBA2/IO31PDB1V0	
D14	GBB2/IO31NDB1V0	
D15	GBC2/IO32PDB1V0	
D16	GCA2/IO32NDB1V0	
E1	GND	
E2	GFC2/IO50NDB3V0	
E3	GFB2/IO50PDB3V0	
E4	V <sub>CCI</sub> B3	
E5	NC	
E6	NC	
E7	GND	
E8	NC	

256-Pin FBGA	
Pin Number	AFS090 Function
E9	IO22RSB0V0
E10	GND
E11	IO24RSB0V0
E12	NC
E13	V <sub>CCI</sub> B1
E14	GCC2/IO33NDB1V0
E15	GCB2/IO33PDB1V0
E16	GND
F1	GFB0/IO48NDB3V0
F2	GFB1/IO48PDB3V0
F3	GFC0/IO49NDB3V0
F4	NC
F5	GFC1/IO49PDB3V0
F6	NC
F7	NC
F8	NC
F9	NC
F10	NC
F11	NC
F12	NC
F13	NC
F14	NC
F15	GCC1/IO34PDB1V0
F16	GCC0/IO34NDB1V0
G1	GEC0/IO46NPB3V0
G2	V <sub>CCI</sub> B3
G3	GEC1/IO46PPB3V0
G4	GFA1/IO47PDB3V0
G5	GND
G6	GFA0/IO47NDB3V0
G7	GND
G8	V <sub>CC</sub>
G9	GND
G10	V <sub>CC</sub>
G11	GDA1/IO37NDB1V0
G12	GND

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256-Pin FBGA	
Pin Number	AFS090 Function
G13	IO37PDB1V0
G14	GCB0/IO35NPB1V0
G15	V <sub>CCI</sub> B1
G16	GCB1/IO35PPB1V0
H1	GEB1/IO45PDB3V0
H2	GEB0/IO45NDB3V0
H3	XTAL2
H4	XTAL1
H5	GNDOSC
H6	V <sub>ccosc</sub>
H7	V <sub>CC</sub>
H8	GND
H9	V <sub>CC</sub>
H10	GND
H11	GDC0/IO38NDB1V0
H12	GDC1/IO38PDB1V0
H13	GDB1/IO39PDB1V0
H14	GDB0/IO39NDB1V0
H15	GCA0/IO36NDB1V0
H16	GCA1/IO36PDB1V0
J1	GEA0/IO44NDB3V0
J2	GEA1/IO44PDB3V0
J3	IO43NDB3V0
J4	GEC2/IO43PDB3V0
J5	NC
J6	NC
J7	GND
J8	V <sub>CC</sub>
J9	GND
J10	V <sub>CC</sub>
J11	GDC2/IO41NPB1V0
J12	NC
J13	NC
J14	GDA0/IO40PDB1V0
J15	NC
J16	GDA2/IO40NDB1V0

256-Pin FBGA	
Pin Number	AFS090 Function
K1	NC
K2	V <sub>CCI</sub> B3
K3	NC
K4	NC
K5	GND
K6	NC
K7	V <sub>CC</sub>
K8	GND
К9	V <sub>CC</sub>
K10	GND
K11	NC
K12	GND
K13	NC
K14	NC
K15	V <sub>CCI</sub> B1
K16	NC
L1	NC
L2	NC
L3	NC
L4	NC
L5	NC
L6	NC
L7	GNDA
L8	AC0
L9	NC
L10	NC
L11	PTEM
L12	TDO
L13	$V_{JTAG}$
L14	NC
L15	GDB2/IO41PPB1V0
L16	NC
M1	GND
M2	NC
M3	NC
M4	V <sub>CCI</sub> B3

256-Pin FBGA	
Pin Number	AFS090 Function
M5	NC
M6	NC
M7	NC
M8	AG1
M9	NC
M10	AC2
M11	AG3
M12	$V_{PUMP}$
M13	V <sub>CCI</sub> B1
M14	TMS
M15	TRST
M16	GND
N1	GEB2/IO42PDB3V0
N2	GEA2/IO42NDB3V0
N3	NC
N4	V <sub>CC33PMP</sub>
N5	V <sub>CC15A</sub>
N6	NC
N7	AC1
N8	NC
N9	NC
N10	AG2
N11	AC4
N12	GNDA
N13	VCC33A
N14	$V_{CCNVM}$
N15	TCK
N16	TDI
P1	V <sub>CCNVM</sub>
P2	GNDNVM
P3	GNDA
P4	NC
P5	NC
P6	NC
P7	AG0
P8	NC

256-Pin FBGA	
Pin Number	AFS090 Function
P9	GNDA
P10	AC3
P11	AV4
P12	AG4
P13	NC
P14	ADCGNDREF
P15	PTBASE
P16	GNDNVM
R1	V <sub>CCI</sub> B3
R2	PCAP
R3	NC
R4	NC
R5	AV0
R6	AT0
R7	AV1
R8	NC
R9	AV2
R10	AT3
R11	AV3
R12	NC
R13	NC
R14	NC
R15	PUB
R16	V <sub>CCI</sub> B1
T1	GND
T2	NCAP
T3	V <sub>CC33N</sub>
T4	NC
T5	AT1
T6	ATRTN0
T7	NC
T8	NC
T9	AT2
T10	ATRTN1
T11	AT4
T12	ATRTN2

256-Pin FBGA	
Pin Number	AFS090 Function
T13	GNDA
T14	V <sub>ССЗЗАСАР</sub>
T15	VAREF
T16	GND

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256-Pin FBGA	
Pin Number	AFS250 Function
A1	GND
A2	V <sub>CCI</sub> B0
А3	GAA0/IO00RSB0V0
A4	GAA1/IO01RSB0V0
A5	GND
A6	IO11RSB0V0
A7	IO14RSB0V0
A8	IO15RSB0V0
A9	IO24RSB0V0
A10	IO25RSB0V0
A11	IO26RSB0V0
A12	GND
A13	GBA0/IO38RSB0V0
A14	IO32RSB0V0
A15	V <sub>CCI</sub> B0
A16	GND
B1	V <sub>COMPLA</sub>
B2	$V_{CCPLA}$
В3	IO07RSB0V0
B4	IO06RSB0V0
B5	GAB1/IO03RSB0V0
В6	IO10RSB0V0
В7	V <sub>CCI</sub> B0
В8	IO16RSB0V0
В9	IO17RSB0V0
B10	V <sub>CCI</sub> B0
B11	IO27RSB0V0
B12	GBC0/IO34RSB0V0
B13	GBA1/IO39RSB0V0
B14	IO33RSB0V0
B15	NC
B16	NC
C1	V <sub>CCI</sub> B3
C2	GND
С3	VMV3
C4	NC

256-1	256-Pin FBGA	
Pin Number	AFS250 Function	
C5	V <sub>CCI</sub> B0	
C6	GAC1/IO05RSB0V0	
C7	IO12RSB0V0	
C8	IO22RSB0V0	
C9	IO23RSB0V0	
C10	IO30RSB0V0	
C11	IO31RSB0V0	
C12	V <sub>CCI</sub> B0	
C13	GBC1/IO35RSB0V0	
C14	VMV1	
C15	GND	
C16	V <sub>CCI</sub> B1	
D1	IO75NDB3V0	
D2	GAB2/IO75PDB3V0	
D3	IO76NDB3V0	
D4	GAA2/IO76PDB3V0	
D5	GAB0/IO02RSB0V0	
D6	GAC0/IO04RSB0V0	
D7	IO13RSB0V0	
D8	IO20RSB0V0	
D9	IO21RSB0V0	
D10	IO28RSB0V0	
D11	GBB0/IO36RSB0V0	
D12	NC	
D13	GBA2/IO40PDB1V0	
D14	IO40NDB1V0	
D15	GBB2/IO41PDB1V0	
D16	IO41NDB1V0	
E1	GND	
E2	IO73NDB3V0	
E3	IO73PDB3V0	
E4	V <sub>CCI</sub> B3	
E5	IO74NPB3V0	
E6	IO08RSB0V0	
E7	GND	
E8	IO18RSB0V0	

256-Pin FBGA	
Pin Number	AFS250 Function
E9	NC
E10	GND
E11	GBB1/IO37RSB0V0
E12	IO50PPB1V0
E13	V <sub>CCI</sub> B1
E14	IO42NDB1V0
E15	GBC2/IO42PDB1V0
E16	GND
F1	NC
F2	NC
F3	IO72NDB3V0
F4	IO72PDB3V0
F5	NC
F6	GAC2/IO74PPB3V0
F7	IO09RSB0V0
F8	IO19RSB0V0
F9	NC
F10	IO29RSB0V0
F11	IO43NDB1V0
F12	IO43PDB1V0
F13	IO44NDB1V0
F14	GCA2/IO44PDB1V0
F15	GCB2/IO45PDB1V0
F16	IO45NDB1V0
G1	IO70NPB3V0
G2	V <sub>CCI</sub> B3
G3	GFB2/IO70PPB3V0
G4	GFA2/IO71PDB3V0
G5	GND
G6	IO71NDB3V0
G7	GND
G8	V <sub>CC</sub>
G9	GND
G10	V <sub>CC</sub>
G11	GCC0/IO47NDB1V0
G12	GND

256-Pin FBGA	
Pin Number	AFS250 Function
G13	GCC1/IO47PDB1V0
G14	IO46NPB1V0
G15	V <sub>CCI</sub> B1
G16	GCC2/IO46PPB1V0
H1	GFC2/IO69PDB3V0
H2	IO69NDB3V0
H3	XTAL2
H4	XTAL1
H5	GNDOSC
H6	V <sub>ccosc</sub>
H7	V <sub>CC</sub>
H8	GND
H9	V <sub>CC</sub>
H10	GND
H11	IO51NDB1V0
H12	IO51PDB1V0
H13	GCA1/IO49PDB1V0
H14	GCA0/IO49NDB1V0
H15	GCB0/IO48NDB1V0
H16	GCB1/IO48PDB1V0
J1	GFA0/IO66NDB3V0
J2	GFA1/IO66PDB3V0
J3	GFB0/IO67NDB3V0
J4	GFB1/IO67PDB3V0
J5	GFC0/IO68NDB3V0
J6	GFC1/IO68PDB3V0
J7	GND
J8	V <sub>CC</sub>
19	GND
J10	V <sub>CC</sub>
J11	IO56NPB1V0
J12	GDB0/IO53NPB1V0
J13	GDA1/IO54PDB1V0
J14	GDC1/IO52PPB1V0
J15	IO50NPB1V0
J16	GDC0/IO52NPB1V0

256-Pin FBGA	
Pin Number	AFS250 Function
K1	IO65NPB3V0
K2	V <sub>CCI</sub> B3
K3	IO65PPB3V0
K4	IO64PDB3V0
K5	GND
K6	IO64NDB3V0
K7	V <sub>CC</sub>
K8	GND
K9	V <sub>CC</sub>
K10	GND
K11	GDC2/IO57PPB1V0
K12	GND
K13	GDA0/IO54NDB1V0
K14	GDA2/IO55PPB1V0
K15	V <sub>CCI</sub> B1
K16	GDB1/IO53PPB1V0
L1	GEC1/IO63PDB3V0
L2	GEC0/IO63NDB3V0
L3	GEB1/IO62PDB3V0
L4	GEB0/IO62NDB3V0
L5	IO60NDB3V0
L6	GEC2/IO60PDB3V0
L7	GNDA
L8	AC0
L9	AV2
L10	AC3
L11	PTEM
L12	TDO
L13	$V_{JTAG}$
L14	IO57NPB1V0
L15	GDB2/IO56PPB1V0
L16	IO55NPB1V0
M1	GND
M2	GEA1/IO61PDB3V0
M3	GEA0/IO61NDB3V0
M4	V <sub>CCI</sub> B3

256-Pin FBGA	
Pin Number	AFS250 Function
M5	IO58NPB3V0
M6	NC
M7	NC
M8	AG1
M9	AC2
M10	AC4
M11	AG5
M12	$V_{PUMP}$
M13	V <sub>CCI</sub> B1
M14	TMS
M15	TRST
M16	GND
N1	GEB2/IO59PDB3V0
N2	IO59NDB3V0
N3	GEA2/IO58PPB3V0
N4	V <sub>CC33PMP</sub>
N5	V <sub>CC15A</sub>
N6	NC
N7	AC1
N8	AG3
N9	AV3
N10	AG4
N11	NC
N12	GNDA
N13	V <sub>CC33A</sub>
N14	V <sub>CCNVM</sub>
N15	TCK
N16	TDI
P1	V <sub>CCNVM</sub>
P2	GNDNVM
P3	GNDA
P4	NC
P5	NC
P6	NC
P7	AG0
P8	AG2

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256-Pin FBGA	
Pin Number	AFS250 Function
PIII Number	GNDA
P10	AC5
	NC NC
P11	
P12	NC
P13	NC
P14	ADCGNDREF
P15	PTBASE
P16	GNDNVM
R1	V <sub>CCI</sub> B3
R2	PCAP
R3	NC
R4	NC
R5	AV0
R6	AT0
R7	AV1
R8	AT3
R9	AV4
R10	AT5
R11	AV5
R12	NC
R13	NC
R14	NC
R15	PUB
R16	V <sub>CCI</sub> B1
T1	GND
T2	NCAP
T3	V <sub>CC33N</sub>
T4	NC
T5	AT1
T6	ATRTN0
T7	AT2
T8	ATRTN1
T9	AT4
T10	ATRTN2
T11	NC
T12	NC
	-

256-Pin FBGA	
Pin Number	AFS250 Function
T13	GNDA
T14	V <sub>ССЗЗАСАР</sub>
T15	VAREF
T16	GND

256-Pin FBGA		
Pin Number AFS600 Function		
A1	GND	
A2	V <sub>CCI</sub> B0	
A3	GAA0/IO01NDB0V0	
A4	GAA1/IO01PDB0V0	
A5	GND	
A6	IO10PDB0V1	
A7	IO12PDB0V1	
A8	IO12NDB0V1	
A9	IO22NDB1V0	
A10	IO22PDB1V0	
A11	IO24NDB1V1	
A12	GND	
A13	GBA0/IO28NDB1V1	
A14	IO29NDB1V1	
A15	V <sub>CCI</sub> B1	
A16	GND	
B1	$V_{COMPLA}$	
B2	$V_{CCPLA}$	
В3	IO00NDB0V0	
B4	IO00PDB0V0	
B5	GAB1/IO02PPB0V0	
В6	IO10NDB0V1	
В7	V <sub>CCI</sub> B0	
В8	IO18NDB1V0	
В9	IO18PDB1V0	
B10	V <sub>CCI</sub> B1	
B11	IO24PDB1V1	
B12	GBC0/IO26NPB1V1	
B13	GBA1/IO28PDB1V1	
B14	IO29PDB1V1	
B15	$V_{CCPLB}$	
B16	$V_{COMPLB}$	
C1	V <sub>CCI</sub> B4	
C2	GND	
C3	VMV4	
C4	VMV0	

256-Pin FBGA	
Pin Number	AFS600 Function
C5	V <sub>CCI</sub> B0
C6	GAC1/IO03PDB0V0
C7	IO06NDB0V0
C8	IO16PDB1V0
C9	IO16NDB1V0
C10	IO25NDB1V1
C11	IO25PDB1V1
C12	V <sub>CCI</sub> B1
C13	GBC1/IO26PPB1V1
C14	VMV2
C15	GND
C16	V <sub>CCI</sub> B2
D1	IO84NDB4V0
D2	GAB2/IO84PDB4V0
D3	IO85NDB4V0
D4	GAA2/IO85PDB4V0
D5	GAB0/IO02NPB0V0
D6	GAC0/IO03NDB0V0
D7	IO06PDB0V0
D8	IO14NDB0V1
D9	IO14PDB0V1
D10	IO23PDB1V1
D11	GBB0/IO27NDB1V1
D12	VMV1
D13	GBA2/IO30PDB2V0
D14	IO30NDB2V0
D15	GBB2/IO31PDB2V0
D16	IO31NDB2V0
E1	GND
E2	IO81NDB4V0
E3	IO81PDB4V0
E4	V <sub>CCI</sub> B4
E5	IO83NPB4V0
E6	IO04NPB0V0
E7	GND
E8	IO08PDB0V1

256-Pin FBGA		
Pin Number AFS600 Function		
E9	IO20NDB1V0	
E10	GND	
E11	GBB1/IO27PDB1V1	
E12	IO33PSB2V0	
E13	V <sub>CCI</sub> B2	
E14	IO32NDB2V0	
E15	GBC2/IO32PDB2V0	
E16	GND	
F1	IO79NDB4V0	
F2	IO79PDB4V0	
F3	IO76NDB4V0	
F4	IO76PDB4V0	
F5	IO82PSB4V0	
F6	GAC2/IO83PPB4V0	
F7	IO04PPB0V0	
F8	IO08NDB0V1	
F9	IO20PDB1V0	
F10	IO23NDB1V1	
F11	IO36NDB2V0	
F12	IO36PDB2V0	
F13	IO39NDB2V0	
F14	GCA2/IO39PDB2V0	
F15	GCB2/IO40PDB2V0	
F16	IO40NDB2V0	
G1	IO74NPB4V0	
G2	V <sub>CCI</sub> B4	
G3	GFB2/IO74PPB4V0	
G4	GFA2/IO75PDB4V0	
G5	GND	
G6	IO75NDB4V0	
G7	GND	
G8	V <sub>CC</sub>	
G9	GND	
G10	V <sub>CC</sub>	
G11	GCC0/IO43NDB2V0	
G12	GND	

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256-Pin FBGA	
Pin Number	AFS600 Function
G13	GCC1/IO43PDB2V0
G14	IO41NPB2V0
G15	V <sub>CCI</sub> B2
G16	GCC2/IO41PPB2V0
H1	GFC2/IO73PDB4V0
H2	IO73NDB4V0
НЗ	XTAL2
H4	XTAL1
H5	GNDOSC
H6	V <sub>CCOSC</sub>
H7	V <sub>CC</sub>
Н8	GND
Н9	V <sub>CC</sub>
H10	GND
H11	IO47NDB2V0
H12	IO47PDB2V0
H13	GCA1/IO45PDB2V0
H14	GCA0/IO45NDB2V0
H15	GCB0/IO44NDB2V0
H16	GCB1/IO44PDB2V0
J1	GFA0/IO70NDB4V0
J2	GFA1/IO70PDB4V0
J3	GFB0/IO71NDB4V0
J4	GFB1/IO71PDB4V0
J5	GFC0/IO72NDB4V0
J6	GFC1/IO72PDB4V0
J7	GND
J8	V <sub>CC</sub>
J9	GND
J10	V <sub>CC</sub>
J11	IO56NPB2V0
J12	GDB0/IO53NPB2V0
J13	GDA1/IO54PDB2V0
J14	GDC1/IO52PPB2V0
J15	IO51NSB2V0
J16	GDC0/IO52NPB2V0

256-Pin FBGA	
Pin Number AFS600 Function	
K1	IO67NPB4V0
K2	V <sub>CCI</sub> B4
К3	IO67PPB4V0
K4	IO65PDB4V0
K5	GND
K6	IO65NDB4V0
K7	V <sub>CC</sub>
K8	GND
К9	V <sub>CC</sub>
K10	GND
K11	GDC2/IO57PPB2V0
K12	GND
K13	GDA0/IO54NDB2V0
K14	GDA2/IO55PPB2V0
K15	V <sub>CCI</sub> B2
K16	GDB1/IO53PPB2V0
L1	GEC1/IO63PDB4V0
L2	GEC0/IO63NDB4V0
L3	GEB1/IO62PDB4V0
L4	GEB0/IO62NDB4V0
L5	IO60NDB4V0
L6	GEC2/IO60PDB4V0
L7	GNDA
L8	AC2
L9	AV4
L10	AC5
L11	PTEM
L12	TDO
L13	$V_{JTAG}$
L14	IO57NPB2V0
L15	GDB2/IO56PPB2V0
L16	IO55NPB2V0
M1	GND
M2	GEA1/IO61PDB4V0
M3	GEA0/IO61NDB4V0
M4	V <sub>CCI</sub> B4

256-Pin FBGA		
Pin Number	AFS600 Function	
M5	IO58NPB4V0	
M6	AV0	
M7	AC1	
M8	AG3	
M9	AC4	
M10	AC6	
M11	AG7	
M12	$V_{PUMP}$	
M13	V <sub>CCI</sub> B2	
M14	TMS	
M15	TRST	
M16	GND	
N1	GEB2/IO59PDB4V0	
N2	IO59NDB4V0	
N3	GEA2/IO58PPB4V0	
N4	V <sub>CC33PMP</sub>	
N5	V <sub>CC15A</sub>	
N6	AG0	
N7	AC3	
N8	AG5	
N9	AV5	
N10	AG6	
N11	AC8	
N12	GNDA	
N13	V <sub>CC33A</sub>	
N14	$V_{CCNVM}$	
N15	TCK	
N16	TDI	
P1	$V_{CCNVM}$	
P2	GNDNVM	
Р3	GNDA	
P4	AC0	
P5	AG1	
P6	AV1	
P7	AG2	
P8	AG4	

256-Pin FBGA	
Pin Number AFS600 Function	
P9	GNDA
P10	AC7
P11	AV8
P12	AG8
P13	AV9
P14	ADCGNDREF
P15	PTBASE
P16	GNDNVM
R1	V <sub>CCI</sub> B4
R2	PCAP
R3	AT1
R4	AT0
R5	AV2
R6	AT2
R7	AV3
R8	AT5
R9	AV6
R10	AT7
R11	AV7
R12	AT9
R13	AG9
R14	AC9
R15	PUB
R16	V <sub>CCI</sub> B2
T1	GND
T2	NCAP
T3	V <sub>CC33N</sub>
T4	ATRTN0
T5	AT3
T6	ATRTN1
T7	AT4
Т8	ATRTN2
Т9	AT6
T10	ATRTN3
T11	AT8
T12	ATRTN4

256-Pin FBGA	
Pin Number	AFS600 Function
T13	GNDA
T14	$V_{CC33ACAP}$
T15	VAREF
T16	GND

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256-Pin FBGA	
Pin Number	AFS1500 Function
A1	GND
A2	V <sub>CCI</sub> B0
A3	GAA0/IO01NDB0V0
A4	GAA1/IO01PDB0V0
A5	GND
A6	IO07PDB0V1
A7	IO13PDB0V2
A8	IO13NDB0V2
A9	IO24NDB1V0
A10	IO24PDB1V0
A11	IO29NDB1V1
A12	GND
A13	GBA0/IO42NDB1V2
A14	IO43NDB1V2
A15	V <sub>CCI</sub> B1
A16	GND
B1	$V_{COMPLA}$
B2	$V_{CCPLA}$
В3	IO00NDB0V0
B4	IO00PDB0V0
B5	GAB1/IO02PPB0V0
В6	IO07NDB0V1
В7	V <sub>CCI</sub> B0
В8	IO22NDB1V0
В9	IO22PDB1V0
B10	V <sub>CCI</sub> B1
B11	IO29PDB1V1
B12	GBC0/IO40NPB1V2
B13	GBA1/IO42PDB1V2
B14	IO43PDB1V2
B15	$V_{CCPLB}$
B16	$V_{COMPLB}$
C1	V <sub>CCI</sub> B4
C2	GND
C3	VMV4
C4	VMV0

25	6-Pin FBGA
Pin Number	AFS1500 Function
C5	V <sub>CCI</sub> B0
C6	GAC1/IO03PDB0V0
C7	IO09NDB0V1
C8	IO23PDB1V0
C9	IO23NDB1V0
C10	IO31NDB1V1
C11	IO31PDB1V1
C12	V <sub>CCI</sub> B1
C13	GBC1/IO40PPB1V2
C14	VMV2
C15	GND
C16	V <sub>CCI</sub> B2
D1	IO124NDB4V0
D2	GAB2/IO124PDB4V0
D3	IO125NDB4V0
D4	GAA2/IO125PDB4V0
D5	GAB0/IO02NPB0V0
D6	GAC0/IO03NDB0V0
D7	IO09PDB0V1
D8	IO15NDB0V2
D9	IO15PDB0V2
D10	IO37PDB1V2
D11	GBB0/IO41NDB1V2
D12	VMV1
D13	GBA2/IO44PDB2V0
D14	IO44NDB2V0
D15	GBB2/IO45PDB2V0
D16	IO45NDB2V0
E1	GND
E2	IO118NDB4V0
E3	IO118PDB4V0
E4	V <sub>CCI</sub> B4
E5	IO123NPB4V0
E6	IO05NPB0V1
E7	GND
E8	IO11PDB0V1

256-Pin FBGA	
Pin Number	AFS1500 Function
E9	IO27NDB1V1
E10	GND
E11	GBB1/IO41PDB1V2
E12	IO48PSB2V0
E13	V <sub>CCI</sub> B2
E14	IO46NDB2V0
E15	GBC2/IO46PDB2V0
E16	GND
F1	IO111NDB4V0
F2	IO111PDB4V0
F3	IO112NDB4V0
F4	IO112PDB4V0
F5	IO120PSB4V0
F6	GAC2/IO123PPB4V0
F7	IO05PPB0V1
F8	IO11NDB0V1
F9	IO27PDB1V1
F10	IO37NDB1V2
F11	IO50NDB2V0
F12	IO50PDB2V0
F13	IO59NDB2V0
F14	GCA2/IO59PDB2V0
F15	GCB2/IO60PDB2V0
F16	IO60NDB2V0
G1	IO109NPB4V0
G2	V <sub>CCI</sub> B4
G3	GFB2/IO109PPB4V0
G4	GFA2/IO110PDB4V0
G5	GND
G6	IO110NDB4V0
G7	GND
G8	V <sub>CC</sub>
G9	GND
G10	V <sub>CC</sub>
G11	GCC0/IO62NDB2V0
G12	GND

256-Pin FBGA	
Pin Number	AFS1500 Function
G13	GCC1/IO62PDB2V0
G14	IO61NPB2V0
G15	V <sub>CCI</sub> B2
G16	GCC2/IO61PPB2V0
H1	GFC2/IO108PDB4V0
H2	IO108NDB4V0
Н3	XTAL2
H4	XTAL1
H5	GNDOSC
H6	V <sub>ccosc</sub>
H7	V <sub>CC</sub>
Н8	GND
H9	V <sub>CC</sub>
H10	GND
H11	IO69NDB2V0
H12	IO69PDB2V0
H13	GCA1/IO64PDB2V0
H14	GCA0/IO64NDB2V0
H15	GCB0/IO63NDB2V0
H16	GCB1/IO63PDB2V0
J1	GFA0/IO105NDB4V0
J2	GFA1/IO105PDB4V0
J3	GFB0/IO106NDB4V0
J4	GFB1/IO106PDB4V0
J5	GFC0/IO107NDB4V0
J6	GFC1/IO107PDB4V0
J7	GND
J8	V <sub>CC</sub>
J9	GND
J10	V <sub>CC</sub>
J11	IO83NPB2V0
J12	GDB0/IO80NPB2V0
J13	GDA1/IO81PDB2V0
J14	GDC1/IO79PPB2V0
J15	IO77NSB2V0
J16	GDC0/IO79NPB2V0

256-Pin FBGA	
Pin Number	AFS1500 Function
K1	IO92NPB4V0
K2	V <sub>CCI</sub> B4
K3	IO92PPB4V0
K4	IO96PDB4V0
K5	GND
K6	IO96NDB4V0
K7	V <sub>CC</sub>
K8	GND
K9	V <sub>CC</sub>
K10	GND
K11	GDC2/IO84PPB2V0
K12	GND
K13	GDA0/IO81NDB2V0
K14	GDA2/IO82PPB2V0
K15	V <sub>CCI</sub> B2
K16	GDB1/IO80PPB2V0
L1	GEC1/IO90PDB4V0
L2	GEC0/IO90NDB4V0
L3	GEB1/IO89PDB4V0
L4	GEB0/I089NDB4V0
L5	IO87NDB4V0
L6	GEC2/IO87PDB4V0
L7	GNDA
L8	AC2
L9	AV4
L10	AC5
L11	PTEM
L12	TDO
L13	VJTAG
L14	IO84NPB2V0
L15	GDB2/IO83PPB2V0
L16	IO82NPB2V0
M1	GND
M2	GEA1/IO88PDB4V0
M3	GEA0/IO88NDB4V0
M4	V <sub>CCI</sub> B4

256-Pin FBGA	
Pin Number	AFS1500 Function
M5	IO85NPB4V0
M6	AV0
M7	AC1
M8	AG3
M9	AC4
M10	AC6
M11	AG7
M12	V <sub>PUMP</sub>
M13	V <sub>CCI</sub> B2
M14	TMS
M15	TRST
M16	GND
N1	GEB2/IO86PDB4V0
N2	IO86NDB4V0
N3	GEA2/IO85PPB4V0
N4	V <sub>CC33PMP</sub>
N5	V <sub>CC15A</sub>
N6	AG0
N7	AC3
N8	AG5
N9	AV5
N10	AG6
N11	AC8
N12	GNDA
N13	V <sub>CC33A</sub>
N14	$V_{CCNVM}$
N14	$V_{CCNVM}$
N15	TCK
N16	TDI
P1	$V_{CCNVM}$
P1	$V_{CCNVM}$
P2	GNDNVM
P2	GNDNVM
Р3	GNDA
P4	AC0
P5	AG1

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256-Pin FBGA		
Pin Number	1	
P6	AV1	
P7	AG2	
P8	AG2 AG4	
P9	GNDA	
P10	AC7	
P11	AV8	
P12	AG8	
P13	AV9	
P14	ADCGNDREF	
P15	PTBASE	
P16	GNDNVM	
P16	GNDNVM	
R1	V <sub>CCI</sub> B4	
R2	PCAP	
R3	AT1	
R4	AT0	
R5	AV2	
R6	AT2	
R7	AV3	
R8	AT5	
R9	AV6	
R10	AT7	
R11	AV7	
R12	AT9	
R13	AG9	
R14	AC9	
R15	PUB	
R16	V <sub>CCI</sub> B2	
T1	GND	
T2	NCAP	
T3	V <sub>CC33N</sub>	
T4	ATRTN0	
T5	AT3	
T6	ATRTN1	
T7	AT4	
T8	ATRTN2	
10	, 11111112	

256-Pin FBGA	
Pin Number	AFS1500 Function
Т9	AT6
T10	ATRTN3
T11	AT8
T12	ATRTN4
T13	GNDA
T14	V <sub>CC33ACAP</sub>
T15	VAREF
T16	GND

## 484-Pin FBGA

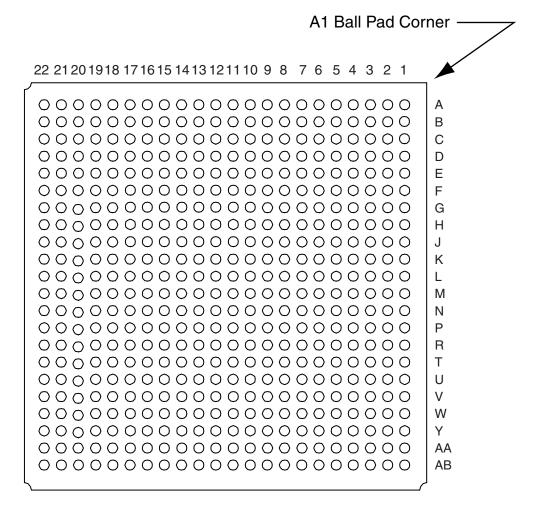


Figure 4-5 • 484-Pin FBGA (Bottom View)

#### Note

For Package Manufacturing and Environmental information, visit Resource center at http://www.actel.com/products/rescenter/package/index.html.

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484-Pin FBGA	
Pin Number	AFS600 Function
A1	GND
A2	V <sub>CC</sub>
А3	GAA1/IO01PDB0V0
A4	GAB0/IO02NDB0V0
A5	GAB1/IO02PDB0V0
A6	IO07NDB0V1
A7	IO07PDB0V1
A8	IO10PDB0V1
A9	IO14NDB0V1
A10	IO14PDB0V1
A11	IO17PDB1V0
A12	IO18PDB1V0
A13	IO19NDB1V0
A14	IO19PDB1V0
A15	IO24NDB1V1
A16	IO24PDB1V1
A17	GBC0/IO26NDB1V1
A18	GBA0/IO28NDB1V1
A19	IO29NDB1V1
A20	IO29PDB1V1
A21	V <sub>CC</sub>
A22	GND
AA1	V <sub>CC</sub>
AA2	GND
AA3	VMV4
AA4	V <sub>CCI</sub> B4
AA5	PCAP
AA6	AG0
AA7	GNDA
AA8	AG1
AA9	AG2
AA10	GNDA
AA11	AG3
AA12	AG6
AA13	GNDA
AA14	AG7

484-Pin FBGA	
Pin Number AFS600 Function	
AA15	AG8
AA16	GNDA
AA17	AG9
AA18	VAREF
AA19	V <sub>CCI</sub> B2
AA20	PTEM
AA21	GND
AA22	V <sub>CC</sub>
AB1	GND
AB2	V <sub>CC</sub>
AB3	NC
AB4	GND
AB5	V <sub>CC33N</sub>
AB6	AT0
AB7	ATRTN0
AB8	AT1
AB9	AT2
AB10	ATRTN1
AB11	AT3
AB12	AT6
AB13	ATRTN3
AB14	AT7
AB15	AT8
AB16	ATRTN4
AB17	AT9
AB18	V <sub>CC33ACAP</sub>
AB19	GND
AB20	NC
AB21	V <sub>CC</sub>
AB22	GND
B1	V <sub>CC</sub>
B2	GND
В3	GAA0/IO01NDB0V0
В4	GND
B5	IO05NDB0V0
В6	IO05PDB0V0

484-Pin FBGA	
Pin Number	AFS600 Function
В7	GND
В8	IO10NDB0V1
В9	IO13PDB0V1
B10	GND
B11	IO17NDB1V0
B12	IO18NDB1V0
B13	GND
B14	IO21NDB1V0
B15	IO21PDB1V0
B16	GND
B17	GBC1/IO26PDB1V1
B18	GBA1/IO28PDB1V1
B19	GND
B20	$V_{CCPLB}$
B21	GND
B22	V <sub>CC</sub>
C1	IO82PDB4V0
C2	NC
C3	IO00NDB0V0
C4	IO00PDB0V0
C5	V <sub>CCI</sub> B0
C6	IO06NDB0V0
C7	IO06PDB0V0
C8	V <sub>CCI</sub> B0
C9	IO13NDB0V1
C10	IO11PDB0V1
C11	V <sub>CCI</sub> B0
C12	V <sub>CCI</sub> B1
C13	IO20NDB1V0
C14	IO20PDB1V0
C15	V <sub>CCI</sub> B1
C16	IO25NDB1V1
C17	GBB0/IO27NDB1V1
C18	V <sub>CCI</sub> B1
C19	$V_{COMPLB}$
C20	GBA2/IO30PDB2V0

484-Pin FBGA	
Pin Number	AFS600 Function
C21	NC
C22	GBB2/IO31PDB2V0
D1	IO82NDB4V0
D2	GND
D3	IO83NDB4V0
D4	GAC2/IO83PDB4V0
D5	GAA2/IO85PDB4V0
D6	GAC0/IO03NDB0V0
D7	GAC1/IO03PDB0V0
D8	IO09NDB0V1
D9	IO09PDB0V1
D10	IO11NDB0V1
D11	IO16NDB1V0
D12	IO16PDB1V0
D13	NC
D14	IO23NDB1V1
D15	IO23PDB1V1
D16	IO25PDB1V1
D17	GBB1/IO27PDB1V1
D18	VMV2
D19	NC
D20	IO30NDB2V0
D21	GND
D22	IO31NDB2V0
E1	IO81NDB4V0
E2	IO81PDB4V0
E3	V <sub>CCI</sub> B4
E4	GAB2/IO84PDB4V0
E5	IO85NDB4V0
E6	GND
E7	V <sub>CCI</sub> B0
E8	NC
E9	NC
E10	GND
E11	IO15NDB1V0
E12	IO15PDB1V0

484-Pin FBGA	
Pin Number	AFS600 Function
E13	GND
E14	NC
E15	NC
E16	V <sub>CCI</sub> B1
E17	GND
E18	NC
E19	IO33PDB2V0
E20	V <sub>CCI</sub> B2
E21	IO32NDB2V0
E22	GBC2/IO32PDB2V0
F1	IO80NDB4V0
F2	IO80PDB4V0
F3	NC
F4	IO84NDB4V0
F5	GND
F6	$V_{COMPLA}$
F7	$V_{CCPLA}$
F8	VMV0
F9	IO08NDB0V1
F10	IO08PDB0V1
F11	V <sub>CCI</sub> B0
F12	V <sub>CCI</sub> B1
F13	IO22NDB1V0
F14	IO22PDB1V0
F15	VMV1
F16	NC
F17	NC
F18	GND
F19	IO33NDB2V0
F20	IO34PDB2V0
F21	IO34NDB2V0
F22	IO35PDB2V0
G1	IO77PDB4V0
G2	GND
G3	IO78NDB4V0
G4	IO78PDB4V0

484-Pin FBGA	
Pin Number	AFS600 Function
G5	V <sub>CCI</sub> B4
G6	NC
G7	VMV4
G8	GND
G9	IO04NDB0V0
G10	IO04PDB0V0
G11	IO12NDB0V1
G12	IO12PDB0V1
G13	NC
G14	NC
G15	GND
G16	NC
G17	NC
G18	V <sub>CCI</sub> B2
G19	IO36PDB2V0
G20	IO36NDB2V0
G21	GND
G22	IO35NDB2V0
H1	IO77NDB4V0
H2	IO76PDB4V0
H3	V <sub>CCI</sub> B4
H4	IO79NDB4V0
H5	IO79PDB4V0
H6	NC
H7	GND
Н8	V <sub>CC</sub>
H9	V <sub>CCI</sub> B0
H10	GND
H11	V <sub>CCI</sub> B0
H12	V <sub>CCI</sub> B1
H13	GND
H14	V <sub>CCI</sub> B1
H15	GND
H16	GND
H17	NC
H18	IO38PDB2V0

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484-Pin FBGA	
Pin Number	AFS600 Function
H19	GCA2/IO39PDB2V0
H20	V <sub>CCI</sub> B2
H21	IO37NDB2V0
H22	IO37PDB2V0
J1	NC
J2	IO76NDB4V0
J3	GFB2/IO74PDB4V0
J4	GFA2/IO75PDB4V0
J5	NC
J6	NC
J7	NC
J8	V <sub>CCI</sub> B4
J9	GND
J10	V <sub>CC</sub>
J11	GND
J12	V <sub>CC</sub>
J13	GND
J14	V <sub>CC</sub>
J15	V <sub>CCI</sub> B2
J16	GCB2/IO40PDB2V0
J17	NC
J18	IO38NDB2V0
J19	IO39NDB2V0
J20	GCC2/IO41PDB2V0
J21	NC
J22	IO42PDB2V0
K1	GFC2/IO73PDB4V0
K2	GND
K3	IO74NDB4V0
K4	IO75NDB4V0
K5	GND
K6	NC
K7	NC
K8	GND
K9	V <sub>CC</sub>
K10	GND

484-Pin FBGA	
Pin Number	AFS600 Function
K11	V <sub>CC</sub>
K12	GND
K13	V <sub>CC</sub>
K14	GND
K15	GND
K16	IO40NDB2V0
K17	NC
K18	GND
K19	NC
K20	IO41NDB2V0
K21	GND
K22	IO42NDB2V0
L1	IO73NDB4V0
L2	V <sub>ccosc</sub>
L3	V <sub>CCI</sub> B4
L4	XTAL2
L5	GFC1/IO72PDB4V0
L6	V <sub>CCI</sub> B4
L7	GFB1/IO71PDB4V0
L8	V <sub>CCI</sub> B4
L9	GND
L10	V <sub>CC</sub>
L11	GND
L12	V <sub>CC</sub>
L13	GND
L14	V <sub>CC</sub>
L15	V <sub>CCI</sub> B2
L16	IO48PDB2V0
L17	V <sub>CCI</sub> B2
L18	IO46PDB2V0
L19	GCA1/IO45PDB2V0
L20	V <sub>CCI</sub> B2
L21	GCC0/IO43NDB2V0
L22	GCC1/IO43PDB2V0
M1	NC
M2	XTAL1

Pin Number         AFS600 Function           M3         V <sub>CCI</sub> B4           M4         GNDOSC           M5         GFC0/IO72NDB4V0           M6         V <sub>CCI</sub> B4           M7         GFB0/IO71NDB4V0           M8         V <sub>CCI</sub> B4           M9         V <sub>CC</sub> M10         GND           M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCAO/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N10         V <sub>CC</sub> N11         GND           N10	484-Pin FBGA	
M4         GNDOSC           M5         GFC0/IO72NDB4V0           M6         V <sub>CCI</sub> B4           M7         GFB0/IO71NDB4V0           M8         V <sub>CCI</sub> B4           M9         V <sub>CC</sub> M10         GND           M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCAO/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N1         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND	Pin Number	AFS600 Function
M5         GFCO/IO72NDB4V0           M6         V <sub>CCI</sub> B4           M7         GFB0/IO71NDB4V0           M8         V <sub>CCI</sub> B4           M9         V <sub>CC</sub> M10         GND           M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCAO/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N10         V <sub>CC</sub> N11         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND	M3	V <sub>CCI</sub> B4
M6         V <sub>CCI</sub> B4           M7         GFB0/IO71NDB4V0           M8         V <sub>CCI</sub> B4           M9         V <sub>CC</sub> M10         GND           M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND <td>M4</td> <td>GNDOSC</td>	M4	GNDOSC
M7         GFB0/IO71NDB4V0           M8         V <sub>CCI</sub> B4           M9         V <sub>CC</sub> M10         GND           M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N13         GND	M5	GFC0/IO72NDB4V0
M8         V <sub>CCI</sub> B4           M9         V <sub>CC</sub> M10         GND           M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M6	V <sub>CCI</sub> B4
M9         V <sub>CC</sub> M10         GND           M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCAO/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M7	GFB0/IO71NDB4V0
M10         GND           M11         VCC           M12         GND           M13         VCC           M14         GND           M15         VCCIB2           M16         IO48NDB2V0           M17         VCCIB2           M18         IO46NDB2V0           M19         GCAO/IO45NDB2V0           M20         VCCIB2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         VCC           N11         GND           N12         VCC           N13         GND           N14         VCC           N15         GND	M8	V <sub>CCI</sub> B4
M11         V <sub>CC</sub> M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M9	V <sub>CC</sub>
M12         GND           M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M10	GND
M13         V <sub>CC</sub> M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M11	V <sub>CC</sub>
M14         GND           M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M12	GND
M15         V <sub>CCI</sub> B2           M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M13	V <sub>CC</sub>
M16         IO48NDB2V0           M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M14	GND
M17         V <sub>CCI</sub> B2           M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M15	V <sub>CCI</sub> B2
M18         IO46NDB2V0           M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M16	IO48NDB2V0
M19         GCA0/IO45NDB2V0           M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M17	V <sub>CCI</sub> B2
M20         V <sub>CCI</sub> B2           M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M18	IO46NDB2V0
M21         GCB0/IO44NDB2V0           M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M19	GCA0/IO45NDB2V0
M22         GCB1/IO44PDB2V0           N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M20	V <sub>CCI</sub> B2
N1         NC           N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M21	GCB0/IO44NDB2V0
N2         GND           N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	M22	GCB1/IO44PDB2V0
N3         IO68PDB4V0           N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N1	NC
N4         NC           N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N2	GND
N5         GND           N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N3	IO68PDB4V0
N6         NC           N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N4	NC
N7         NC           N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N5	GND
N8         GND           N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N6	NC
N9         GND           N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N7	NC
N10         V <sub>CC</sub> N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N8	GND
N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N9	GND
N11         GND           N12         V <sub>CC</sub> N13         GND           N14         V <sub>CC</sub> N15         GND	N10	V <sub>CC</sub>
N13 GND  N14 V <sub>CC</sub> N15 GND	N11	
N14 V <sub>CC</sub> N15 GND	N12	V <sub>CC</sub>
N15 GND	N13	GND
N15 GND	N14	V <sub>CC</sub>
N16 GDB2/IO56PDB2V0	N15	
	N16	GDB2/IO56PDB2V0

484-Pin FBGA	
Pin Number	AFS600 Function
N17	NC
N18	GND
N19	IO47NDB2V0
N20	IO47PDB2V0
N21	GND
N22	IO49PDB2V0
P1	GFA1/IO70PDB4V0
P2	GFA0/IO70NDB4V0
P3	IO68NDB4V0
P4	IO65PDB4V0
P5	IO65NDB4V0
P6	NC
P7	NC
P8	V <sub>CCI</sub> B4
P9	V <sub>CC</sub>
P10	GND
P11	V <sub>CC</sub>
P12	GND
P13	V <sub>CC</sub>
P14	GND
P15	V <sub>CCI</sub> B2
P16	IO56NDB2V0
P17	NC
P18	GDA1/IO54PDB2V0
P19	GDB1/IO53PDB2V0
P20	IO51NDB2V0
P21	IO51PDB2V0
P22	IO49NDB2V0
R1	IO69PDB4V0
R2	IO69NDB4V0
R3	V <sub>CCI</sub> B4
R4	IO64PDB4V0
R5	IO64NDB4V0
R6	NC
R7	GND
R8	GND

484-Pin FBGA	
Pin Number	AFS600 Function
R9	V <sub>CC33A</sub>
R10	GNDA
R11	V <sub>CC33A</sub>
R12	GNDA
R13	V <sub>CC33A</sub>
R14	GNDA
R15	V <sub>CC</sub>
R16	GND
R17	NC
R18	GDA0/IO54NDB2V0
R19	GDB0/IO53NDB2V0
R20	V <sub>CCI</sub> B2
R21	IO50NDB2V0
R22	IO50PDB2V0
T1	NC
T2	GND
T3	IO66PDB4V0
T4	IO66NDB4V0
T5	V <sub>CCI</sub> B4
T6	NC
T7	GNDNVM
T8	GNDA
Т9	NC
T10	AV4
T11	NC
T12	AV5
T13	AC5
T14	NC
T15	GNDA
T16	NC
T17	NC
T18	V <sub>CCI</sub> B2
T19	IO55NDB2V0
T20	GDA2/IO55PDB2V0
T21	GND
T22	GDC1/IO52PDB2V0

484-Pin FBGA	
Pin Number	AFS600 Function
U1	IO67PDB4V0
U2	IO67NDB4V0
U3	GEC1/IO63PDB4V0
U4	GEC0/IO63NDB4V0
U5	GND
U6	$V_{CCNVM}$
U7	V <sub>CCI</sub> B4
U8	V <sub>CC15A</sub>
U9	GNDA
U10	AC4
U11	V <sub>CC33A</sub>
U12	GNDA
U13	AG5
U14	GNDA
U15	PUB
U16	V <sub>CCI</sub> B2
U17	TDI
U18	GND
U19	IO57NDB2V0
U20	GDC2/IO57PDB2V0
U21	NC
U22	GDC0/IO52NDB2V0
V1	GEB1/IO62PDB4V0
V2	GEB0/IO62NDB4V0
V3	V <sub>CCI</sub> B4
V4	GEA1/IO61PDB4V0
V5	GEA0/IO61NDB4V0
V6	GND
V7	V <sub>CC33PMP</sub>
V8	NC
V9	V <sub>CC33A</sub>
V10	AG4
V11	AT4
V12	ATRTN2
V13	AT5
V14	V <sub>CC33A</sub>

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484-Pin FBGA	
Pin Number	AFS600 Function
V15	NC
V16	V <sub>CC33A</sub>
V17	GND
V18	TMS
V19	$V_{JTAG}$
V20	V <sub>CCI</sub> B2
V21	TRST
V22	TDO
W1	NC
W2	GND
W3	NC
W4	GEB2/IO59PDB4V0
W5	IO59NDB4V0
W6	AV0
W7	GNDA
W8	AV1
W9	AV2
W10	GNDA
W11	AV3
W12	AV6
W13	GNDA
W14	AV7
W15	AV8
W16	GNDA
W17	AV9
W18	VMV2
W19	NC
W20	TCK
W21	GND
W22	NC
Y1	GEC2/IO60PDB4V0
Y2	IO60NDB4V0
Y3	GEA2/IO58PDB4V0
Y4	IO58NDB4V0
Y5	NCAP
Y6	AC0

484	4-Pin FBGA
Pin Number	AFS600 Function
Y7	V <sub>CC33A</sub>
Y8	AC1
Y9	AC2
Y10	V <sub>CC33A</sub>
Y11	AC3
Y12	AC6
Y13	V <sub>CC33A</sub>
Y14	AC7
Y15	AC8
Y16	V <sub>CC33A</sub>
Y17	AC9
Y18	ADCGNDREF
Y19	PTBASE
Y20	GNDNVM
Y21	$V_{CCNVM}$
Y22	V <sub>PUMP</sub>

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## 676-Pin FBGA

#### A1 Ball Pad Corner

В 000000000000000000000000 C D E F G Н J K L M Ν R Т U ٧ W Υ 0000000000000000000000000 AA AB AC AD ΑE AF

2625 2423 2221 201918 171615 1413 1211 10 9 8 7 6 5 4 3 2 1

Figure 4-6 • 676-Pin FBGA (Bottom View)

#### Note

For Package Manufacturing and Environmental information, visit Resource center at http://www.actel.com/products/rescenter/package/index.html.

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# **Datasheet Information**

# **List of Changes**

The following table lists critical changes that were made in the current version of the document.

Changes in Current Version (Advanced v0.7)				
The AFS1500-FG484 and AFS1500-FG676 user I/O counts were updated in the "Package I/O Single/Double-Ended (Analog)" table.				
The second paragraph of the "PLL Macro" section was updated to include information about POWERDOWN.				
The description for bit 0 was updated in Table 2-16 • RTC Control/Status Register.	2-34			
3.9 was changed to 7.8 in the "Crystal Oscillator (Xtal Osc)" section.	2-35.			
All function descriptions in Table 2-17 • Signals for VRPSM Macro.	2-36			
In Table 2-18 • Flash Memory Block Pin Names, the RD[31:0] description was updated.	2-38			
The "RESET" section was updated.	2-53			
The "RESET" section was updated.	2-55			
Table 2-33 • FIFO was updated.	2-65			
The VAREF function description was updated in Table 2-34 • Analog Block Pin Description.	2-67			
The "Voltage Monitor" section was updated to include information about low power mode and sleep mode.	2-71			
The text in the "Current Monitor" section was changed from 2 mV to 1 mV.	2-74			
The "Gate Driver" section was updated to include information about forcing 1 V on the drain.	2-76			
The "Analog to Digital Converter Block" section was updated with the following statement: "All results are MSB justified in the ADC."	2-80			
The information about the ADCSTART signal was updated in the "ADC Description" section.	2-83			
Table 2-40 • Electrical Specifications was updated.	2-86			
Table 2-41 • ADC Characteristics in Direct Input Mode was updated.	2-88			
Table 2-42 • ACM Address Decode Table for Analog Quad was updated.	2-89			
In Table 2-44 • Analog Quad ACM Byte Assignment, the Function and Default Setting for Bit 6 in Byte 3 was updated.	2-92			
The "Introduction" section was updated to include information about digital inputs, outputs, and bibufs.	2-95			
In Table 2-59 • Fusion Pro I/O Features, the programmable delay descriptions were updated for the following features:  • Single-ended receiver  • Voltage-referenced differential receiver  • IVDS/IVPECL differential receiver features	2-99			
	2-120			
	The AFS1500-FG484 and AFS1500-FG676 user I/O counts were updated in the "Package I/Os: Single/Double-Ended (Analog)" table.  The second paragraph of the "PLL Macro" section was updated to include information about POWERDOWN.  The description for bit 0 was updated in Table 2-16 • RTC Control/Status Register.  3.9 was changed to 7.8 in the "Crystal Oscillator (Xtal Osc)" section.  All function descriptions in Table 2-17 • Signals for VRPSM Macro.  In Table 2-18 • Flash Memory Block Pin Names, the RD[31:0] description was updated.  The "RESET" section was updated.  The "RESET" section was updated.  Table 2-33 • FIFO was updated.  The "Voltage Monitor" section was updated in Table 2-34 • Analog Block Pin Description.  The "Voltage Monitor" section was updated to include information about low power mode and sleep mode.  The text in the "Current Monitor" section was changed from 2 mV to 1 mV.  The "Gate Driver" section was updated to include information about forcing 1 V on the drain.  The "Analog to Digital Converter Block" section was updated with the following statement: "All results are MSB justified in the ADC."  The information about the ADCSTART signal was updated in the "ADC Description" section.  Table 2-40 • Electrical Specifications was updated.  Table 2-41 • ADC Characteristics in Direct Input Mode was updated.  In Table 2-44 • Analog Quad ACM Byte Assignment, the Function and Default Setting for Bit 6 in Byte 3 was updated.  The "Introduction" section was updated to include information about digital inputs, outputs, and bibufs.			

<b>Previous Version</b>	Changes in Current Version (Advanced v0.7)				
Advanced v0.5 (June 2006)	The "V <sub>CC33PMP</sub> Analog Power Supply (3.3 V)" section was updated to include information about avoiding high current draw.				
	The "V <sub>CCNVM</sub> Flash Memory Block Power Supply (1.5 V)" section was updated to include information about avoiding high current draw.				
	The "VMVx I/O Supply Voltage (quiet)" section was updated to include this statement: VMV and $V_{CCI}$ must be connected to the same power supply and $V_{CCI}$ pins within a given I/O bank.				
	The "PUB Power Up Bar" section was updated to include information about leaving the pin floating if it is not used.				
	The "PTBASE Pass Transistor Base" section was updated to include information about leaving the pin floating if it is not used.				
	The "PTEM Pass Transistor Emitter" section was updated to include information about leaving the pin floating if it is not used.				
	Table 3-3 • Required Conditions to Avoid Stress on Analog Input Pads is new.	3-2			
	The heading was incorrect in the "208-Pin PQFP" table. It should be AFS250 and not AFS090.	4-9			
Advanced v0.4	The low power modes of operation were updated and clarified.	N/A			
(April 2006)	The AFS1500 digital I/O count was updated in Table 1 • Fusion Family.	i			
	The AFS1500 digital I/O count was updated in the "Package I/Os: Single/Double-Ended (Analog)" table.				
	The "Voltage Regulator Power Supply Monitor (VRPSM)" section was updated.	2-36			
	Figure 2-45 • FlashROM Timing Diagram was updated.	2-50			
	The "256-Pin FBGA" table for the AFS1500 is new.	4-23			
Advanced v0.3 (April 2006)	The G was moved in the "Product Ordering Codes" section.				
Advanced v0.2	The "Features and Benefits" section was updated.	i			
(April 2006)	Table 1 • Fusion Family table was updated.				
	"Package I/Os: Single/Double-Ended (Analog)" section was updated.	ii			
	"Product Ordering Codes" section was updated.	iii			
	"Temperature Grade Offerings" section was updated.	iv			
	The "General Description" section was updated to include ARM information.	1-1			
	The "FlashROM" section was updated.	2-50			
	"RESET" section was updated.	2-53			
	"RESET" section was updated.	2-55			
	Figure 2-27 • Real-Time Counter System was updated.	2-31			
	Table 2-18 • Flash Memory Block Pin Names was updated.	2-38			
	Figure 2-32 • Flash Memory Block Diagram was updated to include AUX block information.	2-39			
	Figure 2-33 • Flash Memory Block Organization was updated to include AUX block information.	2-40			
	The note in the "Program Operation" section was updated.	2-42			

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<b>Previous Version</b>	Changes in Current Version (Advanced v0.7)	Page		
Advanced v0.2	.2 Figure 2-69 • Gate Driver Example was updated.			
(continued)	The "Analog Quad ACM Description" section was updated.			
	Information about the maximum pad input frequency was added to the "Gate Driver" section.			
	Figure 2-61 • Analog Block Macro was updated.	2-76		
	Figure 2-61 • Analog Block Macro was updated.			
	The "Analog Quad" section was updated.	2-69		
	The "Voltage Monitor" section was updated.			
l	The "Direct Digital Input" section was updated.	2-73		
	The "Current Monitor" section was updated.	2-74		
	Information about the maximum pad input frequency was added to the "Gate Driver" section.	2-76		
	The "Temperature Monitor" section was updated.	2-78		
	EQ 2-6 is new.	2-83		
	The "ADC Description" section was updated.	2-83		
	Figure 2-16 • Fusion Clocking Options was updated.	2-18		
	Table 2-40 • Electrical Specifications was updated.	2-86		
	The notes in Table 2-62 • Fusion Standard, LVDS, and Standard Plus Hot-Swap I/O Hot-Swap and 5 V Input Tolerance Capabilities were updated.	2-105		
	The "Simultaneous Switching Outputs and Printed Circuit Board Layout" section is new.	2-111		
	LVPECL and LVDS were updated in Table 2-70 • Fusion Standard and LVDS I/O Attributes vs. I/O Standard Applications.	2-118		
	LVPECL and LVDS were updated in Table 2-71 • Fusion Pro I/O Attributes vs. I/O Standard Applications.	2-118		
	The "Timing Model" section was updated.	2-122		
	All voltage-referenced Minimum and Maximum DC Input and Output Level tables were updated.	N/A		
	All Timing Characteristic tables were updated	N/A		
	Table 2-73 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions was updated.	2-126		
	Table 2-77 • Summary of I/O Timing Characteristics – Software Default Settings was updated.	2-129		
	Table 2-79 • I/O Output Buffer Maximum Resistances1 was updated.	2-130		
	The "BLVDS/M-LVDS" section is new. BLVDS and M-LVDS are two new I/O standards included in the datasheet.	2-155		
	The "CoreMP7 Software Tools" section is new.	2-171		
	Table 3-8 • Quiescent Supply Current Characteristics (IDDQ)1 was updated.	3-7		
	Table 3-11 • Different Components Contributing to the Dynamic Power Consumption in Fusion Devices was updated.	3-10		
	Table 3-12 • Different Components Contributing to the Static Power Consumption in Fusion Devices was updated.	3-11		

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<b>Previous Version</b>	Changes in Current Version (Advanced v0.7)				
Advanced v0.2	The "Example of Power Calculation" section was updated.				
(continued)	The Analog System information was deleted from Table 3-15 • Power Consumption.				
	The "108-Pin QFN" table for the AFS090 device is new.	4-2			
	The "180-Pin QFN" table for the AFS090 device is new.	4-6			
	The "208-Pin PQFP" table for the AFS090 device is new.	4-9			
	The "256-Pin FBGA" table for the AFS090 device is new.	4-14			
	The "256-Pin FBGA" table for the AFS090 device is new.	4-17			

# **Datasheet Categories**

In order to provide the latest information to designers, some datasheets are published before data has been fully characterized. Datasheets are designated as "Product Brief," "Advanced," "Production," and "Datasheet Supplement." The definitions of these categories are as follows:

#### **Product Brief**

The product brief is a summarized version of a datasheet (advanced or production) containing general product information. This brief gives an overview of specific device and family information.

#### **Advanced**

This datasheet version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production.

# **Unmarked (production)**

This datasheet version contains information that is considered to be final.

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The datasheet supplement gives specific device information for a derivative family that differs from the general family datasheet. The supplement is to be used in conjunction with the datasheet to obtain more detailed information and for specifications that do not differ between the two families.

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